

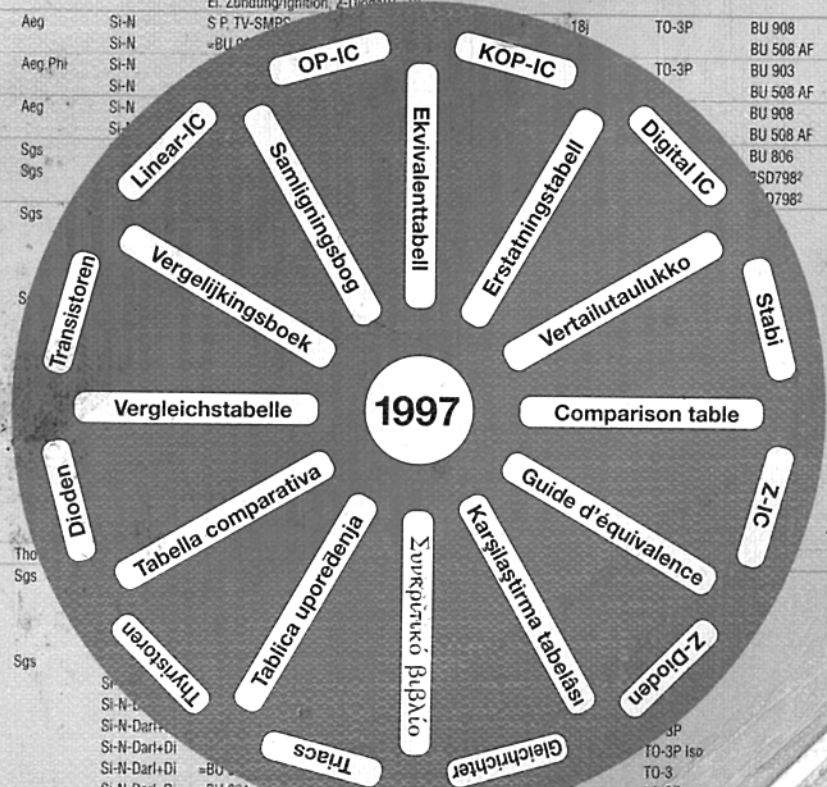
# JAEGER ELEKTRONIK

## SEMICON 1997

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
BUK 427-800A,B	Phi	MOS-N-FET-e	VFET, 600/30V, 45W, 80/275ns(2,8A) A: 4.3/17A, <1Ω(6.5A), B: 3.9/16A, <1.2Ω(6.5A)	16c	SOT-199		BUK 727-600, 2SK1463, 2SK1684, 2SK1859
BUK 428-500A,B	Phi	MOS-N-FET-e	VFET, 500/30V, 45W, 120/410ns(2.9A) A: 6.8/27A, <0.4Ω(8A), B: 6.1/24A, <0.5Ω(8A)	16c	SOT-199		2SK1206, 2SK1523, 2SK1696, 2SK1832
BUK 428-800A,B	Phi	MOS-N-FET-e	VFET, 800/30V, 45W, 160/450ns(2.6A) A: 3.4/14A, <1.5Ω(4A), B: 3/12A, <2Ω(4A)	16c	SOT-199		2SK809A, 2SK1463, 2SK1684, 2SK1859
BUK 428-1000A,B	Phi	MOS-N-FET-e	VFET, 1000/30V, 45W, 160/450ns(2.5A) A: 2.9/12A, <2Ω(3.5A), B: 2.6/10A, <2.6Ω(3.5A)	16c	SOT-199		BUK 426-1000, 2SK1770
BUK 436-50A,B	Phi	MOS-N-FET-e	-BUK 426-50A, B: A=50/200A, B=46/184A, 125W	18p	TO-3P		BUZ 346, 2SK1297, 2SK1379, 2SK1514
BUK 436-60A,B	Phi	MOS-N-FET-e	-BUK 426-60A, B: A=50/200A, B=46/184A, 125W	18p	TO-3P		2SK1297, 2SK1379, 2SK1514, 2SK2096
BUK 436-100A,B	Phi	MOS-N-FET-e	-BUK 426-100A, B: A=33/132A, B=31/124A, 125W	18p	TO-3P		BUZ 345, 2SK850, 2SK906, 2SK1429, ++

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
KSV 3100 ACN-....	Sam	A/D-D/A-IC	8-Bit A/D + 10 Bit D/A-Converter	40	DIP		
KSV 3110(CN-....)	Sam	A/D-D/A-IC	8 Bit A/D + 10 Bit D/A-Conv., Video, TTL In/Out	40	DIP		
KSV 3208(CN)	Sam	A/D-IC	8 Bit, hi-speed, TV, Video, 20MSPS, TTL In/Out	28	DIP		
KSV 3310	Sam	D/A-IC	10 Bit, TV, Video, 20MHz	28	DIP		
KSV 3404	Sam						
KSY 13	Sie						

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International	
KT								
KT 208(A...V)	GUS							
KT 209(A...V)	GUS							
KT 814 A,B,G,V	GUS							
KT 815 A,B,G,V	GUS							
KT 816 A,B,G,V	GUS							
KT 817 A,B,G,V	GUS							
KT 818 A,B,G,V	GUS							
KT 819 A,B,G,V	GUS							
KT 3030	Sam							
KT 3031	Sam							
KT 3032	Sam							
KT 3033	Sam							
KT 3040 J	Sam							
KT 3054 J	Sam							
KT 3064 J	Sam							
KT 3107(A...V)	GUS							
KT 3170 J,N	Sam							
KT 5116 J	Sam							
KT 8518	Sam							
KT 8520	Sam							
KT 8521	Sam							
KT 8554(J)	Sam							
KT 8555(J)	Sam							
KT 8557(J)	Sam							
KT 8592(N)	Sam							
KT 8593(N)	Sam							
KTA 200	Kec							
KTA 473	Kec							
KTA 940	Kec							
KTA 950	Kec							
KTA 958(A)	Kec							
KTA 1001	Kec							
KTA 1015	Kec							
KTA 1021	Kec							
KTA 1023	Kec							
KTA 1024	Kec							
KTA 1070	Kec							
KTA 1270	Kec							
KTA 1271	Kec							
KTA 1272	Kec							
KTA 1273	Kec							
KTA 1274	Kec							
KTA 1275	Kec							
BU 806	Phi,Sgs,Tix	Si-N-Darl+Di	TV-HA, 400/200V, 8/15A, 60W, sat<1.5V(5A)	17j	TO-220	BU 806	17j	BU 18
BU 806 AF		Si-N-Darl+Di	-BU 806 Iso	17c				
BU 806 FI	Tho	Si-N-Darl+Di	-BU 806: Iso, 30W	17c	TO-220Iso			
BU 807	Phi,Sgs,Tix	Si-N-Darl+Di	-BU 806: 330/150V	17j	TO-220	BU 806	17j	BU 18
BU 807 FI	Tho	Si-N-Darl+Di	-BU 807: Iso, 30W	17c	TO-220Iso			
BU 808 DF1 [SGS]	Sgs	Si-N-Darl+Di	-BU 808FI: integr. Damper-Diode	18c	TO-3P Iso			
BU 808 FI [SGS]	Sgs	Si-N-Darl	CTV-HA, 1400/700V, 5/10A, 50W, hFE>25 sat<1.6V(5A)	18c	TO-3P Iso			
BU 808 [Philips]	Phi	Si-N	3Ph.-Motor Drv, 1500/700V, 12/20A, 160W, sat<1V(9V)	23a	TO-3			BUX 8
BU 810	Sgs	Si-N-Darl+Di	S P, 600/400V, 7/10A, 75W, <0.6/2ps, sat<3V(7A)	17j	TO-220	2SD798	17j	2SC35
BU 824	Phi	Si-N-Darl+Di	S P, 650/375V, 0.5/1A, 12.5W, hFE>325, <1/2.5ps	13h	TO-202			
BU 826	Phi	Si-N-Darl+Di	S P, 800/375V, 6/8A, 125W, <1.3/2.2ps, sat<2.5V(4A)	18j	TO-3P	BU 826	18j	BU
BU 826 A		Si-N-Darl+Di	-BU 826: 1000/400V	18j	TO-3P			
BU 900	Tho	Si-N-Darl	Tripletion, 650/400V, 8A, 70W, hFE>7000, sat<4V(3A) El. Zündung/Ignition, Z-Diode	17j	TO-220			
BU 902	Aeg	Si-N	S P, TV-SMPS	18j	TO-3P	BU 908	16j	BU 50
BU 902 F		Si-N	-BU 902			BU 508 AF	16c	BU 50
BU 903	Aeg,Phi	Si-N			TO-3P	BU 903	18j	BU 50
BU 903 F		Si-N				BU 508 AF	16c	BU 50
BU 908	Aeg	Si-N				BU 908	18j	BU 50
BU 908 AF		Si-N				BU 508 AF	16c	BU 50
BU 910	Sgs					BU 806	17j	BU 80
BU 911	Sgs					2SD798	17j	2SD7
BU 912						2SD798	17j	2SD7
BU 920	Sgs							
BU 920 P								
BU 920 PFI								
BU 920 T								
BU 921	S							2SD1
BU 921 P								BU 93
BU 921 PFI								BU 93
BU 921 T								
BU 921 ZP								2SD1
BU 921 ZPFI								
BU 921 ZT								
BU 921 ZTFI								
BU 922								
BU 922 P								
BU 922 PFI								
BU 922 T								
BU 926	Tho							
BU 930	Sgs							18j
BU 930 P								BUV 4
BU 930 Z								BUT 13
BU 930 ZP								BUT 51
BU 931 R								
BU 931 RPI								
BU 931 Z								
BU 931 ZP								
BU 931 ZPFI								
BU 932	Sgs							
BU 932 P								
BU 932 R								



80.000 types

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International	
N								
N		GaAs-N-FET	=2SK1963 (SMD-Marking)	51	SOT-173		=2SK1963	
N 0		Si-N	=BFS 505 (SMD-Marking)	35(2mm)	SOT-323		=BFS 505	
N 1	Itt	Si-Di	Uni, 30V, Uf<1V(0,1A)	31a		1N4148	31a	BA 127, BAY 18...21, 1N4148...49, ++
N 1		Si-N	=BFR 53 (SMD-Marking)	35	SOT-23		=BFR 53	
N 1		Si-P	=D71F2T1 (SMD-Marking)	39	SOT-89		=D71F2T1	
N 1		Si-N+R	=RT 1N137P (SMD-Marking)	39	SOT-89		=RT 1N137P	
N 1		Si-N+R	=RT 1N141C (SMD-Marking)	35	SOT-23		=RT 1N141C	
N 1		Si-N+R	=RT 1N141M (SMD-Marking)	35(2mm)	SOT-323		=RT 1N141M	
N 2		Si-Di	=BA 127	31a		1N4148	31a	=BA 127
N 2		Si-N	=2SC1653-N2 (SMD-Marking)	35	SOT-23		=2SC1653	
N 2		Si-N	=BFS 520 (SMD-Marking)	35(2mm)	SOT-323		=BFS 520	
N 2		Si-N+R	=RT 1N241C (SMD-Marking)	35	SOT-23		=RT 1N241C	
N 2		Si-N+R	=RT 1N241M (SMD-Marking)	35(2mm)	SOT-323		=RT 1N241M	
N 3		Si-N	=2SC1653-N3 (SMD-Marking)	35	SOT-23		=2SC1653	
N 3		Si-N+R	=RT 1N441C (SMD-Marking)	35	SOT-23		=RT 1N441C	
N 3		Si-N+R	=RT 1N441M (SMD-Marking)	35(2mm)	SOT-323		=RT 1N441M	
N 4		Si-N	=2SC1653-N4 (SMD-Marking)	35	SOT-23		=2SC1653	
N 4		Si-N	=BFR 53R (SMD-Marking)	35	SOT-23		=BFR 53R	
N 4		Si-N	=BFS 540 (SMD-Marking)	35(2mm)	SOT-323		=BFS 540	
N 4		Si-N+R	=RT 1N434C (SMD-Marking)	35	SOT-23		=RT 1N434C	
N 4		Si-N+R	=RT 1N434M (SMD-Marking)	35(2mm)	SOT-323		=RT 1N434M	
N 5		Si-N	=2SC1653-N5 (SMD-Marking)	35	SOT-23		=2SC1653	
N 5		Si-N+R	=RT 1N144C (SMD-Marking)	35	SOT-23		=RT 1N144C	
N 5		Si-N+R	=RT 1N144M (SMD-Marking)	35(2mm)	SOT-323		=RT 1N144M	
N 6		Si-Di	=1N4148	31a		1N4148	31a	=1N4148
N 6		Si-N	=2SC1653-N6 (SMD-Marking)	35	SOT-23		=2SC1653	
N 6		Si-N	=BFS 25A (SMD-Marking)	35(2mm)	SOT-323		=BFS 25A	
N 6		Si-N+R	=RT 1N430C (SMD-Marking)	35	SOT-23		=RT 1N430C	
N 6		Si-N+R	=RT 1N430M (SMD-Marking)	35(2mm)	SOT-323		=RT 1N430M	
N 7		Si-N	=2SC1653-N7 (SMD-Marking)	35	SOT-23		=2SC1653	
N 7		Si-N+R	=RT 1N140C (SMD-Marking)	35	SOT-23		=RT 1N140C	
N 7		Si-N+R	=RT 1N140M (SMD-Marking)	35(2mm)	SOT-323		=RT 1N140M	
N 8	Itt	Si-Di	Uni, 20V, Uf<1V(10mA), 1.5pF(0V)	31a		1N4148	31a	BA 127, BAY 17...21, 1N4148...49, ++
N 9		Si-Di	=1SS372 (SMD-Marking)	35(2mm)	SOT-323		=1SS372	
N 9		Si-Di	=1SS374 (SMD-Marking)	35	SOT-23		=1SS374	
N 10		Si-Di	=BA 176	31a		BA 159	31a	=BA 176
N 10		Si-N	=SO 918 (SMD-Marking)	35	SOT-23		=SO 918	
N 11	Itt	Si-Di	Uni, 20V, Uf=0,66...0,82V	31a		1N4148	31a	BA 127, BAY 17...21, 1N4148...49, ++
N 11		N-FET	=2SK334-N11 (SMD-Marking)	35	SOT-23		=2SK334	
N 11		Si-N	=SO 2369 (SMD-Marking)	35	SOT-23		=SO 2369	
N 12		Si-Di	=BA 127	31a		1N4148	31a	=BA 127
N 12		N-FET	=2SK334-N12 (SMD-Marking)	35	SOT-23		=2SK334	
N 12		Si-N	=SO 2221 (SMD-Marking)	35	SOT-23		=SO 2221	
N 13		Si-N	=SO 2222 (SMD-Marking)	35	SOT-23		=SO 2222	
N 13		N-FET	=2SK334-N13 (SMD-Marking)	35	SOT-23		=2SK334	
N 13 H1	Nec	PUT	=2N6027	2a	TO-18	=2N6027		=2N6027
N 13 H2	Nec	PUT	=2N6028	2a	TO-18	=2N6028		=2N6028
N 13 T1	Nec	PUT	=2N6027	7a	TO-92			=2N6027
N 13 T2	Nec	PUT	=2N6028	7a	TO-92			=2N6028
N 14		N-FET	=2SK334-N14 (SMD-Marking)	35	SOT-23		=2SK334	
N 14 0		Si-N+R	=RT 1N140S (SMD-Marking)	41	(TO-92S)		=RT 1N140S	
N 14 1		Si-N+R	=RT 1N141S (SMD-Marking)	41	(TO-92S)		=RT 1N141S	
N 14 4		Si-N+R	=RT 1N144S (SMD-Marking)	41	(TO-92S)		=RT 1N144S	
N 15		Si-N	=2SC3360-N15 (SMD-Marking)	35	SOT-23		=2SC3360	
N 16		Si-N	=2SC3360-N16 (SMD-Marking)	35	SOT-23		=2SC3360	
N 17		Si-Di	Uni, 20V, Uf<1V(0,1A)	31a		1N4148	31a	BA 127, BAY 17...21, 1N4148...49, ++
N 17		Si-N	=2SC3360-N17 (SMD-Marking)	35	SOT-23		=2SC3360	
N 17		Si-N	=SO 1613 (SMD-Marking)	35	SOT-23		=SO 1613	
N 18		Si-N	=SO 1711 (SMD-Marking)	35	SOT-23		=SO 1711	
N 20	Itt	Si-Di	SS, 75/100V, Uf=0,62...0,72V(5V), <1V(0,1A), <4ns	31a		1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148...49, ++
N 20		Si-N	=SO 2222A (SMD-Marking)	35	SOT-23		=SO 2222A	
N 24	Itt	Si-Di	Uni, 35V, Uf<1V(0,1A)	31a		1N4148	31a	BA 127, BAY 18...21, 1N4148...49, ++
N 24 1		Si-N+R	=RT 1N241S (SMD-Marking)	41	(TO-92S)		=RT 1N241S	
N 27		Si-N	=SO 1893 (SMD-Marking)	35	SOT-23		=SO 1893	
N 28		Si-N	=BFR 520 (SMD-Marking)	35	SOT-23		=BFR 520	
N 28		Si-N	=SO 3572 (SMD-Marking)	35	SOT-23		=SO 3572	
N 30		Si-N	=BFR 505 (SMD-Marking)	35	SOT-23		=BFR 505	
N 32	Itt	Si-Di	Uni, 10V, Uf<1V(50mA)	31a		1N4148	31a	BA 127, BAY 17...21, 1N4148...49, ++
N 33		Si-N	=BFG 505 (SMD-Marking)	44	SOT-143		=BFG 505	
N 36		Si-N	=BFG 520 (SMD-Marking)	44	SOT-143		=BFG 520	
N 37		Si-N	=BFG 540 (SMD-Marking)	44	SOT-143		=BFG 540	
N 39		Si-N	=BFG 505X (SMD-Marking)	44	SOT-143		=BFG 505X	
N 42		Si-N	=BFG 520X (SMD-Marking)	44	SOT-143		=BFG 520X	
N 43		Si-N	=BFG 540X (SMD-Marking)	44	SOT-143		=BFG 540X	
N 43 0		Si-N+R	=RT 1N430S (SMD-Marking)	41	(TO-92S)		=RT 1N430S	
N 43 4		Si-N+R	=RT 1N434S (SMD-Marking)	41	(TO-92S)		=RT 1N434S	
N 44		Si-N	=SO 3571 (SMD-Marking)	35	SOT-23		=SO 3571	
N 44 1		Si-N+R	=RT 1N441S (SMD-Marking)	41	(TO-92S)		=RT 1N441S	
N 45		Si-N	=BFG 505XR (SMD-Marking)	44	SOT-143		=BFG 505XR	
N 47		Si-N	=SO 3570 (SMD-Marking)	35	SOT-23		=SO 3570	
N 48		Si-N	=BFG 520XR (SMD-Marking)	44	SOT-143		=BFG 520XR	
N 49		Si-N	=BFG 540XR (SMD-Marking)	44	SOT-143		=BFG 540XR	
N 54		Si-N	=SO 2221A (SMD-Marking)	35	SOT-23		=SO 2221A	
N 62		Si-Di	=BA 127	31a		1N4148	31a	=BA 127
N 66		Si-N	=SO 269 (SMD-Marking)	35	SOT-23		=SO 269	
N 71		Si-N	=SO 3904 (SMD-Marking)	35	SOT-23		=SO 3904	
N 72		Si-N	=SO 3903 (SMD-Marking)	35	SOT-23		=SO 3903	
N 74....	Phi	TTL-Logic	=74....-Serie (TTL-Logic)					... 74.... (TTL-Logic)
N 79		Si-N	=SO 5550 (SMD-Marking)	35	SOT-23		=SO 5550	
N 80		Si-N	=SO 5551 (SMD-Marking)	35	SOT-23		=SO 5551	
N 81		Si-N	=SO 2369A (SMD-Marking)	35	SOT-23		=SO 2369A	

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
N 87		Si-N	=SO 502S (SMD-Marking)	35		SOT-23	-SO 502S
N 88		Si-P	=SO 970(SMD-Marking)	35		SOT-23	-SO 970
N 91		Si-N	=SO 642(SMD-Marking)	35		SOT-23	-SO 642
N 94		Si-N	=SO 517 (SMD-Marking)	35		SOT-23	-SO 517
N 103	Itt	Si-Di	Uni, 50V, Uf<1,42(0,4A)	31a	BY 133	31a	BY 126...127, BY 133...135, 1N4001...07, ++
N 125	Tsm	Si-Di	Uni, 50V, 0,15A, Uf<1(0,1A), 2pF(0V)	31a	DO-35	1N4148	BA 127, BAY 18...21, 1N4148...49, ++
N 180		Si-Di	=1N4148	31a		1N4148	-1N4148
N 203 A...YY	Nec	50Hz-Thy	0,5A, 0,8A-(Tc=25°), Igt/Ih<0,2/<5mA, tq=25µs A=100V, B=200V, C=300V, D=400V, YY=50V	7n	TO-92	BRX 49	7a BT 149/..., TAG 59-..., 2N6681...85
N 213	Nec	SBS	=N 313: SMD, 0,1A, 0,135W	35(AAG)	SOT-23		-
N 313	Nec	SBS	0,175A, Itrm=1A, Itsm=5A, 0,3W, Ub=7...9V, Is<0,2mA ΔU<0,5V, ΔIs<0,1µA, lh<1,5mA	7p(AGA)	TO-92		BS 08A, 2N4992
N 413 L	Nec	Diac	Ub=26...32V, Ib<0,05mA, Itsm=2A	31	DO-7		1N5761, D3202U
N 413 M		Diac	=N413L: Ub=29...37V	31	DO-7		1N5762, D3202Y, BR100, DO201YR
N 413 N		Diac	=N413L: Ub=34...40V	31	DO-7		1N5762, D3202U
N 3101 A	Phi	RAM-IC	64x4 Bit, TTL Bipolar		16-DIP		-
N 3101 ?	Phi	RAM-IC	=N 3101A: Min		16-MDIP		-
N 9401(N)	Phi	DIG-IC	CRC Generator/Check, 12MHz				-
N 9403(N)	Phi	FIFO-IC	16x4 Bit, ser./par., 10MHz Transfer				-
<b>NA</b>							
NA		MOS-N-FET-e	=2SK1273 (SMD-Marking)	39		SOT-89	-2SK1273
NA		Si-N	=BFS 20 (SMD-Marking)	35		SOT-23	-BFS 20
NA		GaAs-N-FET-d	=CFY 35-20 (SMD-Marking)	44		SOT-143	-
NA		Si-N	=KRC101S (SMD-Marking)	35		SOT-23	-KRC 101S
NA 1		MOS-N-FET-e	=2SK2053 (SMD-Marking)	39		SOT-89	-2SK2053
NA 01 E....	Nsc	Si-N	Uni, 25V, 0,8A, 0,6W, 200MHz	7e	TO-92	BC 337	7a BC 337...338, BC 635, BC 637, BC 639
NA 01 F....		Si-N	=NA 01E:	7c	TO-92	BC 337	7a BC 337...338, BC 635, BC 637, BC 639
NA 01 H....		Si-N	=NA 01E:	7a	TO-92	BC 337	7a BC 337...338, BC 635, BC 637, BC 639
NA 2		MOS-N-FET-e	=2SK2054 (SMD-Marking)	39		SOT-89	-2SK2054
NA 02 E....	Nsc	Si-P	Uni, 25V, 0,8A, 0,6W, 200MHz	7e	TO-92	BC 327	7a BC 327...328, BC 636, BC 638, BC 640
NA 02 F....		Si-P	=NA 02E:	7c	TO-92	BC 327	7a BC 327...328, BC 636, BC 638, BC 640
NA 02 H....		Si-P	=NA 02E:	7a	TO-92	BC 327	7a BC 327...328, BC 636, BC 638, BC 640
NA 3		MOS-N-FET-e	=2SK2055 (SMD-Marking)	39		SOT-89	-2SK2055
NA 4		MOS-N-FET-e	=2SK2157 (SMD-Marking)	39		SOT-89	-2SK2157
NA 11 E....	Nsc	Si-N	Uni, 25V, 1A, 0,6W, 200MHz	7e	TO-92	BC 337	7a BC 337...338, BC 635, BC 637, BC 639
NA 11 F....		Si-N	=NA 11E:	7c	TO-92	BC 337	7a BC 337...338, BC 635, BC 637, BC 639
NA 11 H....		Si-N	=NA 11E:	7a	TO-92	BC 337	7a BC 337...338, BC 635, BC 637, BC 639
NA 12 E....	Nsc	Si-P	Uni, 25V, 1A, 0,6W, 200MHz	7e	TO-92	BC 327	7a BC 327...328, BC 636, BC 638, BC 640
NA 12 F....		Si-P	=NA 12E:	7c	TO-92	BC 327	7a BC 327...328, BC 636, BC 638, BC 640
NA 12 H....		Si-P	=NA 12E:	7a	TO-92	BC 327	7a BC 327...328, BC 636, BC 638, BC 640
NA 13 E....	Nsc	Si-N		7e	TO-92	BC 337	7a
NA 21 E....	Nsc	Si-N	Uni, 25V, 1,5A, 0,6W, 200MHz	7e	TO-92	2SD1207	7c MPS 650, 2SC2236, 2SD1146, 2SD1207, ++
NA 21 F....		Si-N	=NA 21E:	7c	TO-92	2SD1207	7c MPS 650, 2SC2236, 2SD1146, 2SD1207, ++
NA 21 H....		Si-N	=NA 21E:	7a	TO-92	2SD1207	7c MPS 650, 2SC2236, 2SD1146, 2SD1207, ++
NA 21 X....		Si-N	=NA 21E: 0,75W	30n	TO-237	(2SC4135) <sup>5</sup>	30j (2SD1295, 2SD1801, BD 515, BD 525, ++) <sup>5</sup>
NA 21 Y....		Si-N	=NA 21E: 0,75W	30j	TO-237	(2SC4135) <sup>5</sup>	30j 2SD1295, 2SD1801, (BD 515, BD 525, ++) <sup>5</sup>
NA 21 Z....		Si-N	=NA 21E: 0,75W	30m	TO-237	(2SC4135) <sup>5</sup>	30j BD 515, BD 525, (2SD1295, 2SD1801) ++ <sup>5</sup>
NA 22 E....	Nsc	Si-P	Uni, 25V, 1,5A, 0,6W, 200MHz	7e	TO-92	2SB892	7c(9mm) MPS 750, 2SA966, 2SA1382, 2SB892, ++
NA 22 F....		Si-P	=NA 22E:	7c	TO-92	2SB892	7c(9mm) MPS 750, 2SA966, 2SA1382, 2SB892, ++
NA 22 H....		Si-P	=NA 22E:	7a	TO-92	2SB892	7c(9mm) MPS 750, 2SA966, 2SA1382, 2SB892, ++
NA 22 X....		Si-P	=NA 22E: 0,75W	30n	TO-237	(2SA1593) <sup>5</sup>	30j (2SB968, 2SB1201, BD 516, BD 526, ++) <sup>5</sup>
NA 22 Y....		Si-P	=NA 22E: 0,75W	30j	TO-237	(2SA1593) <sup>5</sup>	30j 2SB968, 2SB1201, (BD 516, BD 526, ++) <sup>5</sup>
NA 22 Z....		Si-P	=NA 22E: 0,75W	30m	TO-237	(2SA1593) <sup>5</sup>	30j BD 516, BD 526, (2SD968, 2SD1201) ++ <sup>5</sup>
NA 31 K....	Nsc	Si-N	LFS Out, 35V, 2A, 1,75W, >20MHz	13m	TO-202	(2SC4135) <sup>4</sup>	30j BC 365, BD 505, BD 515, BD 525, ++
NA 31 L....		Si-N	=NA 31K:	13h	TO-202	(2SC4135) <sup>4</sup>	30j BD 429, BD 813, BD 815, BD 817, ++
NA 31 M....		Si-N	=NA 31K:	13j	TO-202	(2SC4135) <sup>4</sup>	30j 2SC1226
NA 31 X....		Si-N	=NA 31K: 0,75W	30n	TO-237	(2SC4135) <sup>5</sup>	30j (2SD1078, 2SD1801, BD 515, BD 525, ++) <sup>5</sup>
NA 31 Y....		Si-N	=NA 31K: 0,75W	30j	TO-237	2SC4135	30j 2SD1078, 2SD1801, (BD 515, BD 525), ++ <sup>5</sup>
NA 31 Z....		Si-N	=NA 31K: 0,75W	30h	TO-237	(2SC4135) <sup>5</sup>	30j BD 375, 2SD1380, (2SD1078, 2SD1801), ++ <sup>5</sup>
NA 32 K....		Si-P	LFS Out, 35V, 2A, 1,75W, >20MHz	13m	TO-202	(2SA1593) <sup>5</sup>	30j BC 362, BD 506, BD 516, BD 526, ++
NA 32 L....		Si-P	=NA 32K:	13h	TO-202	(2SA1593) <sup>5</sup>	30j BD 430, BD 814, BD 816, BD 818, ++
NA 32 M....		Si-P	=NA 32K:	13j	TO-202	(2SA1593) <sup>4</sup>	30j 2SA699
NA 32 X....		Si-P	=NA 32K: 0,75W	30n	TO-237	(2SA1593) <sup>5</sup>	30j (2SB838, 2SB1201, BD 516, BD 526, ++) <sup>5</sup>
NA 32 Y....		Si-P	=NA 32K: 0,75W	30j	TO-237	2SA1593	30j 2SB838, 2SB1201, (BD 516, BD 526), ++ <sup>5</sup>
NA 32 Z....		Si-P	=NA 32K: 0,75W	30h	TO-237	(2SA1593) <sup>4</sup>	30j BD 376, 2SB1009, (2SB838, 2SD1201), ++ <sup>5</sup>
NA 41 U....	Nsc	Si-N	LFS P, 50V, 3,5A, 25W	14h	TO-126	BD 237	14h BD 175, BD 185, BD 233, BD 437, ++
NA 41 W....		Si-N	=NA 41U:	17j	TO-220	BD 243 C	17j BD 241, BD 243, BD 533, BD 933, ++
NA 42 U....	Nsc	Si-P	LFS P, 50V, 2,5A, 25W	14h	TO-126	BD 238	14h BD 176, BD 186, BD 234, BD 438, ++
NA 42 W....		Si-P	=NA 42U:	17j	TO-220	BD 244 C	17j BD 242, BD 244, BD 534, BD 934, ++
NA 51 U....	Nsc	Si-N	LFS P, 50V, 3,5A, 30W	14h	TO-126	BD 189	14h BD 177, BD 187, BD 439, 2N5191...92, ++
NA 51 W....		Si-N	=NA 51U:	17j	TO-220	BD 243 C	17j BD 243, BD 535, BD 539A, BD 949, ++
NA 52 U....	Nsc	Si-P	LFS P, 50V, 3,5A, 30W	14h	TO-126	BD 190	14h BD 178, BD 188, BD 440, 2N5194...95, ++
NA 52 W....		Si-P	=NA 52U:	17j	TO-220	BD 244 C	17j BD 244, BD 536, BD 540A, BD 950, ++
NA 61 U....	Nsc	Si-N	LFS P, 50V, 4,5A, 40W	14h	TO-126	BD 189	14h BD 187, BD 439, 2N5191...5192, ++
NA 61 W....		Si-N	=NA 61U:	17j	TO-220	BD 243 C	17j BD 243, BD 539A, BD 543A, BD 949, ++
NA 62 U....	Nsc	Si-P	LFS P, 50V, 4,5A, 40W	14h	TO-126	BD 190	14h BD 188, BD 440, 2N5194...5195, ++
NA 62 W....		Si-P	=NA 62U:	17j	TO-220	BD 244 C	17j BD 244, BD 540A, BD 544A, BD 950, ++
NA 71 U....	Nsc	Si-N	LFS P, 65V, 3,5A, 40W	14h	TO-126	BD 189	14h BD 189, BD 441, 2N5192
NA 71 W....		Si-N	=NA 71U:	17j	TO-220	BD 243 C	17j BD 243A, BD 537, BD 539B, BD 951, ++
NA 72 U....	Nsc	Si-P	LFS P, 65V, 3,5A, 40W	14h	TO-126	BD 190	14h BD 190, BD 442, 2N5195
NA 72 W....		Si-P	=NA 72U:	17j	TO-220	BD 244 C	17j BD 244A, BD 538, BD 540B, BD 952, ++
NAS 29(A....C)	Nsc	Si-N	=BD 239(A....C)	17j	TO-220	BD 243 C	17j -BD 239
NAS 30(A....C)	Nsc	Si-P	=BD 240(A....C)	17j	TO-220	BD 244 C	17j -BD 240
NAS 31(A....C)	Nsc	Si-N	=BD 241(A....C)	17j	TO-220	BD 243 C	17j -BD 241
NAS 32(A....C)	Nsc	Si-P	=BD 242(A....C)	17j	TO-220	BD 244 C	17j -BD 242
NAS 41(A....C)	Nsc	Si-N	=BD 243(A....C)	17j	TO-220	BD 243 C	17j -BD 243
NAS 42(A....C)	Nsc	Si-P	=BD 244(A....C)	17j	TO-220	BD 244 C	17j -BD 244
<b>NB</b>							
NB		MOS-N-FET-e	=2SK1483 (SMD-Marking)	39		SOT-89	-2SK1483
NB		Si-N	=BF 599 (SMD-Marking)	35		SOT-23	-BF 599
NB		GaAs-N-FET-d	=CFY 35-23 (SMD-Marking)	44		SOT-143	-

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International	
NB		Si-N	=KRC102S (SMD-Marking)	35	SOT-23		=KRC 102S	
NB 011 E....	Nsc	Si-N	Uni, 40V, 0,03A, 0,6W, 120MHz	7e	TO-92	BC 546	7a	BC 167, BC 182, BC 237, BC 547, ++
NB 011 F....		Si-N	=NB 011E:	7c	TO-92	BC 546	7a	BC 167, BC 182, BC 237, BC 547, ++
NB 011 H....		Si-N	=NB 011E:	7a	TO-92	BC 546	7a	BC 167, BC 182, BC 237, BC 547, ++
NB 012 E....	Nsc	Si-N	=NB 011E: 55V	7e	TO-92	BC 546	7a	BC 167, BC 182, BC 237, BC 547, ++
NB 012 F....		Si-N	=NB 011F: 55V	7c	TO-92	BC 546	7a	BC 167, BC 182, BC 237, BC 547, ++
NB 012 H....		Si-N	=NB 011H: 55V	7a	TO-92	BC 546	7a	BC 167, BC 182, BC 237, BC 547, ++
NB 013 E....	Nsc	Si-N	=NB 011E: In	7e	TO-92	BC 550	7a	BC 184, BC 413...414, BC 550
NB 013 F....		Si-N	=NB 011F: In	7c	TO-92	BC 550	7a	BC 184, BC 413...414, BC 550
NB 013 H....		Si-N	=NB 011H: In	7a	TO-92	BC 550	7a	BC 184, BC 413...414, BC 550
NB 014 E....	Nsc	Si-N	=NB 011E: 55V, In	7e	TO-92	BC 550	7a	BC 550, 2SC2240, 2SC2459
NB 014 F....		Si-N	=NB 011F: 55V, In	7c	TO-92	BC 550	7a	BC 550, 2SC2240, 2SC2459
NB 014 H....		Si-N	=NB 011H: 55V, In	7a	TO-92	BC 550	7a	BC 550, 2SC2240, 2SC2459
NB 021 E....	Nsc	Si-P	Uni, 40V, 0,03A, 0,6W, 120MHz	7e	TO-92	BC 556	7a	BC 212, BC 257, BC 307, BC 557, ++
NB 021 F....		Si-P	=NB 021F:	7c	TO-92	BC 556	7a	BC 212, BC 257, BC 307, BC 557, ++
NB 021 H....		Si-P	=NB 021H:	7a	TO-92	BC 556	7a	BC 212, BC 257, BC 307, BC 557, ++
NB 022 E....	Nsc	Si-P	=NB 021E: 55V	7e	TO-92	BC 556	7a	BC 212, BC 257, BC 307, BC 557, ++
NB 022 F....		Si-P	=NB 021F: 55V	7c	TO-92	BC 556	7a	BC 212, BC 257, BC 307, BC 557, ++
NB 022 H....		Si-P	=NB 021H: 55V	7a	TO-92	BC 556	7a	BC 212, BC 257, BC 307, BC 557, ++
NB 023 E....	Nsc	Si-P	=NB 021E: In	7e	TO-92	BC 560	7a	BC 212, BC 415...416, BC 560
NB 023 F....		Si-P	=NB 021F: In	7c	TO-92	BC 560	7a	BC 212, BC 415...416, BC 560
NB 023 H....		Si-P	=NB 021H: In	7a	TO-92	BC 560	7a	BC 212, BC 415...416, BC 560
NB 024 E....	Nsc	Si-P	=NB 021E: 55V, In	7e	TO-92	BC 560	7a	BC 560, 2SA970, 2SA1049
NB 024 F....		Si-P	=NB 021F: 55V, In	7c	TO-92	BC 560	7a	BC 560, 2SA970, 2SA1049
NB 024 H....		Si-P	=NB 021H: 55V, In	7a	TO-92	BC 560	7a	BC 560, 2SA970, 2SA1049
NB 111 E....	Nsc	Si-N	Uni, 40V, 0,1A, 0,6W, >100MHz	7e	TO-92	BC 546	7a	BC 167, BC 182, BC 237, BC 547, ++
NB 111 F....		Si-N	=NB 111E:	7c	TO-92	BC 546	7a	BC 167, BC 182, BC 237, BC 547, ++
NB 111 H....		Si-N	=NB 111E:	7a	TO-92	BC 546	7a	BC 167, BC 182, BC 237, BC 547, ++
NB 112 E....	Nsc	Si-N	=NB 111E: 55V	7e	TO-92	BC 546	7a	BC 174, BC 182, BC 190, BC 546, ++
NB 112 F....		Si-N	=NB 111F: 55V	7c	TO-92	BC 546	7a	BC 174, BC 182, BC 190, BC 546, ++
NB 112 H....		Si-N	=NB 111H: 55V	7a	TO-92	BC 546	7a	BC 174, BC 182, BC 190, BC 546, ++
NB 113 E....	Nsc	Si-N	=NB 111E: 70V	7e	TO-92	BC 546	7a	BC 546, 2SC2240, 2SC2459, 2SC3245(A)
NB 113 F....		Si-N	=NB 111F: 70V	7c	TO-92	BC 546	7a	BC 546, 2SC2240, 2SC2459, 2SC3245(A)
NB 113 H....		Si-N	=NB 111H: 70V	7a	TO-92	BC 546	7a	BC 546, 2SC2240, 2SC2459, 2SC3245(A)
NB 121 E....	Nsc	Si-P	Uni, 40V, 0,1A, 0,6W, >100MHz	7e	TO-92	BC 556	7a	BC 212, BC 257, BC 307, BC 557, ++
NB 121 F....		Si-P	=NB 121E:	7c	TO-92	BC 556	7a	BC 212, BC 257, BC 307, BC 557, ++
NB 121 H....		Si-P	=NB 121E:	7a	TO-92	BC 556	7a	BC 212, BC 257, BC 307, BC 557, ++
NB 122 E....	Nsc	Si-P	=NB 121E: 55V	7e	TO-92	BC 556	7a	BC 212, BC 256, BC 266, BC 556, ++
NB 122 F....		Si-P	=NB 121F: 55V	7c	TO-92	BC 556	7a	BC 212, BC 256, BC 266, BC 556, ++
NB 122 H....		Si-P	=NB 121H: 55V	7a	TO-92	BC 556	7a	BC 212, BC 256, BC 266, BC 556, ++
NB 123 E....	Nsc	Si-P	=NB 121E: 70V	7e	TO-92	BC 556	7a	BC 556, 2SA970, 2SA 1049, 2SA1285(A)
NB 123 F....		Si-P	=NB 121F: 70V	7c	TO-92	BC 556	7a	BC 556, 2SA970, 2SA1049, 2SA1285(A)
NB 123 H....		Si-P	=NB 121H: 70V	7a	TO-92	BC 556	7a	BC 556, 2SA970, 2SA1049, 2SA1285(A)
NB 211 E....	Nsc	Si-N	Uni, 40V, 0,5A, 0,6W, >50MHz	7e	TO-92	BC 639	7c	BC 337, BC 635, BC 637, BC 639
NB 211 F....	Nsc	Si-N	=NB 211E:	7c	TO-92	BC 639	7c	BC 337, BC 635, BC 637, BC 639
NB 211 H....		Si-N	=NB 211E:	7a	TO-92	BC 639	7c	BC 337, BC 635, BC 637, BC 639
NB 211 X....		Si-N	=NB 211E: 0,75W	30n	TO-237	(2SC4135) <sup>5</sup>	30j	BC 365, BD 507, BD 515, BD 525, ++
NB 211 Y....		Si-N	=NB 211E: 0,75W	30j	TO-237	2SC4135	30j	BC 365, BD 507, BD 515, BD 525, ++
NB 211 Z....		Si-N	=NB 211E: 0,75W	30m	TO-237	(2SC4135) <sup>5</sup>	30j	BC 365, BD 507, BD 515, BD 525, ++
NB 212 E....	Nsc	Si-N	=NB 211E: 55V	7e	TO-92	BC 639	7c	BC 337A, BC 637, BC 639, 2SD667
NB 212 F....		Si-N	=NB 211F: 55V	7c	TO-92	BC 639	7c	BC 337A, BC 637, BC 639, 2SD667
NB 212 H....		Si-N	=NB 211H: 55V	7a	TO-92	BC 639	7c	BC 337A, BC 637, BC 639, 2SD667
NB 212 X....		Si-N	=NB 211E: 55V, 0,75W	30n	TO-237	(2SC4135) <sup>5</sup>	30j	BC 366, BD 517, BD 525, ++
NB 212 Y....		Si-N	=NB 211E: 55V, 0,75W	30j	TO-237	2SC4135	30j	BC 366, BD 517, BD 525, ++
NB 212 Z....		Si-N	=NB 211E: 70V, 0,75W	30m	TO-237	(2SC4135) <sup>5</sup>	30j	BC 366, BD 517, BD 525, ++
NB 213 E....	Nsc	Si-N	=NB 211E: 70V	7e	TO-92	BC 639	7c	BC 639, 2SD667
NB 213 F....		Si-N	=NB 211F: 70V	7c	TO-92	BC 639	7c	BC 639, 2SD667
NB 213 H....		Si-N	=NB 211H: 70V	7a	TO-92	BC 639	7c	BC 639, 2SD667
NB 213 X....		Si-N	=NB 211E: 70V, 0,75W	30n	TO-237	(2SC4135) <sup>5</sup>	30j	BC 367, BD 519, BD 527, BD 529, ++
NB 213 Y....		Si-N	=NB 211E: 70V, 0,75W	30j	TO-237	2SC4135	30j	BC 367, BD 519, BD 527, BD 529, ++
NB 213 Z....		Si-N	=NB 211E: 70V, 0,75W	30m	TO-237	(2SC4135) <sup>5</sup>	30j	BC 367, BD 519, BD 527, BD 529, ++
NB 221 E....	Nsc	Si-P	Uni, 40V, 0,5A, 0,6W, >50MHz	7e	TO-92	BC 640	7c	BC 327, BC 636, BC 638, BC 640
NB 221 F....		Si-P	=NB 221E:	7c	TO-92	BC 640	7c	BC 327, BC 636, BC 638, BC 640
NB 221 H....		Si-P	=NB 221E:	7a	TO-92	BC 640	7c	BC 327, BC 636, BC 638, BC 640
NB 221 X....		Si-P	=NB 221E: 0,75W	30n	TO-237	(2SA1593) <sup>5</sup>	30j	BC 362, BD 508, BD 516, BD 526, ++
NB 221 Y....		Si-P	=NB 221E: 0,75W	30j	TO-237	2SA1593	30j	BC 362, BD 508, BD 516, BD 526, ++
NB 221 Z....		Si-P	=NB 221E: 0,75W	30m	TO-237	(2SA1593) <sup>5</sup>	30j	BC 362, BD 508, BD 516, BD 526, ++
NB 222 E....	Nsc	Si-P	=NB 221E: 55V	7e	TO-92	BC 640	7c	BC 327A, BC 638, BC 640, 2SB647
NB 222 F....		Si-P	=NB 221F: 55V	7c	TO-92	BC 640	7c	BC 327A, BC 638, BC 640, 2SB647
NB 222 H....		Si-P	=NB 221H: 55V	7a	TO-92	BC 640	7c	BC 327A, BC 638, BC 640, 2SB647
NB 222 X....		Si-P	=NB 221E: 55V, 0,75W	30n	TO-237	(2SA1593) <sup>5</sup>	30j	BC 363, BD 518, BD 526, ++
NB 222 Y....		Si-P	=NB 221E: 55V, 0,75W	30j	TO-237	2SA1593	30j	BC 363, BD 518, BD 526, ++
NB 222 Z....		Si-P	=NB 221E: 55V, 0,75W	30m	TO-237	(2SA1593) <sup>5</sup>	30j	BC 363, BD 518, BD 526, ++
NB 223 E....	Nsc	Si-P	=NB 221E: 70V	7e	TO-92	BC 640	7c	BC 640, 2SB647
NB 223 F....		Si-P	=NB 221F: 70V	7c	TO-92	BC 640	7c	BC 640, 2SB647
NB 223 H....		Si-P	=NB 221H: 70V	7a	TO-92	BC 640	7c	BC 640, 2SB647
NB 223 X....		Si-P	=NB 221E: 70V, 0,75W	30n	TO-237	(2SA1593) <sup>5</sup>	30j	BC 364, BD 520, BD 528, BD 530
NB 223 Y....		Si-P	=NB 221E: 70V, 0,75W	30j	TO-237	2SA1593	30j	BC 364, BD 520, BD 528, BD 530
NB 223 Z....		Si-P	=NB 221E: 70V, 0,75W	30m	TO-237	(2SA1593) <sup>5</sup>	30j	BC 364, BD 520, BD 528, BD 530
NB 311 E....	Nsc	Si-N	Uni, 40V, 1,5A, 0,6W, >20MHz	7e	TO-92	2SD1207	7c	MPS 650...651, 2SD1146, 2SC3328
NB 311 F....		Si-N	=NB 311E:	7c	TO-92	2SD1207	7c	MPS 650...651, 2SD1146, 2SC3328
NB 311 H....		Si-N	=NB 311E:	7a	TO-92	2SD1207	7c	MPS 650...651, 2SD1146, 2SC3328
NB 311 K....		Si-N	=NB 311E: 1,75W	13m	TO-202	(2SC4135) <sup>4</sup>	30j	BC 365, BD 507, BD 515, BD 525, ++
NB 311 L....		Si-N	=NB 311E: 1,75W	13h	TO-202	(2SC4135) <sup>4</sup>	30j	BD 813, BD 815, BD 817, ++
NB 311 M....		Si-N	=NB 311E: 1,75W	13j	TO-202	(2SC4135) <sup>4</sup>	30j	2SC1226, 2SC1848
NB 311 X....		Si-N	=NB 311E: 0,75W	30n	TO-237	(2SC4135) <sup>5</sup>	30j	BC 365, BD 507, BD 515, BD 525, ++
NB 311 Y....		Si-N	=NB 311E: 0,75W	30j	TO-237	2SC4135	30j	BC 365, BD 507, BD 515, BD 525, ++
NB 311 Z....		Si-N	=NB 311E: 0,75W	30m	TO-237	(2SC4135) <sup>5</sup>	30j	BC 365, BD 507, BD 515, BD 525, ++
NB 312 E....	Nsc	Si-N	=NB 311E: 55V	7e	TO-92	2SD1207	7c	MPS 650...651, 2SC3328
NB 312 F....		Si-N	=NB 311F: 55V	7c	TO-92	2SD1207	7c	MPS 650...651, 2SC3328
NB 312 H....		Si-N	=NB 311H: 55V	7a	TO-92	2SD1207	7c	MPS 650...651, 2SC3328
NB 312 K....		Si-N	=NB 311E: 55V, 1,75W	13m	TO-202	(2SC4135) <sup>4</sup>	30j	BC 366, BD 517, BD 525, ++
NB 312 L....		Si-N	=NB 311E: 55V, 1,75W	13h	TO-202	(2SC4135) <sup>4</sup>	30j	BD 815, BD 817



Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International	
NB 312 M....		Si-N	=NB 311E: 55V, 1,75W	13j	TO-202	(2SC4135) <sup>4</sup>	30j	2SC1848
NB 312 X....		Si-N	=NB 311E: 55V, 0,75W	30n	TO-237	(2SC4135) <sup>5</sup>	30j	BC 366, BD 517, BD 525, ++
NB 312 Y....		Si-N	=NB 311E: 55V, 0,75W	30j	TO-237	2SC4135	30j	BC 366, BD 517, BD 525, ++
NB 312 Z....		Si-N	=NB 311E: 55V, 0,75W	30m	TO-237	(2SC4135) <sup>5</sup>	30j	BC 366, BD 517, BD 525, ++
NB 313 E....	Nsc	Si-N	=NB 311E: 70V	7e	TO-92	(2SC4135) <sup>4</sup>	30j	MPS 651, 2SC3328
NB 313 F....		Si-N	=NB 311F: 70V	7c	TO-92	(2SC4135) <sup>4</sup>	30j	MPS 651, 2SC3328
NB 313 H....		Si-N	=NB 311H: 70V	7a	TO-92	(2SC4135) <sup>4</sup>	30j	MPS 651, 2SC3328
NB 313 K....		Si-N	=NB 311E: 70V, 1,75W	13m	TO-202	(2SC4135) <sup>4</sup>	30j	BC 367, BD 519, BD 527, BD 529
NB 313 L....		Si-N	=NB 311E: 70V, 1,75W	13h	TO-202	(2SC4135) <sup>4</sup>	30j	BD 817
NB 313 M....		Si-N	=NB 311E: 70V, 1,75W	13j	TO-202	(2SC4135) <sup>4</sup>	30j	2SC1848
NB 313 X....		Si-N	=NB 311E: 70V, 1,75W	30n	TO-237	(2SC4135) <sup>5</sup>	30j	BC 367, BD 519, BD 527, BD 529
NB 313 Y....		Si-N	=NB 311E: 70V, 0,75W	30j	TO-237	2SC4135	30j	BC 367, BD 519, BD 527, BD 529
NB 313 Z....		Si-N	=NB 311E: 70V, 0,75W	30m	TO-237	(2SC4135) <sup>5</sup>	30j	BC 367, BD 519, BD 527, BD 529
NB 321 E....	Nsc	Si-P	Uni, 40V, 1,5A, 0,6W, >20MHz	7e	TO-92	2SB892	7c(9mm)	MPS 750...751, 2SA1382, 2SA1315
NB 321 F....		Si-P	=NB 321E:	7c	TO-92	2SB892	7c(9mm)	MPS 750...751, 2SA1382, 2SA1315
NB 321 H....		Si-P	=NB 321E:	7a	TO-92	2SB892	7c(9mm)	MPS 750...751, 2SA1382, 2SA1315
NB 321 K....		Si-P	=NB 321E: 1,75W	13m	TO-202	(2SA1593) <sup>4</sup>	30j	BC 362, BD 508, BD 516, BD 526, ++
NB 321 L....		Si-P	=NB 321E: 1,75W	13h	TO-202	(2SA1593) <sup>4</sup>	30j	BD 814, BD 816, BD 818, ++
NB 321 M....		Si-P	=NB 321E: 1,75W	13j	TO-202	(2SA1593) <sup>4</sup>	30j	2SA699, 2SA887
NB 321 X....		Si-P	=NB 321E: 0,75W	30n	TO-237	(2SA1593) <sup>5</sup>	30j	BC 362, BD 508, BD 516, BD 526, ++
NB 321 Y....		Si-P	=NB 321E: 0,75W	30j	TO-237	2SA1593	30j	BC 362, BD 508, BD 516, BD 526, ++
NB 321 Z....		Si-P	=NB 321E: 0,75W	30m	TO-237	(2SA1593) <sup>5</sup>	30j	BC 362, BD 508, BD 516, BD 526, ++
NB 322 E....	Nsc	Si-P	=NB 321E: 55V	7e	TO-92	2SB892	7c(9mm)	MPS 750...751, 2SA1315
NB 322 F....		Si-P	=NB 321F: 55V	7c	TO-92	2SB892	7c(9mm)	MPS 750...751, 2SA1315
NB 322 H....		Si-P	=NB 321H: 55V	7a	TO-92	2SB892	7c(9mm)	MPS 750...751, 2SA1315
NB 322 K....		Si-P	=NB 321E: 55V, 1,75W	13m	TO-202	(2SA1593) <sup>4</sup>	30j	BC 363, BD 518, BD 526, ++
NB 322 L....		Si-P	=NB 321E: 55V, 1,75W	13h	TO-202	(2SA1593) <sup>4</sup>	30j	BD 816, BD 818
NB 322 M....		Si-P	=NB 321E: 55V, 1,75W	13j	TO-202	(2SA1593) <sup>4</sup>	30j	2SA887
NB 322 X....		Si-P	=NB 321E: 55V, 0,75W	30n	TO-237	(2SA1593) <sup>5</sup>	30j	BC 363, BD 518, BD 526, ++
NB 322 Y....		Si-P	=NB 321E: 55V, 0,75W	30j	TO-237	2SA1593	30j	BC 363, BD 518, BD 526, ++
NB 322 Z....		Si-P	=NB 321E: 55V, 0,75W	30m	TO-237	(2SA1593) <sup>5</sup>	30j	BC 363, BD 518, BD 526, ++
NB 323 E....	Nsc	Si-P	=NB 321E: 70V	7e	TO-92	(2SA1593) <sup>4</sup>	30j	MPS 751, 2SA1315
NB 323 F....		Si-P	=NB 321F: 70V	7c	TO-92	(2SA1593) <sup>4</sup>	30j	MPS 751, 2SA1315
NB 323 H....		Si-P	=NB 321H: 70V	7a	TO-92	(2SA1593) <sup>4</sup>	30j	MPS 751, 2SA1315
NB 323 K....		Si-P	=NB 321E: 70V, 1,75W	13m	TO-202	(2SA1593) <sup>4</sup>	30j	BC 364, BD 520, BD 528, BD 530
NB 323 L....		Si-P	=NB 321E: 70V, 1,75W	13h	TO-202	(2SA1593) <sup>4</sup>	30j	BD 818
NB 323 M....		Si-P	=NB 321E: 70V, 1,75W	13j	TO-202	(2SA1593) <sup>4</sup>	30j	2SA887
NB 323 X....		Si-P	=NB 321E: 70V, 0,75W	30n	TO-237	(2SA1593) <sup>5</sup>	30j	BC 364, BD 520, BD 528, BD 530
NB 323 Y....		Si-P	=NB 321E: 70V, 0,75W	30j	TO-237	2SA1593	30j	BC 364, BD 520, BD 528, BD 530
NB 323 Z....		Si-P	=NB 321E: 70V, 0,75W	30m	TO-237	(2SA1593) <sup>5</sup>	30j	BC 364, BD 520, BD 528, BD 530
NBD 517		Si-N	=BD 517	13m	TO-202	=BD 517		=BD 517
NBD 518		Si-P	=BD 518	13m	TO-202	=BD 518		=BD 518
NC		MOS-N-FET-e	=2SK1485 (SMD-Marking)	39	SOT-89			=2SK1485
NC		Si-N	=KRC103S (SMD-Marking)	35	SOT-23			=KRC 103S
NCp		Si-N	=BF 840 (SMD-Marking)	35	SOT-23			=BF 840
ND		Si-N	=2SD1306-D (SMD-Marking)	35	SOT-23			=2SD1306
ND		MOS-N-FET-e	=2SK1583 (SMD-Marking)	39	SOT-89			=2SK1583
ND		Si-N	=KRC104S (SMD-Marking)	35	SOT-23			=KRC 104S
ND 16 AT...MT	Gie	Si-Di	=NP 16 AT...MT:	17r	TO-220			-
ND 30 AP...MP	Gie	Si-Di	=NP 30 AP...MP:	16r	TO-247			-
TDA 7265	Tho	LIN-IC	Dual Audio Out, 2x 25W(±20V/8Ω)	11-OILP				-
NDp		Si-N	=BF 841 (SMD-Marking)	35	SOT-23			=BF 841
<b>NE...NI</b>								
NE		Si-N	=2SD1306-E (SMD-Marking)	35	SOT-23			=2SD1306
NE		MOS-N-FET-e	=2SK1585 (SMD-Marking)	39	SOT-89			=2SK1585
NE		Si-N	=KRC105S (SMD-Marking)	35	SOT-23			=KRC 105S
NE 8 T26A	Mot	I/O-IC	=MC 6880ALAP	16-DIC/DIP				MC 6880ALAP, MC 8T26ALAP
NE 8 T28	Mot	I/O-IC	=MC 6889LP	16-DIC/DIP				MC 6889LP, MC 8T28LP
NE 86 C92	Phi	LIN-IC	Twisted Pair Transceiver Interface	20-DIP				-
NE 86 C92 ?	Phi	LIN-IC	=NE 8392A:	20-MDIP				-
NE 502 A	Phi	LIN-IC	µComp, Ethernet Encoder/Decoder, 0...+70°					-
NE 521 D	Phi	KOP-IC	=NE 521FN: SMD	14-MDIP				-
NE 521 FN	Phi	KOP-IC	Dual, Sense Amp., hi-speed, ±7V, 0...+70°	14-DIC/DIP				SE 521...
NE 522 D	Phi	KOP-IC	=NE 522FN: SMD	14-MDIP				-
NE 522 FN	Phi	KOP-IC	Dual, Sense Amp., hi-speed, ±7V, 0...+70°	14-DIC/DIP				SE 522...
NE 527 D	Phi	KOP-IC	=NE 527FN: SMD	14-MDIP				-
NE 527 FN	Phi	KOP-IC	hi-speed, ±15V, 0...+70°	14-DIC/DIP				SE 527...
NE 527 H	Phi	KOP-IC	=NE 527FN: Fig. →	TO-100				SE 527...
NE 529 D	Phi	KOP-IC	=NE 529FN: SMD	14-MDIP				-
NE 529 FN	Phi	KOP-IC	hi-speed, ±15V, 0...+70°	14-DIC/DIP				SE 529..., LM 161, LM 261, LM 361
NE 529 H	Phi	KOP-IC	=NE 529FN: Fig. →	TO-100				SE 529..., LM 161, LM 261, LM 361
NE 530 FE,N	Phi	OP-IC	±18V, 35V/µs, 0...+70°, (=LM 741)	8-DIC/DIP				SE 530..., (LM 741)
NE 531 FE,N	Phi	OP-IC	±22V, 35V/µs, 0...+70°, (=LM 748)	8-DIC/DIP				SE 531..., (LM 748, LF 356)
NE 531 H	Phi	OP-IC	=NE 531FE,N: Fig. →	TO-99				SE 531..., (LM 741, LF 356)
NE 532 D	Phi,Sgs	OP-IC	=LM 158(A)H: 0...+70°	8-MDIP				SA 532...
NE 532 FE,J,N	Phi,Sgs	OP-IC	=LM 158(A)H: 0...+70°	8-DIC/DIP	4558/8-D	8-DIP		SA 532..., SE 532...
NE 535 FE,N	Phi	OP-IC	Uni, ±18V, 12V/µs, 0...+70°	8-DIC/DIP				SE 535...
NE 535 H	Phi	OP-IC	=NE 535FE,N:	TO-99				SE 535...
NE 538 FE,N	Phi	OP-IC	±22V, 60V/µs, 0...+70°, (=LM 741)	8-DIC/DIP				SE 538..., (LM 741)
NE 538 H	Phi	OP-IC	=NE 538 FE,N: Fig. →	TO-99				SE 538..., (LM 741)
NE 540	Phi	LIN-IC	NF					-
NE 542 N	Phi,Sig	LIN-IC	2x Audio Inp, In, 24V, 0...+70°	8-DIP				-
NE 544 D	Phi	LIN-IC	=NE 544N: SMD	16-MDIP				-
NE 544 N	Phi	LIN-IC	Servo-Verstärker/Amplifier, 0...+70°	14-DIP				SL 76544, SN 76544
NE 545(B)N	Phi,Sig	LIN-IC	Dolby B	16-DIP				LM 1011, NE 645, NE 650
NE 550 A,F,N	Phi,Sig	Z-IC	+2...37V, 0,15A	14-DIP	723/14-D	14-DIP		... 723...
NE 550 L	Phi,Sig	Z-IC	=NE 550 A,F,N: Fig. →	TO-100	723/TO	TO-100		... 723...
NE 555 B,CDP,N,P,V	Phi,Tho,++	LIN-IC	=NE 555CH,CM: Fig. →	8-DIP	NE 555 N	8-DIP		=NE 555CH,CM
NE 555 CH,CM	Phi,Tho,++	LIN-IC	Zeitgeber/Timer, 4,5...16V, 0...+70°	TO-99				CA555..., LM555..., SE555..., TDB0555..., ++
NE 555 D	Phi,Tho,++	LIN-IC	=NE 555CH,CM: SMD	8-MDIP				=NE 555CH,CM
NE 555 F,J	Phi,Tho,++	LIN-IC	=NE 555CH,CM: Fig. →	14-DIC				=SE 555...

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
NE 555 FE	Phi,Tho,++	LIN-IC	=NE 555CH,CM: Keramik	8-DIC	(NE 555 N)	8-DIP	*NE 555CH,CM
NE 555 ID	Sam	LIN-IC	=NE 555CH,CM: SMD, -40...+85°	8-MDIP			*SE 555...
NE 555 IN	Sam	LIN-IC	=NE 555CH,CM: -40...+85°	8-DIP			*SE 555...
NE 555 MDG	Tho	LIN-IC	=NE 555CH,CM: 4.5...18V, -55...+125°	8-DIP	(NE 555 N)	8-DIP	*SE 555...
NE 556 D	Phi,Tho,++	LIN-IC	=NE 556F,N: SMD	14-MDIP			*NE 556F,N
NE 556 A,B,(C)DP	Phi,Tho,++	LIN-IC	=NE 556F,N	14-DIP	NE 556 N	14-DIP	*NE 556F,N
NE 556(-1)F,J,N	Phi,Tho,++	LIN-IC	Dual, Zeitgeber/Timer, 4,5...16V, 0...+70°	14-DIP	NE 556 N	14-DIP	LM556..., MC3456..., SE556..., TDB0556...
NE 556 ID	Sam	LIN-IC	=NE 556: SMD, -40...+85°	14-MDIP			*NE 556F,N
NE 556 IN	Sam	LIN-IC	=NE 556: -40...+85°	14-DIP			*NE 556F,N
NE 558(C)D	Phi,Sam	LIN-IC	=NE 558F,N: SMD	16-MDIP			-
NE 558(C)F,N	Phi,Sam	LIN-IC	Quad Zeitgeber/Timer, 18V, 0...+70°	16-DIC/DIP			SA 558, SE 558
NE 564 D	Phi	LIN-IC	=NE 564F,N: SMD	16-MDIP			-
NE 564 F,N	Phi	LIN-IC	PLL, <=50MHz, 0...+70°	16-DIC/DIP			SE 564
NE 565 D	Phi	LIN-IC	=NE 565F,N: SMD	14-MDIP			-
NE 565 F,N	Phi	LIN-IC	PLL, ±12V, <=500kHz, 0...+70°	14-DIC/DIP			LM 565, SE 565, TDB 0565, TDC0565
NE 566 D	Phi	LIN-IC	=NE 566N: SMD	8-MDIP			-
NE 566 F	Phi	LIN-IC	=NE 566N: Fig. →	14-DIC			-
NE 566 N	Phi	LIN-IC	Funktions-/Function-Generator (Square, Triangle W.)	8-DIP			LM 566, SE 566
NE 567 D	Phi	LIN-IC	=NE 567FE/N: SMD	8-MDIP			-
NE 567 F	Phi	LIN-IC	=NE 567FE/N: Fig. →	14-DIC			-
NE 567 FE,N	Phi	LIN-IC	PLL Tone/Frequ.-Decoder, 0...+70°	8-DIC/DIP	LM 567 CN		*LM 567CN
NE 568(A)D	Phi	LIN-IC	=NE 568(A)N: SMD	20-MDIP			-
NE 568(A)N	Phi	LIN-IC	PLL, <=150MHz, 0...+70°	20-DIP			-
NE 570 F,N	Phi	LIN-IC	Audio-Kompressor/Expander, 0...+70°	16-DIC/DIP			-
NE 571 D	Phi	LIN-IC	=NE 571F,N: SMD	16-MDIP			-
NE 571 F,N	Phi	LIN-IC	Audio-Kompressor/Expander, 0...+70°	16-DIC/DIP			SA 571
NE 572 D	Phi	LIN-IC	=NE 572F,N: SMD	16-MDIP			-
NE 572 F,N	Phi	LIN-IC	progr. Audio Kompressor/Expander, 0...+70°	16-DIC/DIP			SA 572
NE 575 D	Phi	LIN-IC	=NE 575N: SMD	20-MDIP			SA 575D
NE 575(A)N	Phi	LIN-IC	Audio-Kompressor/Exp., Ucc=5V, 0...+70°	20-DIP			SA 575(A)N
NE 576 D	Phi	LIN-IC	=NE 576N: SMD	14-MDIP			SA 576D
NE 576 N	Phi	LIN-IC	Kompressor/Expander, 0...+70°, lo-power	14-DIP			SA 576N
NE 577 D	Phi	LIN-IC	=NE 577N: SMD	14-MDIP			SA 577D
NE 577 N	Phi	LIN-IC	Kompressor/Expander, 0...+70°, lo-power	14-DIP			SA 577N
NE 578 D	Phi	LIN-IC	=NE 578N: SMD	16-MDIP			SA 578D
NE 578 N	Phi	LIN-IC	Kompressor/Expander, 0...+70°, lo-power	16-DIP			SA 578N
NE 582(N)	Phi	DIG-IC	Interface, 6Bit-Tr./Inverter, 10V, OC	16-DIP			-
NE 587 D	Phi	LIN-IC	=NE 587F,N: SMD	20-MDIP			-
NE 587 F,N	Phi	LIN-IC	7-Segm.-LED-Decoder, Drv., 0...+70°	18-DIC/DIP			-
NE 589 D	Phi	LIN-IC	=NE 589N: SMD	20-MDIP			-
NE 589 N	Phi	LIN-IC	7-Segm.-Decoder, Drv., 0...+70°	18-DIP			-
NE 590 F,N	Phi	LIN-IC	8x Darl., 250mA, Peripher. Drv., 0...+70°	16-DIC/DIP			-
NE 591 F,N	Phi	LIN-IC	8x Darl., 250mA, Peripher. Drv., 0...+70°	16-DIC/DIP			-
NE 592 D,D14	Phi,Mot,Tix	LIN-IC	=NE 592H: SMD	14-MDIP			LM 592M, NJM 592M
NE 592 D8	Phi	LIN-IC	=NE 592H: SMD	8-MDIP			NJM 592M8, SA 592D8, TL 592D8, µA 592S
NE 592 F,F14,N,N14	Phi,Mot,Tix	LIN-IC	=NE 592H: Fig. →	14-DIC,DIP	NE 592/14-D	14-DIP	LM 592, NJM 592D, SE 592F,J, µA 592D,P
NE 592 H	Phi,Mot	LIN-IC	Diff. Video-Verst./Amp, 90MHz, Ucc=±3...8V, 0...+70°	TO-100			SE 592H
NE 592 N8	Phi	LIN-IC	=NE 592H: Fig. →	8-DIC,DIP	NE 592/8-D	8-DIP	NJM 592D8, SA, SE 592..., TL 592BP, µA592T
NE 594 D	Phi	LIN-IC	=NE 594F,N: SMD	20-MDIP			SA 594
NE 594 F,N	Phi	LIN-IC	FLT Drv 0...+70°	18-DIC/DIP			SA 594
NE 600 D	Phi	LIN-IC	SMD, HF-Verst./Gain Stage, Mixer	14-MDIP			SA 600D
NE 602(A)D	Phi	LIN-IC	=NE 602FE,N: SMD	8-MDIP			SA 602(A)
NE 602(A)FE,N	Phi	LIN-IC	VHF Mx.Os, lo-power, 0...+70°	8-DIC/DIP			SA 602(A)FE,N
NE 604(A)D	Phi	LIN-IC	=NE 604F,N: SMD	16-MDIP			SA 604(A)D
NE 604(A)F,N	Phi	LIN-IC	FM IF, lo-power, 0...+70°	16-DIC/DIP			SA 604(A)F,N
NE 605 D	Phi	LIN-IC	=NE 605F,N: SMD	20-MDIP			SA 605D
NE 605 F,N	Phi	LIN-IC	FM IF, lo-power, 0...+70°	20-DIC/DIP			SA 605F,N
NE 606 D	Phi	LIN-IC	=NE 606N: SMD	20-MDIP			SA 606D
NE 606 N	Phi	LIN-IC	FM IF, Mx, lo-volt, hi-performance, 0...+70°	20-DIP			SA 606N
NE 607 D	Phi	LIN-IC	=NE 607N: SMD	20-MDIP			SA 607D
NE 607 N	Phi	LIN-IC	FM IF, Mx, lo-volt, hi-performance, 0...+70°	20-DIP			SA 607N
NE 608 D	Phi	LIN-IC	=NE 608N: SMD	20-MDIP			SA 608D
NE 608 N	Phi	LIN-IC	FM IF, Mx, lo-volt, hi-performance, 0...+70°	20-DIP			SA 608N
NE 612(A)D	Phi	LIN-IC	=NE 612N: SMD	8-MDIP			SA 612(A)D
NE 612(A)N	Phi	LIN-IC	VHF Mx.Os, lo-power, <=500MHz, 0...+70°	8-DIP			SA 612(A)N
NE 614(A)D	Phi	LIN-IC	=NE 614N: SMD	16-MDIP			SA 614(A)D
NE 614(A)N	Phi	LIN-IC	FM IF, lo-power, 0...+70°	16-MDIP			SA 614(A)N
NE 615 D	Phi	LIN-IC	=NE 615N: SMD	20-MDIP			SA 615D
NE 615 N	Phi	LIN-IC	FM Mx, FM IF, lo-power, 0...+70°	20-DIP			SA 615N
NE 616 D	Phi	LIN-IC	=NE 616N: SMD	20-MDIP			SA 616D
NE 616 N	Phi	LIN-IC	FM IF, Mx, lo-volt, hi-performance, 0...+70°	20-DIP			SA 616N
NE 616 D	Phi	LIN-IC	=NE 617N: SMD	20-MDIP			SA 617D
NE 617 N	Phi	LIN-IC	FM IF, Mx, lo-volt, hi-performance, 0...+70°	20-DIP			SA 617N
NE 618 D	Phi	LIN-IC	=NE 618N: SMD	20-MDIP			SA 618D
NE 618 N	Phi	LIN-IC	FM IF, Mx, lo-volt, hi-performance, 0...+70°	20-DIP			SA 618N
NE 624 D	Phi	LIN-IC	=NE 624N: SMD	16-MDIP			SA 624D
NE 624 N	Phi	LIN-IC	FM IF, Mx, lo-power, hi-performance, 0...+70°	16-DIP			SA 624N
NE 625 D	Phi	LIN-IC	=NE 625N: SMD	20-MDIP			SA 625D
NE 625 N	Phi	LIN-IC	FM IF, Mx, lo-power, hi-performance, 0...+70°	20-DIP			SA 625N
NE 630 D	Phi	MOS-IC	=NE 630: SMD	8-MDIP			SA 630D
NE 630 N	Phi	MOS-IC	HF Schalter/RF switch, 0...1GHz, 50Ω	8-DIP			SA 630N
NE 645(B)N	Phi,Sig	LIN-IC	Dolby B + C	16-DIP	NE 645 N	16-DIP	NE 646, NE 650, LM 1112[Nsc]
NE 646(B)N	Phi,Sig	LIN-IC	Dolby B + C	16-DIP	NE 645 N	16-DIP	NE 645, NE 650
NE 648 N	Phi	LIN-IC	Dolby B	16-DIP			NE 649, LM 1112[Nsc]
NE 649 N	Phi	LIN-IC	Dolby B	16-DIP			NE 648
NE 650(B)N	Phi	LIN-IC	Dolby B + C	16-DIP	(NE 645 N)	16-DIP	(NE 545, NE 645)
NE 652	Phi,Sig	LIN-IC	Dolby B + C	18-DIP			TEA 0652
NE 653	Phi	LIN-IC	Dolby B	18-DIP			-
NE 654	Phi	LIN-IC	Dolby B + C, Steuerschltg./Controller	24-DIP			TEA 0654
NE 660 D	Phi	LIN-IC	Dolby, Ucc=1,8...7V	20-MDIP			-
NE 701 D	Phi	ECL-LIN-IC	SMD, HF-Teiler/Prescaler, 1:128/129-64/65, 0...+70°	8-MDIP			SA 701D
NE 702 D	Phi	ECL-LIN-IC	SMD, HF-Teiler/Prescaler, 1:64/65/72, 0...+70°	8-MDIP			SA 702D
NE 703 D	Phi	ECL-LIN-IC	SMD, HF-Teiler/Prescaler, 1:128/129/144, 0...+70°	8-MDIP			SA 703D

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
NE 4558 D	Phi	OP-IC	=NE 4558FE,N: SMD	8-MDIP			-
NE 4558 FE,N	Phi	OP-IC	Dual, Serie 158, ±18V, 0...+70°	8-DIC/DIP	4558/8-D	8-DIP	... 158... 258... 358... 1458...
NE 5007 F,N	Phi	D/A-IC	=DAC 08CF,CN				
NE 5008 F,N	Phi	D/A-IC	=DAC 08HF,HN				
NE 5018 D	Phi	D/A-IC	=NE 5018F,N: SMD	24-MDIP			-
NE 5018 F,N	Phi	D/A-IC	8 Bit, µP-Compatible, 0...+70°	22-DIC/DIP			SE 5018F,N
NE 5019 F,N	Phi	D/A-IC	8 Bit, µP-Compatible, 0...+70°	22-DIC/DIP			-
NE 5020 F,N	Phi	D/A-IC	10 Bit, µP-Compatible, 0...+70°	24-DIC/DIP			-
NE 5030 F	Phi	A/D-IC	10 Bit, hi-speed, 0...+70°	24-DIC			-
NE 5034 F	Phi	A/D-IC	8 Bit, hi-speed, 0...+70°	18-DIC			-
NE 5036 D	Phi	A/D-IC	=NE 5036FE,N: SMD	14-MDIP			-
NE 5036 FE,N	Phi	A/D-IC	6 Bit, ser. Output, 0...+70°	8-DIP/DIC			-
NE 5037 D	Phi	A/D-IC	=NE 5037F,N: SMD	16-MDIP			-
NE 5037 F,N	Phi	A/D-IC	6 Bit, par. Outputs, 0...+70°	16-DIC/DIP			-
NE 5044 D	Phi	LIN-IC	=NE 5044N: SMD	16-MDIP			-
NE 5044 N	Phi	LIN-IC	7-Kanal-/Channel RC Encoder, 0...+70°	16-DIP			-
NE 5045 D	Phi	LIN-IC	=NE 5045N: SMD	16-MDIP			-
NE 5045 N	Phi	LIN-IC	7-Kanal-/Channel RC Decoder, 0...+70°	16-DIP			-
NE 5046 N	Phi	DIG-IC	2-Kanal-/Channel RC Decoder, Ucc=5<10V	8-DIP			-
NE 5050 D	Phi	LIN-IC	=NE 5050N: SMD	20-MDIP			-
NE 5050 N	Phi	LIN-IC	Power Line Modem f. Twisted-pair Communication	20-DIP			-
NE 5060 F	Phi	LIN-IC	JFET, Sample & Hold, hi-speed, 0...+70°	14-DIC			-
NE 5080 N	Phi	LIN-IC	FSK Modem Transmitter, hi-speed	16-DIP			-
NE 5081 N	Phi	LIN-IC	FSK Modem Receiver, hi-speed	20-DIP			-
NE 5090 D	Phi	LIN-IC	=NE 5090N: SMD	16-MDIP			SA 5090D
NE 5090 F,N	Phi	LIN-IC	Relais-/Relay Drv, 0...+70°	16-DIC/DIP			SA 5090N
NE 5105(A)D	Phi	KOP-IC	=NE 5105(A)N: SMD	8-MDIP			-
NE 5105(A)N	Phi	KOP-IC	hi-prec, hi-speed, +6V, 0...+70°	8-DIP			-
NE 5118 F,N	Phi	D/A-IC	8 Bit, µP-Compatible, 0...+70°	22-DIC/DIP			-
NE 5119 F,N	Phi	D/A-IC	8 Bit, µP-Compatible, 0...+70°	22-DIC/DIP			-
NE 5150 F	Phi	D/A-IC	4 Bit, CTV RGB, 110MHz, sRAM, 0...+70°	24-DIC			-
NE 5151 F	Phi	D/A-IC	=NE 5150F: 150MHz, ohne/wo. sRAM	24-DIC			-
NE 5152 F	Phi	D/A-IC	4 Bit, CTV RGB, 110MHz, sRAM, 0...+70°	24-DIC			-
NE 5170 A	Phi	LIN-IC	=NE 5170N: SMD	28-PLCC			-
NE 5170 D	Phi	LIN-IC	=NE 5170N: SMD	24-MDIP			-
NE 5170 N	Phi	LIN-IC	8x Leitungstreiber/Line Driver, 100kBit/s	28-DIP			-
NE 5180 A	Phi	LIN-IC	=NE 5180N: SMD	28-PLCC			-
NE 5180 N	Phi	LIN-IC	8x Diff. Leitungsempfänger/Line Receiver	28-DIP			-
NE 5181 A	Phi	LIN-IC	=NE 5181N: SMD	28-PLCC			-
NE 5181 N	Phi	LIN-IC	8x Diff. Leitungsempfänger/Line Receiver	28-DIP			-
NE 5200 D	Phi	LIN-IC	SMD, HF-Verst./Amp., Dual Gain, 0...+70°	8-MDIP			SA 5200D
NE 5204(A)D	Phi	LIN-IC	=NE 5204N: SMD	8-MDIP			SA 5204(A)D
NE 5204(A)N	Phi	LIN-IC	Breitbandverstärker/Wideband Amp., 0...+70°	8-DIP			SA 5204(A)N
NE 5205(A)D	Phi	LIN-IC	=NE 5205FE,N: SMD	8-MDIP			SA 5205(A)D
NE 5205 EC	Phi	LIN-IC	=NE 5205FE,N: Fig. →	5			-
NE 5205(A)FE,N	Phi	LIN-IC	Breitbandverstärker/Wideband Amp., 0...+70°	8-DIC/DIP			SA 5205(A)N
NE 5209 D	Phi	LIN-IC	=NE 5209N: SMD	16-MDIP			SA 5209D
NE 5209 N	Phi	LIN-IC	Breitbandverstärker/Wideband Amp., 0...+70°	16-DIP			SA 5209N
NE 5210 D	Phi	LIN-IC	Transimpedance Amp., 280MHz, 0...+70°	14-MDIP			-
NE 5211 D	Phi	LIN-IC	SMD, Transimpedance Amp., 180MHz, 0...+70°	14-MDIP			SA 5211D
NE 5212(A)FE,N	Phi	LIN-IC	Transimpedance Amp., 140MHz, 0...+70°	8-DIC/DIP			SA 5212(A)FE,N
NE 5212 D,D8	Phi	LIN-IC	=NE 5212FE,N: SMD	8-MDIP			SA 5212D
NE 5214 D	Phi	LIN-IC	SMD, Glasfaser/Fibre-Optic Postamplifier, 0...+70°	20-MDIP			SA 5214D
NE 5217 D	Phi	LIN-IC	SMD, Glasfaser/Fibre-Optic Postamplifier, 0...+70°	20-MDIP			SA 5217D
NE 5219 D	Phi	LIN-IC	=NE 5219N: SMD	16-MDIP			SA 5219D
NE 5219 N	Phi	LIN-IC	Breitb.-Verst./Wideband Amp., 700MHz, 0...+70°	16-DIP			SA 5219N
NE 5222 D	Phi	LIN-IC	SMD, FDDI Amp., lo-power, lo-noise, 0...+70°	8-MDIP			SA 5222D
NE 5224 D	Phi	LIN-IC	SMD, FDDI Glasfaser/Fibre-Optic Amp., 0...+70°	16-MDIP			SA 5224D
NE 5225 D	Phi	LIN-IC	SMD, FDDI Glasfaser/Fibre-Optic Amp., 0...+70°	16-MDIP			SA 5225D
NE 5230 D	Phi	OP-IC	=NE 5230FE,N: SMD	8-MDIP			SA 5230...
NE 5230 FE,N	Phi	OP-IC	lo-volt, ±9V, 0...+70°	8-DIC/DIP			SA 5230...
NE 5234 D	Phi	OP-IC	=NE 5234N: SMD	14-MDIP			SA 5234...
NE 5234 N	Phi	OP-IC	Quad, lo-volt, +2...5,5V, 0...+70°	14-DIP			SA 5234...
NE 5240 D	Phi	LIN-IC	=NE 5240N: SMD	28-MDIP			-
NE 5240 N	Phi	LIN-IC	Dolby Digital-Decoder, 0...+70°	28-DIP			-
NE 5410 F	Phi	D/A-IC	10 Bit, hi-speed, multiplying, 0...+70°	16-DIC			SE 5410
NE 5512 D	Phi	OP-IC	=NE 5512FE,N: SMD	8-MDIP			SA 5512...
NE 5512 FE,N	Phi	OP-IC	Dual, ±16V, 0...+70°	8-DIC/DIP			SA 5512...
NE 5514 D	Phi	OP-IC	=NE 5514F,N: SMD	14-MDIP			-
NE 5514 F,N	Phi	OP-IC	Quad, ±16V, 0...+70°, (=LM324,LM348)	14-DIC/DIP			SE 5514...
NE 5517 AN	Phi	OP-IC	=NE 5517N: ±22V	16-DIP			-
NE 5517 D	Phi	OP-IC	=NE 5517N: SMD	16-MDIP			-
NE 5517 N	Phi	OP-IC	Dual, Transconductance, ±18V, 0...+70°	16-DIP			-
NE 5520 D	Phi	LIN-IC	=NE 5520N: SMD	16-MDIP			-
NE 5520 F	Phi	LIN-IC	=NE 5520N: Fig. →	16-DIC			-
NE 5520 N	Phi	LIN-IC	LVDT Signal Conditioner, 0...+70°	14-DIP			-
NE 5521 D	Phi	LIN-IC	=NE 5521F,N: SMD	16-MDIP			SA 5521D
NE 5521 F,N	Phi	LIN-IC	LVDT Signal Conditioner, 0...+70°	18-DIC/DIP			SA 5521, SE 5521
NE 5532 A...	Phi,Tix	OP-IC	=NE 5532FE,JG,N,P: lo-noise	8-DIC/DIP	(NE 5532/8-D)	8-DIP	SE 5532A...
NE 5532 D	Phi	OP-IC	=NE 5532FE,JG,N,P: SMD	16-MDIP			-
NE 5532 FE,JG,N,P	Phi,Tix	OP-IC	Dual, ±22V, 10MHz, 9V/µs, 0...+70°	8-DIC/DIP	NE 5532/8-D	8-DIP	BA 15532, KA 5532, NJM 5532, SE 5532
NE 5533 AD,D	Phi	OP-IC	=NE 5534(A)FE,N: Dual, SMD	16-MDIP			-
NE 5533 AN,N	Phi	OP-IC	=NE 5534(A)FE,N: Dual	14-DIP			-
NE 5534(A)D	Phi,Tix	OP-IC	=NE 5534(A)FE,N: SMD	8-MDIP			-
NE 5534 A....	Phi,Tix	OP-IC	=NE 5534FE,JG,N,P: lo-noise	8-DIC/DIP	TDA 1034(BN)	8-DIP	SE 5534A
NE 5534 FE,JG,N,P	Phi,Tix	OP-IC	±22V, 10MHz, 13V/µs, 0...+70°	8-DIC/DIP	TDA 1034(BN)	8-DIP	SA 5534N, SE 5534
NE 5534(A)H	Phi	OP-IC	=NE 5534(A)FE,JG,N,P: Fig. →	TO-99			-
NE 5535 F	Phi	OP-IC	=NE 5535N: Fig. →	14-DIC			-
NE 5535 N	Phi	OP-IC	Dual, ±18V, 15V/µs, 0...+70°	8-DIP			-
NE 5537 D	Phi	LIN-IC	=NE 5537N: SMD	14-MDIP			-
NE 5537 N	Phi	LIN-IC	JFET, Sample & Hold	8-DIP			SE 5537
NE 5539 D	Phi	OP-IC	=NE 5538F,N: SMD	8-MDIP			-
NE 5539 F,N	Phi	OP-IC	Video-Verst./Wideband Amp., 0...+70°	14-DIC/DIP			SE 5539

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
NE 5553 F,N	Phi	Z-IC	Dual Polar., 5...20V, 0,3A, 0...+125°	14-DIC,DIP			-
NE 5553 H	Phi	Z-IC	=NE 5553F,N: Fig. →	TO-99			-
NE 5553 U	Phi	Z-IC	=NE 5553F,N: Fig. →	9-SIL			-
NE 5560 D	Phi	LIN-IC	=NE 5560F,N: SMD	16-MDIP			TDA 1060T
NE 5560 F,N	Phi	LIN-IC	TV, SMPS Controller, 0...+70°	16-DIC/DIP	TDA 1060	16-DIP	B 260D, SE 5560, TDA 1060
NE 5561 D	Phi	LIN-IC	=NE 5560F,N: SMD	8-MDIP			-
NE 5561 FE,N	Phi	LIN-IC	SMPS Controller, 0...+70°	8-DIC/DIP			SE 5561
NE 5562 D	Phi	LIN-IC	=NE 5562F,N: SMD	20-MDIP			-
NE 5562 F,N	Phi	LIN-IC	SMPS Controller, 0...+70°	20-DIC/DIP			SE 5562
NE 5568 D	Phi	LIN-IC	=NE 5568FE,N: SMD	8-MDIP			-
NE 5568 FE,N	Phi	LIN-IC	SMPS-Controller, 0...+70°	8-DIC/DIP			-
NE 5570 D	Phi	LIN-IC	=NE 5570F,N: SMD	24-MDIP			-
NE 5570 F,N	Phi	LIN-IC	DC Motor Controller, 0...+70°	24-DIC/DIP			SA 5570, SE 5570
NE 5592 D	Phi	LIN-IC	=NE 5592N: SMD	14-MDIP			-
NE 5592 N	Phi	LIN-IC	Dual, Video-Verst./Wideband Amp., 110MHz, 0...+70°	14-DIP			-
NE 5750 D	Phi	LIN-IC	=NE 5750F,N: Min	24-MDIP			SA 5750D
NE 5750 F,N	Phi	LIN-IC	Audio Processor f. HF Communication, 0...+70°	24-DIC/DIP			SA 5750E,N
NE 5751 D	Phi	LIN-IC	=NE 5751F,N: Min	28-MDIP			SA 5751D
NE 5751 F,N	Phi	LIN-IC	Audio Processor f. HF Communication, 0...+70°	24-DIC/DIP			SA 5751F,N
NE 5900 D	Phi	CMOS-IC	=NE 5900N: SMD	16-MDIP			-
NE 5900 N	Phi	CMOS-IC	Call Progress Decoder(CPD), 0...+70°	16-DIP			-
NE 8392 A	Phi	LIN-IC	Koaxial Ethernet Transceiver Interface	16-DIP			-
NE 8392 A ?	Phi	LIN-IC	=NE 8392A:	28-PLCC			-
NE 13600 AD,D	Phi	OP-IC	=LM 13600(A): SMD	16-MDIP			-
NE 86950 B	Phi	LIN-IC	Ether Star Ethernet Controller	84-PLCC			-
NE 86950 B ?	Phi	LIN-IC	=NE 86950B:	80-MP			-
NEC 2 p4M	Nec	Thy			TIC 106 M	17e	
NEC 572 C2	Nec	LIN-IC	=µPC 572 C2		µPC 572 C2		µPC 572 C2
NF		MOS-N-FET-e	=2SK1587 (SMD-Marking)	39	SOT-89		+2SK1587
NF		Si-N	=KRC106S (SMD-Marking)	35	SOT-23		+KRC 106S
NFD 15(A...E)	Nec	Si-PNP-Di	2x Di (Diac), 80V, 0,25A, U <sub>bo</sub> =96...152V, I <sub>h</sub> =20mA	7d	TO-92		-
NG		MOS-N-FET-e	=2SK1588 (SMD-Marking)	39	SOT-89		+2SK1588
NG 02		MOS-IC	MCU				-
NH		MOS-N-FET-e	=2SK1584 (SMD-Marking)	39	SOT-89		+2SK1584
NH		Si-N	=KRC107S (SMD-Marking)	35	SOT-23		+KRC 107S
NI		MOS-N-FET-e	=2SK1586 (SMD-Marking)	39	SOT-89		+2SK1586
NI		Si-N	=KRC108S (SMD-Marking)	35	SOT-23		+KRC 108S
NIP 2400	itt	CMOS-IC	TV, HiFi Stereo-Decoder, NICAM Standard	44-PLCC			-
<b>NJ</b>							
NJ		Si-N	=KRC109S (SMD-Marking)	35	SOT-23		+KRC 109S
NJ 8811	Pls	CMOS-IC	Frequ.-Synthesizer Ctrl., Phase Comp. f. SP8901/6	18-DIC,DIP			-
NJ 8812	Pls	CMOS-IC	Frequ.-Synthesizer Ctrl., Phase Comp. f. SP 8793	18-DIP			-
NJ 8820	Pls	CMOS-IC	Frequ.-Synthesizer Control, PROM Interface	20-DIC,DIP			-
NJ 8821	Pls	CMOS-IC	Frequ.-Synthesizer Control, µComp. Interface	20-DIC,DIP			-
NJ 8822	Pls	CMOS-IC	Frequ.-Synthesizer Control, µComp. ser. Interface	16-DIC,DIP			-
NJD 6506 S	Njr	LIN-IC	4x NPN Trans, 20V, 0,2A, 0,5W, hFE=60...600	9-SIP			-
NJD 6507 S	Njr	LIN-IC	4x NPN Trans, 25V, 0,2A, 0,5W, hFE=60...600	9-SIP			-
NJD 6511	Njr	LIN-IC	7x NPN Darlington, 35V, 0,5A, 0,7W, hFE>1000	16-DIP			-
NJD 6512	Njr	LIN-IC	7x NPN Darlington, 35V, 0,5A, 0,7W, hFE>1000	16-DIP			-
NJD 6513	Njr	LIN-IC	7x NPN Darlington, 35V, 0,5A, 0,7W, hFE>1000	16-DIP			-
NJD 6514	Njr	LIN-IC	7x NPN Darlington, 35V, 0,5A, 0,7W, hFE>1000	16-DIP			-
NJH 1001	Njr	Hybrid-IC	Audio Verstärker/Amplifier, In	5-SIP			-
NJH 1014	Njr	Hybrid-IC	Audio Vorverstärker/Preamplifier, In				-
NJH 1601	Njr	Hybrid-Z-IC	+5,1...5,9V	3-Sip			-
NJH 1602	Njr	Hybrid-Z-IC	+5,1...5,9V	4-Sip			-
NJH 1604	Njr	Hybrid-Z-IC	+10,8...13,2V	3-SIP			-
NJH 1605	Njr	Hybrid-Z-IC	+10,8...13,2V	3-SIP			-
<b>NJM</b>							
NJM 022 B(D,L,M)	Njr	OP-IC	=NJM 022D: 1V/µs				-
NJM 022 D	Njr	OP-IC	Dual, Io-power, ±18V, 0,5V/µs, -20...+75	8-DIP			TL 022...
NJM 022 L	Njr	OP-IC	=NJM 022(B): Fig. →	8-SIP			-
NJM 022 M	Njr	OP-IC	=NJM 022(B): SMD	8-MDIP			TL 022...
NJM 062 D	Njr	OP-IC	Dual, J-FET, Serie 153, ±18V, -20...+75°	8-DIP			LF 153..., LF 253..., TA 75062..., TL 062...
NJM 062 L	Njr	OP-IC	=NJM 062D: Fig. →	8-SIP			LF 135..., LF 235..., TA 75062..., TL 062...
NJM 062 M	Njr	OP-IC	=NJM 062D: SMD	8-MDIP			LF 135..., LF 235..., TA 75062..., TL 062...
NJM 064 D	Njr	OP-IC	Quad, J-FET, ±18V, -20...+75°	14-DIP			TA 75064..., TL 064...
NJM 064 M	Njr	OP-IC	=NJM 064D: SMD	14-MDIP			TA 75064..., TL 064...
NJM 072(B)...	Njr	OP-IC	=NJM 082...: Io-noise				+TL 072...
NJM 074 ...	Njr	OP-IC	=NJM 084...: Io-noise				+TL 074...
NJM 78 L02(A)	Njr	Z-IC	+2,6V, 10%(A=5%), 0,1A	7b	TO-92		... 78L02... (TO-92)
NJM 78 L05(A)	Njr	Z-IC	+5V, 10%(A=5%), 0,1A	7b	TO-92	78L05/TO-92	7b ... 78L05... (TO-92)
NJM 78 L06(A)	Njr	Z-IC	+6V, 10%(A=5%), 0,1A	7b	TO-92		... 78L06... (TO-92)
NJM 78 L08(A)	Njr	Z-IC	+8V, 10%(A=5%), 0,1A	7b	TO-92	78L08/TO-92	7b ... 78L08... (TO-92)
NJM 78 L09(A)	Njr	Z-IC	+9V, 10%(A=5%), 0,1A	7b	TO-92		... 78L09... (TO-92)
NJM 78 L12(A)	Njr	Z-IC	+12V, 10%(A=5%), 0,1A	7b	TO-92	78L12/TO-92	7b ... 78L12... (TO-92)
NJM 78 L15(A)	Njr	Z-IC	+15V, 10%(A=5%), 0,1A	7b	TO-92	78L15/TO-92	7b ... 78L15... (TO-92)
NJM 78 L18(A)	Njr	Z-IC	+18V, 10%(A=5%), 0,1A	7b	TO-92		... 78L18... (TO-92)
NJM 78 L20(A)	Njr	Z-IC	+20V, 10%(A=5%), 0,1A	7b	TO-92		... 78L20... (TO-92)
NJM 78 L24(A)	Njr	Z-IC	+24V, 10%(A=5%), 0,1A	7b	TO-92		... 78L24... (TO-92)
NJM 78 LxxU(A)	Njr	Z-IC	=NJM 78L02...L24(A): SMD	39b	SOT-89		... 78Lxx... (SOT-89)
NJM 78 M05(A)	Njr	Z-IC	+5V, 10%(A=5%), 0,5A	17b	TO-220	7805/TO-220	17b ... 78M05... (TO-220)
NJM 78 M06(A)	Njr	Z-IC	+6V, 10%(A=5%), 0,5A	17b	TO-220	7806/TO-220	17b ... 78M06... (TO-220)
NJM 78 M08(A)	Njr	Z-IC	+8V, 10%(A=5%), 0,5A	17b	TO-220	7808/TO-220	17b ... 78M08... (TO-220)
NJM 78 M09(A)	Njr	Z-IC	+9V, 10%(A=5%), 0,5A	17b	TO-220	7809/TO-220	17b ... 78M09... (TO-220)
NJM 78 M12(A)	Njr	Z-IC	+12V, 10%(A=5%), 0,5A	17b	TO-220	7812/TO-220	17b ... 78M12... (TO-220)
NJM 78 M15(A)	Njr	Z-IC	+15V, 10%(A=5%), 0,5A	17b	TO-220	7815/TO-220	17b ... 78M15... (TO-220)
NJM 78 M18(A)	Njr	Z-IC	+18V, 10%(A=5%), 0,5A	17b	TO-220	7818/TO-220	17b ... 78M18... (TO-220)
NJM 78 M20(A)	Njr	Z-IC	+20V, 10%(A=5%), 0,5A	17b	TO-220	7820/TO-220	17b ... 78M20... (TO-220)
NJM 78 M24(A)	Njr	Z-IC	+24V, 10%(A=5%), 0,5A	17b	TO-220	7824/TO-220	17b ... 78M24... (TO-220)
NJM 78 MxxF(A)	Njr	Z-IC	=NJM 78 M05...M24(A): Iso	17b	TO-220 Iso	78xx/IsoTO-220	17b ... 78Mxx... (TO-220 Iso)
NJM 79 L03(A)	Njr	Z-IC	-3V, 10%(A=5%), 0,1A	7a	TO-92		... 79L03... (TO-92)



Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
NJM 79 L05(A)	Njr	Z-IC	-5V, 10%(A=5%), 0,1A	7a	TO-92	79L05/TO-92	7a ... 79L05... (TO-92)
NJM 79 L06(A)	Njr	Z-IC	-6V, 10%(A=5%), 0,1A	7a	TO-92		... 79L06... (TO-92)
NJM 79 L08(A)	Njr	Z-IC	-8V, 10%(A=5%), 0,1A	7a	TO-92		... 79L08... (TO-92)
NJM 79 L09(A)	Njr	Z-IC	-9V, 10%(A=5%), 0,1A	7a	TO-92		... 79L09... (TO-92)
NJM 79 L12(A)	Njr	Z-IC	-12V, 10%(A=5%), 0,1A	7a	TO-92	79L12/TO-92	7a ... 79L12... (TO-92)
NJM 79 L15(A)	Njr	Z-IC	-15V, 10%(A=5%), 0,1A	7a	TO-92		... 79L15... (TO-92)
NJM 79 L18(A)	Njr	Z-IC	-18V, 10%(A=5%), 0,1A	7a	TO-92		... 79L18... (TO-92)
NJM 79 L24(A)	Njr	Z-IC	-24V, 10%(A=5%), 0,1A	7a	TO-92		... 79L24... (TO-92)
NJM 79 LxxU(A)	Njr	Z-IC	=NJM 79L02...L24(A): SMD	39a	SOT-89		... 79Lxx... (SOT-89)
NJM 79 M05(A)	Njr	Z-IC	-5V, 10%(A=5%), 0,5A	17c	TO-220	7905/TO-220	17c ... 79M05... (TO-220)
NJM 79 M06(A)	Njr	Z-IC	-6V, 10%(A=5%), 0,5A	17c	TO-220		... 79M06... (TO-220)
NJM 79 M08(A)	Njr	Z-IC	-8V, 10%(A=5%), 0,5A	17c	TO-220		... 79M08... (TO-220)
NJM 79 M09(A)	Njr	Z-IC	-9V, 10%(A=5%), 0,5A	17c	TO-220		... 79M09... (TO-220)
NJM 79 M12(A)	Njr	Z-IC	-12V, 10%(A=5%), 0,5A	17c	TO-220	7912/TO-220	17c ... 79M12... (TO-220)
NJM 79 M15(A)	Njr	Z-IC	-15V, 10%(A=5%), 0,5A	17c	TO-220	7915/TO-220	17c ... 79M15... (TO-220)
NJM 79 M18(A)	Njr	Z-IC	-18V, 10%(A=5%), 0,5A	17c	TO-220		... 79M18... (TO-220)
NJM 79 M24(A)	Njr	Z-IC	-24V, 10%(A=5%), 0,5A	17c	TO-220		... 79M24... (TO-220)
NJM 79 MxxF(A)	Njr	Z-IC	=NJM 79 M05...M24(A): Iso	17c	TO-220 Iso	(79xx/TO-220) <sup>3</sup>	17c ... 79Mxx... (TO-220 Iso)
NJM 082(B)D	Njr	OP-IC	Dual, J-FET, Serie 080, ±18V, 5(B=3)MHz, -20...+75°	8-DIP			+TL 082...
NJM 82(B)L	Njr	OP-IC	=NJM 082(B)D: Fig. →	8-SIP			
NJM 082 M	Njr	OP-IC	=NJM 082(B)D: SMD	8-MDIP			+TL 082...
NJM 082 S	Njr	OP-IC	=NJM 082(B)D: Fig. →	9-SIP			
NJM 084 ...	Njr	OP-IC	=NJM 082... Quad	14-(M)DIP			+TL 087...
NJM 311 D	Njr	KOP-IC	Serie 111, 36(±18)V, -20...+75°	8-DIP			+LM 311...
NJM 311 M	Njr	KOP-IC	=NJM 311D: SMD	8-MDIP			+LM 311...
NJM 311 T	Njr	KOP-IC	=NJM 311D: Fig. →	TO-99			+LM 311...
NJM 317 F	Njr	Z-IC	Iso, +1,25...37V, >1,5A, -30...+150°	17l	TO-220 Iso		+LM 317...
NJM 318 D	Njr	OP-IC	Serie 118, hi-speed, ±20V, 70V/µs, 15MHz, -20...+75°	8-DIP	318/8-D	8-DIP	+LM 318...
NJM 318 M	Njr	OP-IC	=NJM 318D: SMD	8-MDIP			+LM 318...
NJM 318 T	Njr	OP-IC	=NJM 318D: Fig. →	TO-99			+LM 318
NJM 319 D	Njr	KOP-IC	Dual, Serie 119, 36(±18)V, -20...+75°	14-DIP			+LM 319...
NJM 319 M	Njr	KOP-IC	=NJM 319D: SMD	14-MDIP			+LM 319...
NJM 319 T	Njr	KOP-IC	=NJM 319D: Fig. →	TO-100			+LM 319...
NJM 324 D	Njr	OP-IC	Quad, Serie 124, ±16V, -20...+75°	14-DIP	LM 324 N	14-DIP	+LM 324...
NJM 324 M	Njr	OP-IC	=NJM 324D: SMD	14-MDIP			+LM 324...
NJM 353 D	Njr	OP-IC	Dual, J-FET, Serie 153, ±18V, 13V/µs, -20...+70°	8-DIP			+LF 353...
NJM 353 M	Njr	OP-IC	=NJM 353D: SMD	8-MDIP			+LF 353...
NJM 353 T	Njr	OP-IC	=NJM 353D: Fig. →	TO-99			+LF 353...
NJM 360 D	Njr	KOP-IC	hi-speed, ±8V, <20ns, -20...+75°	8-DIP			+LM 360N
NJM 360 M	Njr	KOP-IC	=NJM 360D: SMD	8-MDIP			
NJM 386 BD	Njr	LIN-IC	=NJM 386D: 22V	8-DIP			
NJM 386 BS	Njr	LIN-IC	=NJM 386S: 22V	9-SIP			
NJM 386 D	Njr	LIN-IC	LF Out, 15V, 0,325W(6V/8Ω), 0,5W(9V/16Ω)	8-DIP			LM 386N-1
NJM 386 L	Njr	LIN-IC	=NJM 386D: Fig. →	8-SIP			
NJM 386 M	Njr	LIN-IC	=NJM 386D: SMD	8-MDIP			
NJM 386 S	Njr	LIN-IC	=NJM 386D: Fig. →	9-SIP			
NJM 387 D(A,B)	Njr	LIN-IC	2x LF Preamp., In, Ucc=8...40V, A: Ur<0,9 B: <1,8µV	8-DIP			LM 387(A)N
NJM 387 L(A,B)	Njr	LIN-IC	=LM 387D: Fig. →	8-SIP			
NJM 387 M(A,B)	Njr	LIN-IC	=NJM 387D: SMD	8-MDIP			
NJM 387 S(A,B)	Njr	LIN-IC	=LM 387D: Fig. →	9-SIP			
NJM 431 D	Njr	Ref-Z-IC	+2,5...36V, 1...100mA, 0,2<0,5Ω, -20...+85°	8-DIP			KA 431..., TL 431..., µA 431...
NJM 431 L	Njr	Ref-Z-IC	=NJM 431D: Fig. →	7(KARef)	TO-92		KA 431...Z, TL 431..., µA 431...
NJM 431 M	Njr	Z-IC	=NJM 431D: SMD	8-MDIP			
NJM 431 U	Njr	Z-IC	=NJM 431D: SMD	39(KARef)	SOT-89		
NJM 555 D	Njr	LIN-IC	=NE 555...	8-DIP	NE 555 N	8-DIP	+NE 555...
NJM 555 L	Njr	LIN-IC	=NE 555...: Fig. →	8-SIP			
NJM 555 M	Njr	LIN-IC	=NE 555...: SMD	8-MDIP			+NE 555...
NJM 555 S	Njr	LIN-IC	=NE 555...: Fig. →	9-SIP			
NJM 556 D	Njr	LIN-IC	=NE 556...	14-DIP	NE 556 N	14-DIP	+NE 556...
NJM 556 M	Njr	LIN-IC	=NE 556...: SMD	14-MDIP			+NE 556...
NJM 567 D	Njr	LIN-IC	=LM 567...	8-DIP	LM 567 CN		+LM 567...
NJM 567 M	Njr	LIN-IC	=NJM 567...: SMD	8-MDIP			+LM 567...
NJM 567 T	Njr	LIN-IC	=NJM 567...: Fig. →	TO-99			+LM 567...
NJM 592 D	Njr	LIN-IC	Diff. Video-Verst./Amp., 90MHz, Ucc<±8V, 0...+70°	14-DIP	NE 592/14-D	14-DIP	LM 592, NE 592FN, SE 592FJ, µA 592D,P
NJM 592 D8	Njr	LIN-IC	NJM 592: Fig. →	8-DIP	NE 592/8-D	8-DIP	NE 592N8, SA 592N8, TL 592BP, µA 592T
NJM 592 M	Njr	LIN-IC	=NJM 592: SMD	14-MDIP			LM 592M, NE 592D
NJM 592 M8	Njr	LIN-IC	NJM 592: SMD	8-MDIP			NE 592D8, SA 592D8, TL 592D8, µA 592S
NJM 703 N	Njr	LIN-IC	HF,IF Verstärker/Amplifier	TO-99/6Pin			
NJM 703 W	Njr	LIN-IC	=NJM 703N: Dual	TO-99			
NJM 723 D	Njr	Z-IC	+2...37V, 0,15A, -20...+75°	14-DIP	723/14-D	14-DIP	... 723...
NJM 723 M	Njr	Z-IC	=NJM 723D: SMD	14-MDIP			... 723...
NJM 723 T	Njr	Z-IC	=NJM 723D: Fig. →	TO-100			... 723...
NJM 741 A	Njr	OP-IC	Uni, Serie 741, ±22V, -55...+125°	TO-99	(741/TO) <sup>16</sup>	TO-99	+LM 741...
NJM 741 B	Njr	OP-IC	=NJM 741A: -20...+75°	TO-99	(741/TO) <sup>16</sup>	TO-99	+LM 741...
NJM 741 C	Njr	OP-IC	=NJM 741A: 18V, 0...+75°	TO-99	741/TO	TO-99	+LM 741...
NJM 741 D	Njr	OP-IC	=NJM 741A: 18V, -20...+75°	8-DIP	741/8-D	8-DIP	+LM 741...
NJM 741 F	Njr	OP-IC	=NJM 741A: 18V, -20...+75°, SMD	8-FLP			+LM 741...
NJM 741 M	Njr	OP-IC	=NJM 741A: SMD	8-MDIP			+LM 741...
NJM 741 T	Njr	OP-IC	=NJM 741A: 18V, -20...+75°	TO-99	741/TO	TO-99	+LM 741...
NJM 1372 AD	Njr	LIN-IC	TV/Vc, Video Modulator, 3,58MHz, Ucc=5V	14-DIP			
NJM 1458 D	Njr	OP-IC	Dual, Serie 158, ±18V, -20...+75°	8-DIP	4558/8-D	8-DIP	+LM 1458...
NJM 1458 M	Njr	OP-IC	=NJM 1458D: SMD	8-MDIP			+LM 1458...
NJM 1496 D	Njr	LIN-IC	Telecom, Double Balanced Modulator/Demodulator	14-DIP			
NJM 1496 M	Njr	LIN-IC	NJM 1496D: SMD	14-MDIP			
NJM 2006	Njr	LIN-IC	Electret Microfon Verst./Amplifier				
NJM 2008(/R)	Njr	LIN-IC	Elektret Microfon Verst./Amplifier				
NJM 2013	Njr	LIN-IC	Electret Microfon Verst./Amplifier				
NJM 2015	Njr	LIN-IC	Electret Microfon Verst./Amplifier				
NJM 2035 D	Njr	LIN-IC	Stereo Modulator, Ucc<3,6V	14-DIP			
NJM 2035 M	Njr	LIN-IC	=NJM 2035D: SMD	14-MDIP			
NJM 2037	Njr	LIN-IC	Audio Inp, In, Equalizer, Ucc=±30V	10-SIL			
NJM 2041 D	Njr	OP-IC	Dual, lo-noise, ±22V, 3V/µs, 7MHz, -20...+75°	8-DIP			
NJM 2041 L	Njr	OP-IC	=NJM 2041D: Fig. →	8-SIP			

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
NJM 2041 M	Njr	OP-IC	=NJM 2041D: SMD			8-MDIP	-
NJM 2041 S	Njr	OP-IC	=NJM 2041D: Fig. →			9-SIP	-
NJM 2043 D	Njr	OP-IC	Dual, lo-noise, ±22V, 6V/μs, 14MHz, -20...+75°			8-DIP	-
NJM 2043 L	Njr	OP-IC	=NJM 2043D: Fig. →			8-SIP	-
NJM 2043 M	Njr	OP-IC	=NJM 2043D: SMD			8-MDIP	-
NJM 2043 S	Njr	OP-IC	=NJM 2043D: Fig. →			9-SIP	-
NJM 2048 D	Njr	Z-IC	S-Reg, 4.8V, 8.6V, 50kHz, Uref=5V, -20...+75°			14-DIP	-
NJM 2048 M	Njr	Z-IC	=NJM 2048D: SMD			14-MDIP	-
NJM 2049 D	Njr	Z-IC	S-Reg, 2x 2V, 50kHz, Uref=5V, -20...+75°			14-DIP	-
NJM 2049 M	Njr	Z-IC	=NJM 2049D: SMD			14-MDIP	-
NJM 2058 D	Njr	OP-IC	Quad, PNP-Trans., ±18V, 1V/μs, -20...+75°			14-DIP	-
NJM 2058 M	Njr	OP-IC	=NJM 2058D: SMD			14-MDIP	-
NJM 2059 D	Njr	OP-IC	Quad, ±18V, 2V/μs, 6MHz, -20...+75°			14-DIP	-
NJM 2059 M	Njr	OP-IC	=NJM 2059D: SMD			14-MDIP	-
NJM 2060 D	Njr	OP-IC	Quad, ±18V, 4V/μs, 10MHz, -20...+75°			14-DIP	-
NJM 2060 M	Njr	OP-IC	=NJM 2060D: SMD			14-MDIP	-
NJM 2063 AD	Njr	LIN-IC	Dolby B Processor, Ucc=1.8...6V			16-DIP	-
NJM 2063 AM	Njr	LIN-IC	=NJM 2063AD: SMD			16-MDIP	-
NJM 2065 AD	Njr	LIN-IC	Dolby B,C Processor, Ucc=1.8...6V			20-DIP	-
NJM 2065 AM	Njr	LIN-IC	=NJM 2065: SMD			20-MDIP	-
NJM 2066 D	Njr	LIN-IC	Dual Kopfh.-Verst./Headphone Amp., Ucc=1.8...5V			16-DIP	-
NJM 2066 M	Njr	LIN-IC	=NJM 2066D: SMD			16-MDIP	-
NJM 2067 D	Njr	LIN-IC	Autoreverse Recorder, Dual LF Preamp., In, Ucc=3V			16-DIP	-
NJM 2067 M	Njr	LIN-IC	=NJM 2067D: SMD			16-MDIP	-
NJM 2068 D	Njr	OP-IC	Dual, lo-noise, ±18V, 7V/μs, 27MHz, -20...+75°			8-DIP	-
NJM 2068 L	Njr	OP-IC	=NJM 2068D: Fig. →			8-SIP	-
NJM 2068 M	Njr	OP-IC	=NJM 2068D: SMD			8-MDIP	-
NJM 2068 S	Njr	OP-IC	=NJM 2068D: Fig. →			9-SIP	-
NJM 2070 D	Njr	LIN-IC	LF Out, Ucc=1.8...15V, 1A, 0.5W(6V/4Ω)			8-DIP	-
NJM 2070 M	Njr	LIN-IC	=NJM 2070D: SMD			8-MDIP	-
NJM 2072 D	Njr	LIN-IC	Signal-Pegel/Level Sensor System, Ucc=0.9...7V			8-DIP	-
NJM 2072 M	Njr	LIN-IC	=NJM 2072D: Min			8-MDIP	-
NJM 2073 D	Njr	LIN-IC	Dual Audio Out, 1.8...15V, 1A, 2x0.25W(4V/4Ω)			8-DIP	-
NJM 2073 M	Njr	LIN-IC	=NJM 2073D: SMD			8-MDIP	-
NJM 2073 S	Njr	LIN-IC	=NJM 2073D: Fig. →			9-SIP	-
NJM 2075 AD	Njr	LIN-IC	Dolby B,C Processor, Ucc=1.8...6V			20-DIP	-
NJM 2075 AM	Njr	LIN-IC	=NJM 2075: SMD			20-MDIP	-
NJM 2076 D	Njr	LIN-IC	Dual LF Out, 1...4.5V, 2x20mW(1.5V/16Ω), 90mW(BTL)			8-DIP	-
NJM 2076 M	Njr	LIN-IC	=NJM 2076D: SMD			8-MDIP	-
NJM 2076 S	Njr	LIN-IC	=NJM 2076D: Fig. →			9-SIP	-
NJM 2078 D	Njr	LIN-IC	Spannungs-/Voltage Detector, Uth=1.2V, -20...+75°			8-DIP	-
NJM 2078 M	Njr	LIN-IC	=NJM 2078D: SMD			8-MDIP	-
NJM 2082 D	Njr	OP-IC	Dual, J-FET, ±18V, 20V/μs, 5MHz, -20...+75°			8-DIP	-
NJM 2082 L	Njr	OP-IC	=NJM 2082D: Fig. →			8-SIP	-
NJM 2082 M	Njr	OP-IC	=NJM 2082D: SMD			8-MDIP	-
NJM 2082 S	Njr	OP-IC	=NJM 2082D: Fig. →			9-SIP	-
NJM 2096 D	Njr	LIN-IC	Dual Audio Out, 1...4.5V, 2x20mW(1.5V/16Ω)			8-DIP	-
NJM 2096 M	Njr	LIN-IC	=NJM 2096D: SMD			8-MDIP	-
NJM 2096 S	Njr	LIN-IC	=NJM 2096D: Fig. →			9-SIP	-
NJM 2097 M	Njr	OP-IC	SMD, Hex, ±7.5V, 5V/μs, 10MHz, -20...+75°			24-MDIP	-
NJM 2100 D	Njr	OP-IC	Dual, lo-volt, ±3.5V, 4V/μs, 12MHz, -20...+75°			8-DIP	-
NJM 2100 L	Njr	OP-IC	=NJM 2100D: Fig. →			8-SIP	-
NJM 2100 M	Njr	OP-IC	=NJM 2100D: SMD			8-MDIP	-
NJM 2103 D	Njr	LIN-IC	System Reset, Ucc=5V, -20...+75°			8-DIP	-
NJM 2103 L	Njr	LIN-IC	=NJM 2103D: Fig. →			8-SIP	-
NJM 2103 M	Njr	LIN-IC	=NJM 2103D: SMD			8-MDIP	-
NJM 2105 S	Njr	LIN-IC	Telecom, Sprechkreis/Speech Network			9-SIP	-
NJM 2106 M	Njr	LIN-IC	SMD, 2x Active Audio Bass Expander, Ucc= 0.9...2.5V			16-MDIP	-
NJM 2107 F	Njr	OP-IC	SMD, lo-volt, ±3.5V, 3V/μs, -25...+75°			-5-MDIP	-
NJM 2175 F	Njr	LIN-IC	=NJM 2175L: SMD			44-MP	-
NJM 2175 L	Njr	LIN-IC	Dolby Pro Logic Surround Sound Decoder, Ucc=12V			56-SDIP	-
NJM 2201 F	Njr	LIN-IC	=LM 2201S: SMD			8-FLP	-
NJM 2201 S	Njr	LIN-IC	FM IF			7-SIP	-
NJM 2201 T	Njr	LIN-IC	=LM 2201S: Fig. →			TO-99	-
NJM 2203 D	Njr	LIN-IC	Telecom, Mischer/Mixer(full balanced), Ucc=12V			16-DIP	-
NJM 2204 AD,BD	Njr	LIN-IC	Telecom, Logarithm. Verstärker/Amplifier			16-DIP	-
NJM 2205 D	Njr	LIN-IC	TV, Video-Modulator			16-DIP	-
NJM 2206 D	Njr	LIN-IC	Telecom, FM Schmalband PLL/Narrowband PLL IF			20-DIP	-
NJM 2206 M	Njr	LIN-IC	=NJM 2206D: SMD			20-MDIP	-
NJM 2207 D	Njr	LIN-IC	Video Superimposer, Ucc=4,75...13V			14-DIP	-
NJM 2207 M	Njr	LIN-IC	=NJM 2207D: SMD			14-MDIP	-
NJM 2207 S	Njr	LIN-IC	=NJM 2207D: Fig. →			16-SQP	-
NJM 2208 D	Njr	LIN-IC	TV, Video Modulator, 3,58MHz, Ucc=5V			16-DIP	-
NJM 2209 M	Njr	LIN-IC	=NJM 2209S: SMD			14-MDIP	-
NJM 2209 S	Njr	LIN-IC	VC, Bildverbess./Video Picture Enhancer, Ucc=5V			9-SIP	-
NJM 2210 D	Njr	LIN-IC	Video Störverminderung/Noise Reducer, Ucc=5V			8-DIP	-
NJM 2210 M	Njr	LIN-IC	=NJM 2210D: SMD			8-MDIP	-
NJM 2211 D	Njr	LIN-IC	FSK Demodulator, Tone Decoder, Ucc=4,5...20V			14-DIP	-
NJM 2211 M	Njr	LIN-IC	=NJM 2211D: SMD			14-MDIP	-
NJM 2214 L	Njr	LIN-IC	VC, Camera, Video On Screen Display, Ucc=5V			22-SDIP	-
NJM 2217 D	Njr	LIN-IC	Video Superimposer, AFC, Ucc=5V			22-DIP	-
NJM 2217 L	Njr	LIN-IC	=NJM 2217D: Fig. →			22-SDIP	-
NJM 2219 D	Njr	LIN-IC	VC, HF Modulator, Ucc=5V			16-DIP	-
NJM 2220 S	Njr	LIN-IC	TV/VC/Camera, Video Sync. Detector, Ucc=4,75...10V			9-SIP	-
NJM 2223 M	Njr	LIN-IC	SMD, Video-Umschalter/Switch, 8dB Amp., Ucc=12V			16-MDIP	-
NJM 2224 M	Njr	LIN-IC	SMD, Video Störverminderung/Noise Reducer, Ucc=5V			8-MDIP	-
NJM 2225(A)M	Njr	LIN-IC	=NJM 2225(A): SMD			16-MDIP	-
NJM 2225(A)S	Njr	LIN-IC	Camera, Blendenaomatik/Auto Iris Function, 9V			16-SQP	-
NJM 2228 D	Njr	LIN-IC	Video Subcarrier Signal Doubler/Tripler, Ucc=5V			8-DIP	-
NJM 2228 M	Njr	LIN-IC	=NJM 2228D: SMD			8-MDIP	-
NJM 2228 S	Njr	LIN-IC	=NJM 2228D: Fig. →			9-SIP	-
NJM 2229 M	Njr	LIN-IC	=NJM 2229S: SMD			16-MDIP	-
NJM 2229 S	Njr	LIN-IC	Video Sync. Separation, AFC, Ucc=5			16-SQP	-

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
NJM 2230 M	Njr	LIN-IC	SMD,TV/VC/Camera, Video Sync Detect, Ucc=4.75...10V	9-SIP			
NJM 2232 AM	Njr	LIN-IC	SMD, Telecom, FM IF, Log. Verst./Amp., Ucc=6V	24-MDIP			
NJM 2233 BD	Njr	LIN-IC	Video Umschalter/Switch, 2-Input, Ucc=5V	8-DIP			
NJM 2233 BL	Njr	LIN-IC	=NJM 2233BD: Fig. →	8-SIP			
NJM 2233 BM	Njr	LIN-IC	=NJM 2233BD: SMD	8-MDIP			
NJM 2234 D	Njr	LIN-IC	Video Umschalter/Switch, 3-Input, Ucc=5V	8-DIP			
NJM 2234 L	Njr	LIN-IC	=NJM 2234D: Fig. →	8-SIP			
NJM 2234 M	Njr	LIN-IC	=NJM 2234D: SMD	8-MDIP			
NJM 2235 D	Njr	LIN-IC	Video Umschalter/Switch, 3-Input, Ucc=5V	8-DIP			
NJM 2235 L	Njr	LIN-IC	=NJM 2235D: Fig. →	8-SIP			
NJM 2235 M	Njr	LIN-IC	=NJM 2235D: SMD	8-MDIP			
NJM 2236(A)D	Njr	LIN-IC	FM Tuner/Front-End, Ucc=1.6...6V, Uosc=80(A=110)mV	8-DIP			
NJM 2236(A)L	Njr	LIN-IC	=NJM 2236(A)D: Fig. →	8-SIP			
NJM 2236(A)M	Njr	LIN-IC	=NJM 2236(A)D: SMD	8-MDIP			
NJM 2237 D	Njr	LIN-IC	AM/FM Radio, Audio Out, 0.5W(4.5V/4Ω), Ucc=1.8...6V	20-DIP			
NJM 2238 D	Njr	LIN-IC	Video Subcarrier Signal Tripler, Ucc=5V	8-DIP			
NJM 2238 M	Njr	LIN-IC	=NJM 2238D: SMD	8-MDIP			
NJM 2238 S	Njr	LIN-IC	=NJM 2238D: Fig. →	9-SIP			
NJM 2240 D	Njr	LIN-IC	Video Subcarrier Signal Quadrupler, Ucc=5V	8-DIP			
NJM 2240 M	Njr	LIN-IC	=NJM 2240D: SMD	8-MDIP			
NJM 2240 S	Njr	LIN-IC	=NJM 2240D: Fig. →	9-SIP			
NJM 2241 M	Njr	LIN-IC	SMD,AM/FM Radio, LF Out, 0.5W(4.5V/4Ω),Ucc=1.8...6V	24-MDIP			
NJM 2243 D	Njr	LIN-IC	Video Umschalter/Switch, 3-Input, 75Ω-Drv, Ucc=5V	8-DIP			
NJM 2243 L	Njr	LIN-IC	=NJM 2243D: Fig. →	8-SIP			
NJM 2243 M	Njr	LIN-IC	=NJM 2243D: SMD	8-MDIP			
NJM 2244 D	Njr	LIN-IC	Video Umschalter/Switch, 3-Input, 75Ω-Drv, Ucc=5V	8-DIP			
NJM 2244 L	Njr	LIN-IC	=NJM 2244D: Fig. →	8-SIP			
NJM 2244 M	Njr	LIN-IC	=NJM 2244D: SMD	8-MDIP			
NJM 2245 D	Njr	LIN-IC	Video Umschalter/Switch, 3-Input, 6dB Amp., Ucc=5V	8-DIP			
NJM 2245 L	Njr	LIN-IC	=NJM 2245D: Fig. →	8-SIP			
NJM 2245 M	Njr	LIN-IC	=NJM 2245D: SMD	8-MDIP			
NJM 2246 D	Njr	LIN-IC	Video Umschalter/Switch, 3-Input, 6dB Amp., Ucc=5V	8-DIP			
NJM 2246 L	Njr	LIN-IC	=NJM 2246D: Fig. →	8-SIP			
NJM 2246 M	Njr	LIN-IC	=NJM 2246D: SMD	8-MDIP			
NJM 2247(A,B)M	Njr	LIN-IC	SMD, Video Superimposer, NTSC/PAL, Ucc=5V	20-MDIP			
NJM 2248 D	Njr	LIN-IC	Video Superimposer, 3-Input, Ucc=5V	8-DIP			
NJM 2248 L	Njr	LIN-IC	=NJM 2248D: Fig. →	8-SIP			
NJM 2248 M	Njr	LIN-IC	=NJM 2248D: SMD	8-MDIP			
NJM 2249 D	Njr	LIN-IC	Video Superimposer, 3-Input, Ucc=5V	8-DIP			
NJM 2249 L	Njr	LIN-IC	=NJM 2249D: Fig. →	8-SIP			
NJM 2249 M	Njr	LIN-IC	=NJM 2249D: SMD	8-MDIP			
NJM 2250 M	Njr	LIN-IC	SMD, Camera-Monitor(1,5"), EVF Driver, Ucc=4.8V	24-MDIP			
NJM 2252 L	Njr	LIN-IC	S-VHS VC, On Screen Display Mix, Ucc=9V	22-SDIP			
NJM 2255 D	Njr	LIN-IC	VC+, Chroma Signal Hue Tint Control, Ucc=5V	8-DIP			
NJM 2256 M	Njr	LIN-IC	SMD, Video Superimposer, NTSC/PAL, Ucc=5V	20-MDIP			
NJM 2258 L	Njr	LIN-IC	S-VHS VC, Video Equalizer, Ucc=5V	22-SDIP			
NJM 2259 M	Njr	LIN-IC	=NJM 2259S: SMD	16-MDIP			
NJM 2259 S	Njr	LIN-IC	UHF-Modulator, 550...620MHz, Ucc=5V	16-SQP			
NJM 2260 E	Njr	LIN-IC	SMD, Telecom, HF-Verst./Amp., 400...1000MHz	8-MDIP			
NJM 2263 D	Njr	LIN-IC	Video Superimposer, 3-Input, 75Ω Drv, Ucc=5V	8-DIP			
NJM 2263 L	Njr	LIN-IC	=NJM 2263D: Fig. →	8-SIP			
NJM 2263 M	Njr	LIN-IC	=NJM 2263D: SMD	8-MDIP			
NJM 2264 D	Njr	LIN-IC	Video Superimposer, 3-Input, 75Ω Drv, Ucc=5V	8-DIP			
NJM 2264 L	Njr	LIN-IC	=NJM 2264D: Fig. →	8-SIP			
NJM 2264 M	Njr	LIN-IC	=NJM 2264D: SMD	8-MDIP			
NJM 2265 D	Njr	LIN-IC	Video Superimposer, 3-Input, 6dB Amp., Ucc=5V	8-DIP			
NJM 2265 L	Njr	LIN-IC	=NJM 2265D: Fig. →	8-SIP			
NJM 2265 M	Njr	LIN-IC	=NJM 2265D: SMD	8-MDIP			
NJM 2266 D	Njr	LIN-IC	Video Superimposer, 3-Input, 6dB Amp., Ucc=5V	8-DIP			
NJM 2266 L	Njr	LIN-IC	=NJM 2266D: Fig. →	8-SIP			
NJM 2266 M	Njr	LIN-IC	=NJM 2266D: SMD	8-MDIP			
NJM 2273 C	Njr	LIN-IC	Video Umschalter/Switch, 3-Input, Mute, Ucc=5V	9-SIP			
NJM 2283 D	Njr	LIN-IC	Video Umschalter/Switch, 2-Input, 3-Chann., Ucc=5V	16-DIP			
NJM 2283 M	Njr	LIN-IC	=NJM 2283D: SMD	16-MDIP			
NJM 2284 D	Njr	LIN-IC	Video Umschalter/Switch, 2-Input, 3-Chann., Ucc=5V	16-DIP			
NJM 2284 M	Njr	LIN-IC	=NJM 2284D: SMD	16-MDIP			
NJM 2285 D	Njr	LIN-IC	Video Umschalter/Switch, 2-Input, 3-Chann., Ucc=5V	16-DIP			
NJM 2285 M	Njr	LIN-IC	=NJM 2285D: SMD	16-MDIP			
NJM 2351 D	Njr	Z-IC	+5V, +10V, -10V, Uref=1,115V, -10...+75°	16-DIP			
NJM 2352 D	Njr	Z-IC	S-Reg, +9V, 50kHz, Uref=1,31V, -20...+75°	8-DIP			
NJM 2352 M	Njr	Z-IC	=NJM 2352D: SMD	8-MDIP			
NJM 2353 D	Njr	Z-IC	±15V, ±0.1A, -20...+75°	14-DIP			
NJM 2355 D	Njr	Z-IC	S-Reg, 2x 0.2A, Uref=5V, -20...+75°	18-DIP			
NJM 2359 D	Njr	Z-IC	S-Reg, 5V/10mA, 24V/4mA, Uref=1,31V, -20...+75°	8-DIP			
NJM 2359 M	Njr	Z-IC	=NJM 2359D: SMD	8-MDIP			
NJM 2360 D	Njr	Z-IC	DC-DC Converter Ctrl., Isw=1,5A, -20...+75°	8-DIP			
NJM 2360 M	Njr	Z-IC	=NJM 2360D: SMD	8-MDIP			
NJM 2362 D	Njr	Z-IC	PWM S-Reg, Current Mode, -20...+75°	14-DIP			
NJM 2403 D	Njr	KOP-IC	Dual, 36(±18)V, -40...+85°	8-DIP			LM 2903...
NJM 2403 M	Njr	KOP-IC	=NJM 2403D: SMD	8-MDIP			LM 2903...
NJM 2403 S	Njr	KOP-IC	=NJM 2403D: Fig. →	9-SIP			LM 2903...
NJM 2403 T	Njr	KOP-IC	=NJM 2403D: Fig. →	TO-99			LM 2903...
NJM 2404 D	Njr	LIN-IC	3/4 Draht-FB/Wired Remote Controller	16-DIP			
NJM 2406 F	Njr	KOP-IC	Min, 7V, -20...+75°	5-MDIP			
NJM 2605 D	Njr	LIN-IC	Motorregler/Motor Control, Ucc=3V	8-DIP			
NJM 2605 M	Njr	LIN-IC	=NJM 2605D: SMD	8-MDIP			
NJM 2606(A)D	Njr	LIN-IC	Motorregler/DC Motor Ctrl., Ucc=3V, 0,1A	8-DIP			
NJM 2606(A)M	Njr	LIN-IC	=NJM 2606(A)D: SMD	8-MDIP			
NJM 2610 S	Njr	LIN-IC	DC Motor Ctrl., bidirectional, Ucc=4...20V, 1,2A	9-SIL			
NJM 2611 D	Njr	LIN-IC	Servo Motor Ctrl., Ucc=2,5...10V, 0,6A	16-DIP			
NJM 2900 M	Njr	OP-IC	=NJM 2900N: SMD	14-MDIP			LM 2900..., (NJM 3900...)16
NJM 2900 N	Njr	OP-IC	Quad, 36(±18)V, 20V/μs, 2,5MHz, -40...+85°	14-DIP			LM 2900..., (NJM 3900...)16
NJM 2901 M	Njr	KOP-IC	=NJM 2901N: SMD	14-MDIP			LM 2901...

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
NJM 2901 N	Njr	KOP-IC	Quad, Serie 139, 36(±18)V, -40...+85°	14-DIP	LM 339 N	14-DIP	•LM 2901...
NJM 2901 V	Njr	KOP-IC	=NJM 2901N: SMD	14-SMDIP			•LM 2901...
NJM 2902 M	Njr	OP-IC	=NJM 2902N: SMD	14-MDIP			• LM 2902...
NJM 2902 N	Njr	OP-IC	Quad, Serie 124, +32/0(±16)V, 0,5V/µs, -40...+85°	14-DIP	LM 324 N	14-DIP	• LM 2902...
NJM 2903 D	Njr	KOP-IC	Dual, 36(±18)V, -40...+85°	8-DIP			•LM 2903...
NJM 2903 L	Njr	KOP-IC	=NJM 2903D: Fig. →	8-SIP			
NJM 2903 M	Njr	KOP-IC	=NJM 2903D: SMD	8-MDIP			•LM 2903...
NJM 2903 S	Njr	KOP-IC	=NJM 2903D: Fig. →	9-SIP			
NJM 2903 T	Njr	KOP-IC	=NJM 2903D: Fig. →	TO-99			•LM 2903...
NJM 2904 D	Njr	OP-IC	Dual, lo-power, Serie 158, +32/0(±16)V, -40...+85°	8-DIP			• LM 2904...
NJM 2904 L	Njr	OP-IC	=NJM 2904D: Fig. →	8-SIP			• LM 2904...
NJM 2904 M	Njr	OP-IC	=NJM 2904D: SMD	8-MDIP			• LM 2904...
NJM 2904 S	Njr	OP-IC	=NJM 2904D: Fig. →	9-SIP			• LM 2904...
NJM 2930-05	Njr	Z-IC	+5V, 10%, 0,15A, lo-drop	17b			LM 2930KC,T-05
NJM 2930-08	Njr	Z-IC	+8V, 10%, 0,15A, lo-drop	17b	TO-220		LM 2930KC,T-08
NJM 2930-85	Njr	Z-IC	+8,5V, 10%, 0,15A, lo-drop	17b	TO-220		-
NJM 2930-xx F	Njr	Z-IC	=NJM 2930-...: Iso	17b	TO-220 Iso		-
NJM 2930 L-05	Njr	Z-IC	+5V, 10%, 0,1A, lo-drop	7b	TO-92		LM 2930LP-05
NJM 2930 L-08	Njr	Z-IC	+8V, 10%, 0,1A, lo-drop	7b	TO-92		LM 2930LP-08
NJM 2930 L-85	Njr	Z-IC	+8,5V, 10%, 0,1A, lo-drop	7b	TO-92		-
NJM 3201	Njr	LIN-IC	SMD, Floppy-Disk, Read/Write Amplifier	42-MDIP			-
NJM 3357 D	Njr	LIN-IC	Telecom, FM Schmalband/Narrowband IF, Ucc=4...8V	16-DIP			MC 3357...
NJM 3357 M	Njr	LIN-IC	=NJM 3357D: SMD	16-MDIP			MC 3357...
NJM 3359 D	Njr	LIN-IC	Telecom, FM Schmalband/Narrowband IF, Ucc=4...9V	18-DIP			MC 3359...
NJM 3403 AD	Njr	OP-IC	Quad, Serie 124, +36/0(±18)V, 1,2V/µs, -20...+75°	14-DIP			• MC 3403...
NJM 3403 AM	Njr	OP-IC	=NJM 3403AD: SMD	14-MDIP			• MC 3403...
NJM 3403 AV	Njr	OP-IC	=NJM 3403AD: SMD	14-SMDIP			• MC 3403...
NJM 3404 AD	Njr	OP-IC	Dual, 36(±18)V, 1,2V/µs, 1,2MHz, -20...+75°	8-DIP			• LM 2904...
NJM 3404 AL	Njr	OP-IC	=NJM 3404AD: Fig. →	8-SIP			• LM 2904...
NJM 3404 AM	Njr	OP-IC	=NJM 3404AD: SMD	8-MDIP			• LM 2904...
NJM 3404 AS	Njr	OP-IC	=NJM 3404AD: Fig. →	9-SIP			• LM 2904...
NJM 3414 D	Njr	OP-IC	Dual, hi-output, 15(±7,5)V, 1V/µs, 1,3MHz, -20...+75°	8-DIP			-
NJM 3414 L	Njr	OP-IC	=NJM 3414D: Fig. →	8-SIP			-
NJM 3414 M	Njr	OP-IC	=NJM 3414D: SMD	8-MDIP			-
NJM 3414 S	Njr	OP-IC	=NJM 3414D: Fig. →	9-SIP			-
NJM 3415 D	Njr	OP-IC	Dual, hi-output, 15(±7,5)V, 1V/µs, 1,3MHz, -20...+75°	8-DIP			-
NJM 3415 L	Njr	OP-IC	=NJM 3415D: Fig. →	8-SIP			-
NJM 3415 M	Njr	OP-IC	=NJM 3415D: SMD	8-MDIP			-
NJM 3415 S	Njr	OP-IC	=NJM 3415D: Fig. →	9-SIP			-
NJM 3470 D,AD	Njr	LIN-IC	Floppy-Disk, Leseverst./Read Amplifier	18-DIP			MC 3470...
NJM 3524 D	Njr	LIN-IC	S-Reg, PWM Ctrl., 60kHz, Uref=5V, -20...+75°	16-DIP			-
NJM 3524 M	Njr	LIN-IC	=NJM 3524D: SMD	16-MDIP			-
NJM 3900 M	Njr	OP-IC	=NJM 3900N: SMD	14-MDIP			LM 2900..., LM 3900...
NJM 3900 N	Njr	OP-IC	=NJM 2900N: 32(±16)V, -40...+85°	14-DIP			LM 2900..., LM 3900...
NJM 4151 D	Njr	LIN-IC	V/F-F/V Converter, Ucc=8...22V	8-DIP			-
NJM 4151 M	Njr	LIN-IC	=NJM 4151D: SMD	8-MDIP			-
NJM 4200 D(A)	Njr	LIN-IC	Analog-Multiplizierer/Multiplier	8-DIP			-
NJM 4200 M(A)	Njr	LIN-IC	=NJM 4200D: SMD	8-MDIP			-
NJM 4250 D	Njr	OP-IC	Serie 250, lo-power, ±18V, -20...+75°	8-DIP			• LM 4250...
NJM 4250 M	Njr	OP-IC	=NJM 4250D: SMD	8-MDIP			• LM 4250...
NJM 4556 D	Njr	OP-IC	Dual, hi-current, ±18V, 70mA, 3V/µs, 8MHz, -20...+75°	8-DIP			-
NJM 4556 L	Njr	OP-IC	=NJM 4556D: Fig. →	8-SIP			-
NJM 4556 M	Njr	OP-IC	=NJM 4556D: SMD	8-MDIP			-
NJM 4556 S	Njr	OP-IC	=NJM 4556D: Fig. →	9-SIP			-
NJM 4558 D	Njr	OP-IC	Dual, Serie 158, 1V/µs, 3MHz, -20...+75°	8-DIP	4558/8-D	8-DIP	• MC 4558...
NJM 4558 F	Njr	OP-IC	=NJM 4558D: SMD	8-FLP			• MC 4558...
NJM 4558 L	Njr	OP-IC	=NJM 4558D: Fig. →	8-SIP			• MC 4558...
NJM 4558 M	Njr	OP-IC	=NJM 4558D: SMD	8-MDIP			• MC 4558...
NJM 4558 S	Njr	OP-IC	=NJM 4558D: Fig. →	9-SIP			• MC 4558...
NJM 4558 T	Njr	OP-IC	=NJM 4558D: Fig. →	TO-99			• MC 4558...
NJM 4559 D,M,S,T	Njr	OP-IC	=NJM 4558D,M,S,T: 2V/µs, 6MHz	8-DIP			• MC 4558...
NJM 4560 D	Njr	OP-IC	Dual, ±18V, 4V/µs, 10MHz, -20...+75°	8-DIP			... 4558...
NJM 4560 L	Njr	OP-IC	=NJM 4560D: Fig. →	8-SIP			... 4558...
NJM 4560 M	Njr	OP-IC	=NJM 4560D: SMD	8-MDIP			... 4558...
NJM 4560 S	Njr	OP-IC	=NJM 4560D: Fig. →	9-SIP			... 4558...
NJM 4560 T	Njr	OP-IC	=NJM 4560D: Fig. →	TO-99			... 4558...
NJM 4562 D	Njr	OP-IC	Dual, ±18V, 0,6V/µs, -20...+75°	8-DIP			-
NJM 4562 L	Njr	OP-IC	=NJM 4562D: Fig. →	8-SIP			-
NJM 4562 M	Njr	OP-IC	=NJM 4562D: SMD	8-MDIP			-
NJM 4562 S	Njr	OP-IC	=NJM 4562D: Fig. →	9-SIP			-
NJM 4562 T	Njr	OP-IC	=NJM 4562D: Fig. →	TO-99			-
NJM 4565 D	Njr	OP-IC	Dual, ±18V, 1,6V/µs, 10MHz, -20...+75°	8-DIP			-
NJM 4565 L	Njr	OP-IC	=NJM 4565D: Fig. →	8-SIP			-
NJM 4565 M	Njr	OP-IC	=NJM 4565D: SMD	8-MDIP			-
NJM 4580 D	Njr	OP-IC	Dual, ±18V, 5V/µs, 15MHz, -20...+75°	8-DIP			-
NJM 4580 L	Njr	OP-IC	=NJM 4580D: Fig. →	8-SIP			-
NJM 4580 M	Njr	OP-IC	=NJM 4580D: SMD	8-MDIP			-
NJM 4587 D	Njr	OP-IC	Dual, lo-noise, ±22V, 15V/µs, 15MHz, -20...+75°	8-DIP			-
NJM 4587 L	Njr	OP-IC	=NJM 4580D: Fig. →	8-SIP			-
NJM 4741 D	Njr	OP-IC	Quad, Serie 124 (=4xNJM 741), -20...+75°	14-DIP			... 224..., ... 324..., ... 4741...
NJM 4741 M	Njr	OP-IC	=NJM 4741: SMD	14-MDIP			... 224..., ... 324..., ... 4741...
NJM 5532 D	Njr	OP-IC	Dual, lo-noise, ±22V, 8V/µs, 10MHz, -20...+75°	8-DIP			• NE 5532...
NJM 5532 M	Njr	OP-IC	=NJM 5532D: SMD	8-MDIP			• NE 5532...
NJM 5532 S	Njr	OP-IC	=NJM 5532D: Fig. →	9-SIP			-
NJM 5534 D	Njr	OP-IC	lo-noise, ±22V, 13V/µs, 10MHz, -20...+75°	8-DIP			• NE 5534...
NJM 5534 M	Njr	OP-IC	=NJM 5534D: SMD	8-MDIP			• NE 5534...
NJM 7805(A)	Njr	Z-IC	+5V, 10%(A=5%), 1A	17b	TO-220	7805/TO-220	... 7805... (TO-220)
NJM 7806(A)	Njr	Z-IC	+6V, 10%(A=5%), 1A	17b	TO-220	7806/TO-220	... 7806... (TO-220)
NJM 7808(A)	Njr	Z-IC	+8V, 10%(A=5%), 1A	17b	TO-220	7808/TO-220	... 7808... (TO-220)
NJM 7809(A)	Njr	Z-IC	+9V, 10%(A=5%), 1A	17b	TO-220	7809/TO-220	... 7809... (TO-220)
NJM 7812(A)	Njr	Z-IC	+12V, 10%(A=5%), 1A	17b	TO-220	7812/TO-220	... 7812... (TO-220)
NJM 7815(A)	Njr	Z-IC	+15V, 10%(A=5%), 1A	17b	TO-220	7815/TO-220	... 7815... (TO-220)
NJM 7818(A)	Njr	Z-IC	+18V, 10%(A=5%), 1A	17b	TO-220	7818/TO-220	... 7818... (TO-220)



inal	Fabric.	Constr.	Info	{ Compl. Fig.	JAEGER	Fig.	International
M 7820(A)	Njr	Z-IC	+20V, 10%(A=5%), 1A	17b	TO-220	7820/TO-220	17b ... 7820... (TO-220)
JM 7824(A)	Njr	Z-IC	+24V, 10%(A=5%), 1A	17b	TO-220	7824/TO-220	17b ... 7824... (TO-220)
NJM 78xx F(A)	Njr	Z-IC	=NJM 7805...7824(A): Iso	17b	TO-220 Iso	78xx/IsoTO-220	17b ... 78xx... (TO-220 Iso)
NJM 7905(A)	Njr	Z-IC	-5V, 10%(A=5%), 1A	17c	TO-220	7905/TO-220	17c ... 7905... (TO-220)
NJM 7906(A)	Njr	Z-IC	-6V, 10%(A=5%), 1A	17c	TO-220		17c ... 7906... (TO-220)
NJM 7908(A)	Njr	Z-IC	-8V, 10%(A=5%), 1A	17c	TO-220		17c ... 7908... (TO-220)
NJM 7909(A)	Njr	Z-IC	-9V, 10%(A=5%), 1A	17c	TO-220		17c ... 7909... (TO-220)
NJM 7912(A)	Njr	Z-IC	-12V, 10%(A=5%), 1A	17c	TO-220	7912/TO-220	17c ... 7912... (TO-220)
NJM 7915(A)	Njr	Z-IC	-15V, 10%(A=5%), 1A	17c	TO-220	7915/TO-220	17c ... 7915... (TO-220)
NJM 7918(A)	Njr	Z-IC	-18V, 10%(A=5%), 1A	17c	TO-220		17c ... 7918... (TO-220)
NJM 7924(A)	Njr	Z-IC	-24V, 10%(A=5%), 1A	17c	TO-220		17c ... 7924... (TO-220)
NJM 79xx F(A)	Njr	Z-IC	=NJM 7905...7924(A): Iso	17c	TO-220 Iso	(79xx/TO-220) <sup>3</sup>	17c ... 79xx... (TO-220 Iso)
NJM 13600 D	Njr	OP-IC	Dual, OTA(Transconductance), 36(±18)V, -20...+75°	16-DIP			LM 13600...
NJM 13600 M	Njr	OP-IC	=NJM 13600D: SMD	16-MDIP			LM 13600...
NJM 13700 D	Njr	OP-IC	=NJM 13600: verbessert/improved	16-DIP			LM 13700...
NJM 13700 M	Njr	OP-IC	=NJM 13700D: SMD	16-MDIP			LM 13700...
NJMDAC-08 DC	Njr	D/A-IC	8 Bit, multiplying, hi-speed, -20...+75°	16-DIP			DAC-08...
NJMDAC-08 MC	Njr	D/A-IC	=NJMDAC-08DC: SMD	16-MDIP			DAC-08...
NJMOP 07D	Njr	OP-IC	lo-offset(<150µV), lo-drift, ±22V, -20...+75°	8-DIP			OP 07...
NJMOP 07M	Njr	OP-IC	=NJMPO 07D: SMD	8-MDIP			OP 07...
NJMREF 01 D	Njr	Ref-Z-IC	+10V ±1%, -20...+75°	8-DIP			
<b>NK...NZ</b>							
NK		Si-N	=2SC2780-NK (SMD-Marking)	39	SOT-89		2SC2780
NK		Si-N	=KRC110S (SMD-Marking)	35	SOT-23		KRC 110S
NL		Si-P	=2SA1520 (SMD-Marking)	35	SOT-23		2SA1520
NL		Si-N	=2SC2780-NL (SMD-Marking)	39	SOT-89		2SC2780
NL 3 T1		PUT	=2N6027				
NM		Ge-Di	=AA 133			AA 133	31a AA 133
NM		Si-N	=2SC2780-NM (SMD-Marking)	39	SOT-89		2SC2780
NM		Si-N	=KRC111S (SMD-Marking)	35	SOT-23		KRC 111S
NM 400	Tho	Si-N	TV-VA, 170V, 2A, 30W, >10MHz	22a	TO-66	2SD1138	17j 2SC779, 2SC825, 2SC1025, 2SD610
NN		Si-N	=KRC112S (SMD-Marking)	35	SOT-23		KRC 112S
NN 16 AT...MT	Gie	Si-Di	=NP 16 AT...MT:	17h	TO-220		
NN 30 AP...MP	Gie	Si-Di	=NP 30 AP...MP:	16h	TO-247		
NO		Si-P	=2SA1213-O (SMD-Marking)	39	SOT-89		2SA1213
NO		Si-N	=2SC3138-O (SMD-Marking)	35	SOT-23		2SC3138
NO		MOS-N-FET-e	=2SK1592 (SMD-Marking)	39	SOT-89		2SK1592
NO		Si-N	=KRC113S (SMD-Marking)	35	SOT-23		KRC 113S
NO5		Si-N	=SO 2484 (SMD-Marking)	35	SOT-23		SO 2484
NO8		Si-N	=SO 930(SMD-Marking)	35	SOT-23		SO 930
NP		MOS-N-FET-e	=2SK1593 (SMD-Marking)	39	SOT-89		2SK1593
NP		Si-N	=KRC114S (SMD-Marking)	35	SOT-23		KRC 114S
NP		Z-Di	=SM 6T 68C (SMD-Marking)	71a(6x4mm)	SOD-6		SM 6T....
NP 16 AT...MT	Gie	Si-Di	Dual, P Rr, 50...1000V, 16A	17e	TO-220		FE 16A...J, MUR 1605CT... 1660CT
NP 30 AP...MP	Gie	Si-Di	Dual, P Rr, 50...1000V, 30A	16e	TO-247		RGP 30AP...MP, MUR 3005PT... 3060PT
NPS....	Spr	Si-N/P	=MPS....	7	TO-92	=MPS....	
NQ		MOS-N-FET-e	=2SK1959 (SMD-Marking)	39	SOT-89		2SK1959
NQ		Si-N	=KRC241S (SMD-Marking)	35	SOT-23		KRC 241S
NQ		Z-Di	=SM 6T 68CA (SMD-Marking)	71a(6x4mm)	SOD-6		SM 6T....
NR		Si-N	=2SD1679-R (SMD-Marking)	35	SOT-23		2SD1679
NR		MOS-N-FET-e	=2SK1960 (SMD-Marking)	39	SOT-89		2SK1960
NR		Si-N	=KRC242S (SMD-Marking)	35	SOT-23		KRC 242S
NR-001 E	Nsc	Si-N	=BC 548	7e	TO-92	BC 546	7a BC 548
NR 8 AT...MT	Gie	Si-Di	=NS 8 AT...MT:	17m	TO-220		
NR 041 E	Gie	Si-N	Uni, In, 20V, 0,03A, 0,6W	7e	TO-92	BC 550	7a BC 169, BC 184, BC 239, BC 549, ++
NR 041 F		Si-N	=NR 041E:	7c	TO-92	BC 550	7a BC 169, BC 184, BC 239, BC 549, ++
NR 041 H		Si-N	=NR 041E:	7a	TO-92	BC 550	7a BC 169, BC 184, BC 239, BC 549, ++
NR-071 E	Nsc	Si-N	=BC 548	7e	TO-92	BC 546	7a BC 548
NR 421 D....	Nsc	Si-N	FM/VHF, 700MHz	7f	TO-92	BF 198	7d BF 225, BF 314, BF 496, BF 502, BF 505++
NR 421 F....		Si-N	=NR 421D:	7c	TO-92	BF 198	7d BF 225, BF 314, BF 496, BF 502, BF 505++
NR 431 E....	Nsc	Si-N	AM/FM, 600MHz	7e	TO-92	BF 198	7d BF 255, BF 314, BF 496, NF 502, BF 505++
NR 431 F....		Si-N	=NR 431E:	7c	TO-92	BF 198	7d BF 255, BF 314, BF 496, NF 502, BF 505++
NR 431 H....		Si-N	=NR 431E:	7a	TO-92	BF 198	7d BF 255, BF 314, BF 496, NF 502, BF 505++
NR 461 E....	Nsc	Si-N	AM/FM IF, 300MHz	7e	TO-92	BF 255	7d BF 240...241, BF 254...255, BF 494...495, ++
NR 461 F....		Si-N	=NR 461E:	7c	TO-92	BF 255	7d BF 240...241, BF 254...255, BF 494...495, ++
NR 461 H....		Si-N	=NR 461E:	7a	TO-92	BF 255	7d BF 240...241, BF 254...255, BF 494...495, ++
NR 601 E	Nsc	Si-P	=BC 328	7e	TO-92	BC 327	7a BC 328
NS		Si-N	=2SD1679-S (SMD-Marking)	35	SOT-23		2SD1679
NS		MOS-N-FET-e	=2SK2109 (SMD-Marking)	39	SOT-89		2SK2109
NS		Si-N	=KRC243S (SMD-Marking)	35	SOT-23		KRC 243S
NS 8 AT...MT	Gie	Si-Di	P Rr, 50...1000V, 8A	17k	TO-220		BY 239/... GP 80A...M
NSD-U....	Nsc	Si-N/P	=MPS-U....	13m	TO-202	=MPS-U....	
NSL-....		Opto					
NT		Si-N	=2SC4362 (SMD-Marking)	35	SOT-23		2SC4362
NT		Si-N	=2SD1679-T (SMD-Marking)	35	SOT-23		2SD1679
NT		MOS-N-FET-e	=2SK2110 (SMD-Marking)	39	SOT-89		2SK2110
NT		Si-N	=KRC244S (SMD-Marking)	35	SOT-23		KRC 244S
NT 0.6 C0V7	Ntn	Si-St	0,25A, 0,3W, Uf=0,7V(5mA)	12a	(6x4x2,5)	(1N4148)	31a BZ 102/0V7, BZX 55/C0V8, ZPD 1
NT 0.6 C2V7....C75	Ntn	Z-Di	2,7...75V, 5%, 0,3W	12a	(6x4x2,5)	Z-Diode ...V	31a BZX55/..., BZX79/..., ZPD..., 1N5223...67, ++ (BZV 15/...) <sup>4</sup>
NT 3 C10....C100	Ntn	Z-Di	10...100V, 5%, 3W(Tc=45°)	=32b			
NT 05 E15....E150	Ntn	Si-Di	Rr, contr.av., 15...150V, 0,29A	31a	DO-7		BAS 11, BYX 57/...
NT 50 C4V7....C33	Ntn	Z-Di	4,7...33V, 5%, 0,5W	31a	DO-35	Z-Diode ...V	31a BZX55/..., BZX83/..., ZPD..., 1N5230...57, ++
NT 55 C0V7	Ntn	Si-St	0,38A, 0,5W, Uf=0,7V(5mA)	31a	DO-7	(1N4148)	31a BZW 22/C1, BZX 83/COV8, ZPY 1
NT 55 C1V4	Ntn	Si-St	0,22A, 0,5W, Uf=1,4V(5mA)	31a	DO-7	Z-Diode 1,4V	31a BZ 102/1V4
NT 55 C2V1	Ntn	Si-St	0,16A, 0,5W, Uf=2,1V(5mA)	31a	DO-7	Z-Diode 2,1V	31a BZ 102/2V1, BZX 75/C2V1, ZTE 2
NT 55 C2V7....200	Ntn	Z-Di	2,7...200V, 5%, 0,5W	31a	DO-7	Z-Diode ...V	31a BZX55/..., BZX83/..., ZPD..., 1N5223...81, ++
NT 77 C0V7	Ntn	Si-St	1,3A, 1,5W, Uf=0,7V(100mA)	31a	DO-15	(1N4148)	31a BZW 22/C1, ZPY 1, ZY 1
NT 77 C1V4	Ntn	Si-St	0,7A, 1,5W, Uf=1,4V(100mA)	31a	SOD-15	Z-Diode 1,4V	31a
NT 77 C2V7....C200	Ntn	Z-Di	2,7...200V, 5%, 1,5W	31a	SOD-15	Z-Diode ...V	31a BZW22/..., BZY97/..., ZY..., 1N5913... 6031++

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
NT 80 C5V6...27	Ntn	Z-Di	5.6...27V, 5%, 10W(Tc=100°)	17d	TO-220		
NT 80 C5V6R...27R		Z-Di	=NT 80 C5V6...C27:	17c	TO-220		
NT 9967	Ntn	Si-Di	=BA 157	31a	BA 159	31a	=BA 157
NTM 2222(A)	Nec	Si-N	=2N2222(A): SMD	35a	SOT-23		BSR14, BSS79, PMBT2222(A), SMBT2222(A)
NTM 2369(A)	Nec	Si-N	=2N2369(A): SMD	35a	SOT-23		FMMT 2369(A), PMBT 2369(A), 2SC4168
NTM 2907(A)	Nec	Si-P	=2N2907(A): SMD	35a	SOT-23		BSR15...16, BSS80, PMBT2907(A), SMBT2907(A)
NTM 3904	Nec	Si-N	=2N3904: SMD	35a	SOT-23	BC 846	BC 846, BCV 71...70, PMBT 3904, 2SC4209
NTM 3906	Nec	Si-P	=2N3906: SMD	35a	SOT-23	BC 856	BC 856...857, BCX 71, PMBT 3906, 2SA1620
NT-PSV6...P15	Ntn	Z-Di	5.6...15V, 5%, 0.4W	31a	DO-7	Z-Diode...V	BZX55/... BZX83/... ZPD... 1N5232...45,++
NU		MOS-N-FET-e	=2SK2111 (SMD-Marking)	39	SOT-89		=2SK2111
NU		Si-N	=KRC245S (SMD-Marking)	35	SOT-23		=KRC 245S
NV		MOS-N-FET-e	=2SK2112 (SMD-Marking)	39	SOT-89		=2SK2112
NV		Si-N	=KRC246S (SMD-Marking)	35	SOT-23		=KRC 246S
NV 4.2MC1...47MC1...	Nec	Varistor	VDR, Multilayer Metal Oxide Varistors	Chip	(2x1,25)		
NV 4.2MC2...56MC1...	Nec	Varistor	VDR, Multilayer Metal Oxide Varistors	Chip	(3,2x1,6)		
NW		MOS-N-FET-e	=2SK2159 (SMD-Marking)	39	SOT-89		=2SK2159
NW		Si-N	=KRC231S (SMD-Marking)	35	SOT-23		=KRC 231S
NX		Z-Di	=SM 6T 100C (SMD-Marking)	71a(6x4mm)	SOD-6		=SM 6T...
NY		Si-P	=2SA1213-Y (SMD-Marking)	39	SOT-89		=2SA1213
NY		Si-N	=2SC3138-Y (SMD-Marking)	35	SOT-23		=2SC3138
NY		Si-N	=2SC3774 (SMD-Marking)	35	SOT-23		=2SC3774
NY		Si-N	=2SC4004 (SMD-Marking)	35	SOT-23		=2SC4004
NY		MOS-P-FET-e	=2SJ317 (SMD-Marking)	39	SOT-89		=2SJ317
NY		Si-N	=KRC232S (SMD-Marking)	35	SOT-23		=KRC 232S
NY		Z-Di	=SM 6T 100CA (SMD-Marking)	71a(6x4mm)	SOD-6		=SM 6T...
NZ		Si-N	=BFS 20R (SMD-Marking)	35	SOT-23		=BFS 20R
NZ		Si-N	=KRC233S (SMD-Marking)	35	SOT-23		=KRC 233S
<b>O</b>							
O 2		MOS-N-FET-e	=BST 82 (SMD-Marking)	39	SOT-89		=BST 82
O 4		Si-P	=2SA1331-4 (SMD-Marking)	35	SOT-23		=2SA1331
O 5		Si-P	=2SA1330-05 (SMD-Marking)	35	SOT-23		=2SA1330
O 5		Si-P	=2SA1331-5 (SMD-Marking)	35	SOT-23		=2SA1331
O 05		Si-N	=SO 2484R (SMD-Marking)	35	SOT-23		=SO 2484R
O 6		Si-P	=2SA1330-06 (SMD-Marking)	35	SOT-23		=2SA1330
O 6		Si-P	=2SA1331-6 (SMD-Marking)	35	SOT-23		=2SA1331
O 7		Si-P	=2SA1330-07 (SMD-Marking)	35	SOT-23		=2SA1330
O 08		Si-N	=SO 930R (SMD-Marking)	35	SOT-23		=SO 930R
O 11		Si-N	=SO 2369R (SMD-Marking)	35	SOT-23		=SO 2369R
O 12		Si-N	=SO2221R (SMD-Marking)	35	SOT-23		=SO 2221R
O 13		Si-N	=SO 2222R (SMD-Marking)	35	SOT-23		=SO 2222R
O 15		Si-P	=2SA1609-015 (SMD-Marking)	35(2mm)	SOT-323		=2SA1609
O 16		Si-P	=2SA1609-016 (SMD-Marking)	35(2mm)	SOT-323		=2SA1609
O 17		Si-P	=2SA1609-017 (SMD-Marking)	35(2mm)	SOT-323		=2SA1609
O 17		Si-N	=SO 1613R (SMD-Marking)	35	SOT-23		=SO 1613R
O 18		Si-N	=SO 1711R (SMD-Marking)	35	SOT-23		=SO 1711R
O 20		Si-N	=SO 1711AR (SMD-Marking)	35	SOT-23		=SO 1711AR
O 27		Si-N	=SO 1893R (SMD-Marking)	35	SOT-23		=SO 1893R
O 54		Si-N	=SO 2221AR (SMD-Marking)	35	SOT-23		=SO 2221AR
O 71		Si-N	=SO 3904R (SMD-Marking)	35	SOT-23		=SO 3904R
O 72		Si-N	=SO 3903R (SMD-Marking)	35	SOT-23		=SO 3903R
O 79		Si-N	=SO 5550R (SMD-Marking)	35	SOT-23		=SO 5550R
O 80		Si-N	=SO 5551R (SMD-Marking)	35	SOT-23		=SO 5551R
O 81		Si-N	=SO 2369AR (SMD-Marking)	35	SOT-23		=SO 2369AR
<b>OA</b>							
OA		Si-P/N	=μPA608T (SMD-Marking)	46	SOT-163		=μPA608T
OA 5	Phi	Ge-Di	Uni, lo-ohm, 100V, 0,13A	1a	AA 133	31a	AA 132...133, 1N270
OA 7	Mat,Phi	Ge-Di	S, 25V, 0,14A	1a			AA 49, AA 15, AA 17...18
OA 9	Mat,Phi	Ge-Di	S, 25V, 0,27A	1a	(AA 133)	31a	(AA 18)
OA 31	Phi	Ge-Di	Rr P, 120V, 3,8A	(32a)			
OA 47	Mat,Phi	Ge-Di	S, 25V, 0,11A, <70ns	31a	AA 133	31a	AA 18
OA 50	Phi	Ge-Di	-OA 81, OA 85				
OA 51	Phi	Ge-Di	-OA 81, OA 85				
OA 53	Phi	Ge-Di	-OA 81, OA 85				
OA 55	Phi	Ge-Di	-OA 81, OA 85				
OA 56	Phi	Ge-Di	-OA 81, OA 85				
OA 60	Phi	Ge-Di	-OA 70				
OA 61	Phi	Ge-Di	-OA 81, OA 85				
OA 70	Mat,Phi	Ge-Di	Vid-Dem, lo-ohm, 22.5V, 50mA	31a	AA 138	31a	AA 114, AA 116, 1N60
OA 71	Phi	Ge-Di	-OA 81, OA 85				
OA 72	Mat,Phi	Ge-Di	Dem, hi-ohm, 45V, 35mA	31a	AA 119	31a	AA 113, AA 119, 1N34, 1N54, 1N60
OA 73	Phi	Ge-Di	Dem, 30V, 15mA	31a			AA 113, AA 119, 1N34, 1N54, 1N60
OA 74	Phi	Ge-Di	-OA 81, OA 85				
OA 79	Mat,Phi	Ge-Di	Dem, hi-ohm, 45V, 35mA	31a	AA 119	31a	AA 113, AA 119, 1N34, 1N54, 1N60
OA 81	Mat,Phi	Ge-Di	=OA 91	31a	AA 133	31a	=OA 91
OA 85	Mat,Phi	Ge-Di	=OA 95	31a	AA 133	31a	=OA 95
OA 86	Phi	Ge-Di	S, 90V, 35mA	31a			AA 15
OA 87	Phi	Ge-Di	S, 90V, 35mA	31a			AA 15
OA 90	Mat,Phi	Ge-Di	Vid-Dem, lo-ohm, 30V, 30mA	31a	AA 138	31a	AA 114, AA 116, 1N60
OA 91(S)	Mat,Phi	Ge-Di	Uni, 115V, 50mA	31a	AA 133	31a	AA 117...118, AA 132...133
OA 92	ldr,Mat	Ge-Di	S, 15V, 10mA	31a			AA 21, AA 27
OA 95(S)	Mat,Phi	Ge-Di	Uni, 115V, 50mA	31a	AA 133	31a	AA 117...118, AA 132...133
OA 99(S)	Mat	Ge-Di	Dem, 45V, 50mA	31a			1N60
OA 126/5...18	Aeg	Z-Di	5...18V, 0,25W	31a	DO-7	Z-Diode...V	BZX55/... BZX79/... ZPD... 1N5230...48,++
OA 127	Aeg	Si-Di	Uni, 19/19V, 0,15/0,25A, Uf<1,1V(0,05A)	31a	DO-7	1N4148	BA 147/25, BA 127, BAY 17, 1N4148, ++
OA 128	Aeg	Si-Di	=OA 127: 35/35V	31a	DO-7	1N4148	BA 147/50, BA 127, BAY 18, 1N4148, ++
OA 129	Aeg	Si-Di	=OA 127: 75/75V	31a	DO-7	1N4148	BA 147/100, BA 188, BAY 19, 1N4148, ++
OA 130	Aeg	Si-Di	=OA 127: 135/135V	31a	DO-7	1N4148	BA 147/150, BA 189, BAY 20, BAY 45, ++
OA 131	Aeg	Si-Di	=OA 127: 230/230V	31a	DO-7	1N4148	BA 147/230, BAY 21, BAY 46, BA 157, ++
OA 132	Aeg	Si-Di	=OA 127: 320/320V	31a	DO-7	1N4148	BA 147/300, BAY 21, BAY 46, BA 157, ++
OA 150	Aeg	Ge-Di	Uni, 100V, 35mA	31a	AA 133	31a	AA 117...118, AA 132...133
OA 154(Q)	Aeg	Ge-Di	Ring-Dem, 55V, 30mA	31a			

Original	Fabric.	Constr.	Info	(Comp. Fig.	JAEGER	Fig.	International	
OA 159	Aeg	Ge-Di	TV-AGC, 40V, 20mA	31a	AA 138	31a	AA 113, AA 119, 1N54, 1N60	
OA 160	Aeg	Ge-Di	Vid-Dem, 25V, 20mA	31a	AA 138	31a	AA 112, AA 114, AA 116, 1N60	
OA 161	Aeg	Ge-Di	Uni, 140V, 35mA	31a	AA 133	31a	AA 133	
OA 172	Aeg	Ge-Di	Dem, hi-ohm, 40V, 10mA	31a	AA 119	31a	AA 113, AA 119, 1N34, 1N54, 1N60	
OA 174	Aeg	Ge-Di	Uni, 70V, 35mA	31a	AA 133	31a	AA 117...118, AA 132...134	
OA 180	Aeg	Ge-Di	S, lo-ohm, 30V, 150mA	31a			AA 113, AA 119, 1N34, 1N54, 1N60	
OA 181	Aeg	Ge-Di	Dem, hi-ohm	31a	AA 119	31a	AA 113, AA 119, 1N34, 1N54, 1N60	
OA 182	Aeg	Ge-Di	Uni, 100V, 150mA	31a			AA 117...118, AA 132...133	
OA 182 B	Aeg	Ge-Br	Rr-Br, 70V, 150mA	42			-	
OA 182 R	Aeg	Ge-Br	Ringmodulator, 75V, 150mA	42			-	
OA 200	Phi,Mat	Si-Di	Uni, 50/50V, 0,16/0,25A, Uf<1,15V(0,03A)	31a	DO-7	1N4148	31a	BA 127, BAY 18, BAY 44, 1N4148...49, ++
OA 202	Phi,Mat	Si-Di	=OA 200: 150/150V	31a	DO-7	BA 159	31a	BA 157, BA 189, BAY 20, BAY 45, ++
OA 210	Phi,Mat	Si-Di	Rr, Uni, 400/400V, 0,5A, Uf<1,5V(0,5A)	-32a		BY 133	31a	BY 126...127, BY 134...135, 1N4004...09, ++
OA 211	Phi,Mat	Si-Di	=OA 210: 800/800V	-32a		BY 133	31a	BY 127, BY 133, BY 227, 1N4006...07, ++
OA 212		Si-Di	=BY 127	31a		BY 133	31a	=BY 127
OA 213		Si-Di	=BY 127	31a		BY 133	31a	=BY 127
OA 214	Phi,Mat	Si-Di	=OA 210: 700/700V	-32a		BY 133	31a	BY 127, BY 133, BY 227, 1N4006...07, ++
OA 257	old	Ge-Di	=OA 90	31a		AA 138	31a	=OA 90
OA 258	old	Ge-Di	=OA 90					=OA 90
OA 261	old	Ge-Di	=OA 81	31a		AA 133	31a	=OA 81
OA 265	old	Ge-Di	=OA 85					=OA 85
OA 266	old	Ge-Di	=OA 85					=OA 85
OA 357	Itt	Ge-Di	=AA 116					=AA 116
OA 358	Itt	Ge-Di	=AA 27					=AA 27
OA 359	Itt	Ge-Di	=AA 27					=AA 27
OA 361	Itt	Ge-Di	=AA 117					=AA 117
OA 366	Itt	Ge-Di	=AA 118					=AA 118
OA 625	Hfo	Ge-Di	=GA 100	31a	SOD-6			=GA 100
OA 626	Hfo	Ge-Di	=GA 105	31a	SOD-6			=GA 105
OA 645	Hfo	Ge-Di	=GA 101	31a	SOD-6			=GA 101
(2)OA 646	Hfo	Ge-Di	=GA 109	31a	SOD-6			=GA 109
OA 647	Hfo	Ge-Di	=GA 106	31a	SOD-6			=GA 106
OA 665	Hfo	Ge-Di	=GA 102	31a	SOD-6			=GA 102
OA 666	Hfo	Ge-Di	=GA 107	31a	SOD-6			=GA 107
OA 685	Hfo	Ge-Di	=GA 103	31a	SOD-6			=GA 103
OA 686	Hfo	Ge-Di	=GA 108	31a	SOD-6			=GA 108
OA 705	Hfo	Ge-Di	=GA 104	31a	SOD-6			=GA 104
OA 720	Hfo	Ge-Di	Uni, S, 25V, 50mA	31a	SOD-6			AA 117...118, AA 132...134, 1N34, 1N54
OA 721	Hfo	Ge-Di	Uni, S, 25V, 75mA	31a	SOD-6			AA 135...136
OA 741	Hfo	Ge-Di	Uni, S, 50V, 75mA	31a	SOD-6			AA 136
OA 780	Hfo	Ge-Di	Uni, S, 95V, 50mA	31a	SOD-6			AA 117...118, AA 132...133
OA 900	Hfo	Si-Di	Rr, Uni, 25V, Uf<1,1V(0,1A)	31a	DO-7			BA 127, BA 147/25, BAY 17, 1N4148...49, ++
OA 901	Hfo	Si-Di	=OA 900: 50V	31a	DO-7			BA 127, BA 147/50, BAY 18, 1N4148...49, ++
OA 902	Hfo	Si-Di	=OA 900: 75V	31a	DO-7			BA 188, BA 147/100, BAY 19, BAY 45, ++
OA 903	Hfo	Si-Di	=OA 900: 150V	31a	DO-7			BA 189, BA 147/150, BAY 20, BAY 45, ++
OA 904	Hfo	Si-Di	=OA 900: 250V	31a	DO-7			BA 147/300, BAY 21, BAY 46, BAY 88, ++
OA 905	Hfo	Si-Di	=OA 900: 350V	31a	DO-7			BA 157, BA 199/350, BAY 21, BAY 88, ++
OA 910	Hfo	Si-Di	FM/VHF AFC, 25V, 10...35pF(10V), <3Ω	31a	DO-7			BA 111, BA 124, 1S2790, 1S1V50, ++
OA 1122 Si	Aeg	Si-Di	UHF Mx, 18V, 220...550MHz	Koax	SOD-50			-
OA 1154 Q	Tsm	Ge-Di	=OA 154Q	31a	DO-7			=OA 154Q
OA 1161	Tsm	Ge-Di	=OA 161	31a	DO-7			=OA 161
OA 1180	Tsm	Ge-Di	=OA 180	31a	DO-7			=OA 180
OA 1182	Tsm	Ge-Di	=OA 182	31a	DO-7			=OA 182
OA 1182 D		Ge-Di	=OA 182: 60V	31a	DO-7			=OA 182
OAZ 200	Phi	Z-Di	4,7V, 5%	1c				BZX55/C4V7, BZX79/C4V7, ZPD4,7, 1N5230++
OAZ 201	Phi	Z-Di	5,1V, 5%	1c				BZX55/C5V1, BZX79/C5V1, ZPD5,1, 1N5231++
OAZ 202	Phi	Z-Di	5,6V, 5%	1c				BZX55/C5V6, BZX79/C5V6, ZPD5,6, 1N5232++
OAZ 203	Phi	Z-Di	6,2V, 5%	1c				BZX55/C6V2, BZX79/C6V2, ZPD6,2, 1N5234++
OAZ 204	Phi	Z-Di	6,8V, 5%	1c				BZX55/C6V8, BZX79/C6V8, ZPD6,8, 1N5235++
OAZ 205	Phi	Z-Di	7,5V, 5%	1c				BZX55/C7V5, BZX79/C7V5, ZPD7,5, 1N5236++
OAZ 206	Phi	Z-Di	8,2V, 5%	1c				BZX55/C8V2, BZX79/C8V2, ZPD8,2, 1N5237++
OAZ 207	Phi	Z-Di	9,1V, 5%	1c				BZX55/C9V1, BZX79/C9V1, ZPD9,1, 1N5239++
OAZ 208	Phi	Z-Di	4,3V, 15%	1c				BZX55/C4V3, BZX79/C4V3, ZPD4,3, 1N5229++
OAZ 209	Phi	Z-Di	5,1V, 15%	1c				BZX55/C5V1, BZX79/C5V1, ZPD5,1, 1N5231++
OAZ 210	Phi	Z-Di	6,2V, 15%	1c				BZX55/C6V2, BZX79/C6V2, ZPD6,2, 1N5234++
OAZ 211	Phi	Z-Di	7,5V, 15%	1c				BZX55/C7V5, BZX79/C7V5, ZPD7,5, 1N5236++
OAZ 212	Phi	Z-Di	9,1V, 15%	1c				BZX55/C9V1, BZX79/C9V1, ZPD9,1, 1N5239++
OAZ 213	Phi	Z-Di	12V, 15%	1c				BZX55/C12, BZX79/C12, ZPD12, 1N5242, ++
<b>OC....OD</b>								
OC		N-FET	=XN 1D873 (SMD-Marking)	45	SOT-153			=XN 1D873
OC		N-FET	=XP 1D873 (SMD-Marking)	45(2mm)	SOT-353			=XP 1D873
OC 16	Phi	Ge-P	LFS P, -/32V, 1,5A, 4W(Tc=45°)		(AD 162)	22a	(AD 162)	
OC 18	Phi	Ge-P	LFS P, 30W					
OC 19	Gpd,Phi	Ge-P	LFS P, 32V, 3A, 50W	23a	TO-3			AD 149, AUY 19...20, 2N2137...2146
OC 20	Gpd,Phi	Ge-P	LFS P, 100V, 8A, 30W(Tc=45°)	23a	TO-3			AL 100...101, ASZ 15, ASZ 18, 2N2527, ++
OC 22	Gpd,Phi	Ge-P	LFS P, 47/32V, 1A, 21,5W	23a	TO-3	AL 102	23a	AD 149, AUY 19...20, 2N2137...2146
OC 23	Gpd,Phi	Ge-P	=OC 22: 55/40V	23a	TO-3	AL 102	23a	AD 149, AUY 19...20, 2N2137...2146
OC 24	Gpd,Phi	Ge-P	=OC 22: 47/40V	23a	TO-3	AL 102	23a	AD 149, AUY 19...20, 2N2137...2146
OC 25	Gpd	Ge-P	LFS P, 40V, 4A, 22W(Tc=45°)	23a	TO-3			AL 102...103, AUY 28, 2N1529...1548
OC 26	Gpd,Phi	Ge-P	LF P, 40V, 3,5A, 12,5W(Tc=75°)	23a	TO-3	AL 102	23a	AD 149, AUY 19...20, 2N1529...1548
OC 27	Phi	Ge-P	16V, 3,5A, 12W(Tc=45°)	23a	TO-3			AD 149, AUY 19...20, 2N2137...2146
OC 28	Gpd,Phi	Ge-P	S P, 80V, 6A, 30W(Tc=45°)	23a	TO-3	AL 102	23a	AL 102...103, AUY 22A, ASZ 15, ASZ 18, ++
OC 29	Gpd,Phi	Ge-P	=OC 28: 60V	23a	TO-3	AL 102	23a	AL 102...103, AUY 22A, ASZ 15, ASZ 18, ++
OC 30	Gpd,Phi	Ge-P	LFS P, 32V, 1,4A, 6,7W	22a	TO-66	AD 162	22a	AD 162
OC 30 A		Ge-P	=OC 30: 4W	22a	TO-66	AD 162	22a	AD 162
OC 30 B		Ge-P	=OC 30: 60V, 4W	22a	TO-66			-
OC 32	Itt,Nuc	Ge-P	LF, 25V, 10mA, 0,05W, hfe=13	1a				AC 125...126, AC 151
OC 33	Itt,Nuc	Ge-P	=OC 32: hfe=24	1a				AC 125...126, AC 151
OC 34	Itt,Nuc	Ge-P	=OC 32: hfe=39	1a				AC 125...126, AC 151
OC 35	Gpd,Phi	Ge-P	S P, 80V, 6A, 30W(Tc=45°)	23a	TO-3	AL 102	23a	AL 102...103, AUY 22A, ASZ 15, ASZ 18, ++
OC 36	Gpd,Phi	Ge-P	=OC 35: 60V	23a	TO-3	AL 102	23a	AL 102...103, AUY 22A, ASZ 15...18, ++
OC 37	Itt	Ge-P	LF, 30V, 0,125A, 0,065W	1a				AC 125...126, AC 151

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
OC 38	Itt	Ge-P	LF, 30V, 0.065W	1a			AC 125...126, AC 151
OC 44	Phi	Ge-P	AM Inp,Mx,Os, 15MHz	1a	AF 239 S	5g	AF 126, AF 200
OC 45	Phi	Ge-P	AM IF, 6MHz	1a	AF 239 S	5g	AF 126, AF 200
OC 57	Phi	Ge-P	Min, LF Inp,Drv, 7V, 5mA, 0.02W, hfe=35	37a			-
OC 58	Phi	Ge-P	=OC 57: hfe=55	37a			-
OC 59	Phi	Ge-P	=OC 57: hfe=80	37a			-
OC 60	Phi	Ge-P	=OC 57: hFE=75	37a			-
OC 70	Phi	Ge-P	LF Inp,Drv, 32V, 10mA, 0.125W, hfe>20	1a	AC 151	2a	AC 125...126, AC 151
OC 71	Phi	Ge-P	=OC 70: hfe>30	1a	AC 151	2a	AC 125...126, AC 151
OC 72	Phi	Ge-P	LF Drv, 32V, 0.05A, 0.125W	1a	AC 151	2a	AC 125...126, AC 151
OC 73	Phi	Ge-P	LF Drv, 32V, 10mA, 0.125W	1a	AC 151	2a	AC 125...126, AC 151
OC 74	Phi	Ge-P	LF Drv,Out, 20V, 0.3A, 0.22W	1a	AC 188 K	3a	AC 128, AC 153, AC 188
OC 75	Phi	Ge-P	LF Inp, 32V, 10mA, 0.125W	1a	AC 151	2a	AC 125...126, AC 151
OC 76	Phi	Ge-P	S, 32V, 0.125A, 0.125W	1a	AC 151	2a	AC 125...126, AC 151
OC 77	Phi	Ge-P	=OC 76: 60V	1a			ACY 24, ASY 48, ASY 77
OC 79	Phi	Ge-P	LF Drv, 26V, 0.3A, 0.22W	1a	AC 188 K	3a	AC 128, AC 153, AC 188
OC 80(A)	Phi	Ge-P	S, 20V, 0.3A, 0.22W	1a			AC 128, AC 153, AC 188
OC 81	Phi	Ge-P	LF, 32V, 0.2A, 0.6W	1a			AC 128, AC 153, AC 188
OC 82	Phi	Ge-P	LF, 16V, 0.2A, 0.6W	1a			AC 125...126, AC 151
OC 83	Phi	Ge-P	LF, 32V, 0.5A, 0.6W	1a			AC 128, AC 153, AC 188
OC 84	Phi	Ge-P	LF, 32V, 0.5A, 0.6W	1a			AC 128, AC 153, AC 188
OC 122	Phi	Ge-P	L.F.S, 32V, 0.5A, 0.2W	1g			AC 128, AC 153, AC 188
OC 123	Phi	Ge-P	L.F.S, 50V, 0.5A, 0.2W	1g			ACY 24, ASY 48, ASY 77
OC 139	Phi	Ge-N	S, sym, 20V, 0.25A, 0.085W, hFE>20	1a			ASY 28...29, ASY 73...75
OC 140	Phi	Ge-N	=OC 139: 0.4A, hFE>50	1a			ASY 28...29, ASY 73...75
OC 141	Phi	Ge-N	=OC 139: 0.4A, hFE>80	1a			ASY 28...29, ASY 73...75
OC 169	Phi	Ge-P	AM Inp,Mx,IF, 70MHz	1g	AF 239 S	5g	AF 126...127, AF 200
OC 170	Phi	Ge-P	AM Inp,Mx, FM IF, 70MHz	1m	AF 239 S	5g	AF 126, AF 200
OC 171(M,V)	Phi	Ge-P	FM Inp,Mx, 80MHz	1m	AF 239 S	5g	AF 124...125, AF 200
OC 200	Phi,Tix	Si-P	Uni, 30V, 0.05A, 0.25W, 1.2MHz	1a	BC 556	7a	BC 213, BC 258, BC 308, BC 558, ++
OC 201	Phi,Tix	Si-P	Uni, 25V, 0.05A, 0.25W, 3.2MHz	1a	BC 556	7a	BC 213, BC 258, BC 308, BC 558, ++
OC 202	Phi,Tix	Si-P	Uni, 15V, 0.05A, 0.25W, 3.2MHz	1a	BC 556	7a	BC 213, BC 258, BC 308, BC 558, ++
OC 203	Phi,Tix	Si-P	Uni, 60V, 0.05A, 0.25W, 1.2MHz	1a	BC 556	7a	BC 212, BC 257, BC 307, BC 556, ++
OC 204	Phi,Tix	Si-P	Uni, 32V, 0.25A, 0.3W, >0.45MHz	1a	BC 327	7a	BC 327...328, BC 636, BC 638, BC 640
OC 205	Phi,Tix	Si-P	Uni, 60V, 0.25A, 0.3W, >0.45MHz	1a	BC 327	7a	BC 327A, BC 638, BC 640
OC 206	Phi,Tix	Si-P	Uni, 32V, 0.25A, 0.3W, >0.85MHz	1a	BC 327	7a	BC 327...327, BC 636, BC 638, BC 640
OC 207	Phi,Tix	Si-P	Uni, 50V, 0.25A, 0.3W, 2MHz	1a	BC 327	7a	BC 327, BC 638, BC 640
OC 300(30)		Ge-P	=OC 602sp.	2a	AC 151	2a	-
OC 303	Itt	Ge-P	LF Inp,Drv, 32V, 0.05A, 0.067W	2a	AC 151	2a	AC 125...126, AC 151
OC 304	Itt	Ge-P	LF Inp,Drv, 32V, 0.05A, 0.067W	2a	AC 151	2a	AC 125...126, AC 151
OC 305	Itt	Ge-P	LF Inp,Drv, 32V, 0.05A, 0.067W	2a	AC 151	2a	AC 125...126, AC 151
OC 306	Itt	Ge-P	LF Inp In, 32V, 0.05A, 0.067W	2a	AC 151	2a	AC 151r, ACY 32
OC 307	Itt	Ge-P	S, 32V, 0.25A, 0.075W	2a	AC 188 K	3a	AC 128, AC 153, AC 188
OC 308	Itt	Ge-P	LF Drv,Out, 32V, 0.25A, 0.075W	2a	AC 188 K	3a	AC 128, AC 153, AC 188
OC 309	Itt	Ge-P	S, 60V, 0.25A, 0.075W	2a			ACY 24, ASY 48, ASY 77
OC 318	Itt	Ge-P	LF Drv,Out, 20V, 0.3A, 0.135W	2a	AC 188 K	3a	AC 128, AC 153, AC 188
OC 320	Itt	Ge-P	Min, LF, 20V, 35mA, 0.045W, hfe=13	37d			-
OC 330	Itt	Ge-P	Min, LF, 15V, 35mA, 0.045W, hfe>20	37d			-
OC 331	Itt	Ge-P	Min, LF, 7V, 30mA, 0.03W, hfe>20	37d			OC 57...60
OC 340	Itt	Ge-P	=OC 330: hfe>30	37d			-
OC 341	Itt	Ge-P	=OC 331: hfe>30	37d			OC 57...60
OC 342	Itt	Ge-P	=OC 331: hfe>50	37d			OC 57...60
OC 343	Itt	Ge-P	=OC 331: hfe>80	37d			OC 57...60
OC 350	Itt	Ge-P	=OC 330: 8V	37d			OC 57...60
OC 351	Itt	Ge-P	=OC 331: 5V	37d			OC 57...60
OC 360	Itt	Ge-P	=OC 330: In	37d			-
OC 361	Itt	Ge-P	=OC 331: In, hfe>30	37d			OC 57...60
OC 362	Itt	Ge-P	=OC 331: In, hfe>50	37d			OC 57...60
OC 363	Itt	Ge-P	=OC 331: In, hfe>80	37d			OC 57...60
OC 364	Itt	Ge-P	=OC 331: In, hfe>50	37d			OC 57...60
OC 390	Itt	Ge-P	AM Mx,Os,IF	2a	AF 239 S	5g	AF 126, AF 200
OC 400	Itt	Ge-P	=OC 390: hfe=75	2a	AF 239 S	5g	AF 126, AF 200
OC 410	Itt	Ge-P	=OC 390: hfe=110	2a	AF 239 S	5g	AF 126, AF 200
OC 430(K)	Itt	Si-P	Uni, 10V, 0.05A, 0.2W, hfe>10	2a	TO-18L		BC 213, BC 258, BC 308, BC 558, ++
OC 440(K)	Itt	Si-P	=OC 430(K): 30V	2a	TO-18L		BC 213, BC 258, BC 308, BC 558, ++
OC 443(K)	Itt	Si-P	Uni, 25V, 0.05A, 0.2W, hfe>15	2a	TO-18L		BC 213, BC 258, BC 308, BC 558, ++
OC 445(K)	Itt	Si-P	=OC 430(K): 50V	2a	TO-18L		BC 212, BC 257, BC 307, BC 557, ++
OC 449(K)	Itt	Si-P	=OC 443(K): 60V	2a	TO-18L		BC 212, BC 256, BC 266, BC 556, ++
OC 450(K)	Itt	Si-P	=OC 430(K): 75V	2a	TO-18L		BC 556, 2SA893(A), 2SA1017, 2SB715, ++
OC 460(K)	Itt	Si-P	=OC 430(K): hfe>20	2a	TO-18L		BC 213, BC 258, BC 308, BC 558, ++
OC 463(K)	Itt	Si-P	=OC 430(K): hfe>20	2a	TO-18L		BC 213, BC 258, BC 308, BC 558, ++
OC 465(K)	Itt	Si-P	=OC 430(K): 20V, hfe>20	2a	TO-18L		BC 213, BC 258, BC 308, BC 558, ++
OC 466(K)	Itt	Si-P	=OC 430(K): In, hfe>20	2a	TO-18L		BC 214, BC 259, BC 309, BC 559, ++
OC 467(K)	Itt	Si-P	=OC 430(K): 25V, hfe>25	2a	TO-18L		BC 213, BC 258, BC 308, BC 558, ++
OC 468(K)	Itt	Si-P	=OC 430(K): hfe>40	2a	TO-18L		BC 213, BC 258, BC 308, BC 558, ++
OC 469(K)	Itt	Si-P	=OC 430(K): 32V, hFE=25	2a	TO-18L		BC 213, BC 258, BC 308, BC 558, ++
OC 470(K)	Itt	Si-P	=OC 430(K): 30V, hfe>20	2a	TO-18L		BC 213, BC 258, BC 308, BC 558, ++
OC 480(K)	Itt	Si-P	=OC 430(K): 125V	2a	TO-18L		2SA893A, 2SA1017, 2SA1285(A), 2SB716, ++
OC 601	Aeg	Ge-P	LF, 50V, 20mA, 0.05W	1a			AC 125...126, AC 151
OC 602	Aeg	Ge-P	LF Inp, 22V, 0.05A, 0.05W	1a	AC 151	2a	AC 125...126, AC 151
OC 602 sp		Ge-P	LF Drv,Out, 40V, 0.5A, 0.175W	1a	AC 188 K	3a	AC 128, AC 153, AC 188
OC 603	Aeg	Ge-P	LF Inp In, 22V, 0.05A, 0.05W	1a	AC 151	2a	AC 125...126, AC 151
OC 604	Aeg	Ge-P	LF Inp, 22V, 0.05A, 0.05W	1a	AC 151	2a	AC 125...126, AC 151
OC 604 sp		Ge-P	LF Drv,Out, 40V, 0.5A, 0.175W	1a	AC 188 K	3a	AC 128, AC 153, AC 188
OC 612	Aeg	Ge-P	AM/FM IF	1a	AF 239 S	5g	AF 127, AF 200
OC 613	Aeg	Ge-P	AM Inp,Mx,Os	1a	AF 239 S	5g	AF 126, AF 200
OC 614	Aeg	Ge-P	AM/FM IF	1a	AF 239 S	5g	AF 126, AF 200
OC 615(M,V)	Aeg	Ge-P	FM Inp,Mx	1a	AF 239 S	5g	AF 124...125, AF 200
OC 622	Aeg	Ge-P	Min, LF, 15V, 30mA, 0.03W, hfe>20	37d			-
OC 623	Aeg	Ge-P	=OC 622: In, hfe>50	37d			-
OC 624	Aeg	Ge-P	=OC 622: hfe>75	37d			-
OD 502	Mat	Si-N/P	Dual, LF P, ±150/150V, ±8/12A, 100W, 50MHz	=20/2x3Pin			-



Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
OD 503	Mat	Si-N/P	Dual, LF P, ±150/150V, ±10/15A, 150W, 50MHz	=20/2x3Pin			-
OD 603	Aeg	Ge-P	LF P, 40V, 3A, 6W(Tc=45°)				(AD 149, AD 162, AUY 19, AUY 20, ++) <sup>4</sup>
OD 603/50		Ge-P	=OD 603: 60V, 1A				(AD 149, AD 162, AUY 19, AUY 20, ++) <sup>4</sup>
OE		Si-N+R	=XN 421F (SMD-Marking)	46	SOT-163		*XN 421F
<b>OF</b>							
OF		Si-P	=XN 4130 (SMD-Marking)	46	SOT-163		*XN 4130
OF 010	Phi	Si-Di	=1N4007	31a		1N4007	31a *1N4007
OF 048	Phi	Opto	LED				
OF 126	Phi	Si-Di	=1N4148			1N4148	31a *1N4148
OF 132	Phi	Si-Di	=1N4148	31a		1N4148	31a *1N4148
OF 156	Phi	Si-Di	=1N4148	31a		1N4148	31a *1N4148
OF 157	Phi	Si-Di	10V, 75/150mA, Uf=0.5...0.58V(0.2mA)	31a	DO-35	1N4148	31a BA 127, BA 147/25, BA 215, 1N4148...49,++
OF 158	Phi	Si-Di	SS, 40V, -/0.15A, Uf<1.2V(10mA), <4ns	31a	DO-35	1N4148	31a BAW 62, BAW 76, BAX 95, 1N4148...49, ++
OF 160	Phi	Si-Di	=BY 127	31a		BY 133	31a *BY 127
OF 161	Phi	Si-Di	=1N4148	31a		1N4148	31a *1N4148
OF 162	Phi	Si-Di	=1N4148	31a		1N4148	31a *1N4148
OF 164	Phi	Si-St	=BZX 75/C2V1	31a		Z-Diode 2,1V	31a *BZX 75/C2V1
OF 173	Phi	Ge-Di	=1N34			AA 133	31a *1N34
OF 184	Phi	Si-Di	Uni, 40V, 0,2/0,3A, Uf<1V(10mA)	31a	DO-35	1N4148	31a BA 127, BA 147/50, BA 215, 1N4148...49,++
OF 194	Phi	Si-Di	=BY 206	31a		BA 159	31a *BY 206
OF 208	Phi	Si-Di	=1N4148	31a	DO-35	1N4148	31a *1N4148
OF 223	Phi	Si-Di	=BA 148	31a		BA 159	31a *BA 148
OF 238	Phi	Z-Di	=BZX 79C15	31a		Z-Diode 15V	31a *BZX 79C15
OF 241	Phi	Si-Di	=BY 127	31a		BY 133	31a *BY 127
OF 249	Phi	Si-Di	=1N4148	31a		1N4148	31a *1N4148
OF 276	Phi	Si-Di	=BZX 75C2V1	31a		Z-Diode 2,1V	31a *BZX 75C2V1
OF 340	Phi	Z-Di	=BZX 79C5V1	31a		Z-Diode 5,1V	31a *BZX 79C5V1
OF 341(1/15)	Phi	Z-Di	=BZX 79C15	31a		Z-Diode 15V	31a *BZX 79C15
OF 342	Phi	Z-Di	=BZX 79C18	31a		Z-Diode 18V	31a *BZX 79C18
OF 343	Phi	Z-Di	=BZX 79C47	31a		Z-Diode 47V	31a *BZX 79C47
OF 344	Phi	Z-Di	=BZX 79C56	31a		Z-Diode 56V	31a *BZX 79C56
OF 345	Phi	Z-Di	=BZX 79C68	31a		Z-Diode 68V	31a *BZX 79C68
OF 414	Phi	Si-Di	=BAW 56			2x 1N4148	31a *BAW 56
OF 417	Phi	Si-Di	=BAX 12	31a		BA 159	31a *BAX 12
OF 420	Phi	Z-Di	=BZX 79C18	31a		Z-Diode 18V	31a *BZX 79C18
OF 432	Phi	Si-Br	=BY 224/600			4x BY 255	31a *BY 224/600
OF 449	Phi	Si-Di	=BAV 21	31a		BA 159	31a *BAV 21
OF 560	Phi	Si-Di	=RGP 30M			BYW 96 E	31a *RGP 30M
OF 582	Phi	Si-Di	Rr, 1600V, 1,2A	31a	SOD-57	BY 228	31a BY 228, BY 448, DM 513, EM 516, GP 10Y
OF 643		C-Di	UHF Tuning				
OF 799	Phi	Si-Di	TV, Damper-Di			BY 228	31a *BY 228
OH 003...050	Mat	GaAs	Hall Sensors f. VC, CD, FDD				
OH		Si-P	=XN 4402 (SMD-Marking)	46	SOT-163		*XN 4402
OK		Si-N	=2SC3736-OK (SMD-Marking)	39	SOT-89		*2SC3736
OK		Z-Di	=SM 6T 150C (SMD-Marking)	71a(6x4mm)	SOD-6		*SM 6T...
OL		Si-P	=2SA1521 (SMD-Marking)	35	SOT-23		*2SA1521
OL		Si-N	=2SC3736-OL (SMD-Marking)	39	SOT-89		*2SC3736
OL		Z-Di	=SM 6T 150CA (SMD-Marking)	71a(6x4mm)	SOD-6		*SM 6T...
OL		Si-P+R	=XN 1117 (SMD-Marking)	45	SOT-153		*XN 1117
OL		Si-P+R	=XP 1117 (SMD-Marking)	45(2mm)	SOT-353		*XP 1117
OLP 30161	Sie	µC-IC	8-Bit µComp, 768 Byte RAM, On-Line-Prg	40	DIP		
<b>OM...OZ</b>							
OM		Si-P+R	=XN 1118 (SMD-Marking)	45	SOT-153		*XN 1118
OM		Si-P+R	=XP 1118 (SMD-Marking)	45(2mm)	SOT-353		*XP 1118
OM 175	Phi	Hybrid-IC	CATV, 24V, 60mA, 40...860MHz, 105dBµV				-
OM 186	Phi	Hybrid-IC	Näherungsschalter/Proximity Detector, Ucc=pos.				-
OM 187	Phi	Hybrid-IC	=OM 186: Ucc=neg.				-
OM 200(/S2)	Phi	LIN-IC	Hörgeräteverstärker/Hearing Aid Amplifier				-
OM 200/S2A		LIN-IC	=OM 200: Fig. →	44	SOT-143		-
OM 286(A,M)	Phi	Hybrid-IC	Näherungsschalter/Proximity Detector, Ucc=pos.				-
OM 287(A,M)	Phi	Hybrid-IC	=OM 286(M): Ucc=neg.				-
OM 320	Phi	Hybrid-IC	CATV, 24V, 23mA, 40...860MHz, 94dBµV	=7-SIP			-
OM 321	Phi	Hybrid-IC	=OM 320: 33mA, 100dBµV	=7-SIP			-
OM 322	Phi	Hybrid-IC	CATV, 24V, 60mA, 40...860MHz, 105dBµV				-
OM 323(A)	Phi	Hybrid-IC	CATV, 24V, 100mA, 40...860MHz, 113dBµV				-
OM 335	Phi	Hybrid-IC	CATV, 24V, 35mA, 40...860MHz, 101dBµV	=7-SIP			-
OM 336	Phi	Hybrid-IC	CATV, 24V, 65mA, 40...860MHz, 107dBµV	=7-SIP			-
OM 337(A)	Phi	Hybrid-IC	CATV, 24V, 115mA, 40...860MHz, 112dBµV				-
OM 339	Phi	Hybrid-IC	CATV, 24V, 67mA, 40...860MHz, 107dBµV	=7-SIP			-
OM 345	Phi	Hybrid-IC	CATV, 12V, 11.5mA, 40...860MHz, 99dBµV	=5-SIP			-
OM 350	Phi	Hybrid-IC	CATV, 12V, 18mA, 40...860MHz, 100dBµV	=5-SIP			-
OM 360	Phi	Hybrid-IC	CATV, 12V, 55mA, 40...860MHz, 107dBµV	=8-SIP			OM 361A
OM 361 A	Phi	Hybrid-IC	CATV, 12V, 50mA, 40...860MHz, 107dBµV	=8-SIP			OM 360
OM 370(B)	Phi	Hybrid-IC	CATV, 12V, 105mA, 40...860MHz, 112dBµV	=9-SIP			-
OM 370 A	Phi	Hybrid-IC	CATV, 11V, 100mA, 40...860MHz, 110dBµV	=9-SIP			-
OM 386(B,M)	Phi	Hybrid-IC	Näherungsschalter/Proximity Detector, Ucc=pos.				-
OM 387(B,M)	Phi	Hybrid-IC	=OM 386: Ucc=neg.				-
OM 388(B)	Phi	Hybrid-IC	Näherungsschalter/Proximity Detector, Ucc=pos.				-
OM 389(B)	Phi	Hybrid-IC	=OM 388(B): Ucc=neg.				-
OM 390	Phi	Hybrid-IC	Näherungsschalter/Proximity Detector, Ucc=pos.				-
OM 391	Phi	Hybrid-IC	=OM 390: Ucc=neg.				-
OM 901	Phi	Hybrid-IC	14-Bit D/A-Converter, Audio				-
OM 931	Phi	Hybrid-IC	HiFi Audio Out, ±40V, 30W(±26V/8Ω)				OM 961
OM 961	Phi	Hybrid-IC	=OM 931: ±45V, 60W(±35V/8Ω)				OM 991
OM 991	Phi	Hybrid-IC	=OM 931: ±50V, 60W(±50V/8Ω)				-
OM 2860	Phi	Hybrid-IC	Näherungsschalter/Proximity Detector, Ucc=pos.,				-
OM 2870	Phi	Hybrid-IC	=OM 2860: Ucc=neg.				-
ON		Si-P	=XN 4482 (SMD-Marking)	46	SOT-163		*XN 4482
ON 151	Phi	Ge-P	=AF 139			AF 139	*AF 139
ON 222	Phi	Si-N	=BF 181			BF 181	*BF 181

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International	
ON 328	Phi	Thy.	=BRY 39	5g		TO-72	-BRY 39	
ON 595	Phi	Si-N	=BD 135	14h		TO-126	-BD 135	
ON 611	Phi	Si-N	=BF 480				-BF 480	
ON 796	Phi	Si-N	=BC 548				-BC 548	
ON 974	Phi	Si-N	=BU 508	18j		TO-3P	-BU 508	
ON 1128	Phi	Opto	Opto-Koppler/Coupler					
ON 4046	Phi	Si-N	=S 2000A, -BU 508A		S 2000 A,A3	16j	BU 508A, BU 908, S 2000 A	
ON 4147	Phi	Si-N	=S 2000A, -BU 508A		S 2000 A,A3	16j	BU 508A, BU 908, S 2000 A	
ON 4152	Phi	Si-N	=S 2000A, -BU 508A		S 2000 A,A3	16j	BU 508A, BU 908, S 2000 A	
ON 4213	Phi	Si-N	=BUT 56A		BUT 56A	17j	-BUT 56A	
ON 4223	Phi	Si-N+Di	=BU 508D		BU 508D	18j	-BU 508D	
ON 4302	Phi	Si-N	=S 2000A, -BU 508A		S 2000 A,A3	16j	BU 508A, BU 908, S 2000 A	
ON 4337	Phi	Si-N	=BUT 11A		BUT 11 A	17j	-BUT 11A	
ON 4341	Phi	Si-N	=BUT 76A		BUT 76A	17j	-BUT 76A	
ON 4359	Phi	Si-N-Darl+Di	=BD 683		-BD 683		-BD 683	
ON 4437	Phi	Si-N	TV-HA		BU 508 A	18j	-BU 508	
ON 4466	Phi	Si-N	=BUZ 90A		-BUZ 90A		-BUZ 90A	
ON 4521	Phi	MOS-N-FET-e	=BUZ 90		-BUZ 90		-BUZ 90	
ON 4542	Phi	Si-N	=BU 508A		BU 508,S 2000A	18j,16j	-BU 508A	
OO		Si-P	=2SA1255-0 (SMD-Marking)	35		SOT-23	-2SA1255	
OP-07(C,D,E)D	Tix	OP-IC	=OP-07...JG,P: SMD		8-MDIP		NJMOP 07...µA 714LSC	
OP-07 C,J,G,CP	Tix	OP-IC	lo-offset(<150µV), ±22V, 0.6MHz, 0...+70°		8-DIC/DIP		NJMOP 07...µA 714...	
OP-07 D,J,G,DP	Tix	OP-IC	lo-offset(<150µV), ±22V, 0.6MHz, 0...+70°		8-DIC/DIP		NJMOP 07...µA 714...	
OP-07 E,J,G,EP	Tix	OP-IC	lo-offset(<75µV), ±22V, 0.6MHz, 0...+70°		8-DIC/DIP		NJM 07...µA 714...	
OP-27(A,B,C)J	Mot	OP-IC	lo-noise, hi-speed, ±22V, -55...+125°		TO-99		-	
OP-27(A,B,C)Z	Mot	OP-IC	=OP-27(A,B,C)J: Fig. →		8-DIC		-	
OP-27(E,F,G)J	Mot	OP-IC	=OP-27(A,B,C)J: -25...+85°		TO-99		-	
OP-27(E,F,G)P	Mot	OP-IC	=OP-27(A,B,C)J: 0...+70°		8-DIP		-	
OP-27(E,F,G)Z	Mot	OP-IC	=OP-27(A,B,C)J: -25...+85°		8-DIC		-	
OP-37(A,B,C)J	Mot	OP-IC	lo-noise, hi-speed, ±22V, -55...+125°		TO-99		-	
OP-37(A,B,C)Z	Mot	OP-IC	=OP-37(A,B,C)J: Fig. →		8-DIC		-	
OP-37(E,F,G)J	Mot	OP-IC	=OP-37(A,B,C)J: -25...+85°		TO-99		-	
OP-37(E,F,G)P	Mot	OP-IC	=OP-37(A,B,C)J: 0...+70°		8-DIP		-	
OP-37(E,F,G)Z	Mot	OP-IC	=OP-37(A,B,C)J: -25...+85°		8-DIC		-	
OP 160		Opto	LED					
OR 100	Aeg	Diac	Ub=28...36V, Ib<0,1mA, Itsm=2A	31	DO-14	BR 100	31	1N5761, N413M, BR 100, D3202Y, D0201YR
ORP 60		Opto	CdS Foto-Wdst./Resistor					
OT		Si-N	=2SC4364 (SMD-Marking)	35		SOT-23	-2SC4364	
OT		Si-N	=2SC4001 (SMD-Marking)	35		SOT-23	-2SC4001	
OT		Z-Di	=SM 6T 200C (SMD-Marking)	71a(6x4mm)		SOD-6	-SM 6T....	
OT 129		F-Thy+Di	=BT 129			TD 3FP 800H*	17f	-BT 129
OU		Z-Di	=SM 6T 200CA(SMD-Marking)	71a(6x4mm)		SOD-6	-SM 6T....	
OVR-121	Org	Hybrid-Z-IC	+12V, 30mA				-	
OVR-126	Org	Hybrid-Z-IC	+12V, 200mA				-	
OVR-241	Org	Hybrid-Z-IC	+24V, 30mA				-	
OVR-246	Org	Hybrid-Z-IC	+24V, 200mA				-	
OY		Si-P	=2SA1255-Y (SMD-Marking)	35		SOT-23	-2SA1255	
OY		Si-N	=2SC3775 (SMD-Marking)	35		SOT-23	-2SC3775	
OY		Si-N	=2SC4005 (SMD-Marking)	35		SOT-23	-2SC4005	
OY 100		Si-Di	=OY 101			BY 133	31a	-OY 101
OY 101	Aeg	Si-Di	Rr, Uni, 800V, 0,5A	34a	DO-13	BY 133	31a	BY 127, BY 133, BY 227, 1N4006...07, ++
OY 102	Aeg	Si-Di	=OY 101: 400V	34a	DO-13	BY 133	31a	BY 126, BY 134, BY 226, 1N4004...07, ++
OY 241	Sie	Si-Di	Rr, Uni, 800V, 0,45A, Uf<1,3V(0,45A)	34a	DO-13	BY 133	31a	BY 127, BY 133, BY 227, 1N4006...07, ++
OY 1011	Aeg	Si-Di	Rr, Uni, 800/1000V, 0,6A, Uf<1,3V(5A)	34a	DO-13	BY 133	31a	BY 127, BY 133, BY 227, 1N4007, ++
OY 1011/3	Aeg	Si-Di	=OY 1011: 1,5A, Uf<1,3V(3A)	31a	DO-13	BY 255	31a	BY 227, BY 255, GP 15M, 1N5399, ++
OY 1011/4	Aeg	Si-Di	=OY 1011: 0,95A	31a	DO-13	BY 133	31a	BY 127, BY 133, BY 227, 1N4007, ++
OY 1021	Aeg	Si-Di	=OY 1011: 400/600V	34a	DO-13	BY 133	31a	BY 126, BY 134, BY 226, 1N4006...07, ++
OY 5061	Itt	Si-Di	P Rr, 100V, 4A(Tc=50°)	32a	DO-4			BYX 38/300, (BY 229/200, BY 249/300,++) <sup>±</sup>
OY 5062	Itt	Si-Di	=OY 5061: 200V	32a	DO-4			BYX 38/300, (BY 229/200, BY 249/300,++) <sup>±</sup>
OY 5063	Itt	Si-Di	=OY 5061: 300V	32a	DO-4			BYX 38/300, (BY 229/400, BY 249/600,++) <sup>±</sup>
OY 5064	Itt	Si-Di	=OY 5061: 400V	32a	DO-4			BYX 38/600, (BY 229/400, BY 249/600,++) <sup>±</sup>
OY 5065	Itt	Si-Di	=OY 5061: 500V	32a	DO-4			BYX 38/600, (BY 229/600, BY 249/600,++) <sup>±</sup>
OY 5066	Itt	Si-Di	=OY 5061: 600V	32a	DO-4			BYX 38/600, (BY 229/600, BY 249/600,++) <sup>±</sup>
OY 5067	Itt	Si-Di	=OY 5061: 700V	32a	DO-4			BYX 38/900, (BY 229/800) <sup>±</sup>
OZ....		Z-Di				Z-Diode ....V	31a	
<b>P</b>								
P		GaAs-N-FET	=2SK1964 (SMD-Marking)	51		SOT-173	-2SK1964	
P 0		Si-N	=BFP 90A (Marking)	51		SOT-173	-BFP 90A	
P 1	Sie	LIN-IC	Aktiver Matrixpunkt/Cross Point			TO-100	-	
P 1		C-Di	=BB 131 (SMD-Marking)	71(1,7mm)		SOD-323	-BB 131	
P 1		Si-N	=BFP 91A (Marking)	51		SOT-193	-BFP 91A	
P 1(p)		Si-N	=BFR 92 (SMD-Marking)	35		SOT-23	-BFR 92	
P 1		Si-N	=BFS 42 (SMD-Marking)	35(2mm)		SOT-323	-BFS 42	
P 1		Si-N	=D70Y.8T1 (SMD-Marking)	39		SOT-89	-D70Y.8T1	
P 1		Si-P+R	=RT 1P137P (SMD-Marking)	39		SOT-89	-RT 1P137P	
P 1		Si-P+R	=RT 1P141C (SMD-Marking)	35		SOT-23	-RT 1P141C	
P 1		Si-P+R	=RT 1P141M (SMD-Marking)	35(2mm)		SOT-323	-RT 1P141M	
P 01		Si-P	=SO 2906 (SMD-Marking)	35		SOT-23	-SO 2906	
P 1		N-FET	=2SK1577-1 (SMD-Marking)	35		SOT-23	-2SK1577	
P 1 A		Si-N	=PZT 3904 (SMD-Marking)	~39°		SOT-223	-PZT 3904	
P 1 A		Si-N	=PMBT 3904 (SMD-Marking)	35		SOT-23	-PMBT 3904	
P 1 A (p 1 A)		Si-N	=PXT 3904 (SMD-Marking)	39		SOT-89	-PXT 3904	
P 1 A		Si-N	=PMST 3904 (SMD-Marking)	35(2mm)		SOT-323	-PMST 3904	
P 1 B		Si-N	=PMBT 2222 (SMD-Marking)	35		SOT-23	-PMBT 2222	
P 1 B (p 1 B)		Si-N	=PXT 2222 (SMD-Marking)	39		SOT-89	-PXT 2222	
P 1 D		Si-N	=PZTA 42 (SMD-Marking)	~39°		SOT-223	-PZTA 42	
P 1 D		Si-N	=PMBTA 42 (SMD-Marking)	35		SOT-23	-PMBTA 42	
P 1 D (p 1 D)		Si-N	=PXTA 42 (SMD-Marking)	39		SOT-89	-PXTA 42	
P 1 E		Si-N	=PZTA 43 (SMD-Marking)	~39°		SOT-223	-PZTA 43	
P 1 E		Si-N	=PMBTA 43 (SMD-Marking)	35		SOT-23	-PMBTA 43	
P 1 E (p 1 E)		Si-N	=PXTA 43 (SMD-Marking)	39		SOT-89	-PXTA 43	
P 1 F		Si-N	=PMBT 5550 (SMD-Marking)	35		SOT-23	-PMBT 5550	

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
P 1 G		Si-N	=PMBTA 06 (SMD-Marking)	35		SOT-23	•PMBTA 06
P 1 H		Si-N	=PMBTA 05 (SMD-Marking)	35		SOT-23	•PMBTA 05
P 1 J		Si-N	=PMBT 2369 (SMD-Marking)	35		SOT-23	•PMBT 2369
P 1 K		Si-N	=PMBT 6428 (SMD-Marking)	35		SOT-23	•PMBT 6428
P 1 L		Si-N	=PMBT 6429 (SMD-Marking)	35		SOT-23	•PMBT 6429
P 1 M		Si-N	=PZTA 13 (SMD-Marking)	-39°		SOT-223	•PZTA 13
P 1 M		Si-N	=PMBTA 13 (SMD-Marking)	35		SOT-23	•PMBTA 13
P 1 N		Si-N	=PZTA 14 (SMD-Marking)	-39°		SOT-223	•PZTA 14
P 1 N		Si-N	=PMBTA 14 (SMD-Marking)	35		SOT-23	•PMBTA 14
P 1 N (p 1 N)		Si-N	=PXTA 14 (SMD-Marking)	39		SOT-89	•PXTA 14
P 1 P		Si-N	=PMBT 2222A (SMD-Marking)	35		SOT-23	•PMBT 2222A
P 1 P (p 1 P)		Si-N	=PXT 2222A (SMD-Marking)	39		SOT-89	•PXT 2222A
P 1 Q		Si-N	=PMBT 5088 (SMD-Marking)	35		SOT-23	•PMBT 5088
P 1 Q		Si-N	=PMST 5088 (SMD-Marking)	35(2mm)		SOT-323	•PMST 5088
P 1 R		Si-N	=PMST 5089 (SMD-Marking)	35(2mm)		SOT-323	•PMST 5089
P 1 Y		Si-N	=PMBT 3903 (SMD-Marking)	35		SOT-23	•PMBT 3903
P 2		C-Di	=BB 132 (SMD-Marking)	71(1,7mm)		SOD-323	•BB 132
P 2(p)		Si-N	=BFR 92A (SMD-Marking)	35		SOT-23	•BFR 92A
P 2		Si-N	=BFR 92AW (SMD-Marking)	35(2mm)		SOT-323	•BFR 92AW
P 2		Si-N	=BFS 43 (SMD-Marking)	35(2mm)		SOT-323	•BFS 43
P 2		Si-P+R	=RT 1P241C (SMD-Marking)	35		SOT-23	•RT 1P241C
P 2		Si-P+R	=RT 1P241M (SMD-Marking)	35(2mm)		SOT-323	•RT 1P241M
P 2		N-FET	=2SK1577-2 (SMD-Marking)	35		SOT-23	•2SK1577
P 2 A		Si-P	=PZT 3906 (SMD-Marking)	-39°		SOT-223	•PZT 3906
P 2 A		Si-P	=PMBT 3906 (SMD-Marking)	35		SOT-23	•PMBT 3906
P 2 A (p 2 A)		Si-P	=PXT 3906 (SMD-Marking)	39		SOT-89	•PXT 3906
P 2 A		Si-P	=PMST 3906 (SMD-Marking)	35(2mm)		SOT-323	•PMST 3906
P 2 B		Si-P	=PZT 2907 (SMD-Marking)	-39°		SOT-223	•PZT 2907
P 2 B		Si-P	=PMBT 2907 (SMD-Marking)	35		SOT-23	•PMBT 2907
P 2 B (p 2 B)		Si-P	=PXT 2907 (SMD-Marking)	39		SOT-89	•PXT 2907
P 2 D		Si-P	=PZTA 92 (SMD-Marking)	-39°		SOT-223	•PZTA 92
P 2 D		Si-P	=PMBTA 92 (SMD-Marking)	35		SOT-23	•PMBTA 92
P 2 D (p 2 D)		Si-P	=PXTA 92 (SMD-Marking)	39		SOT-89	•PXTA 92
P 2 E		Si-P	=PZTA 93 (SMD-Marking)	-39°		SOT-223	•PZTA 93
P 2 E		Si-P	=PMBTA 93 (SMD-Marking)	35		SOT-23	•PMBTA 93
P 2 E (p 2 E)		Si-P	=PXTA 93 (SMD-Marking)	39		SOT-89	•PXTA 93
P 2 F		Si-P	=PZT 2907A (SMD-Marking)	-39°		SOT-223	•PZT 2907A
P 2 F		Si-P	=PMBT 2907A (SMD-Marking)	35		SOT-23	•PMBT 2907A
P 2 F (p 2 F)		Si-P	=PXT 2907A (SMD-Marking)	39		SOT-89	•PXT 2907A
P 2 G		Si-P	=PMBTA 56 (SMD-Marking)	35		SOT-23	•PMBTA 56
P 2 H		Si-P	=PMBTA 55 (SMD-Marking)	35		SOT-23	•PMBTA 55
P 2 L		Si-P	=PMBT 5401 (SMD-Marking)	35		SOT-23	•PMBT 5401
P 2 T		Si-P	=PMBT 4403 (SMD-Marking)	35		SOT-23	•PMBT 4403
P 2 T (p 2 T)		Si-P	=PXT 4403 (SMD-Marking)	39		SOT-89	•PXT 4403
P 2 T		Si-P	=PMST 4403 (SMD-Marking)	35(2mm)		SOT-323	•PMST 4403
P 2 U		Si-P	=PZTA 63 (SMD-Marking)	-39°		SOT-223	•PZTA 63
P 2 U		Si-P	=PMBTA 63 (SMD-Marking)	35		SOT-23	•PMBTA 63
P 2 V		Si-P	=PMBTA 64 (SMD-Marking)	35		SOT-23	•PMBTA 64
P 2 V (p 2 V)		Si-P	=PXTA 64 (SMD-Marking)	39		SOT-89	•PXTA 64
P 2 X		Si-N	=PMBT 4401 (SMD-Marking)	35		SOT-23	•PMBT 4401
P 2 X (p 2 X)		Si-N	=PXT 4401 (SMD-Marking)	39		SOT-89	•PXT 4401
P 2 X		Si-N	=PMST 4401 (SMD-Marking)	35(2mm)		SOT-323	•PMST 4401
P 3		N-FET	=2SK1577-3 (SMD-Marking)	35		SOT-23	•2SK1577
P 3		C-Di	=BB 133 (SMD-Marking)	71(1,7mm)		SOD-323	•BB 133
P 3		Si-P	=BFS 44 (SMD-Marking)	35(2mm)		SOT-323	•BFS 44
P 3		Si-P+R	=RT 1P441C (SMD-Marking)	35		SOT-23	•RT 1P441C
P 3		Si-P+R	=RT 1P441M (SMD-Marking)	35(2mm)		SOT-323	•RT 1P441M
P 03		Si-P	=SO 2907A (SMD-Marking)	35		SOT-23	•SO 2907A
P 4		Si-N	=2SD1161-P4 (SMD-Marking)	35		SOT-23	•2SD1161
P 4		C-Di	=BB 134 (SMD-Marking)	71(1,7mm)		SOD-323	•BB 134
P 4		Si-N	=BFR 92R (SMD-Marking)	35		SOT-23	•BFR 92R
P 4		Si-P	=BFS 45 (SMD-Marking)	35(2mm)		SOT-323	•BFS 45
P 04		Si-N	=PMSS 3904 (SMD-Marking)	35(2mm)		SOT-323	•PMSS 3904
P 4		Si-P+R	=RT 1P434C (SMD-Marking)	35		SOT-23	•RT 1P434C
P 4		Si-P+R	=RT 1P434M (SMD-Marking)	35(2mm)		SOT-323	•RT 1P434M
P 5		C-Di	=BB 135 (SMD-Marking)	71(1,7mm)		SOD-323	•BB 135
P 5		Si-N	=BFR 92AR (SMD-Marking)	35		SOT-23	•BFR 92AR
P 5		Si-N	=FMMT2369A (SMD-Marking)	35		SOT-23	•FMMT2369A
P 05		Si-P	=SO 2907 (SMD-Marking)	35		SOT-23	•SO 2907
P 5		Si-N	=2SD1161-P5 (SMD-Marking)	35		SOT-23	•2SD1161
p 5 A		Si-Di	=PMMBD 6050 (SMD-Marking)	35		SOT-23	•PMMBD 6050
p 5 B		Si-Di	=PMMBD 6100 (SMD-Marking)	35		SOT-23	•PMMBD 6100
p 5 C		Si-Di	=PMMBD 7000 (SMD-Marking)	35		SOT-23	•PMMBD 7000
p 5 D		Si-Di	=PMMBD 914 (SMD-Marking)	35		SOT-23	•PMMBD 914
P 5		Si-P+R	=RT 1P144C (SMD-Marking)	35		SOT-23	•RT 1P144C
P 5		Si-P+R	=RT 1P144M (SMD-Marking)	35(2mm)		SOT-323	•RT 1P144M
P 6		Si-N	=BFP 96 (Marking)	51		SOT-173	•BFP 96
P 06		Si-P	=PMSS 3906 (SMD-Marking)	35(2mm)		SOT-323	•PMSS 3906
P 06		Si-P	=SO 2894 (SMD-Marking)	35		SOT-23	•SO 2894
P 6		Si-N	=2SD1161-P6 (SMD-Marking)	35		SOT-23	•2SD1161
P 6 A		N-FET	=PMBF 4416 (SMD-Marking)	35		SOT-23	•PMBF 4416
p 6 B		N-FET	=PMBF 5484 (SMD-Marking)	35		SOT-23	•PMBF 5484
p 6 G		N-FET	=PMBF 4393 (SMD-Marking)	35		SOT-23	•PMBF 4393
p 6 H		N-FET	=PMBF 5486 (SMD-Marking)	35		SOT-23	•PMBF 5486
p 6 J		N-FET	=PMBF 4391 (SMD-Marking)	35		SOT-23	•PMBF 4391
p 6 K		N-FET	=PMBF 4392 (SMD-Marking)	35		SOT-23	•PMBF 4392
P 6 KE6.8...440(A)	Gie.Mot.Tho	Z-Di	TAZ, 6,8...440V, 5W, Pbr=600W(1ms)	31a		DO-15, -29	BZW06/..., BZW70/..., BZX70/..., BZY93/...
P 6 KE6.8...440C(A)		Z-Di	bidirektional/back to back	31a		DO-15, -29	BZW06/...B
p 6 M		N-FET	=PMBF 5485 (SMD-Marking)	35		SOT-23	•PMBF 5485
P 6		Si-P+R	=RT 1P430C (SMD-Marking)	35		SOT-23	•RT 1P430C
P 6		Si-P+R	=RT 1P430M (SMD-Marking)	35(2mm)		SOT-323	•RT 1P430M
p 6 S		P-FET	=PMBFJ 176 (SMD-Marking)	35		SOT-23	•PMBFJ 176
p 6 W		P-FET	=PMBFJ 175 (SMD-Marking)	35		SOT-23	•PMBFJ 175

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International	
p 6 X		P-FET	=PMBFJ 174 (SMD-Marking)	35	SOT-23		•PMBFJ 174	
p 6 Y		P-FET	=PMBFJ 177 (SMD-Marking)	35	SOT-23		•PMBFJ 177	
P 7		Si-P+R	=RT 1P140C (SMD-Marking)	35	SOT-23		•RT 1P140C	
P 7		Si-P+R	=RT 1P140M (SMD-Marking)	35(2mm)	SOT-323		•RT 1P140M	
P 7 T-10...-110	Tho	Z-Di	TAZ, 10...110V, 5W, Pbr=700W(1ms)	31a	DO-29		BZW07/..., BZW70/..., BZX70/..., BZY93/...	
P 7 T-...B		Z-Di	=P 7 T-... bidirektional/back to back	31a	DO-29		BZW 07/...B	
P 8		Si-N	=BFG 92A (SMD-Marking)	44	SOT-143		•BFG 92A	
P 08		N-FET	=PMBFJ 108 (SMD-Marking)	35	SOT-23		•PMBFJ 108	
P 9		Si-N	=BCX 70RK (SMD-Marking)	35	SOT-23		•BCX 70RK	
P 09		N-FET	=PMBFJ 109 (SMD-Marking)	35	SOT-23		•PMBFJ 109	
P 9		Si-Di	=1SS379 (SMD-Marking)	35	SOT-23		•1SS379	
p 9 A		Si-N	=PMBS 390A (SMD-Marking)	35	SOT-23		•PMBS 390A	
p 9 A		Si-Di	=PLVA 650A (SMD-Marking)	35	SOT-23		•PLVA 650A	
p 9 B		Si-Di	=PLVA 653A (SMD-Marking)	35	SOT-23		•PLVA 653A	
p 9 C		Si-Di	=PLVA 656A (SMD-Marking)	35	SOT-23		•PLVA 656A	
p 9 D		Si-Di	=PLVA 659A (SMD-Marking)	35	SOT-23		•PLVA 659A	
p 9 E		Si-Di	=PLVA 662A (SMD-Marking)	35	SOT-23		•PLVA 662A	
p 9 F		Si-Di	=PLVA 665A (SMD-Marking)	35	SOT-23		•PLVA 665A	
p 9 G		Si-Di	=PLVA 668A (SMD-Marking)	35	SOT-23		•PLVA 668A	
P 10		N-FET	=PMBFJ 110 (SMD-Marking)	35	SOT-23		•PMBFJ 110	
P 11		N-FET	=PMBFJ 111 (SMD-Marking)	35	SOT-23		•PMBFJ 111	
P 12		N-FET	=PMBFJ 112 (SMD-Marking)	35	SOT-23		•PMBFJ 112	
P 12		Si-P	=SO 2906A (SMD-Marking)	35	SOT-23		•SO 2906A	
P 13		N-FET	=PMBFJ 113 (SMD-Marking)	35	SOT-23		•PMBFJ 113	
P 14 0		Si-P+R	=RT 1P140S (SMD-Marking)	41	(TO-92S)		•RT 1P140S	
P 14 1		Si-P+R	=RT 1P141S (SMD-Marking)	41	(TO-92S)		•RT 1P141S	
P 14 4		Si-P+R	=RT 1P144S (SMD-Marking)	41	(TO-92S)		•RT 1P144S	
P 18		Si-P	=SO 679 (SMD-Marking)	35	SOT-23		•SO 679	
P 24 1		Si-P+R	=RT 1P241S (SMD-Marking)	41	(TO-92S)		•RT 1P241S	
P 25		Si-P	=SO 3906 (SMD-Marking)	35	SOT-23		•SO 3906	
P 26		Si-P	=SO 3905 (SMD-Marking)	35	SOT-23		•SO 3905	
P 30		Si-N	=FB 1A4A (SMD-Marking)	35	SOT-23		•FB 1...	
P 31		Si-N	=FB 1L2Q (SMD-Marking)	35	SOT-23		•FB 1...	
P 32		Si-N	=FB 1A3M (SMD-Marking)	35	SOT-23		•FB 1...	
P 32		Si-P	=SO 5400 (SMD-Marking)	35	SOT-23		•SO 5400	
P 33		Si-N	=FB 1F3P (SMD-Marking)	35	SOT-23		•FB 1...	
P 33		Si-P	=SO 5401 (SMD-Marking)	35	SOT-23		•SO 5401	
P 34		Si-N	=FB 1L3N (SMD-Marking)	35	SOT-23		•FB 1...	
P 35		Si-N	=FB 1A4M (SMD-Marking)	35	SOT-23		•FB 1...	
P 36		Si-N	=FB 1J3P (SMD-Marking)	35	SOT-23		•FB 1...	
P 39		Si-P	=SO 692 (SMD-Marking)	35	SOT-23		•SO 692	
P 40		Si-P	=SO 506 (SMD-Marking)	35	SOT-23		•SO 506	
P 41		Si-N	=BFR 92R (SMD-Marking)	35	SOT-23		•BFR 92R	
P 43 0		Si-P+R	=RT 1P430S (SMD-Marking)	41	(TO-92S)		•RT 1P430S	
P 43 4		Si-P+R	=RT 1P434S (SMD-Marking)	41	(TO-92S)		•RT 1P434S	
P 44 1		Si-P+R	=RT 1P441S (SMD-Marking)	41	(TO-92S)		•RT 1P441S	
P 83 C053	Phi	CMOS-µC-IC	=80C51, TV, Video, 8192x8 mask. ROM	42	SDIP		-	
P 87 C054	Phi	CMOS-µC-IC	=80C51, TV, Video, 16384x8 OTPROM	42	SDIP		-	
P 0100 BA	Tag	50Hz-Thy	200V, 0.5A(Tc=85°C), Igt/Ih 0,02/5mA	7n	TO-92		-	
P 0100 DA		50Hz-Thy	=P 0100BA: 400V	7n	TO-92		-	
P 0100 MA		50Hz-Thy	=P 0100BA: 600V	7n	TO-92		-	
P 0100 NA		50Hz-Thy	=P 0100BA: 800V	7n	TO-92		-	
P 0100 BB...NB		50Hz-Thy	=P 0100BA...BN:	7a	TO-92		-	
P 0100 AD		50Hz-Thy	100V, 0.5A(Tc=85°C), Igt/Ih 0,02/5mA	2a	TO-18		(2N2322...2329A)6	
P 0100 BD		50Hz-Thy	=P 0100AD: 200V	2a	TO-18		(2N2322...2329A)6	
P 0100 CD		50Hz-Thy	=P 0100AD: 300V	2a	TO-18		(2N2322...2329A)6	
P 0100 DD		50Hz-Thy	=P 0100AD: 400V	2a	TO-18		(2N2322...2329A)6	
P 0102 AA	Tag	50Hz-Thy	100V, 0.5A(Tc=85°C), Igt/Ih 0,2/5mA	7n	TO-92		MCR 100-..., BRY 55/..., TAG 70..., ++	
P 0102 BA		50Hz-Thy	=P 0102AA: 200V	7n	TO-92		MCR 100-..., BRY 55/..., TAG 70..., ++	
P 0102 CA		50Hz-Thy	=P 0102AA: 300V	7n	TO-92		MCR 100-..., BRY 55/..., TAG 70..., ++	
P 0102 DA		50Hz-Thy	=P 0102AA: 400V	7n	TO-92		MCR 100-..., BRY 55/..., TAG 70..., ++	
P 0102 AB...DB		50Hz-Thy	=P 0102AA...DA:	7a	TO-92		MCR 100-..., BRY 55/..., TAG 70..., ++	
P 0103 BA...NA	Tag	50Hz-Thy	=P 0102BA...NA:	7n	TO-92		MCR 100-..., BRY 55/..., TAG 70..., ++	
P 0103 BB...NB		50Hz-Thy	=P 0102BA...NA:	7a	TO-92		MCR 100-..., BRY 55/..., TAG 70..., ++	
P 0103 AD...DD		50Hz-Thy	=P 0102AD...DA:	2a	TO-18		2N2322...2329, 2N6332...6337, TAG 615-...	
P 300 A...M	Gie	Si-Di	Rr, 50...1000V, 5A(Tc=100°), Uf<1.2V(3A), 5µs A=50, B=100, D=200, G=400, J=600, K=800, M=1000V	31a	DO-27A	BY 500/800	31a	BY 500/..., MR 820...826
P 600 A...M	Gie, Die	Si-Di	Rr, 50...1000V, 6A, Uf<0.9V(6A), 5µs A=50, B=100, D=200, G=400, J=600, K=800, M=1000V	31a	(9x9mm0)	BY 329/12004	17k	BY 214/..., MR 750...760
P 2221(A)	Itt	Si-N	=2N2221(A)	7a	TO-92	BC 337	7a	
P 2222(A)	Itt	Si-N	=2N2222(A)	7a	TO-92	BC 337	7a	
P 2646...2647	Wab	UJT-P	=2N2646...2647	7h	TO-92			=2N2646...2647
P 2906(A)	Itt	Si-P	=2N2906(A)	7a	TO-92	BC 327	7a	
P 2907(A)	Itt	Si-P	=2N2907(A)	7a	TO-92	BC 327	7a	
P 6009	Tix	Si-P-Darl	L.F.S P, 25V, 1A, 5W, hFE>4000	14h	TO-126	BD 680	14h	BD 466(A...B), BD 876, BDX 45
P 6021		Si-P	=BD 166	14h	TO-126	BD 238	14h	=BD 166
P 7002	Tix	Si-N	=BD 400	14h	TO-126	MJE 340	14h	=BD 400
P 7009	Tix	Si-N-Darl	L.F.S P, 25V, 1A, 5W, hFE>4000	14h	TO-126	BD 679	14h	BD 477(A...B), BD 875, BDX 42
P 7010		Si-N	=BD 139	14h	TO-126	BD 139	14h	=BD 139
P 7020		Si-N	=BD 135	14h	TO-126	BD 139	14h	=BD 135
P 7027		Si-N	=BD 135	14h	TO-126	BD 139	14h	=BD 135
P 7029		Si-N	=BD 410	14h	TO-126	MJE 340	14h	=BD 410
<b>PA...PL</b>								
PA		Si-N	=2SC3295-A (SMD-Marking)	35	SOT-23			=2SC3295
PA		Si-N	=2SC4666A (SMD-Marking)	35(2mm)	SOT-323			=2SC4666A
PA		MOS-P-FET-e	=2SJ179 (SMD-Marking)	39	SOT-89			=2SJ179
PA		PIN-Di	=BA 885 (SMD-Marking)	35	SOT-23			=BA 885
PA		Si-P	=KRA101S (SMD-Marking)	35	SOT-23			=KRA 101S
PA		Si-Di	=MA 735 (SMD-Marking)	71(5mm)				=MA 735
PA		Si-N/P	=µPA609T (SMD-Marking)	46	SOT-163			=µPA609T
pA 2		Si-Di	=PMBD 2836 (SMD-Marking)	35	SOT-23			=PMBD 2836
pA 3		Si-Di	=PMBD 2835 (SMD-Marking)	35	SOT-23			=PMBD 2835



Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
pA 5		Si-Di	=PMBD 2837 (SMD-Marking)	35	SOT-23		+PMBD 2837
pA 6		Si-Di	=PMBD 2838 (SMD-Marking)	35	SOT-23		+PMBD 2838
PA 40 N200	Gie	MOS-N-FET-e	VFET, 60V, 9A, 40W, on=0,2Ω(2,5A)	17p	TO-220		BUZ 20, IRF 532, 533, 2SK918, 2SK1114,++
PA 40 N300		MOS-N-FET-e	=PA 40N200: 8A, on=0,3Ω(2,5A)	17p	TO-220		IRF 521, 2SK918, 2SK993, 2SK1114,++
PA 75 N85	Gie	MOS-N-FET-e	VFET, 60V, 23A, 75W, on=0,085Ω(5A)	23a	TO-3		BUZ24, IRF035, 2N6763, 2SK906, 2SK1429++
PA 75 N120		MOS-N-FET-e	=PA 75N85: 15A, on=0,12Ω(5A)	23a	TO-3		BUZ24, IRF131, 2SK561, 2SK906, 2SK1429++
PA 75 N150		MOS-N-FET-e	=PA 75N85: 15A, on=0,15Ω(5A)	23a	TO-3		BUZ24, IRF131, 2SK561, 2SK906, 2SK1429++
PA 125 N40	Gie	MOS-N-FET-e	VFET, 60V, 48A, 125W, on=0,04Ω(10A)	16p	TO-247		2SK1258, 2SK1379, 2SK1422, 2SK2121
PA 125 N60		MOS-N-FET-e	=PA 125N40: 41A, on=0,06Ω(10A)	16p	TO-247		2SK1297, 2SK1514, 2SK1665, 2SK2096
PA 145		Si-Di	=BA 145	31a		BA 159	+BA 145
PA 148		Si-Di	=BA 148	31a		BA 159	+BA 148
PA 2824 C		Z-IC	+24V	17b	TO-220	7824/TO-220	17b
PA 7915 C		Z-IC	-15V	17c	TO-220	7915/TO-220	17c
PB		Si-N	=2SC3295-B (SMD-Marking)	35	SOT-23		+2SC3295
PB		Si-N	=2SC4666B (SMD-Marking)	35(2mm)	SOT-323		+2SC4666B
PB		MOS-P-FET-e	=2SJ197 (SMD-Marking)	39	SOT-89		+2SJ197
PB		Si-P	=KRA102S (SMD-Marking)	35	SOT-23		+KRA 102S
PB		Si-Di	=MA 736 (SMD-Marking)	71(5mm)			+MA 736
PB 40 N280	Gie	MOS-N-FET-e	VFET, 100V, 8A, 40W, on=0,28Ω(2,5A)	17p	TO-220		BUK 552-100, IRF 522, 2SK470, 2SK918
PB 40 N400		MOS-N-FET-e	=PB 40N280: 7A, 40W, on=0,4Ω(2,5A)	17p	TO-220		BUK 552-100, IRF 522, 2SK470, 2SK918
PB 75 N140	Gie	MOS-N-FET-e	VFET, 100V, 16A, 75W, on=0,14Ω(5A)	23a	TO-3		BUZ36, IRF130, MTM12N10, 2N6765, 2SK572
PB 75 N180		MOS-N-FET-e	=PB 75N140: 14A, 75W, on=0,18Ω(5A)	23a	TO-3		BUZ36, IRF130, MTM12N10, 2N6765, 2SK572
PB 125 N60	Gie	MOS-N-FET-e	VFET, 100V, 39A, 125W, on=0,06Ω(10A)	16p	TO-247		BUZ 345, 2SK1122, 2SK2363, 2SK1304
PB 125 N80		MOS-N-FET-e	=PB 125N60: 33A, 125W, on=0,08Ω(10A)	16p	TO-247		BUZ 345, 2SK1122, 2SK2363, 2SK1304
PBC 107	Tho	Si-N	-BC 107	7c	TO-92	BC 546	7a
PBC 108	Tho	Si-N	-BC 108	7c	TO-92	BC 546	7a
PBC 109	Tho	Si-N	-BC 109	7c	TO-92	BC 550	7a
PBC 182	Tho	Si-N	-BC 182	7c	TO-92	BC 546	7a
PBC 183	Tho	Si-N	-BC 183	7c	TO-92	BC 546	7a
PBC 184	Tho	Si-N	-BC 184	7c	TO-92	BC 550	7a
PBD 3535		LIN-IC	-KA 2413	16-DIP			KA 2413
PBF 259(S)	Mot	Si-N	Vid, 300V, 0,5A, 0,625W, >40MHz	7e	TO-92	BF 420 A	7c
PBF 259 R,RS		Si-N	=PBF 259(S):	7a	TO-92	BF 420 A	7c
PBF 493(S)	Mot	Si-P	Vid, 300V, 0,5A, 0,625W, >50MHz	7e	TO-92	BF 421 A	7c
PBF 493 R,RS		Si-P	=PBF 493(S):	7a	TO-92	BF 421 A	7c
PBL 3717 A	Sgs	LIN-IC	Schrittmotor-/Stepper Motor Driver, 46V, 1A	16-DIP			-
PBYR 280 CT	Phi	Si-Di	Schottky Rr, 80/80V, 1A(Ta=85°), Uf<0,79V(1A)	-39°e	SOT-223		-
PBYR 290	Phi	Si-Di	=PBYR 280CT: 90/90V	-39°e	SOT-223		-
PBYR 2100	Phi	Si-Di	=PBYR 280CT: 100/100V	-39°e	SOT-223		-
PC... (NEC)	Nec	-IC	-μPC...			+μPC...	
PC		MOS-P-FET-e	=2SJ199 (SMD-Marking)	39	SOT-89		+2SJ199
PC		PIN-Di	=BA 886 (SMD-Marking)	35	SOT-23		+BA 886
PC		Si-P	=KRA103S (SMD-Marking)	35	SOT-23		+KRA 103S
PC		Si-Di	=MA 737 (SMD-Marking)	71(5mm)			+MA 737
PC 40 N500	Gie	MOS-N-FET-e	VFET, 150V, 6A, 40W, on=0,5Ω(2,5A)	17p	TO-220		IRF 620, 2SK357
PC 40 N800		MOS-N-FET-e	=PC 40N500: 5A, 40W, on=0,8Ω(2,5A)	17p	TO-220		IRF 620, 2SK357
PC 75 N250	Gie	MOS-N-FET-e	VFET, 150V, 10A, 75W, on=0,25Ω(5A)	23a	TO-3		IRF 233, MTM8N18, 2SK400...401, 2SK412
PC 75 N400		MOS-N-FET-e	=PC 75N250: 7A, 75W, on=0,4Ω(5A)	23a	TO-3		IRF 231, MTM8N18, 2SK400...401, 2SK412
PC 125 N130	Gie	MOS-N-FET-e	VFET, 150V, 30A, 125W, on=0,13Ω(10A)	16p	TO-247		BUZ 341, 2SK851, 2SK902, 2SK1675
PC 125 N180		MOS-N-FET-e	=PC 125N130: 25A, 125W, on=0,18Ω(10A)	16p	TO-247		BUZ 341, 2SK851, 2SK902, 2SK1675
PCA 80 C....	Phi	CMOS-μC-IC	=PCB 80C...: -40...+125°				-
PCA 83 C....	Phi	CMOS-μC-IC	=PCB 83C...: -40...+125°				-
PCA 84 C122A	Phi	μC-IC	8-Bit μC, f. FB-Sender	24-DIP			-
PCA 84 C122B	Phi	μC-IC	8-Bit μC, f. FB-Sender	20-DIP			-
PCA 1201 T	Phi	CMOS-IC	=PCA 1201U: Fig. >	8-FLP			-
PCA 1201 U	Phi	CMOS-IC	Uhr/watch, 32kHz, f. bipolar Motor	Chip			-
PCA 1203 T	Phi	CMOS-IC	=PCA 1203U: Fig. >	8-FLP			-
PCA 1203 U	Phi	CMOS-IC	Uhr/watch, 32kHz, f. bipolar Motor	Chip			-
PCA 1204 T	Phi	CMOS-IC	=PCA 1204U: Fig. >	8-FLP			-
PCA 1204 U	Phi	CMOS-IC	Uhr/watch, 32kHz, f. bipolar Motor	Chip			-
PCA 1205 T	Phi	CMOS-IC	=PCA 1205U: Fig. >	8-FLP			-
PCA 1205 U	Phi	CMOS-IC	Uhr/watch, 32kHz, f. bipolar Motor	Chip			-
PCA 1207 T	Phi	CMOS-IC	=PCA 1207U: Fig. >	8-FLP			-
PCA 1207 U	Phi	CMOS-IC	Uhr/watch, 32kHz, f. bipolar Motor	Chip			-
PCA 1209 T	Phi	CMOS-IC	=PCA 1209U: Fig. >	8-FLP			-
PCA 1209 U	Phi	CMOS-IC	Uhr/watch, 32kHz, f. bipolar Motor	Chip			-
PCA 1212 T	Phi	CMOS-IC	=PCA 1212U: Fig. >	8-FLP			-
PCA 1212 U	Phi	CMOS-IC	Uhr/watch, 32kHz, f. bipolar Motor	Chip			-
PCA 1243 T	Phi	CMOS-IC	=PCA 1243U: Fig. >	8-FLP			-
PCA 1243 U	Phi	CMOS-IC	Uhr/watch, 32kHz, f. bipolar Motor	Chip			-
PCA 1246 T	Phi	CMOS-IC	=PCA 1246U: Fig. >	8-FLP			-
PCA 1246 U	Phi	CMOS-IC	Uhr/watch, 32kHz, f. bipolar Motor	Chip			-
PCA 1247 T	Phi	CMOS-IC	=PCA 1247U: Fig. >	8-FLP			-
PCA 1247 U	Phi	CMOS-IC	Uhr/watch, 32kHz, f. bipolar Motor	Chip			-
PCA 1248 T	Phi	CMOS-IC	=PCA 1248U: Fig. >	8-FLP			-
PCA 1248 U	Phi	CMOS-IC	Uhr/watch, 32kHz, f. bipolar Motor	Chip			-
PCA 1249 T	Phi	CMOS-IC	=PCA 1249U: Fig. >	8-FLP			-
PCA 1249 U	Phi	CMOS-IC	Uhr/watch, 32kHz, f. bipolar Motor	Chip			-
PCA 1260 T	Phi	CMOS-IC	=PCA 1260U: Fig. >	8-FLP			-
PCA 1260 U	Phi	CMOS-IC	Uhr/watch, 32kHz, f. bipolar Motor	Chip			-
PCA 1261 T	Phi	CMOS-IC	=PCA 1261U: Fig. >	8-FLP			-
PCA 1261 U	Phi	CMOS-IC	Uhr/watch, 32kHz, f. bipolar Motor	Chip			-
PCA 1401 T	Phi	CMOS-IC	=PCA 1401U: Fig. >	8-FLP			-
PCA 1401 U	Phi	CMOS-IC	Uhr/watch, 32kHz, EEPROM, f.bip.Motor	Chip			-
PCA 1403 T	Phi	CMOS-IC	=PCA 1403U: Fig. >	8-FLP			-
PCA 1403 U	Phi	CMOS-IC	Uhr/watch, 32kHz, EEPROM, f.bip.Motor	Chip			-
PCA 1404 T	Phi	CMOS-IC	=PCA 1404U: Fig. >	8-FLP			-
PCA 1404 U	Phi	CMOS-IC	Uhr/watch, 32kHz, EEPROM, f.bip.Motor	Chip			-
PCA 1408 T	Phi	CMOS-IC	=PCA 1408U: Fig. >	8-FLP			-
PCA 1408 U	Phi	CMOS-IC	Uhr/watch, 32kHz, EEPROM, f.bip.Motor	Chip			-
PCA 1409 T	Phi	CMOS-IC	=PCA 1409U: Fig. >	8-FLP			-
PCA 1409 U	Phi	CMOS-IC	Uhr/watch, 32kHz, EEPROM, f.bip.Motor	Chip			-
PCA 1411 T	Phi	CMOS-IC	=PCA 1411U: Fig. >	8-FLP			-

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
PCA 1411 U	Phi	CMOS-IC	Uhr/watch, 32kHz, EEPROM, f.bip.Motor	Chip			
PCA 1412 T	Phi	CMOS-IC	=PCA 1412U: Fig. -	8-FLP			
PCA 1412 U	Phi	CMOS-IC	Uhr/watch, 32kHz, EEPROM, f.bip.Motor	Chip			
PCA 1426 T	Phi	CMOS-IC	=PCA 1426U: Fig. -	8-FLP			
PCA 1426 U	Phi	CMOS-IC	Uhr/watch, 32kHz, EEPROM, f.bip.Motor	Chip			
PCA 1446 T	Phi	CMOS-IC	=PCA 1446U: Fig. -	8-FLP			
PCA 1446 U	Phi	CMOS-IC	Uhr/watch, 32kHz, EEPROM, f.bip.Motor	Chip			
PCA 1449 T	Phi	CMOS-IC	=PCA 1449U: Fig. -	8-FLP			
PCA 1449 U	Phi	CMOS-IC	Uhr/watch, 32kHz, EEPROM, f.bip.Motor	Chip			
PCA 1460 T	Phi	CMOS-IC	=PCA 1460U: Fig. -	8-FLP			
PCA 1460 U	Phi	CMOS-IC	Uhr/watch, 32kHz, EEPROM, f.bip.Motor	Chip			
PCA 1461 T	Phi	CMOS-IC	=PCA 1461U: Fig. -	8-FLP			
PCA 1461 U	Phi	CMOS-IC	Uhr/watch, 32kHz, EEPROM, f.bip.Motor	Chip			
PCA 1462 T	Phi	CMOS-IC	=PCA 1462U: Fig. -	8-FLP			
PCA 1462 U	Phi	CMOS-IC	Uhr/watch, 32kHz, EEPROM, f.bip.Motor	Chip			
PCA 1463 T	Phi	CMOS-IC	=PCA 1463U: Fig. -	8-FLP			
PCA 1463 U	Phi	CMOS-IC	Uhr/watch, 32kHz, EEPROM, f.bip.Motor	Chip			
PCA 1512 P	Phi	CMOS-IC	Wecker/d.c. alarm clock, 4,19MHz	8-DIP			
PCA 1517 P	Phi	CMOS-IC	Wecker/d.c. alarm clock, 4,19MHz	8-DIP			
PCA 1584 P	Phi	CMOS-IC	Wecker/alarm clock, 32kHz, EEPROM	8-DIP			
PCA 1584 T	Phi	CMOS-IC	=PCA 1584P: SMD	8-MDIP			
PCA 1585 P	Phi	CMOS-IC	Wecker/alarm clock, 32kHz, EEPROM	8-DIP			
PCA 1585 T	Phi	CMOS-IC	=PCA 1585P: SMD	8-MDIP			
PCA 1586 P	Phi	CMOS-IC	Wecker/alarm clock, 32kHz, EEPROM	8-DIP			
PCA 1586 T	Phi	CMOS-IC	=PCA 1586P: SMD	8-MDIP			
PCA 1587 P	Phi	CMOS-IC	Wecker/alarm clock, 32kHz, EEPROM	8-DIP			
PCA 1587 T	Phi	CMOS-IC	=PCA 1587P: SMD	8-MDIP			
PCA 8582 BP	Phi	EEPROM-IC	CMOS, 256x8Bit, I <sup>2</sup> C-Bus				
PCA 8582 BT	Phi	EEPROM-IC	=PCA 8582BT: SMD				
PCB 80 C31...P	Phi	CMOS-μC-IC	=PCB 80C51P: 0kB ROM	40-DIP			
PCB 80 C31...WP	Phi	CMOS-μC-IC	=PCB 80C31P: SMD	44-PLCC			
PCB 80 C39P	Phi	CMOS-μC-IC	=PCB 80C49P: 0kB ROM	40-DIP			
PCB 80 C39WP	Phi	CMOS-μC-IC	=PCB 80C39P: SMD	44-PLCC			
PCB 80 C48	Phi	CMOS-μC-IC	8 Bit, 64x8Bit RAM, 1024x8Bit ROM	40-DIP			
PCB 80 C49P	Phi	CMOS-μC-IC	8 Bit, 128x8Bit RAM, 2048x8Bit ROM	40-DIP			
PCB 80 C49WP	Phi	CMOS-μC-IC	=PCB 80C49P: SMD	44-PLCC			
PCB 80 C51...P	Phi	CMOS-μC-IC	8 Bit, 128x8Bit RAM, 4096x8Bit ROM	40-DIP			
PCB 80 C51...WP	Phi	CMOS-μC-IC	=PCB 80C51P: SMD	44-PLCC			
PCB 80 C552	Phi	CMOS-μC-IC	=PCB 83C552: 0kB ROM	68-PLCC			
PCB 80 C652P	Phi	CMOS-μC-IC	=PCF 83C652P: 0kB ROM	40-DIP			
PCB 80 C652WP	Phi	CMOS-μC-IC	=PCF 80C652P: SMD	44-PLCC			
PCB 83 C552WP	Phi	CMOS-μC-IC	8 Bit, 256x8Bit RAM, 8x8Bit ROM, I <sup>2</sup> C	68-PLCC			
PCB 83 C562WP	Phi	CMOS-μC-IC	8 Bit, 256x8Bit RAM, 8x8Bit ROM, I <sup>2</sup> C	68-PLCC			
PCB 83 C652P	Phi	CMOS-μC-IC	8 Bit, 256x8Bit RAM, 8x8Bit ROM, I <sup>2</sup> C	40-DIP			
PCB 83 C652WP	Phi	CMOS-μC-IC	=PCF 83C652P: SMD	44-PLCC			
PCB 83 C654P	Phi	CMOS-μC-IC	8 Bit, 256x8Bit RAM, 16x8Bit ROM, I <sup>2</sup> C	40-DIP			
PCB 83 C654WP	Phi	CMOS-μC-IC	=PCB 83 C654P: SMD	44-PLCC			
PCB 83 C851P	Phi	CMOS-μC-IC	8 Bit, 128x8Bit RAM, 4x8Bit ROM, I <sup>2</sup> C	40-DIP			
PCB 83 C851WP	Phi	CMOS-μC-IC	=PCB 83 C851P: SMD	44-PLCC			
PCB 1400	Phi	EAROM-IC	100x14/16 Bit	14-DIP			ER 1400
PCB 8573	Phi	LIN-IC	Uhr+Kalender/Clock+Calendar f. μComp., I <sup>2</sup> C	16-DIP			
PCB 8582	Phi	EEPROM-IC	CMOS, 256x8 Bit, ser. I <sup>2</sup> C-Bus	8-DIP			
PCD 3310 P	Phi	CMOS-IC	Telefon, Impulswahl/Pulse Dial	20-DIP			
PCD 3310 T	Phi	CMOS-IC	=PCD 3310P: SMD	28-MDIP			
PCD 3311(A)T	Phi	CMOS-IC	=PCD 3311P: SMD	16-MDIP			
PCD 3311 P	Phi	CMOS-IC	Telefon, Zweitwahl/DTMF Dialing, I <sup>2</sup> C	14-DIP			
PCD 3312 P	Phi	CMOS-IC	Telefon, Zweitwahl/DTMF Dialing, I <sup>2</sup> C	8-DIP			
PCD 3312 T	Phi	CMOS-IC	=PCD 3312P: SMD	8-MDIP			
PCD 3315 CP	Phi	CMOS-IC	Telefon, Micro Controller	28-DIP			
PCD 3315 CT	Phi	CMOS-IC	=PCD 3315CP: SMD	28-MDIP			
PCD 3315/502,503P	Phi	CMOS-IC	Telefon, Pulse+Zweitwahl/PD+DTMF Dialing	28-DIP			
PCD 3315/502,503T	Phi	CMOS-IC	=PCD 3315P: SMD	28-MDIP			
PCD 3320 D,P	Phi	CMOS-IC	Telefon, Stromschleife-Wahl/Current Loop Dialing	18-DIC/DIP			
PCD 3321 D,P	Phi	CMOS-IC	Telefon, Stromschleife-Wahl/Current Loop Dialing	18-DIC/DIP			
PCD 3322 D,P	Phi	CMOS-IC	Telefon, Stromschleife-Wahl/Current Loop Dialing	18-DIC/DIP			
PCD 3323 D,P	Phi	CMOS-IC	Telefon, Stromschleife-Wahl/Current Loop Dialing	28-DIC/DIP			
PCD 3323 T	Phi	CMOS-IC	=PCD 3323D,P: SMD	28-MDIP			
PCD 3324 D,P	Phi	CMOS-IC	Telefon, Stromschleife-Wahl/Current Loop Dialing	18-DIC/DIP			
PCD 3325 A,AP	Phi	CMOS-IC	Telefon, Stromschleife-Wahl/Current Loop Dialing	18-DIP			
PCD 3326 P	Phi	CMOS-IC	Telefon, Stromschleife-Wahl/Current Loop Dialing	18-DIP			
PCD 3327 P	Phi	CMOS-IC	=PCD 3325A, Ceramic Resonator	18-DIP			
PCD 3327 U	Phi	CMOS-IC	=PCD 3325A, Ceramic Resonator	Chip			
PCD 3341 P	Phi	CMOS-IC	Telefon, Speicher+Wahl/Repertory Dialing	28-DIP			
PCD 3341 T	Phi	CMOS-IC	=PCD 3341P: SMD	28-MDIP			
PCD 3343 D,P	Phi	CMOS-IC	Telefon, Microcontroller	28-DIC/DIP			
PCD 3343 T	Phi	CMOS-IC	=PCD 3343D,P: SMD	28-MDIP			
PCD 3360 P	Phi	CMOS-IC	Telefon, Multitonwecker/Multi Tone Ringer	16-DIP			
PCD 3360 T	Phi	CMOS-IC	=PCD 3360P: SMD	16-MDIP			
PCD 3361 P	Phi	CMOS-IC	Telefon, Multitonwecker/Multi Tone Ringer	8-DIP			
PCD 3361 T	Phi	CMOS-IC	=PCD 3361P: SMD	8-MDIP			
PCD 8571 D	Phi	sRAM-IC	=PCD 8571(P): Keramik	8-DIC			PCF 8571...
PCD 8571(P)	Phi	sRAM-IC	128x8 Bit, I <sup>2</sup> C-Bus	8-DIP			PCF 8571...
PCD 8571 T	Phi	sRAM-IC	=PCD 8571(P): SMD	8-MDIP			PCF 8571...
PCD 8582 DP	Phi	EEPROM-IC	CMOS, 256x8Bit, I <sup>2</sup> C-Bus	8-DIP			PCF 8582...
PCD 8584(P)	Phi	CMOS-IC	I <sup>2</sup> C-Bus Controller	20-DIP			
PCD 8584 T	Phi	CMOS-IC	=PCD 8584(P): SMD	20-MDIP			
PCE 2100 P	Phi	CMOS-IC	LCD Drv, 40 Segments, Duplex	28-DIP			
PCE 2100 T	Phi	CMOS-IC	=PCE 2100P: SMD	28-MDIP			
PCE 2110 P	Phi	CMOS-IC	LCD Drv, 60 Segments, Duplex	40-DIP			
PCE 2110 T	Phi	CMOS-IC	=PCE 2110P: SMD	40-MDIP			
PCE 2111 P	Phi	CMOS-IC	LCD Drv, 64 Segments, Duplex	40-DIP			
PCE 2111 T	Phi	CMOS-IC	=PCF 2111P: SMD	40-MDIP			
PCE 2112 P	Phi	CMOS-IC	LCD Drv, 32 Segments	40-DIP			

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
PCE 2112 T	Phi	CMOS-IC	=PCE 2112P: SMD				40-MDIP
PCF 29 F64(P)	Phi	EEPROM-IC	CMOS, 8k x 8 Bit, Page Erase Option				28-DIP
PCF 29 F64T	Phi	EEPROM-IC	=PCF 29F64(P): SMD				28-MDIP
PCF 80 C....	Phi	CMOS-µC-IC	=PCB 80C....: -40...+85°				-
PCF 83 C....	Phi	CMOS-µC-IC	=PCB 83C....: -40...+85°				-
PCF 84 C00B	Phi	CMOS-µC-IC	8 Bit, 256x8Bit RAM, 0kx8Bit ROM, I²C				28+28-DIP
PCF 84 C00T	Phi	CMOS-µC-IC	=PCB 84C00B: SMD				56-MDIP
PCF 84 C00WP	Phi	CMOS-µC-IC	=PCF 84C00B: Fig. →				68-PLCC
PCF 84 C12P	Phi	CMOS-µC-IC	8 Bit, 64x8Bit RAM, 1kx8Bit ROM				20-DIP
PCF 84 C12T	Phi	CMOS-µC-IC	=PCF 84C12P: SMD				20-MDIP
PCF 84 C20D,P	Phi	CMOS-µC-IC	8 Bit, 64x8Bit RAM, 2kx8Bit ROM, I²C				28-DIC/DIP
PCF 84 C20T	Phi	CMOS-µC-IC	=PCF 84C20D,P: SMD				28-MDIP
PCF 84 C21P	Phi	CMOS-µC-IC	8 Bit, 64x8Bit RAM, 2kx8Bit ROM, I²C				28-DIP
PCF 84 C21T	Phi	CMOS-µC-IC	=PCB 84C21P: SMD				28-MDIP
PCF 84 C22P	Phi	CMOS-µC-IC	8 Bit, 64x8Bit RAM, 2kx8Bit ROM				20-DIP
PCF 84 C22T	Phi	CMOS-µC-IC	=PCF 84C22P: SMD				20-MDIP
PCF 84 C40D,P	Phi	CMOS-µC-IC	8 Bit, 128x8Bit RAM, 4kx8Bit ROM, I²C				28-DIC/DIP
PCF 84 C40T	Phi	CMOS-µC-IC	=PCF 84C40D,P: SMD				28-MDIP
PCF 84 C41P	Phi	CMOS-µC-IC	8 Bit, 128x8Bit RAM, 4kx8Bit ROM, I²C				28-DIP
PCF 84 C41T	Phi	CMOS-µC-IC	=PCB 84C41P: SMD				28-MDIP
PCF 84 C42P	Phi	CMOS-µC-IC	8 Bit, 64x8Bit RAM, 4kx8Bit ROM				20-DIP
PCF 84 C42T	Phi	CMOS-µC-IC	=PCF 84C42P: SMD				20-MDIP
PCF 84 C81P	Phi	CMOS-µC-IC	8 Bit, 256x8Bit RAM, 8kx8Bit ROM, I²C				28-DIP
PCF 84 C81T	Phi	CMOS-µC-IC	=PCB 84C81P: SMD				28-MDIP
PCF 84 C85P	Phi	CMOS-µC-IC	8 Bit, 256x8Bit RAM, 8kx8Bit ROM, I²C				40-DIP
PCF 84 C85T	Phi	CMOS-µC-IC	=PCF 84C85P: SMD				40-MDIP
PCF 84 C121P	Phi	CMOS-µC-IC	8 Bit, 64x8Bit RAM, 1kx8Bit ROM				20-DIP
PCF 84 C121T	Phi	CMOS-µC-IC	=PCF 84C121P: SMD				20-MDIP
PCF 84 C230P	Phi	CMOS-µC-IC	8 Bit, 64x8Bit RAM, 2kx8Bit ROM				40-DIP
PCF 84 C230T	Phi	CMOS-µC-IC	=PCF 84C230P: SMD				40-MDIP
PCF 84 C430H	Phi	CMOS-µC-IC	8 Bit, 128x8Bit RAM, 4kx8Bit ROM, I²C				64-FLP
PCF 1171(A,B)T	Phi	CMOS-IC	=PCF 1171U: SMD				40-MDIP
PCF 1171 U	Phi	CMOS-IC	LCD-Autouhr/Car Clock, 4 Digits				Chip
PCF 1172(A,B)T	Phi	CMOS-IC	=PCF 1172U: SMD				40-MDIP
PCF 1172 U	Phi	CMOS-IC	LCD-Autouhr/Car Clock, 3,5 Digits				Chip
PCF 1174 BT	Phi	CMOS-IC	=PCF 1174U: Fig. →				40-MDIP
PCF 1174 U	Phi	CMOS-IC	LCD-Autouhr/Car Clock, 4 Digits				Chip
PCF 1175 BT	Phi	CMOS-IC	=PCF 1175U: Fig. →				28-MDIP
PCF 1175 U	Phi	CMOS-IC	LCD-Autouhr/Car Clock, 4 Digits				Chip
PCF 1251 P	Phi	CMOS-IC	Spannungsdetektor/Voltage Detector, 1,15V				8-DIP
PCF 1251 T	Phi	CMOS-IC	=PCF 1251P: SMD				8-MDIP
PCF 1252-0...9 P	Phi	CMOS-IC	Power Failure Detector, Reset, f. µC				8-DIP
PCF 1252-...T	Phi	CMOS-IC	=PCF 1252P: SMD				8-MDIP
PCF 1303 T,TD	Phi	CMOS-IC	18-Element LCD Drv, lin, -40...+85°				28-MDIP
PCF 2100 P	Phi	CMOS-IC	LCD Drv, 40 Segments, Duplex				28-DIP
PCF 2100 T	Phi	CMOS-IC	=PCF 2100P: SMD				28-MDIP
PCF 2110 P	Phi	CMOS-IC	LCD Drv, 60 Segments, Duplex				40-DIP
PCF 2110 T	Phi	CMOS-IC	=PCF 2110P: SMD				40-MDIP
PCF 2111 P	Phi	CMOS-IC	LCD Drv, 64 Segments, Duplex				40-DIP
PCF 2111 T	Phi	CMOS-IC	=PCF 2111P: SMD				40-MDIP
PCF 2112 P	Phi	CMOS-IC	LCD Drv, 32 Segments, stat.				40-DIP
PCF 2112 T	Phi	CMOS-IC	=PCF 2112P: SMD				40-MDIP
PCF 2201 V	Phi	CMOS-IC	LCD Matrix/Flat Panel Row/Column Drv				-
PCF 5020 WP/A	Phi	CMOS-µC-IC	hi-speed, Digital Audio Signal-Processor				52-PLCC
PCF 8200	Phi	CMOS-IC	Sprachgenerator/Voice Synthesizer, I²C				24-DIP
PCF 8500...8540	Phi	µC-IC	=MAB 8400...8440: CMOS Technology				-
PCF 8566 P,PN	Phi	CMOS-IC	LCD-Controller, -40...+85°, I²C-Bus				40-DIP
PCF 8566 T,TD	Phi	CMOS-IC	=PCF 8566PN: SMD				40-MDIP
PCF 8567 CP	Phi	CMOS-IC	LCD Drv, 32 Segments, I²C-Bus				40-DIP
PCF 8567 CT	Phi	CMOS-IC	=PCF 8567CP: SMD				40-MDIP
PCF 8568(P)	Phi	MOS-IC	LCD Row Driver f. Dot Matrix Displays				28-DIP
PCF 8568 T	Phi	MOS-IC	=PCF 8568(P): SMD				28-MDIP
PCF 8568 U/7	Phi	MOS-IC	=PCF 8568(P): Chip				-
PCF 8569 T	Phi	CMOS-IC	LCD Drv, 40 Column, 640 Bit RAM, I²C-Bus				56-MP
PCF 8569 V	Phi	CMOS-IC	=PCF 8569T:				64-Tape
PCF 8570(C)P	Phi	CMOS-sRAM-IC	256x8 Bit, I²C-Bus				8-DIP
PCF 8570(C)T	Phi	CMOS-sRAM-IC	=PCF 8570P: SMD				8-MDIP
PCF 8571 P	Phi	CMOS-sRAM-IC	128x8Bit, I²C-Bus				8-DIP
PCF 8571 T	Phi	CMOS-sRAM-IC	=PCF 8571P: SMD				8-MDIP
PCF 8573 P	Phi	CMOS-IC	Uhr & Kalender/Clock & Calendar, I²C				16-DIP
PCF 8573 T	Phi	CMOS-IC	=PCF 8573P: SMD				16-MDIP
PCF 8574(A)P	Phi	CMOS-IC	Ser./par. Converter, bidirectional, I²C				16-DIP
PCF 8574(A)T	Phi	CMOS-IC	=PCF 8574(P): SMD				16-MDIP
PCF 8576 T,TD	Phi	CMOS-IC	LCD-Controller, -40...+85°, I²C-Bus				56-MDIP
PCF 8576 U/(10)	Phi	CMOS-IC	=PCF 8576T,TD: Fig. →				Chip
PCF 8577(A)P,PN	Phi	CMOS-IC	LCD Drv, 32/64 Segments, -40...+85°, I²C				40-DIP
PCF 8577(A)T,TD	Phi	CMOS-IC	=PCF 8577(A)P,PN: SMD				40-MDIP
PCF 8578 T	Phi	CMOS-IC	LCD Drv, f. Dot Matrix Display, I²C-Bus				56-FLP
PCF 8578 U	Phi	CMOS-IC	=PCF 8578T: Fig. →				chip
PCF 8578 V	Phi	CMOS-IC	=PCF 8578T: Tape-automatic Bonding Module				64-lead
PCF 8579 T	Phi	CMOS-IC	LCD Drv, f. Dot Matrix Display, I²C-Bus				56-FLP
PCF 8579 U	Phi	CMOS-IC	=PCF 8579T: Fig. →				chip
PCF 8579 V	Phi	CMOS-IC	=PCF 8579T: Tape-automatic Bonding Module				64-lead
PCF 8581(P)	Phi	EEPROM-IC	CMOS, 128x8Bit, I²C-Bus, 4,5...5,5V				8-DIP
PCF 8581 C	Phi	EEPROM-IC	=PCF 8581(P): 2,5...6V				8-DIP
PCF 8581 T,CT	Phi	EEPROM-IC	=PCF 8581(P): SMD				8-MDIP
PCF 8582(A)P	Phi	EEPROM-IC	CMOS, 256x8Bit, I²C-Bus				8-DIP
PCF 8582(A)T	Phi	EEPROM-IC	=PCF 8582P: SMD				16-MDIP
PCF 8583 P	Phi	CMOS-sRAM-IC	256x8Bit, Clock, Calendar, I²C				8-DIP
PCF 8583 T	Phi	CMOS-sRAM-IC	=PCF 8583P: SMD				8-MDIP
PCF 8591 P,PN	Phi	CMOS-A/D-IC	A/D-D/A, 8 Bit, -40...+85°, I²C-Bus				16-DIP
PCF 8591 T,TD	Phi	CMOS-A/D-IC	=PCF 8591PN: SMD				16-MDIP
PD....(NEC)	Nec	....-IC	µPD....				µPD....

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
PD		Si-P	=2SA1171-D (SMD-Marking)	35	SOT-23		*2SA1171
PD		MOS-P-FET-e	=2SJ205 (SMD-Marking)	39	SOT-89		*2SJ205
PD		Si-P	=KRA104S (SMD-Marking)	35	SOT-23		*KRA 104S
PD		Si-Di	=MA 738 (SMD-Marking)	71(5mm)			*MA 738
PDSP 1601	Pls	CMOS-IC	Digital Signal Proc., Augmented ALU, 10MHz	84-LCC			-
PDSP 1610	Pls	CMOS-IC	Digital Signal Proc., Multi-prec. Multiply Accu				-
PDSP 1630	Pls	CMOS-IC	Digital Signal Proc., Pre-progr. Sequencer, 10MHz				-
PDSP 1640	Pls	CMOS-IC	Digital Signal Proc., Mask. Modulo Counter, 40MHz	28-DIC			-
PDSP 16112	Pls	CMOS-IC	Digital Signal Proc., Complex Number Multiplier	120-LCC			-
PDSP 16401	Pls	CMOS-IC	Digital Signal Proc., 2-Dimensional Edge Detector	68-LCC			-
PE		Si-P	=2SA1171-E (SMD-Marking)	35	SOT-23		*2SA1171
PE		MOS-P-FET-e	=2SJ207 (SMD-Marking)	39	SOT-89		*2SJ207
PE		Si-P	=KRA105S (SMD-Marking)	35	SOT-23		*KRA 105S
PE		Si-Di	=MA 739 (SMD-Marking)	71(5mm)			*MA 739
PE 2 D.G		Si-Di	=EGP 20...			-EGP 20...	*EGP 20...
PE 3100	Fch,Nsc	Si-N	VHF, 30V, >500MHz	7	TO-92	BF 959	BF 314, BF 502, BF 505, BF 507, BF 959++
PE 4001	Fch	Si-N	=SE 4001	7	TO-92	-SE 4001	*SE 4001
PE 4002	Fch	Si-N	=SE 4002	7	TO-92	-SE 4002	*SE 4002
PE 4010	Nsc	Si-N	=SE 4010	7e	TO-92	-SE 4010	*SE 4010
PE 5010	Fch	Si-N	AM/FM, 30V, >375MHz			BF 198, BF 255	BF 198...199, BF 240...241, BF 254...255
PE 5013	Fch	Si-N	AM/FM, 20V, >300MHz			BF 198, BF 255	BF 198...199, BF 240...241, BF 254...255
PE 5015	Fch	Si-N	AM/FM, 20V, >300MHz			BF 198, BF 255	BF 198...199, BF 240...241, BF 254...255
PE 5251	Pecor	Si-N-Darl	S P, 400/400V, 100W, hFE>140(3A,5V), sat<1.2V(5A)	23a	TO-3		BU 322(A), BUW 81(A), 2SD520... 521, ++
PE 5252		Si-N-Darl	=PE 5251: 450/450V	23a	TO-3		BU 322(A), BUW 81(A), 2SD520... 521, ++
PE 5253		Si-N-Darl	=PE 5251: 500/500V	23a	TO-3		BU 322A, BUW 81(A), 2SD520...521, ++
PE 6020	Fch	Si-N	=SE 6020	7	TO-92	-SE 6020	*SE 6020
PE 6021	Fch	Si-N	=SE 6021	7	TO-92	-SE 6021	*SE 6021
PE 6022	Fch	Si-N	=SE 6022	7	TO-92	-SE 6022	*SE 6022
PE 7058		Si-N	Vid, 220/220V, 2A(ss), 90MHz	7e	TO-92		-
PE 7059		Si-N	=PE 7058: 300/300V	7e	TO-92		-
PE 8050	Fch,Nsc	Si-N	LF Drv.Out, 30V, 1.5A, >100MHz	7e	TO-92	2SD1207	MPS 650...51, 2SD1051, 2SD1207, 2SD1331++
PE 8051	Fch,Nsc	Si-N	=PE 8050: 45V	7e	TO-92	2SD1207	MPS 650...51, 2SD1051, 2SD1207, 2SD1331++
PE 8052	Fch	Si-N	=PE 8050: 20V	7e	TO-92	2SD1207	MPS 650...51, 2SD1051, 2SD1207, 2SD1331++
PE 8550	Fch,Nsc	Si-P	LF Drv.Out, 30V, 1.5A, >100MHz	7e	TO-92	2SB892	MPS 750...51, 2SB819, 2SB892, 2SB987,++
PE 8551	Fch,Nsc	Si-P	=PE 8550: 45V	7e	TO-92	2SB892	MPS 750...51, 2SB819, 2SB892, 2SB987,++
PE 8552	Fch	Si-P	=PE 8550: 20V	7e	TO-92	2SB892	MPS 750...51, 2SB819, 2SB892, 2SB987,++
PEB 2025-P	Sie	CMOS-IC	Telecom, ISDN, Exchange Power Controller (IEPC)	22-DIP			-
PEB 2030	Sie	MOS-IC	Telecom, Frame Aligner (FRAC) f. PCM	24-DIC			SM 300B
PEB 2035-C,-P	Sie	CMOS-IC	Telecom, Advanced Frame Aligner (ACFA)	40-DIC,DIP			-
PEB 2035-N		CMOS-IC	=PEB 2035-C,-P: SMD	44-PLCC			-
PEB 2040	Sie	MOS-IC	Telecom, Memory Time Switch(MTS) f. PCM	40-DIC			SM 233
PEB 2045-C,-P	Sie	CMOS-IC	Telecom, Memory Time Switch(MTSC) f. PCM, 0...+70°	40-DIC,DIP			PEF 2045-C,-P
PEB 2045-N		CMOS-IC	=PEB 2045-C,-P: SMD	44-PLCC			PEF 2045-N
PEB 2046-C,-P	Sie	CMOS-IC	Telecom, Memory Time Switch Small(MTSS), 0...+70°	40-DIC,DIP			PEF 2046-C,-P
PEB 2046-N		CMOS-IC	=PEB 2046-C,-P: SMD	44-PLCC			PEF 2046-N
PEB 2050-C,-P	Sie	MOS-IC	Telecom, Peripheral Board Control (PBC) f. PCM	40-DIC,DIP			-
PEB 2050-N		MOS-IC	=PEB 2050-C,-P: SMD	44-PLCC			-
PEB 2051	Sie	MOS-IC	Telecom, Peripheral Board Control (PBC)f.PCM	40-DIC			-
PEB 2052-C,-P	Sie	CMOS-IC	Telecom, PCM Interface Ctrl.(PIC)	40-DIC,DIP			-
PEB 2052-N		CMOS-IC	=PEB 2052-C,-P: SMD	44-PLCC			-
PEB 2055-C,-P	Sie	CMOS-IC	Telecom, ISDN, Extended PCM Interf. Ctrl. (EPIC-1)	40-DIC,DIP			-
PEB 2055-N		CMOS-IC	=PEB 2055-C,-P: SMD	44-PLCC			-
PEB 2056-C,-P	Sie	CMOS-IC	Telecom, ISDN, Extended PCM Interf. Ctrl. (EPIC-2)	28-DIC,DIP			-
PEB 2056-N		CMOS-IC	=PEB 2056-C,-P: SMD	44-PLCC			-
PEB 2060-C,-P	Sie	CMOS-IC	Telecom, Signal Processor Codec Filter(SICOFI)	22-DIC,DIP			-
PEB 2060-N		CMOS-IC	=PEB 2060-C,-P: SMD	28-PLCC			-
PEB 2070-C,-P	Sie	CMOS-IC	Telecom, ISDN, Communication Controller (ICC)	24-DIC,DIP			-
PEB 2070-N		CMOS-IC	=PEB 2070-C,-P: SMD	28-PLCC			-
PEB 2075-N		CMOS-IC	=PEB 2075-P: SMD	44-PLCC			-
PEB 2075-P	Sie	CMOS-IC	Telecom, ISDN, D-Channel Exchange Ctrl. (IDEG)	28-DIP			-
PEB 2080-C,-P	Sie	CMOS-IC	Telecom, ISDN, S-Bus Interface (SBC)	22-DIC,DIP			-
PEB 2080-N		CMOS-IC	=PEB 2080-C,-P: SMD	28-PLCC			-
PEB 2081-N		CMOS-IC	=PEB 2081-P: SMD	28-PLCC			-
PEB 2081-P	Sie	CMOS-IC	Telecom, ISDN, S/T-Bus Interface Extended (SBCX)	28-DIP			-
PEB 2085-C,-P	Sie	CMOS-IC	Telecom, ISDN, Subscriber Access Ctrl. (ISAC-S)	40-DIC,DIP			-
PEB 2085-N		CMOS-IC	=PEB 2085-P: SMD	44-PLCC			-
PEB 2091-N	Sie	CMOS-IC	Telecom, ISDN, Echo-Cancellation (IEC-O)	44-PLCC			-
PEB 2095-C,-P	Sie	CMOS-IC	Telecom, ISDN, Burst Transceiver (IBC)	24-DIC,DIP			-
PEB 2095-N		CMOS-IC	=PEB 2095-C,-P: SMD	28-PLCC			-
PEB 2235-C,-P	Sie	CMOS-IC	Telecom, ISDN, Primary Access Transceiver(IPAT)	28-DIC,DIP			-
PEB 2235-N		CMOS-IC	=PEB 2235-C,-P: SMD	28-PLCC			-
PEB 2260-N	Sie	CMOS-IC	Telecom, Dual Channel Codec Filter(SICOFI-2)	28-PLCC			-
PEB 2912	Sie	LIN-IC	Telecom, Filter f. PCM (CCITT G712)	16-DIC			SM 153B
PEB 3030	Sie	LIN-IC	Telecom, Subscriber Line Interface	24-DIC			SM 340
PEB 20901-C,-P	Sie	CMOS-IC	Telecom, ISDN, Echo-Cancellation (IEC-T)	40-DIC,DIP			-
PEB 20901-N		CMOS-IC	=PEB 20901-C,-P: SMD	44-PLCC			-
PEB 20902-C,-P	Sie	CMOS-IC	Telecom, ISDN, Echo-Cancellation (IEC-T)	24-DIC,DIP			-
PEB 20902-N		CMOS-IC	=PEB 20902-C,-P: SMD	28-PLCC			-
PEB 20950-C,-P	Sie	CMOS-IC	Telecom, ISDN, Subscriber Access Ctrl. (ISAC-P)	40-DIC,DIP			-
PEB 20950-N		CMOS-IC	=PEB 20950-C,-P: SMD	44-PLCC			-
PEF 2045-...		CMOS-IC	=PEB 2045-...: -40...+85°				-
PEF 2046-...		CMOS-IC	=PEB 2046-...: -40...+85°				-
PF 0025...5015	Hit	MOS-/GaAs	HF Leistungsmodule/Power Modules				-
PF		MOS-P-FET-e	=2SJ208 (SMD-Marking)	39	SOT-89		*2SJ208
PF		Si-P	=KRA106S (SMD-Marking)	35	SOT-23		*KRA 106S
PF 4 HZ...10HZ	Tho	Si-Di	Rr, contrav., 400...1000V, 3A	31a	DO-27		BYW 18/..., BYW 83...86, BYM 56B...E
PF 8 Z6V8...Z 180	Tho	Z-Di	TAZ, 6,8...180V, Pbr=800W(1ms)	31a	DO-27A		BZW 03/..., BZW 11/...
PCF 6V4...171	Tho	Z-Di	TAZ, 6,4...171V, Pbr=1.5kW(1ms)	31a	DO-27A		1N5629...5663
PFR 305	Tho	Si-Di	Ffr, 50V, 3A, Uf<1V(3A), <50ns	31a	DO-27A	BYV 28/200	BYV 28/50, EGP 30A, FE 3A
PFR 310		Si-Di	=PFR 305: 100V	31a		BYV 28/200	BYV 28/100, EGP 30B, FE 3B
PFR 850	Tho	Si-Di	Ffr, 50V, 3A, Uf<1.25V(3A), <150ns	31a	DO-27A	BYW 95 C	BY 318/..., BYM 36A, BYW 72, MR 850,++
PFR 851	Tho	Si-Di	=PFR 850: 100V	31a	DO-27A	BYW 95 C	BY 318/..., BYM 36A, BYW 72, MR 851,++
PFR 852	Tho	Si-Di	=PFR 850: 200V	31a	DO-27A	BYW 95 C	BY 318/..., BYM 36A, BYW 72, MR 852,++

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International	
PFR 853	Tho	Si-Di	=PFR 850: 300V	31a	DO-27A	BYW 95 C	31a	BY 318/..., BYM 36B, BYW 73, MR 854,++
PFR 854	Tho	Si-Di	=PFR 850: 400V	31a	DO-27A	BYW 95 C	31a	BY 318/..., BYM 36B, BYW 77, MR 854,++
PFR 855	Tho	Si-Di	=PFR 850: 500V	31a	DO-27A	BYW 95 C	31a	BY 318/..., BYM 36C, BYW 76, MR 856,++
PFR 856	Tho	Si-Di	=PFR 850: 600V	31a	DO-27A	BYW 95 C	31a	BY 318/..., BYM 36C, BYW 76, MR 856,++
PFZ 6V8...400(A)	Tho	Z-Di	TAZ, 6,8...400V, Pbr=1.5kW(1ms)	31a	DO-27A			1N5629...5665
PFZD 6V8...180	Tho	S-Di	=PF 8Z...: bidirectional	31a	DO-27A			BZW 11/...B
pGI		Si-N	=PMBT 5551 (SMD-Marking)	35	SOT-23			*PMBT 5551
PH		MOS-P-FET-e	=2SJ206 (SMD-Marking)	39	SOT-89			*2SJ206
PH		Si-P	=KRA107S (SMD-Marking)	35	SOT-23			*KRA 107S
PH		Si-Di	=MA 643 (SMD-Marking)	71(5mm)				*MA 643
PH 2222(A)	Phi	Si-N	=2N2222(A): 0.625W	7a	TO-92	*2N2222(A)		*2N2222(A)
PH 2369	Phi	Si-N	=2N2369: 0.5W	7a	TO-92	*2N2369		*2N2369
PH 2907(A)	Phi	Si-P	=2N2907: 0.625W	7a	TO-92	*2N2907(A)		*2N2907(A)
PH 2955(T)	Phi	Si-P	=TIP 2955	17j	TO-220	(BD 250 C) <sup>6</sup>	18j	BD 743C...F, BD 911, BDT 85, BDT 87
PH 3055(T)	Phi	Si-N	=TIP 3055	17j	TO-220	(BD 249 C) <sup>6</sup>	18j	BD 744C...F, BD 912, BDT 86, BDT 88
PH 5415	Phi	Si-P	=2N5415: 0.625W	7a	TO-92			2SA1626
PH 5416	Phi	Si-P	=2N5416: 0.625W	7a	TO-92			2SA1626
PH 6659	Phi	MOS-N-FET-e	=2N6659: 1W	7e	TO-92			-
PH 6660	Phi	MOS-N-FET-e	=2N6660: 1W	7e	TO-92			-
PH 6661	Phi	MOS-N-FET-e	=2N6661: 1W	7e	TO-92			-
PH 13002	Phi	Si-N	=MJ 4360: 28W	14j	TO-126	(BUX 85) <sup>4</sup>	17j	BUX 99, (BUV 63, BUV 93, BUX 84...85) <sup>4</sup>
PH 13003	Phi	Si-N	=MJ 4361: 28W	14j	TO-126	(BUX 85) <sup>4</sup>	17j	BUX 99, (BUV 63, BUV 93, BUX 84...85) <sup>4</sup>
PI		Si-P	=KRA108S (SMD-Marking)	35	SOT-23			*KRA 108S
PIB		N-FET	=2SK1070-B (SMD-Marking)	35	SOT-23			*2SK1070
PIC		N-FET	=2SK1070-C (SMD-Marking)	35	SOT-23			*2SK1070
PIC 600	Uni	Hybrid-Z-IC	Power Out f. S-Reg., In/Out < +60V, 5A, -55...+125°	22/4Pin	TO-66/4			-
PIC 601	Uni	Hybrid-Z-IC	=PIC 600: +80V	22/4Pin	TO-66/4			-
PIC 602	Uni	Hybrid-Z-IC	=PIC 600: +100V	22/4Pin	TO-66/4			-
PIC 610	Uni	Hybrid-Z-IC	=PIC 600: -60V	22/4Pin	TO-66/4			-
PIC 611	Uni	Hybrid-Z-IC	=PIC 600: -80V	22/4Pin	TO-66/4			-
PIC 612	Uni	Hybrid-Z-IC	=PIC 600: -100V	22/4Pin	TO-66/4			-
PIC 625	Uni	Hybrid-Z-IC	Power Out f. S-Reg., In/Out < +60V, 15A, -55...+125°	22/4Pin	TO-66/4			-
PIC 626	Uni	Hybrid-Z-IC	=PIC 625: +80V	22/4Pin	TO-66/4			-
PIC 627	Uni	Hybrid-Z-IC	=PIC 625: +100V	22/4Pin	TO-66/4			-
PIC 635	Uni	Hybrid-Z-IC	=PIC 625: -60V	22/4Pin	TO-66/4			-
PIC 636	Uni	Hybrid-Z-IC	=PIC 625: -80V	22/4Pin	TO-66/4			-
PIC 637	Uni	Hybrid-Z-IC	=PIC 625: -100V	22/4Pin	TO-66/4			-
PIC 645	Uni	Hybrid-Z-IC	Power Out f. S-Reg., In/Out < +60V, 15A, -55...+125°	23/3Pin	TO-3/3			-
PIC 646	Uni	Hybrid-Z-IC	=PIC 645: +80V	23/3Pin	TO-3/3			-
PIC 647	Uni	Hybrid-Z-IC	=PIC 645: +100V	23/3Pin	TO-3/3			-
PIC 655	Uni	Hybrid-Z-IC	=PIC 645: -60V	23/3Pin	TO-3/3			-
PIC 656	Uni	Hybrid-Z-IC	=PIC 645: -80V	23/3Pin	TO-3/3			-
PIC 657	Uni	Hybrid-Z-IC	=PIC 645: -100V	23/3Pin	TO-3/3			-
PIC 660	Uni	Hybrid-Z-IC	Power Out f. S-Reg., In/Out < +60V, 15A, -55...+125°	22/4Pin	TO-66/4			-
PIC 661	Uni	Hybrid-Z-IC	=PIC 660: +80V	22/4Pin	TO-66/4			-
PIC 662	Uni	Hybrid-Z-IC	=PIC 660: +100V	22/4Pin	TO-66/4			-
PIC 670	Uni	Hybrid-Z-IC	=PIC 660: -60V	22/4Pin	TO-66/4			-
PIC 671	Uni	Hybrid-Z-IC	=PIC 660: -80V	22/4Pin	TO-66/4			-
PIC 672	Uni	Hybrid-Z-IC	=PIC 660: -100V	22/4Pin	TO-66/4			-
PIC 1640	Itt	MOS-IC	Interface Controller f. µComp.	40-DIC				-
PIC 1650(A)	Itt,Pls	µC-IC	8-Bit µComp, 32x8Bit RAM, 512x12Bit ROM	40-DIC				-
PIC 1650-532	Pls	µC-IC	Televue Controller	40-DIP				-
PIC 1650-533	Pls	µC-IC	Viewdata Controller	40-DIP				-
PIC 1650-536	Pls	µC-IC	Televue Autodialer, Terminal Identifier	40-DIP				-
PIC 1655 A	Pls	µC-IC	8-Bit µComp, 32x8Bit RAM, 512x12Bit ROM	28-DIP				-
PIC 1655 XT	Pls	µC-IC	=PIC 1655A: Mask Progr. Prescaler f. RTCC	28-DIP				-
PIC 7501...7506	Uni	Hybrid-Z-IC	=PIC 600...612: hi-rel	22/4Pin	TO-66/4			-
PIC 7507...7512	Uni	Hybrid-Z-IC	=PIC 625...637: hi-rel	22/4Pin	TO-66/4			-
PIC 7513...7518	Uni	Hybrid-Z-IC	=PIC 645...657: hi-rel	23/3Pin	TO-3/3			-
PIC 7519...7524	Uni	Hybrid-Z-IC	=PIC 600...612: hi-rel	22/4Pin	TO-66/4			-
PIC 7525...7530	Uni	Hybrid-Z-IC	=PIC 625...637: hi-rel	22/4Pin	TO-66/4			-
PIC 7531...7536	Uni	Hybrid-Z-IC	=PIC 645...657: hi-rel	23/3Pin	TO-3/3			-
PIC 7555...7560	Uni	Hybrid-Z-IC	=PIC 660...672: hi-rel	22/4Pin	TO-66/4			-
PIC 7561...7566	Uni	Hybrid-Z-IC	=PIC 660...672: hi-rel	22/4Pin	TO-66/4			-
PID		N-FET	=2SK1070-D (SMD-Marking)	35	SOT-23			*2SK1070
PIE		N-FET	=2SK1070-E (SMD-Marking)	35	SOT-23			*2SK1070
PIP 2250	Itt	CMOS-IC	CTV, PIP-Processor	68-PLCC				-
PJ		Si-P	=KRA109S (SMD-Marking)	35	SOT-23			*KRA 109S
PK		Si-P	=2SA1173-PK (SMD-Marking)	39	SOT-89			*2SA1173
PK		Si-P	=KRA110S (SMD-Marking)	35	SOT-23			*KRA 110S
pXX		MOS-N-FET-e	=PMBF 170 (SMD-Marking)	35	SOT-23			*PMBF 170
PL		Si-P	=2SA1173-PL (SMD-Marking)	39	SOT-89			*2SA1173
PL		Si-P	=2SB1234 (SMD-Marking)	35	SOT-23			*2SB1234
PL 3V3Z...200Z	Ssc	Z-Di	=BZY 97 C3V3...C200	31a	DO-15	Z-Diode ...V	31a	*BZY 93/...
PL 4001	Gie	Si-Di	*1N4001	31a	DO-27	1N4007	31a	
PL 4002	Gie	Si-Di	*1N4002	31a	DO-27	1N4007	31a	
PL 4003	Gie	Si-Di	*1N4003	31a	DO-27	1N4007	31a	
PL 4004	Gie	Si-Di	*1N4004	31a	DO-27	1N4007	31a	
PL 4005	Gie	Si-Di	*1N4005	31a	DO-27	1N4007	31a	
PL 4006	Gie	Si-Di	*1N4006	31a	DO-27	1N4007	31a	
PL 4007	Gie	Si-Di	*1N4007	31a	DO-27	1N4007	31a	
PLE 0,7	Tho	Si-St	0,4A, Uf=0,65...0,75V(5mA), <10Ω	31a	DO-15	(1N4148)	31a	BZX 83/C0V8, BZW 22/C1, ZPY 1
PLE 1,5	Tho	Si-St	0,4A, Uf=1,35...1,55V(5mA), <20Ω	31a	DO-15	Z-Diode 1,4V	31a	-
PLE 2	Tho	Si-St	1,9...2,2V(5mA), <30Ω	31a	DO-15	Z-Diode 2,1V	31a	-
PLQ 0,8	Tho	Si-Di	FRr, 50V, 1A, Uf<1,1V(1A), <50ns	31a	DO-15	BYV 27/200	31a	BYV 26B, EGP 10A, FE 1A
PLQ 1	Tho	Si-Di	=PLQ 0,8: 100V	31a	DO-15	BYV 27/200	31a	BYV 26B, EGP 10B, FE 1B
PLR 810	Tho	Si-Di	FRr, 50V, 1A, Uf<1,1A(1A), <300ns	31a	DO-15	BYD 33 M	31a	BY 201/..., MR 810...818, RGP 10A...M, ++
PLR 811	Tho	Si-Di	=PLR 810: 100V	31a	DO-15	BYD 33 M	31a	BY 201/..., MR 811...818, RGP 10B...M, ++
PLR 812	Tho	Si-Di	=PLR 810: 200V	31a	DO-15	BYD 33 M	31a	BY 201/..., MR 812...818, RGP 10D...M, ++
PLR 813	Tho	Si-Di	=PLR 810: 300V	31a	DO-15	BYD 33 M	31a	BY 201/..., MR 813...818, RGP 10G...M, ++
PLR 814	Tho	Si-Di	=PLR 810: 400V	31a	DO-15	BYD 33 M	31a	BY 201/..., MR 814...818, RGP 10G...M, ++
PLR 815	Tho	Si-Di	=PLR 810: 500V	31a	DO-15	BYD 33 M	31a	BY 201/..., MR 815...818, RGP 10J...M, ++
PLR 816	Tho	Si-Di	=PLR 810: 600V	31a	DO-15	BYD 33 M	31a	BY 201/..., MR 816...818, RGP 10J...M, ++

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International	
PLR 817	Tho	Si-Di	=PLR 810: 800V	31a	DO-15	BYD 33 M	31a	BY 245/..., MR 817...818, RGP 10K...M, ++
PLR 818	Tho	Si-Di	=PLR 810: 1000V	31a	DO-15	BYD 33 M	31a	BY 245/..., BY 400, MR 818, RGP 10M, ++
<b>PM...PN</b>								
PM		Si-P	=2SA1173-PM (SMD-Marking)	39	SOT-89			*2SA1173
PM		Si-P	=KRA111S (SMD-Marking)	35	SOT-23			*KRA 111S
PM 10PNP	Phb	Si-P	LFS P, 30V, 3A, 10W, 150MHz	17j	TO-220			2SA473, 2SA1288, 2SB1273
PM 108...	Pmi	OP-IC	*µA 108...					*µA 108...
PM 139...	Pmi	KOP-IC	*µA 139...					*µA 139...
PM 208...	Pmi	OP-IC	*µA 208...					*µA 208...
PM 339...	Pmi	KOP-IC	*µA 339...					*µA 339...
PM 725...	Pmi	KOP-IC	*µA 725...					*µA 725...
PM 741(C)J	Pmi	OP-IC	Uni, Serie 741, ±18V, 0...70°	TO-99		741/TO	TO-99	... 741...
PM 747(C)K	Pmi	OP-IC	Dual, Serie 747, ±18V, 0...+70°	TO-100				... 747...
PM 1458...	Pmi	OP-IC	*µA 1458...					*µA 1458...
PM 1558...	Pmi	OP-IC	*µA 1558...					*µA 1558...
PM 4136...	Pmi	OP-IC	*µA 4136...					*µA 4136...
PM 4550...50502	Hit	MOS-N/P	VFET, Leistungsmodule/Power Modules					
PMBF 107	Phi	MOS-N-FET-e	=BS 107: SMD, 0,1/0,25A	35a	SOT-23			BSS 131
PMBF 170	Phi	MOS-N-FET-e	=BS 170: SMD, 0,25/0,5A	35a	SOT-23			BSS 145, BST 82
PMBF 4391...4393	Phi	N-FET	=2N4391...4393: SMD	35b	SOT-23			BSR 56...58, SO 4391...4393
PMBF 4416(A)	Phi	N-FET	=2N4416(A): SMD	35f	SOT-23			-
PMBF 5484...5486	Phi	N-FET	=2N5484...5486: SMD	35f	SOT-23			-
PMBFJ 108...110	Phi	N-FET	=J 108...110: SMD	35b	SOT-23			-
PMBFJ 111...113	Phi	N-FET	=J 111...113: SMD	35b	SOT-23			BSR 111...113
PMBFJ 170	Phi	MOS-N-FET-e	*PMBF 170	35a	SOT-23			-
PMBFJ 174...177	Phi	P-FET	=BSJ 174...177: SMD	35b	SOT-23			BSR 174...177
PMBFJ 308...310	Phi	N-FET	=J 308...310: SMD	35f	SOT-23			-
PMBS 3904	Phi	Si-N	=2N3904: SMD	35a	SOT-23	BC 846	35a	BC 846, BCV 71...72, SMBT 3904, 2SC4209++
PMBS 3906	Phi	Si-P	=2N3906: SMD	35a	SOT-23	BC 856	35a	BC 856...857, BCX 71, SMBT 3906, 2SA1620+
PMBT 2222(A)	Phi	Si-N	=2N2222(A): SMD	35a	SOT-23			BSR 14, BSS 79, BSS 81, SMBT 2222(A)
PMBT 2369	Phi	Si-N	=2N2369: SMD	35a	SOT-23			2SC4168
PMBT 2907(A)	Phi	Si-P	=2N2907(A): SMD	35a	SOT-23			BSR 15...16, BSS 80, BSS 82, SMBT 2907(A)
PMBT 3640	Phi	Si-P	=2N3640: SMD	35a	SOT-23			BSV 52
PMBT 3903...3904	Phi	Si-N	=2N3903...3904: SMD	35a	SOT-23	BC 846	35a	BC 846, BCV 71...72, SMBT 3904, 2SC4209++
PMBT 3905...3906	Phi	Si-P	=2N3905...3906: SMD	35a	SOT-23	BC 856	35a	BC 856...857, BCX 71, SMBT 3906, 2SA1620+
PMBT 4401	Phi	Si-N	=2N4401: SMD	35a	SOT-23	BC 817	35a	BCW 65...66, BSR 13, 2SC3392, 2SD1782
PMBT 4403	Phi	Si-P	=2N4403: SMD	35a	SOT-23	BC 807	35a	BCW 68, BSR 15...16, 2SA1338, 2SB1198
PMBT 5088	Phi	Si-N	=2N5088: SMD	35d	SOT-23			-
PMBT 5401	Phi	Si-P	=2N5401: SMD	35a	SOT-23			-
PMBT 5550	Phi	Si-N	=2N5550: SMD	35a	SOT-23			-
PMBT 5551	Phi	Si-N	=2N5551: SMD	35a	SOT-23			-
PMBT 6428	Phi	Si-N	=2N6428: SMD	35a	SOT-23	BC 850	35a	BC 850, SMBT 6428, 2SC3323
PMBT 6429	Phi	Si-N	=2N6429: SMD	35a	SOT-23	BC 850	35a	BC 850, SMBT 6429, 2SC3323
PMBT-A05...06	Phi	Si-N	=MPS-A05...06: SMD	35a	SOT-23			BCW 65...66, SMBTA 05...06, 2SD1782
PMBT-A12...14	Phi	Si-N-Darl	=MPS-A12...14: SMD	35a	SOT-23			BCV 27, SMBTA 13...14, 2SD1478, 2SD2026++
PMBT-A42...43	Phi	Si-N	=MPS-A42...43: SMD	35a	SOT-23			SMBTA 42...43
PMBT-A55...56	Phi	Si-P	=MPS-A55...56: SMD	35a	SOT-23			BCW 68, BCX 42, SMBTA 55...56, 2SB1195, ++
PMBT-A63...64	Phi	Si-P-Darl	=MPS-A63...64: SMD	35a	SOT-23			BCV 26, BCV 46, SMBTA 63...64
PMBT-A92...93	Phi	Si-P	=MPS-A92...93: SMD	35a	SOT-23			SMBTA 92...93
PMBTH 10	Phi	Si-N	=MPS-H 10: SMD	35a	SOT-23			BF 517, BF 547, BFS 17, 2SC3077, ++
PMBTH 81	Phi	Si-P	=MPS-H 81: SMD	35a	SOT-23			BF 569, BF 579, BF 767
PMLL 4148	Phi	Si-Di	SMD, SS, 100V, 0,2A, <4ns	72a(3,4mm)	SOD-80	1N4148 SMD	72a(3,4mm)	BAS 32, LL 4148
PMSS 3904	Phi	Si-N	=2N3904: SMD	35a(2mm)	SOT-323			2SC4116
PMSS 3906	Phi	Si-P	=2N3906: SMD	35a(2mm)	SOT-323			2SA1602, 2SA1622
PMST 3904	Phi	Si-N	=2N3904: SMD	35a(2mm)	SOT-323			2SC4116
PMST 3906	Phi	Si-P	=2N3906: SMD	35a(2mm)	SOT-323			2SA1602, 2SA1622
PMST 4401	Phi	Si-N	=2N4401: SMD	35a(2mm)	SOT-323			2SD1820A
PMST 4403	Phi	Si-P	=2N4403: SMD	35a(2mm)	SOT-323			2SB1219A
PMST 5088	Phi	Si-N	=2N5088: SMD	35a(2mm)	SOT-323			BC 850W, 2SC4116
PMST 5089	Phi	Si-N	=2N5089: SMD	35a(2mm)	SOT-323			BC 850W, 2SC4116
PN		PIN-Di	=BA 779 (SMD-Marking)	35	SOT-23			*BA 779
PN		Si-P	=KRA112S (SMD-Marking)	35	SOT-23			*KRA 112S
PN 10NPN	Phb	Si-N	LFS P, 30V, 3A, 10W, 150MHz	17j	TO-220			2SC1173, 2SC3252, 2SD1912
PN 30	Phb	Si-N	LFS P, 50V, 3A, 25W, 1MHz	17j	TO-220			BD 241(A...C), BD 539(A...D), BD 935, ++
PN 70	New	Si-P	Uni, 50V, 0,2A, 0,2W, 250MHz, hFE>50	8a	TO-106			BC 212, BC 257, BC 307, BC 557, ++
PN 71	New	Si-P	=PN 70: 45V, hFE>100	8a	TO-106			BC 212, BC 257, BC 307, BC 557, ++
PN 72	New	Si-P	=PN 70: 25V, hFE>50	8a	TO-106			BC 214, BC 259, BC 309, BC 559, ++
PN 107	New	Si-N	=BC 107: 0,2W	8a	TO-106	-BC 107		*BC 107
PN 108	New	Si-N	=BC 108: 0,2W	8a	TO-106	-BC 108		*BC 108
PN 109	New	Si-N	=BC 109: 0,2W	8a	TO-106	-BC 109		*BC 109
PN 918	Fch,Nsc,New	Si-N	=2N918: 0,625W	7e	TO-92	-2N918		*2N918
PN 929	Fch,Nsc,New	Si-N	=2N929: 0,625W	7e	TO-92	-2N929		*2N929
PN 930	Fch,Nsc,New	Si-N	=2N930: 0,625W	7e	TO-92	-2N930		*2N930
PN 1613	Fch,New	Si-N	=2N1613: 0,625W	7e	TO-92	-2N1613		*2N1613
PN 1711	Fch,New	Si-N	=2N1711: 0,625W	7e	TO-92	-2N1711		*2N1711
PN 1893	Fch	Si-N	=2N1893	7	TO-92	-2N1893		*2N1893
PN 2218...2222(A)	Fch,Nsc,++	Si-N	=2N2218...2222(A): 0,625W	7e[NSC,Ph]		-2N2218...22		*2N2218...2222(A)
PN 2218...2222(A)	Tsm	Si-N	=2N2218...2222(A): 0,625W	7a[Tungsr]	TO-92	-2N2218...22		*2N2218...2222(A)
PN 2369(A)	Nsc,Phi	Si-N	=2N2369(A): 0,625W	7e	TO-92	-2N2369(A)		*2N2369(A)
PN 2484	Fch,Nsc	Si-N	=2N2484: 0,625W	7e	TO-92	-2N2484		*2N2484
PN 2904...2907(A)	Fch,Nsc,++	Si-P	=2N2904...2907(A): 0,625W	7e	TO-92	-2N2904...07		*2N2904...2907(A)
PN 3014	Fch	Si-N	=2N3014	7	TO-92	-2N3014		*2N3014
PN 3054	New	Si-N	LFS-L, 50V, 4A, 25W, 0,8MHz	17j	TO-220	BD 243 C	17j	BD 243(A...C), BD 539(A...D), BD 535, ++
PN 3250...3251(A)	Fch,Mic	Si-P	=2N3250...3251(A): 0,625W	7e	TO-92			*2N3250...3251(A)
PN 3439...3440	Phi	Si-N	=2N3439...3440: 0,625W	7e	TO-92			*2N3439...3440
PN 3548	Mic	Si-P	=2N3548	7e	TO-92			*2N3548
PN 3563...3569	Fch,Nsc,Mic	Si-N	=2N3563...3569: 0,625W	7e	TO-92	-2N3563...69		*2N3563...3569
PN 3638...3640(A)	Fch,Nsc	Si-N	=2N3638...3640(A): 0,625W	7e	TO-92			*2N3638...3640(A)
PN 3641...3646	Fch,Nsc	Si-N	=2N3641...3646: 0,625W	7e	TO-92			*2N3641...3646
PN 3684...3687	Nsc	N-FET	=2N3684...3687: 0,36W	7f	TO-92			*2N3684...3687
PN 3688...3692	Fch,Nsc	Si-N	=2N3688...3692: 0,625W	7e	TO-92			*2N3688...3692
PN 3694	Fch,Nsc	Si-N	=2N3694: 0,625W	7e	TO-92			*2N3694



Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
PN 3819	Nsc	N-FET	=2N3819: 0,36W	8b	TO-106		*2N3819
PN 4013...4014	Nsc	Si-N	=2N4013...4014: 0,625W	7e	TO-92		*2N4013...4014
PN 4054	New	Si-P	LFS-L: 50V, 4A, 25W, 0,8MHz	17j	TO-220	BD 244 C	BD 244(A...C), BD 540(A...D), BD 536, ++
PN 4091...4093	Nsc	N-FET	=2N4091...4093: 0,36W	7f	TO-92		*2N4091...4093
PN 4121...4122	Fch,Nsc	Si-P	=2N4121...4122: 0,625W	7e	TO-92		*2N4121...4122
PN 4140...4143	Fch,Nsc	Si-N/P	=2N4140...4143: 0,625W	7e	TO-92		*2N4140...4143
PN 4220...4224	Nsc	N-FET	=2N4220...4224: 0,36W	7f	TO-92		*2N4220...4224
PN 4248...4250(A)	Fch,Nsc	Si-P	=2N4248...4250(A): 0,625W	7e	TO-92		*2N4248...4250(A)
PN 4257...4258(A)	Fch,Nsc	Si-P	=2N4257...4258(A): 0,625W	7e	TO-92		*2N4257...4258(A)
PN 4274...4275	Nsc	Si-N	=2N4274...4275: 0,625W	7e	TO-92		*2N4274...4275
PN 4302...4304	Nsc	N-FET	=2N4302...4304: 0,36W	7f	TO-92		*2N4302...4304
PN 4313	Fch,Nsc	Si-P	=2N4313: 0,625W	7e	TO-92		*2N4313
PN 4342...4343	Nsc	P-FET	=2N4342...4343: 0,35W	7b	TO-92		*2N4342...4343
PN 4354...4357	Fch,Nsc	Si-P	=2N4354...4357: 0,625W	7e	TO-92		*2N4354...4357
PN 4360	Nsc	P-FET	=2N4360: 0,35W	7b	TO-92		*2N4360
PN 4391...4393	Nsc	N-FET	=2N4391...4393: 0,36W	7f, 7d	TO-92	*2N4391...93	*2N4391...4393
PN 4416(A)	Nsc,Phi	N-FET	=2N4416(A): 0,36W	7f, 7d	TO-92		*2N4416(A)
PN 4423	Nsc	Si-P	=2N4423: 0,625	7e	TO-92		*2N4423
PN 4856...4861	Nsc	N-FET	=2N4856...4861: 0,36W	7f	TO-92		*2N4856...4861
PN 4888...4889	Fch	Si-P	=2N4888...4889: 0,625	7e	TO-92		*2N4888...4889
PN 4916...4917	Fch,Nsc	Si-P	=2N4916...4917: 0,625	7e	TO-92		*2N4916...4917
PN 4945...4946	Fch	Si-N	=2N4945...4946	7	TO-92		*2N4945...4946
PN 4965	Fch	Si-P	=2N4965	7	TO-92		*2N4965
PN 5033	Nsc	P-FET	=2N5033: 0,35	7b	TO-92		*2N5033
PN 5126...5137	Fch,Nsc,Mic	Si-N	=2N5126...5137: 0,625W	7e	TO-92		*2N5126...5137
PN 5138...5139	Fch,Nsc,Mic	Si-P	=2N5138...5139: 0,625W	7e	TO-92		*2N5138...5139
PN 5140...5143	Fch,Nsc	Si-P	=2N5140...5143: 0,625W	7e	TO-92		*2N5140...5143
PN 5163	Nsc	N-FET	=2N5163: 0,36W	7f	TO-92		*2N5163
PN 5179	Nsc	Si-N	=2N5179: 0,625W	7f	TO-92	*2N5179	*2N5179
PN 5415...5416	Phi	Si-P	=2N5415...5416: 0,625W	7e	TO-92	*2N5415...16	*2N5415...5416
PN 5447...5448	Nsc	Si-P	=2N5447...5448	7e	TO-92	*2N5447...48	*2N5447...5448
PN 5855...5858	Fch	Si-N/P	=2N5855...5858: 0,625W	7e	TO-92	*2N5855...58	*2N5855...5858
PN 5910	Fch,Nsc	Si-P	=2N5910: 0,625W	7e	TO-92		*2N5910
PN 5964...5965	Fch	Si-N	=2N5964...5965: 0,625W	7e	TO-92		*2N5964...65
PN 6076	Fch	Si-P	=2N6076	7	TO-92		*2N6076
PN 7055	Nsc	Si-N	Vid, 220/220V, 0,03A, 0,625W, >50MHz	7e	TO-92	BF 420 A	BF 298...299, BF 420(A), BF 422(A), ++
PNA 7506(D)	Phi	A/D-IC	6 Bit, Video, 20MHz, NMOS/TTL compatible		18-MDIP		-
PNA 7507(A)	Phi	A/D-IC	7 Bit				-
PNA 7509 D	Phi	NMOS-A/D-IC	=PNA 7509N: SMD		24-MDIP		-
PNA 7509 N,P	Phi	NMOS-A/D-IC	7 Bit, Video, 22MHz, 0...+70°		24-DIP		-
PNA 7518 N,P	Phi	NMOS-D/A-IC	8 Bit, multiplying, 0...+70°		16-DIP		-
PO		Si-P	=2SA1712-0 (SMD-Marking)	35	SOT-23		*2SA1712
PO		Si-N	=2SC2884-0 (SMD-Marking)	39	SOT-89		*2SC2884
PO		MOS-P-FET-e	=2SJ212 (SMD-Marking)	39	SOT-89		*2SJ212
PO		Si-N	=BFP 90A (Marking)	51	SOT-173		*BFP 90A
PO		Si-P	=KRA113S (SMD-Marking)	35	SOT-23		*KRA 113S
PO		Si-N	=KTC4376-0 (SMD-Marking)	39	SOT-89		*KTC 4376
PO 6		Si-P	=PMBS 3906 (SMD-Marking)	35	SOT-23		*PMBS 3906
PO 38	Mot	Si-N	Vid, 300V, 0,5A, 0,8W, >35MHz	2a	TO-39	(MPS-U10)6	(BF 461...462, BF 758...759, MPS-U10,++)6
PO 39	Mot-	Si-P	Vid, 300V, 0,5A, 0,6W, >35MHz	2a	TO-39	(MPS-U60)6	(BF 464...465, BF 761...762, MPS-U60,++)6
PP		MOS-P-FET-e	=2SJ213 (SMD-Marking)	39	SOT-89		*2SJ213
PP		Si-P	=KRA114S (SMD-Marking)	35	SOT-23		*KRA 114S
PQ		Si-N-Darl	=2SD1511-Q (SMD-Marking)	39	SOT-89		*2SD1511
PQ		Si-N	=2SD1821-Q (SMD-Marking)	35(2mm)	SOT-323		*2SD1821
PQ		Si-N	=2SD2240-Q (SMD-Marking)	35(1,6mm)	SS Mini		*2SD2240
PQ		Si-N	=2SD814-Q (SMD-Marking)	35	SOT-23		*2SD814
PQ		MOS-P-FET-e	=2SJ355 (SMD-Marking)	39	SOT-89		*2SJ355
PQ		Si-P	=KRA221S (SMD-Marking)	35	SOT-23		*KRA 221S
<b>PR...PS</b>							
PR		Si-P	=2SA1712-R (SMD-Marking)	35	SOT-23		*2SA1712
PR		Si-N-Darl	=2SD1511-R (SMD-Marking)	39	SOT-89		*2SD1511
PR		Si-N	=2SD1821-R (SMD-Marking)	35(2mm)	SOT-323		*2SD1821
PR		Si-N	=2SD2240-R (SMD-Marking)	35(1,6mm)	SS Mini		*2SD2240
PR		Si-N	=2SD814-R (SMD-Marking)	35	SOT-23		*2SD814
PR		MOS-P-FET-e	=2SJ356 (SMD-Marking)	39	SOT-89		*2SJ356
PR		Si-P	=KRA222S (SMD-Marking)	35	SOT-23		*KRA 222S
PR 1		Si-Di			1N4007	31a	
PR 121	Tho	Si-Di	FRr, 1200V, 1A, Uf<1,5V(1A), <500ns	31a	DO-15	BY 228	BY 231/1200, BY 245/1200, BY 228, BY 458
PR 141	Tho	Si-Di	=PR 121: 1400V	31a	DO-15	BY 228	BY 231/1400, BY 228, BY 448
PR 5400...5408	Itt	Si-Di	=1N5400...5408	31a	DO-27A	BY 255	31a
PRF 540	Phi	MOS-N-FET-e	VFET, SMPS, 100V, 27A, 125W, <30/80ns	17p	TO-220		(BUZ 341, BUZ 349, 2SK851, 2SK906)6
PRF 542	Phi	MOS-N-FET-e	VFET, SMPS, 100V, 24A, 125W, <30/80ns	17p	TO-220		(BUZ 341, BUZ 349, 2SK851, 2SK906)6
PRF 640	Phi	MOS-N-FET-e	VFET, SMPS, 200V, 18A, 125W, <30/80ns	17p	TO-220		(BUZ 341, BUZ 350, 2SK851, 2SK901)6
PRF 642	Phi	MOS-N-FET-e	VFET, SMPS, 200V, 16A, 125W, <30/80ns	17p	TO-220		(BUZ 341, BUZ 350, 2SK851, 2SK901)6
PRFZ 40	Phi	MOS-N-FET-e	VFET, SMPS, 50V, 51A, 125W, <25/70ns	17p	TO-220		STVHD 90, (BUZ 346, 2SK1379)6
PRFZ 42	Phi	MOS-N-FET-e	VFET, SMPS, 50V, 46A, 125W, <25/70ns	17p	TO-220		STVHD 90, (BUZ 346, 2SK1379)6
PS		Si-N-Darl	=2SD1511-S (SMD-Marking)	39	SOT-89		*2SD1511
PS		Si-N	=2SD1821-S (SMD-Marking)	35(2mm)	SOT-323		*2SD1821
PS		Si-N	=2SD2240-S (SMD-Marking)	35(1,6mm)	SS Mini		*2SD2240
PS		Si-N	=2SD814-S (SMD-Marking)	35	SOT-23		*2SD814
PS		Si-P	=KRA223S (SMD-Marking)	35	SOT-23		*KRA 223S
PSB 79 C30E-N		CMOS-IC	=PSB 79C30E-P: SMD		44-PLCC		-
PSB 79 C30E-P	Sie	CMOS-IC	Telecom, ISDN, IOM-2 Digital Subscr. Ctrl. (DSC/E)		40-DIP		-
PSB 2110-N		CMOS-IC	=PSB 2110-P: SMD		44-PLCC		-
PSB 2110-P	Sie	CMOS-IC	Telecom, ISDN Terminal Adaptor (ITAC)		40-DIP		-
PSB 2120-P	Sie	CMOS-IC	Telecom, ISDN Remote Power Controller (IRPC)		22-DIP		-
PSB 2121-P	Sie	CMOS-IC	Telecom, General Purpose Controller (GPPC)		16-DIP		-
PSB 2121-T		CMOS-IC	=PSB 2121-P: SMD		20-MDIP		-
PSB 2160-N		CMOS-IC	=PSB 2160-P: SMD		28-PLCC		-
PSB 2160-P	Sie	CMOS-IC	Telecom, Audio Ringing Codec Filter (ARCOFI)		24-DIP		-
PSB 3530	Sie	LIN-IC	Telecom, Subscriber Station Interface		28-DIC		SM 339
PSB 4500-P	Sie	LIN-IC	Telecom, Sprechkreis/Speech Circuit		20-DIP		-

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International	
PSB 4500-T		LIN-IC	=PSB 4500-P: SMD	20-MDIP			-	
PSB 4501-P	Sie	LIN-IC	Telecom, Sprechkreis/Speech Circuit, Microf. Mute	20-DIP			-	
PSB 4501-T		LIN-IC	=PSB 4501-P: SMD	20-MDIP			-	
PSB 4505(A)	Sie	LIN-IC	Telecom, Sprechkreis/Enhanced Speech Circuit (ESC) Ucc2 Voltage Limiting = 5V, A=6.5V	28-DIP			-	
PSB 4506(A)	Sie	LIN-IC	Telecom, Sprechkreis/Enhanced Speech Circuit (ESC) Ucc2 Voltage Limiting = 5V, A=6.5V	28-DIP			-	
PSB 4510	Sie	LIN-IC	Telecom, Lauthorsprechschaltung/Speaker Interface	28-DIP			-	
PSB 6520(-2)	Sie	LIN-IC	Telecom, Telefonklingel/Tone Ringer (TRI)	8-DIP			S 124A, LS 1240	
PSB 6521(-2)	Sie	LIN-IC	Telecom, Telefonklingel/Tone Ringer (TRI)	8-DIP			LS 1241	
PSB 6522-T	Sie	LIN-IC	=PSB 6520: SMD	8-MDIP			-	
PSB 6523-T	Sie	LIN-IC	=PSB 6521: SMD	8-MDIP			-	
PSB 6530	Sie	LIN-IC	Telecom, Telefonklingel/Tone Ringer (TRI)	8-DIP			-	
PSB 6531	Sie	LIN-IC	Telecom, Telefonklingel/Tone Ringer (TRI)	8-DIP			-	
PSB 6620	Sie	LIN-IC	Telecom, Rufdetector/Ringing Detector	8-DIP			-	
PSB 7510	Sie	CMOS-IC	Telecom, LCD Controller	64-µPack			SM 851	
PSB 7520	Sie	CMOS-IC	Telecom, LCD Controller	64-µPack			-	
PSB 8510(-1...-6)	Sie	CMOS-IC	Telecom, Progr. Tastwahl/Pulse/Tone Dialer (PDC)	20-DIP			-	
PSB 8590	Sie	LIN-IC	Telecom, Tastwahl/DTMF Frequ. Generator	16-DIP			S 359	
PSB 8591	Sie	LIN-IC	Telecom, Tastwahl/DTMF Frequ. Generator	20-DIP			-	
PSB 8592	Sie	LIN-IC	Telecom, Tastwahl/DTMF Frequ. Generator	20-DIP			-	
PSB 8593	Sie	CMOS-IC	Telecom, Tastwahl/DTMF Frequ. Generator	20-DIP			-	
PSB 45030	Sie	LIN-IC	Telecom, Hands-Free Add-On Circuit (HAC)	28-DIP			-	
PSB 85200-N	Sie	CMOS-IC	Telecom, Progr. Pulse/Tone Dialer, Display (PDC-D)	20-DIP			-	
PSP 2210	Itt	NMOS-IC	Videospeicher-/Memory Processor	40-DIP			-	
<b>PT....PZ</b>								
PT		Si-N	=2SC4002 (SMD-Marking)	35	SOT-23		-2SC4002	
PT		Si-N	=2SC4365 (SMD-Marking)	35	SOT-23		-2SC4365	
PT		Si-N	=2SD1821-T (SMD-Marking)	35(2mm)	SOT-323		-2SD1821	
PT		Si-N	=2SD2240-T (SMD-Marking)	35(1,6mm)	SS Mini		-2SD2240	
PT		Si-N	=2SD814-T (SMD-Marking)	35	SOT-23		-2SD814	
PT		Si-P	=KRA224S (SMD-Marking)	35	SOT-23		-KRA 224S	
PT 1011		Si-N	=BD 241B	17j	TO-220	BD 243 C	17j	-BD 241B
PT 1013		Si-P	=BD 244A	17j	TO-220	BD 244 C	17j	-BD 244A
PT 1014	Tix	Si-N	=BD 243A	17j	TO-220	BD 243 C	17j	-BD 243A
PT 1017		Si-N	=BD 239B	17j	TO-220	BD 243 C	17j	-BD 239B
PT 1021		Si-N	=BD 243B	17j	TO-220	BD 243 C	17j	-BD 243B
PT 1142		Si-N	=BD 243	17j	TO-220	BD 243 C	17j	-BD 243
PT 2013	Tix	Si-P	=BD 244B	17j	TO-220	BD 244 C	17j	-BD 244B
PT 2014		Si-P	=BD 246B	18j	TO-3P	BD 246 C	18j	-BD 246B
PT 2035		Si-P	=BD 180			BD 190	14h	-BD 180
PT 2070		Si-P	=BD 136	14h	TO-126	BD 140	14h	-BD 136
PT 2925		Si-N	=BD 519			+BD 519		-BD 519
PT 3025		Si-P	=BD 520			+BD 530		-BT 520
PT 3160	Tix	Si-N	=BD 167			BD 243 C	17j	-BD 167
PT 3180	Tix	Si-N	=BD 169			BD 243 C	17j	-BD 169
PT 3260	Tix	Si-P	=BD 168			BD 244 C	17j	-BD 168
PT 3280	Tix	Si-P	=BD 170			BD 244 C	17j	-BD 170
PT 4160		Si-N	=BD 199			BD 243 C	17j	-BD 199
PT 4260		Si-P	=BD 200			BD 244 C	17j	-BD 200
PT 6004		Si-P-Darl	=BD 650			BD 902	17j	-BD 650
PT 6005		Si-N-Darl	=BD 649			BD 901	17j	-BD 649
PT 6007		Si-N-Darl	=BD 701			BD 901	17j	-BD 701
PT 6042		Si-N-Darl	=BD 647	17j	TO-220	BD 901	17j	-BD 647
PTE 801	Mot	Si-N	UHF Drv.Out, 55/30V, 0,75A, PQ=2W(960MHz)	55r	SOT-172			-
PTN 1	Say	PUT	40V, 50mA, Itsm=5A, 0,3W, Ip<2µA, Iv>70µA	7a	TO-92			-
PTN 2	Say	PUT	40V, 50mA, Itsm=5A, 0,3W, Ip<0,15µA, Iv>25µA	7a	TO-92			-
PTZ 2.0...43(A,B)	Rhm	Z-Di	2...43V, 1W, A: ±5%, B: 0...+10%	71a(5mm)				BZG 03/... HZF ..., MA 1Z..., RD...FM
PU		Si-P	=KRA225S (SMD-Marking)	35	SOT-23			-KRA 225S
PU 42 C26	Mat	Si-P	3x PNP Trans. Array		10-SIP			-
PU 61 C56	Mat	MOS-N-FET-e	2xVFET Array, LogL, 37/20V, 6/12A, 15W, <0,14Ω(3A)	8-SIP				-
PU 393		Si-N	=BF 393	7e	TO-92	BF 420 A	7c	-BF 393
PU 1101	Mat	Si-N-Darl	4x N-Darl Array	12-SIP				-
PU 1501	Mat	Si-N-Darl	4x N-Darl Array	12-SIP				-
PU 1601	Mat	Si-N/P-Darl	3x N-Darl + 3x P-Darl Array	12-SIP				-
PU 1619...1620	Mat	Si-N/P-Darl	3x N-Darl + 3x P-Darl Array	12-SIP				-
PU 3110...3173	Mat	Si-N(-Darl)	3x NPN (Darl-)Trans. Array	8-SIP				-
PU 3210...3273	Mat	Si-P(-Darl)	3x PNP (Darl-)Trans. Array	8-SIP				-
PU 4110...4173	Mat	Si-N(-Darl)	4x NPN (Darl-)Trans. Array	10-SIP				-
PU 4210...4273	Mat	Si-P(-Darl)	4x PNP (Darl-)Trans. Array	10-SIP				-
PU 4310...4320	Mat	Si-P/N	2x NPN + 2x PNP Trans. Array	10-SIP				-
PU 4325	Mat	Si-P/N(Darl)	2x PNP Trans. + 2x NPN Darl	10-SIP				-
PU 4410...4473	Mat	Si-N(-Darl)	2x2 NPN (Darl-)Trans. Array	10-SIP				-
PU 4510...4573	Mat	Si-P(-Darl)	2x2 PNP (Darl-)Trans. Array	10-SIP				-
PU 7456	Mat	MOS-N-FET-e	4xVFET Array, LogL, 35/20V, 6/12A, 15W, <0,15Ω(3A)	10-SIP				-
PU 7457	Mat	MOS-N-FET-e	4xVFET Array, LogL, 100/20V, 3/9A, 15W, <0,45Ω(2A)	10-SIP				-
PU 8432	Mat	MOS-N-FET-e	4xVFET Array, LogL, 150/20V, 6/12A, 15W, <0,6Ω(3A)	10-SIP				-
PU 8456	Mat	MOS-N-FET-e	=PU 7456: gebogene/bended Leads	10-SIP				-
PUA 3228	Mat	Si-P	3x PNP Trans. Array	8-SIP				-
PV		PIN-Di	=1SV294 (SMD-Marking)	35	SOT-23			-1SV294
PV		Si-P	=KRA226S (SMD-Marking)	35	SOT-23			-KRA 226S
PVPU 2204	Itt	NMOS-IC	CTV, Digital Video Processor	40-DIP		PVPU 2204	40-DIP	-
PW....		Z-Di				Z-Diode ....V	31a	
PX 0013 CE		Opto	LED					
PXE 0012 CE		Opto	LED					
PXT 2222(A)	Phi	Si-N	=2N2222(A): SMD	39b	SOT-89			BCX 55...56, SXT 2222, 2SD1005...1006, ++
PXT 2907(A)	Phi	Si-P	=2N2907(A): SMD	39b	SOT-89			BCX 52...53, SXT 2907, 2SB803...805, ++
PXT 3904	Phi	Si-N	=2N3904: SMD	39b	SOT-89			SXT 3904, 2SC3803
PXT 3906	Phi	Si-P	=2N3906: SMD	39b	SOT-89			SXT 3906, 2SA1483
PXT 4401	Phi	Si-N	=2N4401: SMD	39b	SOT-89			BCX 55...56, 2SD1005...1006, 2SD1767, ++
PXT 4403	Phi	Si-P	=2N4403: SMD	39b	SOT-89			BCX 52...53, 2SB803...805, 2SB1260, ++

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
PXTA 14	Phi	Si-N-Darl	=MPS-A14: SMD	39b	SOT-89		BCV 29, BCV 49, BST 50, 2SD1470...1471,++
PXTA 27	Phi	Si-N-Darl	=MPS-A27: SMD	39b	SOT-89		BCV 29, BCV 49, BST 50, 2SD1470...71, ++
PXTA 42	Phi	Si-N	=MPS-A42: SMD	39b	SOT-89		BST 40
PXTA 43	Phi	Si-N	=MPS-A43: SMD	39b	SOT-89		BST 40
PXTA 64	Phi	Si-P-Darl	=MPS-A64: SMD	39b	SOT-89		BCV 28, BCV 48, BST 60, 2SB1125, ++
PXTA 77	Phi	Si-P-Darl	=MPS-A77: SMD	39b	SOT-89		BCV 28, BCV 48, BST 60, 2SB1125, ++
PXTA 92	Phi	Si-P	=MPS-A92: SMD	39b	SOT-89		BST 16
PXTA 93	Phi	Si-P	=MPS-A93: SMD	39b	SOT-89		BST 15...16
PY		Si-N	=2SC2884-Y (SMD-Marking)	39	SOT-89		-2SC2884
PY		Si-N	=2SC3859 (SMD-Marking)	35	SOT-23		-2SC3859
PY		Si-N	=KTC4376-Y (SMD-Marking)	39	SOT-89		-KTC 4376
PY 55/....	Tho	Si-Di	-BYX 55/....	31a	DO-15	BYD 33 M	31a
PY 126	Tho	Si-Di	-BY 126	31a	DO-15	BY 133	31a
PY 127	Tho	Si-Di	-BY 127	31a	DO-15	BY 133	31a
PY 206		Si-Di	-BY 206	31a	DO-15	BA 159	31a
PY 207	Tho	Si-Di	-BY 207	31a	DO-15	BA 159	31a
PY 208/....	Ssc	Si-Di	-BY 208/....	31a	DO-15	BA 159	31a
PY 210/....	Tho	Si-Di	-BY 210/....	31a	DO-15	BA 159	31a
PZfJ 108...110	Phi	N-FET	=J 108...110: 1.5W	-39°e	SOT-223		-
PZT 2222(A)	Phi,Sie	Si-N	=2N2222(A): 1.5W	-39°b	SOT-223		-
PZT 2907(A)	Phi,Sie	Si-P	=2N2907(A): 1.5W	-39°b	SOT-223		-
PZT 3904	Phi,Sie	Si-N	=2N3904: 1.5W	-39°b	SOT-223		-
PZT 3906	Phi,Sie	Si-P	=2N3906: 1.5W	-39°b	SOT-223		-
PZTA 05...06	Phi	Si-N	=MPS-A05...06: 1.5W	-39°j	SOT-223		-
PZTA 13...14	Phi,Sie	Si-N-Darl	=MPS-A13...14: 1.5W	-39°b	SOT-223		-
PZTA 42...43	Phi,Sie	Si-N	=MPS-A42...43: 1.5W	-39°b	SOT-223		-
PZTA 44...45	Phi	Si-N	=MPS-A44...45: 1.5W	-39°j	SOT-223		-
PZTA 55...56	Phi	Si-P	=MPS-A55...56: 1.5W	-39°j	SOT-223		-
PZTA 63...64	Phi,Sie	Si-P-Darl	=MPS-A63...64: 1.5W	-39°b	SOT-223		-
PZTA 92...93	Phi,Sie	Si-P	=MPS-A92...93: 1.5W	-39°b	SOT-223		-
<b>Q</b>							
Q 2		Si-N	=2SC1321-Q2 (SMD-Marking)	35	SOT-23		-2SC1321
Q 2		Si-N	=2SC2813-Q2 (SMD-Marking)	35	SOT-23		-2SC2813
Q 3		Si-N	=2SC1321-Q3 (SMD-Marking)	35	SOT-23		-2SC1321
Q 3		Si-N	=2SC2813-Q3 (SMD-Marking)	35	SOT-23		-2SC2813
Q 3		Si-N	=BFQ 33C (Marking)	51	SOT-173		-BFQ 33C
Q 4		Si-N	=2SC1321-Q4 (SMD-Marking)	35	SOT-23		-2SC1321
Q 4		Si-P	=2SA1331-Q4 (SMD-Marking)	35	SOT-23		-2SA1331
Q 4		Si-N	=2SC2813-Q4 (SMD-Marking)	35	SOT-23		-2SC2813
Q 5		Si-P	=2SA1331-Q5 (SMD-Marking)	35	SOT-23		-2SA1331
Q 5		Si-N	=2SC1321-Q5 (SMD-Marking)	35	SOT-23		-2SC1321
Q 5		Si-N	=2SC2813-Q5 (SMD-Marking)	35	SOT-23		-2SC2813
Q 6		Si-P	=2SA1331-Q6 (SMD-Marking)	35	SOT-23		-2SA1331
Q 6		Si-N	=BFQ 66 (Marking)	51	SOT-173		-BFQ 66
QA		Si-N	=2SC2620-A (SMD-Marking)	35	SOT-23		-2SC2620
QA		Si-N+R	=RN 1421 (SMD-Marking)	35	SOT-23		-RN 1421
QA		Si-N	=µPA673T (SMD-Marking)	46(2mm)	SOT-363		-µPA673T
QB		Si-N	=2SC2620-B (SMD-Marking)	35	SOT-23		-2SC2620
QB		Si-N+R	=RN 1422 (SMD-Marking)	35	SOT-23		-RN 1422
QC		Si-N	=2SC2620-C (SMD-Marking)	35	SOT-23		-2SC2620
QC		Si-N+R	=RN 1423 (SMD-Marking)	35	SOT-23		-RN 1423
QD		Si-N+R	=RN 1424 (SMD-Marking)	35	SOT-23		-RN 1424
QD		Z-Di	=SM 4T 6V8 (SMD-Marking)	71a(6x4mm)	SOD-6		-SM 4T....
QE		Si-N+R	=RN 1425 (SMD-Marking)	35	SOT-23		-RN 1425
QE		Z-Di	=SM 4T 6V8A (SMD-Marking)	71a(6x4mm)	SOD-6		-SM 4T....
QF		Si-N+R	=RN 1426 (SMD-Marking)	35	SOT-23		-RN 1426
QF		Z-Di	=SM 4T 7V5 (SMD-Marking)	71a(6x4mm)	SOD-6		-SM 4T....
QG		Si-N+R	=RN 1427 (SMD-Marking)	35	SOT-23		-RN 1427
QG		Z-Di	=SM 4T 7V5A (SMD-Marking)	71a(6x4mm)	SOD-6		-SM 4T....
QI		Si-N	=2SC4196 (SMD-Marking)	35	SOT-23		-2SC4196
QI		Si-N	=2SC4261 (SMD-Marking)	35(2mm)	SOT-323		-2SC4261
QL		Si-P	=2SA1580 (SMD-Marking)	35	SOT-23		-2SA1580
QN		Z-Di	=SM 4T 10 (SMD-Marking)	71a(6x4mm)	SOD-6		-SM 4T....
QO		Si-N	=2SC2714-O (SMD-Marking)	35	SOT-23		-2SC2714
QO		Si-N	=2SC4215-O (SMD-Marking)	35(2mm)	SOT-323		-2SC4215
QO		Si-N	=2SC4915-O (SMD-Marking)	35(1,6mm)	SS Mini		-2SC4915
QP		Z-Di	=SM 4T 10A (SMD-Marking)	71a(6x4mm)	SOD-6		-SM 4T....
QR		Si-N	=2SC2714-R (SMD-Marking)	35	SOT-23		-2SC2714
QR		Si-N	=2SC4215-R (SMD-Marking)	35(2mm)	SOT-323		-2SC4215
QR		Si-N	=2SC4915-R (SMD-Marking)	35(1,6mm)	SS Mini		-2SC4915
QS		Z-Di	=SM 4T 12 (SMD-Marking)	71a(6x4mm)	SOD-6		-SM 4T....
QT		Si-N	=2SC4412 (SMD-Marking)	35	SOT-23		-2SC4412
QT		Z-Di	=SM 4T 12A (SMD-Marking)	71a(6x4mm)	SOD-6		-SM 4T....
QV		PIN-Di	=1SV298 (SMD-Marking)	44	SOT-143		-1SV298
QW		Z-Di	=SM 4T 15 (SMD-Marking)	71a(6x4mm)+	SOD-6		-SM 4T....
QX		Z-Di	=SM 4T 15A (SMD-Marking)	71a(6x4mm)	SOD-6		-SM 4T....
QY		Si-N	=2SC2714-Y (SMD-Marking)	35	SOT-23		-2SC2714
QY		Si-N	=2SC3863 (SMD-Marking)	35	SOT-23		-2SC3863
QY		Si-N	=2SC4215-Y (SMD-Marking)	35(2mm)	SOT-323		-2SC4215
QY		Si-N	=2SC4498 (SMD-Marking)	35	SOT-23		-2SC4498
QY		Si-N	=2SC4915-Y (SMD-Marking)	35(1,6mm)	SS Mini		-2SC4915
QY		MOS-N-FET-e	=2SK2247 (SMD-Marking)	39	SOT-89		-2SK2247
<b>R</b>							
R....	Sam	Si-N/P+R	=KSR..... z.B./e.g. "R 1004"=KSR1004	Samsung			
R 1(p)		Si-N	=BFR 93 (SMD-Marking)	35	SOT-23		-BFR 93
R 1		Si-P	=D71Y.8T1 (SMD-Marking)	39	SOT-89		-D71Y.8T1
R 01		Si-N+R	=KSR 1101 (SMD-Marking)	35	SOT-23		-KSR 1101
R 2		Si-N	=2SC2351-R2 (SMD-Marking)	35	SOT-23		-2SC2351
R 2(p)		Si-N	=BFR 93A (SMD-Marking)	35	SOT-23		-BFR 93A
R 2		Si-N	=BFR 93AW (SMD-Marking)	35(2mm)	SOT-323		-BFR 93AW

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
R 02		Si-N+R	=KSR 1102 (SMD-Marking)	35	SOT-23		-KSR 1102
R 2 M	Sak	Z-Di	Avalanche, 135...180V, 1A(100µs)	31a	DO-14		-
R 3		Si-N	=2SC2351-R3 (SMD-Marking)	35	SOT-23		-2SC2351
R 3		N-FET	=2SK283-R3 (SMD-Marking)	35	SOT-23		-2SK283
R 03		Si-N+R	=KSR 1103 (SMD-Marking)	35	SOT-23		-KSR 1103
R 4		N-FET	=2SK283-R4 (SMD-Marking)	35	SOT-23		-2SK283
R 4		Si-N	=BFR 93R (SMD-Marking)	35	SOT-23		-BFR 93R
R 04		Si-N+R	=KSR 1104 (SMD-Marking)	35	SOT-23		-KSR 1104
R 5		N-FET	=2SK283-R5 (SMD-Marking)	35	SOT-23		-2SK283
R 5		Si-N	=BFR 93AR (SMD-Marking)	35	SOT-23		-BFR 93AR
R 5 F 400...900 CP	Aeg	F-Thy+Di	400...900V, 6,4A(Tc=65°C), 10A-, Igt=50mA	22a	TO-66		-
R 05		Si-N+R	=KSR 1105 (SMD-Marking)	35	SOT-23		-KSR 1105
R 6		N-FET	=2SK283-R6 (SMD-Marking)	35	SOT-23		-2SK283
R 06		Si-N	=KSR 1106 (SMD-Marking)	35	SOT-23		-KSR 1106
R 7(p)		Si-N	=BFR 106 (SMD-Marking)	35	SOT-23		-BFR 106
R 07		Si-N+R	=KSR 1107 (SMD-Marking)	35	SOT-23		-KSR 1107
R 8		Si-N	=BFG 93A (SMD-Marking)	44	SOT-143		-BFG 93A
R 08		Si-N+R	=KSR 1108 (SMD-Marking)	35	SOT-23		-KSR 1108
R 09		Si-N+R	=KSR 1109 (SMD-Marking)	35	SOT-23		-KSR 1109
R 10 A...M	Sym	Si-Di	FRr, 50...1000V, 1A, Uf<1,3V(1A), <150...500ns A=50, B=100, D=200, G=400, J=600, K=800, M=1000V	31a	DO-41	BYD 33 M 31a	BYT52A...M, BYV12...16, RG1A...M, RGP10A...M
R 10		Si-N+R	=KSR 1110 (SMD-Marking)	35	SOT-23		-KSR 1110
R 11		Si-N+R	=KSR 1111 (SMD-Marking)	35	SOT-23		-KSR 1111
R 12		Si-N+R	=KSR 1112 (SMD-Marking)	35	SOT-23		-KSR 1112
R 13		Si-N+R	=KSR 1113 (SMD-Marking)	35	SOT-23		-KSR 1113
R 14		Si-N+R	=KSR 1114 (SMD-Marking)	35	SOT-23		-KSR 1114
R 22		Si-N	=2SC3356 (SMD-Marking)	35	SOT-23		-2SC3356
R 30 A...M	Sym	Si-Di	FRr, 50...1000V, 3A, Uf<1,3V(3A), <150...500ns A=50, B=100, D=200, G=400, J=600, K=800, M=1000V	31a	DO-27A	RGP 30 M BYW 96 E 31a	BYW95A...C, BYW96D...E, RG3A...M, RGP30A...M
R 51		Si-P+R	=KSR 2101 (SMD-Marking)	35	SOT-23		-KSR 2101
R 52		Si-P+R	=KSR 2102 (SMD-Marking)	35	SOT-23		-KSR 2102
R 53		Si-P+R	=KSR 2103 (SMD-Marking)	35	SOT-23		-KSR 2103
R 54		Si-P+R	=KSR 2104 (SMD-Marking)	35	SOT-23		-KSR 2104
R 55		Si-P+R	=KSR 2105 (SMD-Marking)	35	SOT-23		-KSR 2105
R 56		Si-P+R	=KSR 2106 (SMD-Marking)	35	SOT-23		-KSR 2106
R 57		Si-P+R	=KSR 2107 (SMD-Marking)	35	SOT-23		-KSR 2107
R 58		Si-P+R	=KSR 2108 (SMD-Marking)	35	SOT-23		-KSR 2108
R 59		Si-P+R	=KSR 2109 (SMD-Marking)	35	SOT-23		-KSR 2109
R 60		Si-P+R	=KSR 2110 (SMD-Marking)	35	SOT-23		-KSR 2110
R 61		Si-P+R	=KSR 2111 (SMD-Marking)	35	SOT-23		-KSR 2111
R 62		Si-P+R	=KSR 2112 (SMD-Marking)	35	SOT-23		-KSR 2112
R 63		Si-P+R	=KSR 2113 (SMD-Marking)	35	SOT-23		-KSR 2113
R 64		Si-P+R	=KSR 2114 (SMD-Marking)	35	SOT-23		-KSR 2114
R 0103 AA	Tag	Triac	100V, 0.64A-(Tc=85°C), Igt/Ih <5/25mA	7n	TO-92		MAC 92(A)-..., MAC 95-..., Z0104...
R 0103 BA		Triac	=R 0103AA: 200V	7n	TO-92		MAC 92(A)-..., MAC 95-..., Z0104...
R 0103 CA		Triac	=R 0103AA: 300V	7n	TO-92		MAC 92(A)-..., MAC 95-..., Z0104...
R 0103 DA		Triac	=R 0103AA: 400V	7n	TO-92		MAC 92(A)-..., MAC 95-..., Z0104...
R 0106 AA	Tag	Triac	100V, 0.6A-(Tc=85°C), Igt/Ih <10/25mA	7n	TO-92		MAC 91A-..., MAC 94(A)-...
R 0106 BA		Triac	=R 0106AA: 200V	7n	TO-92		MAC 91A-..., MAC 94(A)-...
R 0106 CA		Triac	=R 0106AA: 300V	7n	TO-92		MAC 91A-..., MAC 94(A)-...
R 0106 DA		Triac	=R 0106AA: 400V	7n	TO-92		MAC 91A-..., MAC 94(A)-...
R 0107 AA...DA	Tag	Triac	=R 0106AA...DA:	7n	TO-92		TAG 91-..., MAC 92-..., MAC 94-...
R 250-(L)A...M	Mic	Si-Di	Rr, 50...800V, 6A, Uf<1,1V(10A), L: Uf<1V(6A) A=50, B=100, D=200, F=300, H=400, K=500, M=600V, P=700V, S=800V	31a	(8x10mm0)	BY 329/1200 <sup>4</sup> 17k	BY 214/..., MR 750...760, P 600A...K
R 1001...R 2112	Sam	...-N/P	=KSR 1001...KSR 2112 [Samsung]				-KSR 1001...KSR 2112 [Samsung]
R 1038	Aei	Si-		23a	TO-3		-
R 1039	Aei	Si-		23a	TO-3		-
R 2008	Aei	Si-N	=BU 208(A)	23a	TO-3	BU 208 A 23a	-BU 208(A)
R 2009	Aei	Si-		23a	TO-3		-
R 2010(B)	Aei	Si-		23a	TO-3		-
R 2406		Si-N	=BD 243	17j	TO-220	BD 243 C 17j	-BD 243
R 2499		Si-N	=BD 245	18j	TO-3P	BD 245 C 18j	-BD 245
R 2513		Si-P	=BD 242A	17j	TO-220	BD 244 C 17j	-BD 242A
R 3272		Si-N	=BU 908	18j	TO-3P	BU 908 18j	-BU 908
R 3460	Tix	Si-N	FLT-Ballast, 850/400V, 2,5A, 50W	17j	TO-220		-
R 4050	Tix	Si-N	HA, SMPS, 1300/600V, 4A, 100W	18j	TO-3P	BU 508 A 18j	BU 508A, BU 903, BU 908, 2SC4022,++
R 4051	Tix	Si-N	=R 4050: 1100/550V	18j	TO-3P	BU 508 A 18j	BU 508A, BU 903, BU 908, 2SC3387,++
R 4060	Tix	Si-N	=R 4050: 80W	17j	TO-220		BU 506, BU 603
R 4061	Tix	Si-N	=R 4051: 80W	17j	TO-220		BU 506, BU 603
RA		Si-N	=BF 772 (SMD-Marking)	44	SOT-143		-BF 772
RA		Si-N	=BFQ 81 (SMD-Marking)	35	SOT-23		-BFQ 81
RA		Si-P+R	=RN 2421 (SMD-Marking)	35	SOT-23		-RN 2421
RA-1(A...Z)	Sak	Si-Di	Rr, Uni, 100...1500V, 0,5...1A, Uf<0,95...1,4V(1A) RA-1=400V, A=600V, B=800V, C=1000V, D=1200V(0,6A), E=1400V(0,6A), F=1500V(0,5A), Y=100V, Z=200V	31a	DO-14	BY 133(1300V) 31a	BY 126...127, BY 133...135, BY 269, ++
RA-2(C)	Sak	Si-Di	Rr, Uni, 600...1000V, 1,2A, Uf<0,93V(1,5A) RA-2=600V, C=1000V	31a	DO-27	BYD 33 M 31a	BY 226...227, GP 15J...M, 1N5397...99, ++
RAO		Si-N	=2SC3718-0 (SMD-Marking)	35	SOT-23		-2SC3718
RAY		Si-N	=2SC3718-Y (SMD-Marking)	35	SOT-23		-2SC3718
RB		Si-N	=2SC2618-B (SMD-Marking)	35	SOT-23		-2SC2618
RB		Si-N	=BF 771 (SMD-Marking)	35	SOT-23		-BF 771
RB		Si-P+R	=RN 2422 (SMD-Marking)	35	SOT-23		-RN 2422
RB 1...7		Si-Br				4x 1N4007 31a	
RBG		N-FET	=2SK711-GR (SMD-Marking)	35	SOT-23		-2SK711
RBL		N-FET	=2SK711-BL (SMD-Marking)	35	SOT-23		-2SK711
RBV		N-FET	=2SK711-V (SMD-Marking)	35	SOT-23		-2SK711
RC							
RC		Si-N	=2SC2618-C (SMD-Marking)	35	SOT-23		-2SC2618
RC(s)		Si-N	=BFR 193 (SMD-Marking)	35	SOT-23		-BFR 193
RC		Si-P+R	=RN 2423 (SMD-Marking)	35	SOT-23		-RN 2423

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
RC-2	Sak	Si-Di	FRR, 1500/2000V, 0.2A, Uf<2V(0.2A), <800ns	31a	-DO-14	BY 203/20	31a BY 203/20, SHG 2
RC 555 NB	Ray	LIN-IC	Timer	8-DIP		NE 555 N	8-DIP NE 555
RC 723 CN,DB	Ray	Z-IC	+2...37V, 0.15A	14-DIP		723/14-D	14-DIP ... 723...
RC 723 T	Ray	Z-IC	=RC 723 CN,CB: Fig. *	TO-100		723/TO	TO-100 ... 723...
RC 741 DB,NB	Ray	OP-IC	Uni, Serie 741, ±18V, 0...+70°	8-DIP		741/8-D	8-DIP ... 741...
RC 741 T	Ray	OP-IC	=RC 741 DB,NB: Fig. *	TO-99		741/TO	TO-99 ... 741...
RC 747 DB	Ray	OP-IC	Dual, Serie 747, ±18V, 0...+70°	14-DIP		747/14-D	14-DIP ... 747...
RC 747 T	Ray	OP-IC	=RC 747 DB: Fig. *	TO-100			... 747...
RC 1458 NB	Ray	OP-IC	Dual, Serie 158, ±18V, 0...+70°	8-DIP		4558/8-D	8-DIP ... 358... 1458... 1558...
RC 4136 D	Ray,Tix	OP-IC	=RC 4136: SMD	14-MDIP			RV 4136D, µA 4136SC
RC 4136 J,N	Ray,Tix	OP-IC	Quad, ±18V, 3MHz, 0...+70°	14-DIC,DIP			RM 4136, RV 4136, µA 4136
RC 4151	Rca	LIN-IC	=LM 331...	8-DIP			-LM 331...
RC 4193 JG,P	Ray,Tix	Z-IC	S-Reg, lo-power, 2.5...24V 0.15A, 0...+70°	8-DIC,DIP			RM 4193
RC 4195 NB	Ray	Z-IC	±0...27V, 0.15A	8-DIP			-
RC 4558 D	Ray,Tix	OP-IC	=RC 4558DE,JG,P: SMD	8-MDIP			... 258... 358... 1458... 4558...
RC 4558 DE,JG,P	Ray,Tix	OP-IC	Dual, Serie 157, ±18V, 3MHz, 0...+70°	8-DIC,DIP	4558/8-D	8-DIP	... 258... 358... 1458... 4558...
RC 4559 D	Ray,Tix	OP-IC	=RC 4559P: SMD	8-MDIP			NJM 4559...
RC 4559 P	Ray,Tix	OP-IC	Dual, ±18V, 4MHz, 0...+70°	8-DIP			NJM 4559...
RC 4739(DB)	Ray	OP-IC	Dual, lo-noise	14-DIP			µA 739, TBA 231(A)
RC 7805	Ray	Z-IC	+5V, 1.5A	17b	TO-220	7805/TO-220	17b ... 7808... (TO-220)
RC 7805 CK	Ray	Z-IC	+5V, 1.5A	23a	TO-3	7805/TO-3	23a
RC 7806	Ray	Z-IC	+6V, 1.5A	17b	TO-220	7806/TO-220	17b ... 7806... (TO-220)
RC 7808	Ray	Z-IC	+8V, 1.5A	17b	TO-220	7808/TO-220	17b ... 7808... (TO-220)
RC 7812	Ray	Z-IC	+12V, 1.5A	17b	TO-220	7812/TO-220	17b ... 7812... (TO-220)
RC 7812 CK	Ray	Z-IC	+12V, 1.5A	23a	TO-3	7812/TO-3	23a ... 7812... (TO-3)
RC 7815	Ray	Z-IC	+15V, 1.5A	17b	TO-220	7815/TO-220	17b ... 7815... (TO-220)
RC 7818	Ray	Z-IC	+18V, 1.5A	17b	TO-220	7818/TO-220	17b ... 7818... (TO-220)
RC 7824	Ray	Z-IC	+24V, 1.5A	17b	TO-220	7824/TO-220	17b ... 7824... (TO-220)
RC 7905	Ray	Z-IC	-5V, 1.5A	17c	TO-220	7905/TO-220	17c ... 7905... (TO-220)
RC 7912	Ray	Z-IC	-12V, 1.5A	17c	TO-220	7912/TO-220	17c ... 7912... (TO-220)
RC 7915	Ray	Z-IC	-15V, 1.5A	17c	TO-220	7915/TO-220	17c ... 7915... (TO-220)
RCA 29	Rca	Si-N	LFS P, 40V, 3A, 30W, >3MHz	17j	TO-220	BD 243 C	17j BD 241, BD 243, BD 533, BD 933, ++
RCA 29 A		Si-N	=RCA 29: 60V	17j	TO-220	BD 243 C	17j BD 241A, BD 243A, BD 535, BD 935, ++
RCA 29 B		Si-N	=RCA 29: 80V	17j	TO-220	BD 243 C	17j BD 241B, BD 243B, BD 537, BD 937, ++
RCA 29 C		Si-N	=RCA 29: 100V	17j	TO-220	BD 243 C	17j BD 241C, BD 243C, BD 937, 2SD712, ++
RCA 30	Rca	Si-P	LFS P, 40V, 3A, 30W, >3MHz	17j	TO-220	BD 244 C	17j BD 242, BD 244, BD 534, BD 934, ++
RCA 30 A		Si-P	=RCA 30: 60V	17j	TO-220	BD 244 C	17j BD 242A, BD 244A, BD 536, BD 936, ++
RCA 30 B		Si-P	=RCA 30: 80V	17j	TO-220	BD 244 C	17j BD 242B, BD 244B, BD 538, BD 938, ++
RCA 30 C		Si-P	=RCA 30: 100V	17j	TO-220	BD 244 C	17j BD 242C, BD 244C, BD 938, 2SB682, ++
RCA 31	Rca	Si-N	LFS P, 40V, 5A, 40W, >3MHz	17j	TO-220	BD 243 C	17j BD 243, BD 539, BD 543, BD 947, ++
RCA 31 A		Si-N	=RCA 31: 60V	17j	TO-220	BD 243 C	17j BD 243A, BD 539A, BD 543A, BD 949, ++
RCA 31 B		Si-N	=RCA 31: 80V	17j	TO-220	BD 243 C	17j BD 243B, BD 539B, BD 543B, BD 951, ++
RCA 31 C		Si-N	=RCA 31: 100V	17j	TO-220	BD 243 C	17j BD 243C, BD 539C, BD 543C, BD 953, ++
RCA 32	Rca	Si-P	LFS P, 40V, 5A, 40W, >3MHz	17j	TO-220	BD 244 C	17j BD 244, BD 540, BD 544, BD 948, ++
RCA 32 A		Si-P	=RCA 32: 60V	17j	TO-220	BD 244 C	17j BD 244A, BD 540A, BD 544A, BD 950, ++
RCA 32 B		Si-P	=RCA 32: 80V	17j	TO-220	BD 244 C	17j BD 244B, BD 540B, BD 544B, BD 952, ++
RCA 32 C		Si-P	=RCA 32: 100V	17j	TO-220	BD 244 C	17j BD 244C, BD 540C, BD 544C, BD 954, ++
RCA 41	Rca	Si-N	LFS P, 40V, 7A, 65W, >3MHz	17j	TO-220	BD 809	17j BD 543, BD 705, BD 795, BD 805, ++
RCA 41 A		Si-N	=RCA 41: 60V	17j	TO-220	BD 809	17j BD 543A, BD 707, BD 797, BD 807, ++
RCA 41 B		Si-N	=RCA 41: 80V	17j	TO-220	BD 809	17j BD 543B, BD 709, BD 799, BD 809, ++
RCA 41 C		Si-N	=RCA 41: 100V	17j	TO-220	BD 809	17j BD 543C, BD 711, BD 801
RCA 42	Rca	Si-P	LFS P, 40V, 7A, 65W, >3MHz	17j	TO-220	BD 810	17j BD 544, BD 706, BD 796, BD 806, ++
RCA 42 A		Si-P	=RCA 42: 60V	17j	TO-220	BD 810	17j BD 544A, BD 708, BD 798, BD 808, ++
RCA 42 B		Si-P	=RCA 42: 80V	17j	TO-220	BD 810	17j BD 544B, BD 710, BD 800, BD 810, ++
RCA 42 C		Si-P	=RCA 42: 100V	17j	TO-220	BD 810	17j BD 544C, BD 712, BD 802
RCA 410	Rca	Si-N	S P, 200/200V, 7A, 125W, 4MHz	23a	TO-3		BUX 18(A,B), TIP 55(A), 2SC3835, ++
RCA 411	Rca	Si-N	=RCA 410: 300/300V	23a	TO-3		BUX 18A,B, TIP 55A...56A, 2SC3813, ++
RCA 413	Rca	Si-N	S P, 400/325V, 7A, 125W, 4MHz, hFE=20...80	23a	TO-3		BUX 18B, BUX 44, TIP 56A...57A, 2SC3040++
RCA 423	Rca	Si-N	=RCA 413: hFE=30...90	23a	TO-3		BUX 18B, BUX 44, TIP 56A...57A, 2SC3040++
RCA 431	Rca	Si-N	S P, 400/325V, 7A, 125W	23a	TO-3		BUX 18B, BUX 44, TIP 56A...57A, 2SC3040++
RCA 1000...1001	Rca	Si-N-Darl+Di	=MJ 1000...1001	23a	TO-3	*MJ 1000...01	*MJ 1000...1001
RCA 3054	Rca	Si-N	LFS P, 90V, 4A, 36W, >0.8MHz	17j	TO-220	BD 243 C	17j BD 243B, BD 539C, BD 953, 2SD613, ++
RCA 3055	Rca	Si-N	LFS P, 100V, 15A, 75W, >0.8MHz	17j	TO-220	(BD 245C) <sup>6</sup>	18j BD 545C, BD 743C, BD 911
RCA 3773	Rca	Si-N	=2N3773	23a	TO-3	*2N3773	*2N3773
RCA 6340...6341	Rca	Si-N	=2N6340...6341	23a	TO-3	*2N6340...6341	*2N6340...6341
RCA 8203(A...B)	Rca	Si-P-Darl	P, 40...80V, 8A, 60W, hFE=1k...20k	17j	TO-220	BD 902	17j BDW 47(A...D), BDX 54(A...F), BD 900, ++
RCA 8350(A...B)	Rca	Si-P-Darl	P, 40...80V, 10A, 70W, hFE=1k...20k	23a	TO-3	BDW 84C	18j BDW 84(A...D), BDX 84(A...C), BDX 86(A...C)
RCA 8638(C...E)	Rca	Si-P	LFS P, 140...100V, 20A, 200, >2MHz	23a	TO-3	BD 246 C	18j BDW 30, BDY 58, 2N5671...72
RCA 8766(A...E)	Rca	Si-N-Darl+Di	S P, 350...450V, 10A, 150W, hFE>100	23a	TO-3		BU 922(P), BUW 81(A), MJ 10002...03, ++
RCA 9113(A...B)	Rca	Si-N	S P, 300...400V, 15A, 175W	23a	TO-3	BUW 13 A	18j BUW 44, BUX 13, BUS 23(A...B), 2SC4140,++
RCA 9116(C...E)	Rca	Si-P	S P, 140...100V, 20A, 200W, >2MHz	23a	TO-3		-
RCA 9166A...B	Rca	Si-N	S P, 275...225V, 16A, 250W, >4MHz	23a	TO-3		-
RCA 9202(B...C)	Rca	Si-N-Darl+Di	P, 300...400V, 4A, 65W, hFE=750	17j	TO-220		2SD977...978, 2SD987, 2SD1072
RCA 9203A...B	Rca	Si-N-Darl	S P, 250...300V, 4A, 50W, hFE>500	17j	TO-220		2SD816, 2SD977, 2SD1073
RCA 9228A...D	Rca	Si-N-Darl+Di	LFS P, 60...120V, 50A, 300W, hFE>2000	23a	TO-3		-
RCA 9229A...D	Rca	Si-P-Darl+Di	LFS P, 60...120V, 50A, 300W, hFE>2000	23a	TO-3		-
RCP 111(A...D)	Rca	Si-N	S, Vid Out, -200...350V, 0.15A, 6.2W, 80MHz	13m	TO-202	MPS-U10	13m
RCs		Si-N	=BFP 193 (SMD-Marking)	44	SOT-143		*BFP 193
RCs		Si-N	=BFO 193 (SMD-Marking)	39	SOT-89		*BFO 193
RCs		Si-N	=BFR 193 (SMD-Marking)	35	SOT-23		*BFR 193
RCS 617	Rca	Si-N		23a	TO-3	BD 317	23a
RCS 618	Rca	Si-P		23a	TO-3	BD 318	23a
<b>RD...RF</b>							
RD		Si-P+R	=RN 2424 (SMD-Marking)	35	SOT-23		*RN 2424
RD		Z-Di	=SM 4T 18 (SMD-Marking)	71a(6x4mm)	SOD-6		*SM 4T....
RD		Si-N	=2SC2618-D (SMD-Marking)	35	SOT-23		*2SC2618
RD 3.9...200	Tho	Z-Di	3.9...200V, ±5%, 1.3W	34a	DO-13	Z-Diode ...V	31a BZD10/..., BZW22/..., BZX61/..., ZPY...++
RD 4A...35A	Nec	Z-Di	4...35V, 0.2W	31a	DO-7	Z-Diode ...V	31a BZX55/..., BZX85/..., BZX97/..., ZPD...++
RD 4B...35B	Nec	Z-Di	4...35V, 1W	34a	DO-1	Z-Diode ...V	31a BZD10/..., BZV85/..., BZW22/..., ZPY...++
RD 5C...35C	Nec	Z-Di	5...35V, 3W	32a	DO-4		BZX 98/..., 1N2970...91, 1N3996...4000
RD 5D...35D	Nec	Z-Di	5...35V, 10W	32a	DO-4		BZX 98/..., 1N2970...91, 1N3996...4000

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International	
RD 2.0E...120E...	Nec	Z-Di	2...120V, 0.4W, ...EL...EN...ESB... ES(A)B8--8...+3%, ES(A)B1--8...-4%, ES(A)B2--5...+1%, ES(A)B3--2...+3%, ES(A)B4--1...+2%	31a	DO-35	Z-Diode ...V	31a	BZX55/..., BZX79/..., BZX83/..., ZPD...++
RD 8.2EW...9.1EW	Nec	Z-Di	bidirectional, 8.2...9.1V, 10%, 0.4W	31a	DO-34			-
RD 2.0F...82F	Nec	Z-Di	2...82V, 1W, FB--6...+10%, FB1--8...-3%, FB2--5...0%, FB3--2...+4%, FC--10%	31a	SOD-51	Z-Diode ...V	31a	BZV85/..., BZX61/..., ZPY..., 1N4728...62,++
RD 4.7FM...51FM	Nec	Z-Di	4.7...51V, 5%, 1W, Pbr=400W(10µs)	71a(5mm)				BZG 04/..., HZF ..., MA 1Z..., PTZ...
RD 7H...10H	Nec	Z-Di	HF, 7...10V, 0.1W	2c	TO-1			-
RD 2.0HS...4.7HS	Nec	Z-Di	2.0...4.7V, -5%, 0.25W	31	DO-34	Z-Diode ...V	31	BZX55/..., BZX79/..., BZX83/..., ZPD...++
RD 4.7J...39J	Nec	Z-Di	In. 4.7...39V, 5%, 0.4W, JS(A)B-5%, JS(A)B1--5...0%, JS(A)B2--2.5%, JS(A)B3-0...+5%	31a	DO-35	(Z-Diode ...V)	31a	BZV 39/..., 1N4099...4123
RD 2.0M...47M(MB...)	Nec	Z-Di	SMD, 2.0...47V, 5%, 0.15W, MB-5%, MB1--5...0%, MB2--2%, MB3-0...+5%	35p	SOT-23			BZX 84/..., HZM ...
RD 2.4MW...9.1MW	Nec	Z-Di	=RD 2.4M...9.1M Dual	35n	SOT-23			-
RD 2.0P...120P	Nec	Z-Di	SMD, 2.0...120V, 5%, 1W, Pbr=400W(10µs)	39q	SOT-89			BZV 49/..., BZX 78/...
RD 2.0S...39S	Nec	Z-Di	=RD 2.0M...39M: 0.2W, Pbr=85W(10µs)	71a(1,7mm)				DTZ ..., HZU ...
RD 2.0UH...4.7UH	Nec	Z-Di	=RD 2.0HS, 4.7HS: SMD, 0.15W	71a(1,3mm)				RD ...UJ, RD ...UM
RD 4.7UJ...39UJ	Nec	Z-Di	=RD 4.7S...39S: SMD, 0.15W, Pbr=2.2W(10µs)	71a(1,3mm)				RD ...UM
RD 2.0UM...39UM	Nec	Z-Di	=RD 2.0M...39M: 0.15W	71a(1,3mm)				RD ...UJ
RD 6.2 Z	Nec	Z-Di	SMD, Z, Dual Tuner Di, 5.9...6.5V, <60Ω(5mA)	35n	SOT-23			-
RD 10	Sie	Ge-St	0.2A, Uf=22...0.35V(100mA)	31a	DO-14			-
RD B-50		Ge-P		2a		(AC 188 K)	3a	-
RDs		Si-N	=BFP 180 (SMD-Marking)	44	SOT-143			+BFP 180
RD(s)		Si-N	=BFP 193 (SMD-Marking)	44	SOT-143			+BFP 193
RDs		Si-N	=BFR 180 (SMD-Marking)	35	SOT-23			+BFR 180
RE		Si-P	=2SA1514K-E (SMD-Marking)	35	SOT-23			+2SA1514K
RE		Si-P	=2SA1579-E (SMD-Marking)	35(2mm)	SOT-323			+2SA1579
RE		Si-P+R	=RN 2425 (SMD-Marking)	35	SOT-23			+RN 2425
RE		Z-Di	=SM 4T 18A (SMD-Marking)	71a(6x4mm)	SOD-6			+SM 4T...
REs		Si-N	=BFP 280 (SMD-Marking)	44	SOT-143			+BFP 280
REs		Si-N	=BFR 280 (SMD-Marking)	35	SOT-23			+BFR 280
RF		Si-P+R	=RN 2426 (SMD-Marking)	35	SOT-23			+RN 2426
RF-1(A,B,Z)	Sak	Si-Di	FRr, 200...800V, 0.6A, Uf<2V(0.6A), <400ns RF 1=400V, A=600V, B=800V, Z=200	31a	(7x4mm0)	BA 159	31a	BY 201/..., BYX 55/..., RGP 10D...M, ++
RF 2.7...200	Tho	Z-Di	=BZX 46 C27V...C200: 0.4W	31a	DO-7	Z-Diode ...V	31a	+BZX 46/...
RF 03 E14		Se-Di						HS 15
RF 400	Fch	C-Di	FM/VHF AFC, 30V, 10pF(4V)	31a	DO-35			BA 111, BA 124, 1S2970, 1SV50, ++
RF 401	Fch	C-Di	FM/VHF AFC, 30V, 7pF(4V)	31a				BA 111, BA 124, 1S2970, 1SV50, ++
RF 500	Fch	C-Di	Dual, FM Tuning	7e	TO-92			BB 104, BB 204, BB 304, MV 104, 1SV55,++
RFH 10 N45...N50	Rca	MOS-N-FET-e	VFET, 450...500V, 10A, 150W, <160/1080ns	18p	TO-3P			BUZ 339, 2SK 557, 2SK642, 2SK644, 2SK724
RFH 12 N35...N40	Rca	MOS-N-FET-e	VFET, 350...400V, 12A, 150W, <200/950ns	18p	TO-3P			BUZ 325...326, 2SK351, 2SK634, 2SK559
RFH 25 N18...N20	Rca	MOS-N-FET-e	VFET, 180...200V, 25A, 150W, <305/600ns	18p	TO-3P			BUZ 341, 2SK851, 2SK902, 2SK1669
RFH 25 P08...P10	Rca	MOS-P-FET-e	VFET, 80...100V, 25A, 150W, <300/650ns	18p	TO-3P			-
RFH 30 N12...N15	Rca	MOS-N-FET-e	VFET, 120...150V, 30A, 150W, <745/825ns	18p	TO-3P			BUZ 341, 2SK851, 2SK902, 2SK1669
RFH 35 N08...N10	Rca	MOS-N-FET-e	VFET, 80...100V, 35A, 150W, <550/800ns	18p	TO-3P			BUZ 349, 2SK850, 2SK906
RFH 45 N05...N06	Rca	MOS-N-FET-e	VFET, 50...60V, 45A, 150W, <454/725ns	18p	TO-3P			2SK849, 2SK857, 2SK1379
RFK 25 N18...N20	Rca	MOS-N-FET-e	VFET, 180...200V, 25A, 150W, <305/600ns	23a	TO-3			BUZ 341, IRF 250...252, 2SK851, 2SK902
RFK 25 P08...P10	Rca	MOS-P-FET-e	VFET, 80...100V, 25A, 150W, <300/650ns	23a	TO-3			IRF 9150
RFK 30 N12...N15	Rca	MOS-N-FET-e	VFET, 120...150V, 30A, 150W, <745/825ns	23a	TO-3			BUZ 341, IRF 250...251, 2SK851, 2SK902
RFK 35 N08...N10	Rca	MOS-N-FET-e	VFET, 80...100V, 35A, 150W, <550/800ns	23a	TO-3			BUZ 345, 2N6764, 2SK850...851
RFK 45 N05...N06	Rca	MOS-N-FET-e	VFET, 50...60V, 45A, 150W, <454/725ns	23a	TO-3			BUZ 345, 2SK849, 2SK850...851, 2SK857
RFL 1 N08...N10	Rca	MOS-N-FET-e	VFET, 80...100V, 1A, 8.33V, <70/95ns	2a	TO-39			IRFF 110, IRFF 112
RFL 1 N12...N15	Rca	MOS-N-FET-e	VFET, 120...150V, 1A, 8.33V, <70/95ns	2a	TO-39			IRFF 210...213
RFL 1 N18...N20	Rca	MOS-N-FET-e	VFET, 180...200V, 1A, 8.33V, <55/90ns	2a	TO-39			IRFF 220, IRFF 222
RFL 1 P08...P10	Rca	MOS-P-FET-e	VFET, 80...100V, 1A, 8.33V, <70/95ns	2a	TO-39			IRFF 910, IRFF 9112
RFL 2 N05...N06	Rca	MOS-N-FET-e	VFET, 50...60V, 2A, 8.33V, <45/80ns	2a	TO-39			IRFF 110...113
RFL 4 N12...N15	Rca	MOS-N-FET-e	VFET, 120...150V, 4A, 8.33V, <310/270ns	2a	TO-39			IRFF 230...233
RFM 3 N45...N50	Rca	MOS-N-FET-e	VFET, 450...500V, 3A, 75W, <105/210ns	23a	TO-3			BUZ 84, BUZ 355...356, IRF 430...433
RFM 4 N35...N40	Rca	MOS-N-FET-e	VFET, 350...400V, 4A, 75W, <105/300ns	23a	TO-3			BUZ 63, IRF 330...333, 2SK259...260
RFM 5 P12...P15	Rca	MOS-P-FET-e	VFET, 120...150V, 5A, 75W, <160/250ns	23a	TO-3			IRF 9230...9233, 2SJ114...115
RFM 6 N45...N50	Rca	MOS-N-FET-e	VFET, 450...500V, 6A, 100W, <125/400ns	23a	TO-3			BUZ 94, BUZ 330...331, IRF 440...443
RFM 6 P08...P10	Rca	MOS-P-FET-e	VFET, 80...100V, 6A, 75W, <160/250ns	23a	TO-3			IRF 9230...9233, 2SJ114...115
RFM 7 N35...N40	Rca	MOS-N-FET-e	VFET, 350...400V, 7A, 100W, <120/350ns	23a	TO-3			BUZ 330...331, IRF 340...343, 2SK501
RFM 8 N18...N20	Rca	MOS-N-FET-e	VFET, 180...200V, 8A, 75W, <195/240ns	23a	TO-3			BUZ 64, IRF 230, IRF 232, 2SK633
RFM 8 P08...P10	Rca	MOS-P-FET-e	VFET, 80...100V, 8A, 100W, <210/450ns	23a	TO-3			IRF 9130...9133, 2SJ114...115
RFM 10 N12...N18	Rca	MOS-N-FET-e	VFET, 120...150V, 10A, 75W, <310/270ns	23a	TO-3			IRF 240...243, 2SK401, 2SK631, 2SK633
RFM 10 N45...N50	Rca	MOS-N-FET-e	VFET, 450...500V, 10A, 150W, <160/1080ns	23a	TO-3			BUZ 45, BUZ 339, IRF 450...453, 2SK724
RFM 10 P12...P15	Rca	MOS-P-FET-e	VFET, 120...150V, 10A, 100W, <200/325ns	23a	TO-3			IRF 9240...9243, 2SJ131
RFM 12 N08...N10	Rca	MOS-N-FET-e	VFET, 80...100V, 12A, 75W, <445/280ns	23a	TO-3			IRF 130...133, 2N6765
RFM 12 N18...N20	Rca	MOS-N-FET-e	VFET, 180...200V, 12A, 100W, <250/340ns	23a	TO-3			BUZ 36, BUZ 350, IRF 240...243, 2SK901
RFM 12 N35...N40	Rca	MOS-N-FET-e	VFET, 350...400V, 12A, 150W, <200/950ns	23a	TO-3			BUZ 323, IRF 350...353, 2SK788, 2SK899
RFM 12 P08...P10	Rca	MOS-P-FET-e	VFET, 80...100V, 12A, 100W, <235/450ns	23a	TO-3			IRF 9130...9132, 2SJ112...113
RFM 15 N05...N06	Rca	MOS-N-FET-e	VFET, 50...60V, 15A, 75W, <215/315ns	23a	TO-3			IRF 130...131, 2N6765, 2SK629
RFM 15 N12...N15	Rca	MOS-N-FET-e	VFET, 120...150V, 15A, 100W, <300/470ns	23a	TO-3			BUZ 36, BUZ 350, IRF 240...243, 2SK901
RFM 18 N08...N10	Rca	MOS-N-FET-e	VFET, 80...100V, 18A, 100W, <540/450ns	23a	TO-3			BUZ 24, BUZ 349, IRF 140...143, 2SK629
RFM 25 N06	Rca	MOS-N-FET-e	VFET, S P, 60V, 25A, 100W, <285/425ns	23a	TO-3			BUZ 76, IRF 610...613, 2SK923
RFP 2 N08...N10	Rca	MOS-N-FET-e	VFET, 80...100V, 2A, 25W, <70/70ns	17p	TO-220			BUZ 76, IRF 610...613, 2SK923
RFP 2 N12...N15	Rca	MOS-N-FET-e	VFET, 120...150V, 2A, 25W, <70/70ns	17p	TO-220			BUZ 76, IRF 610, IRF 612, 2SK923
RFP 2 N18...N20	Rca	MOS-N-FET-e	VFET, 180...200V, 2A, 25W, <55/65ns	17p	TO-220			BUZ 172, IRF 9510, IRF 9512
RFP 2 P08...P10	Rca	MOS-P-FET-e	VFET, 80...100V, 2A, 25W, <70/70ns	17p	TO-220			BUZ 41A...42, IRF 830...833, 2SK513
RFP 3 N45...N50	Rca	MOS-N-FET-e	VFET, 450...500V, 3A, 60W, <105/210ns	17p	TO-220			IRF 510...513, 2SK346, 2SK463, 2SK917, ++
RFP 4 N05...N06	Rca	MOS-N-FET-e	VFET, 50...60V, 4A, 25W, <45/55ns	17p	TO-220			IRF 9630...9633
RFP 4 N35...N40	Rca	MOS-N-FET-e	VFET, 350...400V, 4A, 60W, <105/300ns	17p	TO-220			IRF 840...843, 2SK554...555
RFP 5 P12...P15	Rca	MOS-P-FET-e	VFET, 120...150V, 5A, 60W, <160/250ns	17p	TO-220			IRF 9520
RFP 6 N45...N50	Rca	MOS-N-FET-e	VFET, 450...500V, 6A, 75W, <125/160ns	17p	TO-220			IRF 840...843, 2SK554...555
RFP 6 P08...P10	Rca	MOS-P-FET-e	VFET, 80...100V, 6A, 60W, <160/250ns	17p	TO-220			IRF 9520
RFP 7 N35...N40	Rca	MOS-N-FET-e	VFET, 350...400V, 7A, 75W, <120/350ns	17p	TO-220			IRF 840...843, 2SK554...555
RFP 8 N18...N20	Rca	MOS-N-FET-e	VFET, 180...200V, 8A, 60W, <195/240ns	17p	TO-220			BUZ 30, BUZ 73, IRF 630, IRF 632, 2SK741
RFP 8 P08...P10	Rca	MOS-P-FET-e	VFET, 80...100V, 8A, 75W, <210/450ns	17p	TO-220			IRF 9640...9643
RFP 10 N12...N15	Rca	MOS-N-FET-e	VFET, 120...150V, 10A, 60W, <310/270ns	17p	TO-220			BUZ 31...32, IRF 630, 2SK740, 2SK925
RFP 10 P12...P15	Rca	MOS-P-FET-e	VFET, 120...150V, 10A, 75W, <200/325ns	17p	TO-220			IRF 9640...9641
RFP 10 N08...N10	Rca	MOS-N-FET-e	VFET, 80...100V, 12A, 60W, <445/280ns	17p	TO-220			BUZ 20, IRF 640...643, 2SK919, 2SK922



Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International	
RFP 12 N18...N20	Rca	MOS-N-FET-e	VFET, 180...200V, 12A, 75W, <250/340ns	17p			BUZ 31, IRF 640, IRF 642, 2SK925	
RFP 12 P08...P10	Rca	MOS-P-FET-e	VFET, 80...100V, 12A, 75W, <235/450ns	17p	TO-220		IRF 9540, IRF 9542, 2SJ127	
RFP 15 N05...N06	Rca	MOS-N-FET-e	VFET, 50...60V, 15A, 60W, <215/315ns	17p	TO-220		BUZ 21, IRF 640...643, 2SK673, 2SK971, ++	
RFP 15 N12...N15	Rca	MOS-N-FET-e	VFET, 120...150V, 15A, 75W, <300/470ns	17p	TO-220		BUZ 30A, IRF 640...643	
RFP 18 N08...N10	Rca	MOS-N-FET-e	VFET, 80...100V, 18A, 75W, <540/450ns	17p	TO-220		BUZ 21...22, BUZ 30A, IRF 540, IRF 542	
RFP 25 N06	Rca	MOS-N-FET-e	VFET, S P, 60V, 25A, 75W, <285/425ns	17p	TO-220		BUZ 21...22, BUZ 30A, IRF 540...543	
RFs	Si-N		=BFP 181 (SMD-Marking)	44	SOT-143		•BFP 181	
RFs	Si-N		=BFR 181 (SMD-Marking)	35	SOT-23		•BFR 181	
<b>RG...RK</b>								
RG		Si-P+R	=RN 2427 (SMD-Marking)	35	SOT-23		•RN 2427	
RG 1 A...M	Gie	Si-Di	FRr, 50...1000V, 1A, Uf<1.3V(1A), <150...500ns A=50, B=100, D=200, G=400, J=600, K=800, M=1000V	31a	SOD-57	BYD 33 M	31a	BYT 52A...M, BYV 12...16, RGP 10A...M, ++
RG 1C	Sak	Si-Di	FRr, 1000V, 0.7A, Uf<3.3V(0.7A), 100ns	31a	DO-14	BA 159	31a	BA 159, BYT 52M, MR 818, RGP 10M, ++
RG 2 A...M	Gie	Si-Di	FRr, 50...1000V, 2A, Uf<1.3V(2A), <150...500ns A=50, B=100, D=200, G=400, J=600, K=800, M=1000V	31a	SOD-57	BYW 95 C(600V) BYW 96E(1000V)	31a 31a	BY 218/... BYV 37...38, BYW 95...96... ++
RG 2 A2	Sak	Si-Di	TV Damper-Di, 1300V, 0.5A, Uf<3.5V(0.5A), 100ns	31a	DO-14	(BY 228)	31a	BY 231/1400, BY 268...269, RGP 15-14
RG 2(A,Y,Z)	Sak	Si-Di	FRr, 70...600V, 0.5A, Uf<1.8V(1.5A), 100ns RG 2=400V, A=600V, Y=70V, Z=200	31a	DO-14	BA 159	31a	BY 201/... BYX 55/... RGP 10B...M, ++
RG 3 A...M	Gie	Si-Di	FRr, 50...1000V, 3A, Uf<1.3V(3A), <150...500ns A=50, B=100, D=200, G=400, J=600, K=800, M=1000V	31a	SOD-64	BYW 95 C(600V) BYW 96E(1000V)	31a 31a	BYW 95A...C, BYW 96D...E, RGP 30A...M, ++
RG 4 A...M	Gie	Si-Di	FRr, 50...1000V, 3A, Uf<1.3V(3A), <150...500ns A=50, B=100, D=200, G=400, J=600, K=800, M=1000V	31a	SOD-64	BYW 95 C(600V) BYW 96E(1000V)	31a 31a	BYW 95A...C, BYW 96D...E, RGP 30A...M, ++
RG 4	Sak	Si-Di	FRr, 400V, 3A, Uf<1.8V(3A), 100ns	31a	(8x7mm0)	BYW 95 C	31a	BYT 56G...M, BYW 74...76, BYW 95...96... ++
RG 4 A	Sak	Si-Di	FRr, 600V, 2A, Uf<2V(2A), 100ns	31a	(8x7mm0)	BYW 95 C	31a	BYT 56J...M, BYW 76, BYW 95...96... ++
RG 4 C	Sak	Si-Di	FRr, 1000V, 2A, Uf<3V(2A), 100ns	31a	(8x7mm0)	BYW 96 E	31a	BYT 56M, BYT 78, BYW 96E... RGP 30M, ++
RG 4 Y	Sak	Si-Di	FRr, 70V, 3.5A, Uf<1.3V(3.5A), 100ns	31a	(8x7mm0)	BYW 95 C	31a	BYT 56G...M, BYW 72...76, BYW 95...96... ++
RG 4 Z	Sak	Si-Di	FRr, 200V, 1.5A, Uf<1.7V(3A), 100ns	31a	(8x7mm0)	BYW 95 C	31a	BYT 56G...M, BYW 72...76, BYW 95...96... ++
RG 10	Sak	Si-Di	FRr, 400V, 1.2A, Uf<1.8V(1.5A), 100ns	31a	DO-14	BYD 33 M	31a	BYD 33G...M, BYV 13...16, BYV 95B...E, ++
RG 10 A	Sak	Si-Di	FRr, 600V, 1A, Uf<2V(1A), 100ns	31a	DO-14	BYD 33 M	31a	BYD 33J...M, BYV 14...16, BYV 95C...E, ++
RG 10 Y	Sak	Si-Di	FRr, 70V, 1.5A, Uf<1.1V(1.5A), 100ns	31a	DO-14	BYD 33 M	31a	BYD 33D...M, BYV 13...16, BYV 95A...E, ++
RGB 2932		IC	CTV, RGB Double-scan Processor					
RGL 27 A...M	Gie	Si-Di	=BYM 31/...					•BYM 31/...
RGL 34 A...M	Gie	Si-Di	=BYM 06/...					•BYM 06/...
RGL 41 A...M	Gie	Si-Di	=BYM 11/...					•BYM 11/...
RGM 30 A...M	Gie	Si-Di	Dual, FRr, 30A(Tc=100°), Uf<1.3V(15A), <150...500ns A=50, B=100, D=200, G=400, J=600, K=800, M=1000V	23f	TO-3			BYV 74/... FE 30A...G, MUR 3005...3060PT
RGM 30 AD...MD		Si-Di	=RGM 30A...M:	23s	TO-3			FE 30AD...GD
RGM 30 AN...MN		Si-Di	=RGM 30A...M:	23n	TO-3			FE 30AN...GN
RGP 01-10...20	Gie	Si-Di	Rr, S, 1000...2000V, 0.1A, Uf<1.5V(0.1A), <300ns	31a	SOD-22	BY 203/20	31a	BY 203/... SHG 1.5...2
RGP 10 A...M	Gie	Si-Di	FRr, 50...1000V, 1A, Uf<1.3V(1A), <150...500ns A=50, B=100, D=200, G=400, J=600, K=800, M=1000V	31a	SOD-22	BYD 33 M	31a	BYT 52A...M, BYV 12...16, RG 1A...M, ++
RGP 15 A...M	Gie	Si-Di	FRr, 50...1000V, 1.5A, Uf<1.3V(1.5A), <150...500ns A=50, B=100, D=200, G=400, J=600, K=800, M=1000V	31a	DO-15	BYD 33 M	31a	BYV 12...16, BYV 36A...E, RG 2A...M, ++
RGP 15-10...20	Gie	Si-Di	FRr, 1000...2000V, 1A, Uf<1.8V(1A), <250ns	31a	DO-15	BY 228(1600V)	31a	BY 231/... BY 228, BY 448
RGP 20 A...J	Gie	Si-Di	FRr, 50...600V, 2A, Uf<1.3V(2A), <150...250ns A=50, B=100, D=200, G=400, J=600V	31a	DO-27A	BYW 95 C	31a	BYM 26A...E, BYW 95A...C, BYW 32...36, ++
RGP 25 A...M	Gie	Si-Di	FRr, 50...1000V, 2.5A, Uf<1.3V(2.5A), <150...500ns A=50, B=100, D=200, G=400, J=600, K=800, M=1000V	31a	DO-27A	BYW 95 C(600V) BYW 96 E	31a 31a	BYT 56G...M, BYW 95A...C, BYW 96D...E, ++
RGP 30 A...M	Gie	Si-Di	FRr, 50...1000V, 3A, Uf<1.3V(3A), <150...500ns A=50, B=100, D=200, G=400, J=600, K=800, M=1000V	31a	DO-27A	RGP 30 M BYW 96 E RGP 30 M	31a 31a 31a	BYW 95A...C, BYW 96D...E, RG 3A...M, ++ BY 399S, BY 438, BYW 96E, RG 3M
RGP 80 A...M	Gie	Si-Di	P FRr, 8A(Tc=100°), Uf<1.2V(8A), <150...500ns A=50, B=100, D=200, G=400, J=600, K=800, M=1000V	17k	TO-200	BY 359/1500	17k	BY 329/... BY 359/... ESM 765/... ++
RGP 5005	Gie	Si-Di	FRr, 50V, 0.5A, Uf<1.2V(0.5A), <750ns	31a	SOD-22	BYD 33 M	31a	BY 208/... RGP 10A...M, MR 810...818, ++
RGP 5010	Gie	Si-Di	=RGP 5005: 100V	31a	SOD-22	BYD 33 M	31a	BY 208/... RGP 10B...M, MR 811...818, ++
RGP 5020	Gie	Si-Di	=RGP 5005: 200V	31a	SOD-22	BYD 33 M	31a	BY 208/... RGP 10D...M, MR 812...818, ++
RGP 5040	Gie	Si-Di	=RGP 5005: 400V	31a	SOD-22	BYD 33 M	31a	BY 208/... RGP 10G...M, MR 814...818, ++
RGP 5060	Gie	Si-Di	=RGP 5005: 600V	31a	SOD-22	BYD 33 M	31a	BY 208/... RGP 10J...M, MR 816...818, ++
RGP 5080	Gie	Si-Di	=RGP 5005: 800V, <1µs	31a	SOD-22	BYD 33 M	31a	BY 208/... RGP 10K...M, MR 817...818, ++
RGP 5100	Gie	Si-Di	=RGP 5005: 1000V, <1µs	31a	SOD-22	BYD 33 M	31a	BY 208/... BY 268, RGP 10M, MR 818, ++
RGPP 10 A...M	Sym	Si-Di	=RGP 10A...M	31a	DO-41	•RGP 10A...M		•RGP 10A...M
RGPP 15 A...M	Sym	Si-Di	=RGP 15A...M	31a	DO-15	•RGP 15A...M		•RGP 15A...M
RGPP 20 A...M	Sym	Si-Di	=RGP 20A...M	31a	DO-15	•RGP 20A...M		•RGP 20A...M
RGPP 30 A...M	Sym	Si-Di	=RGP 30A...M	31a	DO-27A	•RGP 30A...M		•RGP 30A...M
RGPP 60 A...M	Sym	Si-Di	FRr, 50...1000V, 6A, Uf<1.2V(6A), <150...500ns A=50, B=100, D=200, G=400, J=600, K=800, M=1000V	31a	(9x9mm0)			BYV 61...63, FE 6A...H
RGs	Si-N		=BFP 182 (SMD-Marking)	44	SOT-143			•BFP 182
RGs	Si-N		=BFR 182 (SMD-Marking)	35	SOT-23			•BFR 182
RH		Z-Di	=SM 4T 22 (SMD-Marking)	71a(6x4mm)	SOD-6			•SM 4T....
RH 1(A,B,C,Z)	Sak	Si-Di	FRr, 200...1000V, 0.6A, Uf<1.3V, 0.6A), <4µs RH 1=400V, A=600V, B=800V, C=1000V, Z=200V	31a	DO-14	BA 159	31a	BY 126...127, BY 133...134, 1N4003...07, ++
RH 2 F	Sak	Si-Di	TV-Damper-Di, 1500V, 1A, Uf<1V(1A), <4.2µs	31a	DO-14	BY 228	31a	BY 228, BY 448, DM 513, GP 10W...Y, ++
RH 3 F	Sak	Si-Di	TV-Damper-Di, 1500V, 2.5A, Uf<1.5V(2.5A), <4µs	31a	DO-27A	BY 228	31a	BY 228, BY 448
RH 4 F	Sak	Si-Di	TV-Damper-Di, 1500V, 1.5A, Uf<1V(1A), <4µs	31a	(8x7mm0)	BY 228	31a	BY 228, BY 448, BY 350/1500, GH 3F
RH 10 F	Sak	Si-Di	TV-Damper-Di, 1500V, 0.8A, Uf<1V(1A), <4µs	31a	DO-14	BY 228	31a	BY 228, BY 448, DM 513, GP 10W...Y, ++
RHF 1203 CX	Rhm	GaAs-FET	4V, 60mA, Idss=12...60mA, F=0.9/Gp=10.5dB(12GHz)	51(SGSD)	SOT-173			
RHs	Si-N		=BFP 183 (SMD-Marking)	44	SOT-143			•BFP 183
RHs	Si-N		=BFR 183 (SMD-Marking)	35	SOT-23			•BFR 183
RHs	Si-N		=BFP 196 (SMD-Marking)	44	SOT-143			•BFP 196
RJH 6674	Rca	Si-N	=2N6674:	18j	TO-3P			BUV 47(A), BUW 12(A), 2SC3042, 2SC4138++
RJH 6675	Rca	Si-N	=2N6675:	18j	TO-3P			BUV 47(A), BUW 12(A), 2SC3450, 2SC3637++
RJH 6676	Rca	Si-N	=2N6676:	18j	TO-3P			BUV 48(A), BUW 13(A), 2SC3520, 2SC4140++
RJH 6677	Rca	Si-N	=2N6677:	18j	TO-3P			BUV 48(A), BUW 13(A), 2SC3451, 2SC3638++
RJH 6678	Rca	Si-N	=2N6678:	18j	TO-3P			BUV 48(A), BUW 13(A), 2SC3451, 2SC3638++
RJH 6686	Rca	Si-N	=2N6686:	18j	TO-3P			BUW 50...52, BUX 70
RJH 6687	Rca	Si-N	=2N6687:	18j	TO-3P			BUW 51...52
RJH 6688	Rca	Si-N	=2N6688:	18j	TO-3P			BUW 51...52
RK		Z-Di	=SM 4T 22A (SMD-Marking)	71a(6x4mm)	SOD-6			•SM 4T....
RK 13	Sak	Si-Di	Schottky, S, 30V, 1.7A, Uf<0.55V(2A), 200ns	31a	DO-14			
RK 14	Sak	Si-Di	Schottky, S, 40V, 1.7A, Uf<0.55V(2A), 200ns	31a	DO-14			
RK 16	Sak	Si-Di	Schottky, S, 60V, 1.5A, Uf<0.62V(1.5A), 100ns	31a	SOD-22			
RK 19	Sak	Si-Di	Schottky, S, 90V, 1.5A, Uf<0.81V(1.5A), 100ns	31a	SOD-22			

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International	
RK 33	Sak	Si-Di	Schottky, S, 30V, 2.5A, Uf<0,55V(2,5A), 100ns	31a	DO-14	-	-	
RK 34	Sak	Si-Di	Schottky, S, 40V, 2.5A, Uf<0,55V(2,5A), 100ns	31a	DO-14	-	-	
RK 35	Sak	Si-Di	Schottky, S, 60V, 2A, Uf<0,62V(2A), 100ns	31a	DO-14	-	-	
RK 39	Sak	Si-Di	Schottky, S, 90V, 2A, Uf<0,81V(2A), 100ns	31a	DO-14	-	-	
RK 42	Sak	Si-Di	Schottky, S, 20V, 3A, Uf<0,47V(3A), 100ns	31a	(8x7mm0)	-	-	
RK 43	Sak	Si-Di	Schottky, S, 30V, 3A, Uf<0,55V(3A), 100ns	31a	(8x7mm0)	-	-	
RK 44	Sak	Si-Di	Schottky, S, 40V, 3A, Uf<0,55V(3A), 100ns	31a	(8x7mm0)	-	-	
RK 46	Sak	Si-Di	Schottky, S, 60V, 3.5A, Uf<0,62V(3,5A), 100ns	31a	(8x7mm0)	-	-	
RK 49	Sak	Si-Di	Schottky, S, 90V, 3.5A, Uf<0,81V(3,5A), 100ns	31a	(8x7mm0)	-	-	
RKs		Si-P	=BFP 194 (SMD-Marking)	44	SOT-143		-BFP 194	
RKs		Si-P	=BFR 194 (SMD-Marking)	35	SOT-23		-BFR 194	
<b>RL</b>								
RL		Si-P	=2SA1563 (SMD-Marking)	35	SOT-23		-2SA1563	
RL		Z-Di	=SM 4T 24 (SMD-Marking)	71a(6x4mm)	SOD-6		-SM 4T....	
RL 2 Z	Sak	Si-Di	FRr, 200V, 2A, Uf<0,98(2A), 50ns	31a	DO-14	BYV 27/200	31a	BY 218/200, BYV 27/200, BYW 32...36,++
RL 3 Z	Sak	Si-Di	FRr, 200V, 3.5A, Uf<0,95(3,5A), 50ns	31a	DO-27	BYV 28/200	31a	BY 318/200, BYV 28/200, BYW 16/200,++
RL 4 Z	Sak	Si-Di	FRr, 200V, 3.5A, Uf<0,95(3,5A), 50ns	31a	(8x7mm0)	BYV 28/200	31a	BY 318/200, BYV 28/200, BYW 16/200,++
RL 10 Z	Sak	Si-Di	FRr, 200V, 2A, Uf<0,98(2A), 50ns	31a	DO-14	BYV 27/200	31a	BY 318/200, BYV 28/200, BYW 16/200,++
RL 31(g)	Sie	Ge-Di	=AA 113	31a	AA 138	31a	AA 113	
RL 32(g)	Sie	Ge-Di	Dem, hi-ohm, 45V, 15mA	31a	AA 138	31a	AA 113, AA 119, 1N34, 1N54, 1N60	
RL 34(g)	Sie	Ge-Di	Uni, 75V, 50mA	31a	AA 133	31a	AA 117...118, AA 132...133	
RL 41(g)	Sie	Ge-Di	Dem, lo-ohm, 22.5V, 50mA	31a	AA 138	31a	AA 114, AA 116, 1N60	
RL 43(g)	Sie	Ge-Di	Uni, 115V, 50mA	31a	AA 133	31a	AA 117...118, AA 132...133	
RL 44(g)	Sie	Ge-Di	Uni, 115V, 50mA	31a	AA 133	31a	AA 117...118, AA 132...133	
RL 52	Sie	Ge-Di	Dem, hi-ohm, 45V, 20mA	31a	AA 119	31a	AA 113, AA 119, 1N34, 1N54, 1N60	
RL 53		Ge-Di	=AA 117				-AA 117	
RL 54		Ge-Di	=AA 118				-AA 118	
RL 101		Ge-Di	=AA 116				-AA 116	
RL 102		Ge-Di	=AA 116				-AA 116	
RL 103		Ge-Di	=AA 113				-AA 113	
RL 104		Ge-Di	=AA 119				-AA 119	
RL 105		Ge-Di	=AA 119				-AA 119	
RL 106		Ge-Di	=AA 119				-AA 119	
RL 107		Ge-Di	=AA 27				-AA 27	
RL 108		Ge-Di	=AA 28				-AA 28	
RL 109		Ge-Di	=AA 27				-AA 27	
RL 110		Ge-Di	=AA 113				-AA 113	
RL 111		Ge-Di	=AA 113				-AA 113	
RL 112		Ge-Di	=AA 113				-AA 113	
RL 113		Ge-Di	=AA 113				-AA 113	
RL 114		Ge-Di	=AA 117				-AA 117	
RL 115		Ge-Di	=AA 117				-AA 117	
RL 116		Ge-Di	=AA 117				-AA 117	
RL 118		Ge-Di	=AA 117				-AA 117	
RL 119		Ge-Di	=AA 117				-AA 117	
RL 120		Ge-Di	=AA 28				-AA 28	
RL 121		Ge-Di	=AA 118				-AA 118	
RL 122		Ge-Di	=AA 118				-AA 118	
RL 131	Sie	Ge-Di	=AA 119				-AA 119	
RL 132	Sie	Ge-Di	=AA 119				-AA 119	
RL 133	Sie	Ge-Di	=AA 116				-AA 116	
RL 141	Sie	Ge-Di	=AA 116				-AA 116	
RL 143	Sie	Ge-Di	=AA 117				-AA 117	
RL 232(g)	Sie	Ge-Di	=2x RL 32: Matched Pair	31a	2x AA 119	31a	-RL 32	
RL 233	Sie	Ge-Di	=2x AA 113	31a	2x AA 119	31a	-AA 113	
RL 246(g)	Sie	Ge-Di	=AA 118	31a	AA 133	31a	-AA 118	
RL 247(g)	Sie	Ge-Di	=2x RL 44: Matched Pair	31a	AA 133	31a	-RL 44	
RL 252	Sie	Ge-Di	=2x RL 52: Matched Pair	31a	2x AA 119	31a	-RL 52	
RLR 4001...4004	Sak	Si-Di	=1N4001...4004: 0.8A, Uf<1V(0,8A)	72a(5mm)	(MELF)		SM 4001...4004	
RLS 4148...4154	Rhm	Si-Di	=1N4148...4154: SMD	72a(3,4mm)	SOD-80	1N4148 SMD	72a(3,4mm) BAS 32, LL 4148	
RLS 4446...4450	Rhm	Si-Di	=1N4446...4450: SMD	72a(3,4mm)	SOD-80	1N4148 SMD	72a(3,4mm) BAS 32, LL 4148	
RLS 4454	Rhm	Si-Di	=1N4454: SMD	72a(3,4mm)	SOD-80	1N4148 SMD	72a(3,4mm) BAS 32, LL 4148	
RLS 4606	Rhm	Si-Di	=1N4606: SMD	72a(3,4mm)	SOD-80		-	
RLZ 2.0...56(A...D)	Rhm	Z-Di	SMD, 2...39V, ±5%, 0,4W, A=-9...-4%, B=-6...-1%, C=-3...+2%, D=-1...+4%	72a(3,4mm)	SOD-80	Z-Di ...V(SMD)	72a(3,4mm) BZD 27/..., BZV 55/..., HZK ... (L)	
RLZ 5221B...5252B	Rhm	Z-Di	=1N5221B...5252B: SMD, 0,4W	72a(3,4mm)	SOD-80	Z-Di ...V(SMD)	72a(3,4mm) BZD 27/..., BZV 55/..., HZK ... (L), RLZ ... (J)	
RLZ 2.0...24J(A...C)	Rhm	Z-Di	SMD, 2...24V, ±5%, 0,4W, A=-5...-0%, B=+2,5%, C=0...+5%	72a(3,4mm)	SOD-80	Z-Di ...V(SMD)	72a(3,4mm) BZD 27/..., BZV 55/..., HZK ... (L)	
<b>RM...RS</b>								
RM		Z-Di	=SM 4T 24A (SMD-Marking)	71a(6x4mm)	SOD-6		-SM 4T....	
RM 1(A...Z)	Sak	Si-Di	Rr, 200...1500V, 1...0,5A, Uf<0,95...1,4V(1A) RM 1=400/1, A=600/1, B=800/0,8, C=1000V/0,8A, D=1200/0,6, E=1400/0,6, F=1500/0,5, Z=200V/1A	31a	=DO-14	BY 133	31a	BY 126...127, GP 100...Y, 1N4003...07, ++
RM 2(A...Z)	Sak	Si-Di	Rr, 200...1000V, 1,2A, Uf<0,91V(1,5A) RM 2=400V, A=600V, B=800V, C=1000V, Z=200V	31a	=DO-14	BY 255	31a	BY 226...227, BY 251...255, 1N5393...99, ++
RM 3(A)	Sak	Si-Di	Rr, 400...600V, 2,5A, Uf<0,95V(2,5A) RM 3=400V, A=600V	31a	DO-27A	BY 255	31a	BY 251...255, BYW 17/..., 1N5406...08, ++
RM 3.3...39	Tho	Z-Di	=BZX 84C3V3...C39	35p	SOT-23		-BZX 84C...	
RM 4(A...Z)	Sak	Si-Di	Rr, 100...1000V, 3A, Uf<0,95V(3A) RM 4=400, A=AM=600, B=800, C=1000, Y=100, Z=200V	31a	(8x7mm0)	BY 255	31a	BY 251...255, BYW 17/..., 1N5401...08, ++
RM 10(A...Z)	Sak	Si-Di	Rr, 200...800V, 1,2A, Uf<0,91V(1,5A) RM 10=400V, A=600V, B=800V, Z=200V	31a	=DO-14	BY 255	31a	BY 226...227, BY 251...255, 1N5393...99, ++
RM 11 A,B,C	Sak	Si-Di	Rr, 600...1000V, 1,2A, Uf<0,92V(1,5A) RM 11A=600V, B=800V, C=1000V	31a	=DO-14	BY 255	31a	BY 226...227, BY 251...255, 1N5397...99, ++
RM 25	Sak	Z-Di	Avalanche, 50...61.5V	31a	=DO-14		-	
RM 26	Sak	Z-Di	Avalanche, 60...70V	31a	=DO-14		-	
RM 555	Ray	LIN-IC	Timer	8-DIP	NE 555 N	8-DIP	NE 555	
RM 723 T	Ray	Z-IC	+2...37V, 0,15A	TO-100	723/TO	TO-100	... 723...	
RM 741 T	Ray	OP-IC	Uni, Serie 741, ±22V, -55...+125°	TO-99	741/TO	TO-99	... 741...	
RM 747 T	Ray	OP-IC	Dual, Serie 747, ±22V, -55...+125°	TO-100			... 747...	
RM 1558	Ray	OP-IC	Dual, Serie 158	8-DIP	(4558/8-D) <sup>16</sup>	8-DIP	... 158... 1558...	
RM 4136 FK	Ray,Tix	OP-IC	=RC 4136: SMD, ±22V, -22...+125°	20-LCC			-	

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International
RM 4136 J	Ray,Tix	OP-IC	=RC 4136: ±22V, -22...+125°	14-DIC			µA 4136DM
RM 4193 JG	Ray,Tix	Z-IC	=RC 4193: ...55...+125°	8-DIC			
RM 4558 JG	Ray,Tix	OP-IC	=RC 4558DE,JG,P: ±22V, -55...+125°	8-DIC			... 158 ..... 1558...
RN		Z-Di	=SM 4T 27 (SMD-Marking)	71a(6x4mm)	SOD-6		=SM 4T....
RN 30 AP...MP	Gie	Si-Di	=RP 16 AP...MP:	16h	TO-247		
RN 1001	Tos	Si-N+R	S, Rb=Rbe=4,7kΩ, 50/50V, 0,1A, 0,4W, 250MHz	(RN2001	7c	TO-92	AA 1L3M, DTC 143ES, UN 421L, 2SC4363,++
RN 1002	Tos	Si-N+R	=RN 1001: Rb=Rbe=10kΩ	(RN2002	7c	TO-92	AA 1A4M, DTC 114ES, UN 4211, 2SC3402,++
RN 1003	Tos	Si-N+R	=RN 1001: Rb=Rbe=22kΩ	(RN2003	7c	TO-92	AA 1F4M, DTC 124ES, UN 4212, 2SC3400,++
RN 1004	Tos	Si-N+R	=RN 1001: Rb=Rbe=47kΩ	(RN2004	7c	TO-92	AA 1L4M, DTC 144ES, UN 4213, 2SC3399,++
RN 1005	Tos	Si-N+R	=RN 1001: Rb=2,2k, Rbe=47kΩ	(RN2005	7c	TO-92	DTC 123JS, KSR 1013
RN 1006	Tos	Si-N+R	=RN 1001: Rb=4,7k, Rbe=47kΩ	(RN2006	7c	TO-92	DTC 143ZS, KSR 1014, 2SC4133, 2SC4195
RN 1007	Tos	Si-N+R	=RN 1001: Rb=10k, Rbe=47kΩ	(RN2007	7c	TO-92	AA 1A4P, DTC 114YS, UN 4214, 2SC4048,++
RN 1008	Tos	Si-N+R	=RN 1001: Rb=22k, Rbe=47kΩ	(RN2008	7c	TO-92	AA 1F4N, DTC 124XS, KSR 1007
RN 1009	Tos	Si-N+R	=RN 1001: Rb=47k, Rbe=22kΩ	(RN2009	7c	TO-92	AA 1L4L, DTC 144WS, UN 421E, 2SC3401,++
RN 1010	Tos	Si-N+R	=RN 1001: Rb=4,7kΩ, Rbe=-	(RN2010	7c	TO-92	AA 1L3Z, DTC 143TS, UN 4216, 2SC3901,++
RN 1011	Tos	Si-N+R	=RN 1001: Rb=10kΩ, Rbe=-	(RN2011	7c	TO-92	AA 1A4Z, DTC 114TS, UN 4215, 2SC3860,++
RN 1101	Tos	Si-N+R	=RN 1001: SMD	(RN2101	35a(1,6mm)	SS Mini	DTC 143EE
RN 1102	Tos	Si-N+R	=RN 1002: SMD	(RN2102	35a(1,6mm)	SS Mini	DTC 114EE
RN 1103	Tos	Si-N+R	=RN 1003: SMD	(RN2103	35a(1,6mm)	SS Mini	DTC 124EE
RN 1104	Tos	Si-N+R	=RN 1004: SMD	(RN2104	35a(1,6mm)	SS Mini	DTC 144EE
RN 1105	Tos	Si-N+R	=RN 1005: SMD	(RN2105	35a(1,6mm)	SS Mini	DTC 123JE
RN 1106	Tos	Si-N+R	=RN 1006: SMD	(RN2106	35a(1,6mm)	SS Mini	DTC 143ZE
RN 1107	Tos	Si-N+R	=RN 1007: SMD	(RN2107	35a(1,6mm)	SS Mini	DTC 114YE
RN 1108	Tos	Si-N+R	=RN 1008: SMD	(RN2108	35a(1,6mm)	SS Mini	DTC 124XE
RN 1109	Tos	Si-N+R	=RN 1009: SMD	(RN2109	35a(1,6mm)	SS Mini	DTC 144WE
RN 1110	Tos	Si-N+R	=RN 1010: SMD	(RN2110	35a(1,6mm)	SS Mini	DTC 143TE
RN 1111	Tos	Si-N+R	=RN 1011: SMD	(RN2111	35a(1,6mm)	SS Mini	DTC 114TE
RN 1201...1211	Tos	Si-N+R	=RN 1001...1011:	(RN2201...11	41c	-RN 1001...	-RN 1001...1011
RN 1221	Tos	Si-N+R	S, Rb=Rbe=1kΩ, 50/50V, 0,8A, 0,3W, 300MHz	(RN2221	41c		
RN 1222	Tos	Si-N+R	=RN 1221: Rb=Rbe=2,2kΩ	(RN2222	41c		
RN 1223	Tos	Si-N+R	=RN 1221: Rb=Rbe=4,7kΩ	(RN2223	41c		
RN 1224	Tos	Si-N+R	=RN 1221: Rb=Rbe=10kΩ	(RN2224	41c		
RN 1225	Tos	Si-N+R	=RN 1221: Rb=0,47k, Rbe=10kΩ	(RN2225	41c		
RN 1226	Tos	Si-N+R	=RN 1221: Rb=1k, Rbe=10kΩ	(RN2226	41c		
RN 1227	Tos	Si-N+R	=RN 1221: Rb=2,2k, Rbe=10kΩ	(RN2227	41c		
RN 1241	Tos	Si-N+R	S, Rb=5,6kΩ, Rbe=-, 50/20V, 0,3A, 0,3W, 30MHz		41c		
RN 1242	Tos	Si-N+R	=RN 1241: Rb=10kΩ, Rbe=-		41c		
RN 1243	Tos	Si-N+R	=RN 1241: Rb=22kΩ, Rbe=-		41c		
RN 1244	Tos	Si-N+R	=RN 1241: Rb=2,2kΩ, Rbe=-		41c		
RN 1301	Tos	Si-N+R	=RN 1001: SMD	(RN2301	35a(2mm)	SOT-323	DTC 143EU
RN 1302	Tos	Si-N+R	=RN 1002: SMD	(RN2302	35a(2mm)	SOT-323	DTC 114EU, 2SC4398
RN 1303	Tos	Si-N+R	=RN 1003: SMD	(RN2303	35a(2mm)	SOT-323	DTC 124EU, 2SC4397
RN 1304	Tos	Si-N+R	=RN 1004: SMD	(RN2304	35a(2mm)	SOT-323	DTC 144EU, 2SC4396
RN 1305	Tos	Si-N+R	=RN 1005: SMD	(RN2305	35a(2mm)	SOT-323	DTC 123JU
RN 1306	Tos	Si-N+R	=RN 1006: SMD	(RN2306	35a(2mm)	SOT-323	DTC 143ZU
RN 1307	Tos	Si-N+R	=RN 1007: SMD	(RN2307	35a(2mm)	SOT-323	DTC 114YU
RN 1308	Tos	Si-N+R	=RN 1008: SMD	(RN2308	35a(2mm)	SOT-323	DTC 124XU
RN 1309	Tos	Si-N+R	=RN 1009: SMD	(RN2309	35a(2mm)	SOT-323	DTC 144WU
RN 1310	Tos	Si-N+R	=RN 1010: SMD	(RN2310	35a(2mm)	SOT-323	DTC 143TU
RN 1311	Tos	Si-N+R	=RN 1011: SMD	(RN2311	35a(2mm)	SOT-323	DTC 114TU
RN 1401	Tos	Si-N+R	=RN 1001: SMD	(RN2401	35a	SOT-23	FA 1L3M, DTC 143EK, UN 221L, 2SC4362,++
RN 1402	Tos	Si-N+R	=RN 1002: SMD	(RN2402	35a	SOT-23	FA 1A4M, DTC 114EK, UN 2211, 2SC3398,++
RN 1403	Tos	Si-N+R	=RN 1003: SMD	(RN2403	35a	SOT-23	FA 1F4M, DTC 124EK, UN 2212, 2SC3396,++
RN 1404	Tos	Si-N+R	=RN 1004: SMD	(RN2404	35a	SOT-23	FA 1L4M, DTC 144EK, UN 2213, 2SC3395,++
RN 1405	Tos	Si-N+R	=RN 1005: SMD	(RN2405	35a	SOT-23	BCR 108, DTC 123JK, KSR 1113
RN 1406	Tos	Si-N+R	=RN 1006: SMD	(RN2406	35a	SOT-23	DTC 143ZK, KSR 1114, 2SC4146
RN 1407	Tos	Si-N+R	=RN 1007: SMD	(RN2407	35a	SOT-23	FA 1A4P, DTC 114YK, UN 2214, 2SC4047,++
RN 1408	Tos	Si-N+R	=RN 1008: SMD	(RN2408	35a	SOT-23	BCR 142, FA 1F4M, DTC 124XK, KSR 1107
RN 1409	Tos	Si-N+R	=RN 1009: SMD	(RN2409	35a	SOT-23	FA 1L4L, DTC 144WK, UN 221E, 2SC3397,++
RN 1410	Tos	Si-N+R	=RN 1010: SMD	(RN2410	35a	SOT-23	FA 1L3Z, DTC 143TK, UN 2216, 2SC3900,++
RN 1411	Tos	Si-N+R	=RN 1011: SMD	(RN2411	35a	SOT-23	FA 1A4Z, DTC 114TK, UN 2215, 2SC3859,++
RN 1421...1427	Tos	Si-N+R	=RN 1221...1227: SMD	(RN2421...27	35a	SOT-23	
RN 1441...1444	Tos	Si-N+R	=RN 1241...1244: SMD	(RN2441...44	35a	SOT-23	
RN 1501...1511	Tos	Si-N+R	=RN 1001...1011: SMD, Dual	(RN2501...11	45	SOT-153	
RN 1601...1611	Tos	Si-N+R	=RN 1001...1011: SMD, Dual	(RN2601...11	46	SOT-163	
RN 1801	Tos	Si-N+R	Buzzer Drv, 30/30V, hi-Ueb=30V, 15/30mA, 0,3W Rb=18k, Rbc=100k, Rc=680Ω	42(ECBC)	(4x4x2,5)		
RN 1901...1911	Tos	Si-N+R	=RN 1001...1011: SMD, Dual	(RN2901...11	46(2mm)	SOT-363	
RN 2001	Tos	Si-P+R	S, Rb=Rbe=4,7kΩ, 50/50V, 0,1A, 0,4W, 200MHz	(RN1001	7c	TO-92	AN 1L3M, DTA 143ES, UN 411L, 2SA1656,++
RN 2002	Tos	Si-P+R	=RN 2001: Rb=Rbe=10kΩ	(RN1002	7c	TO-92	AN 1A4M, DTA 114ES, UN 4111, 2SA1348,++
RN 2003	Tos	Si-P+R	=RN 2001: Rb=Rbe=22kΩ	(RN1003	7c	TO-92	AN 1F4M, DTA 124ES, UN 4112, 2SA1346,++
RN 2004	Tos	Si-P+R	=RN 2001: Rb=Rbe=47kΩ	(RN1004	7c	TO-92	AN 1F4M, DTA 124ES, UN 4112, 2SA1346,++
RN 2005	Tos	Si-P+R	=RN 2001: Rb=2,2k, Rbe=47kΩ	(RN1005	7c	TO-92	DTA 123JS, KSR 2013
RN 2006	Tos	Si-P+R	=RN 2001: Rb=4,7k, Rbe=47kΩ	(RN1006	7c	TO-92	DTA 143ZS, KSR 2014, 2SA1591, 2SA1616
RN 2007	Tos	Si-P+R	=RN 2001: Rb=10k, Rbe=47kΩ	(RN1007	7c	TO-92	AN 1A4P, DTA 114YS, UN 4114, 2SA1564,++
RN 2008	Tos	Si-P+R	=RN 2001: Rb=22k, Rbe=47kΩ	(RN1008	7c	TO-92	AN 1F4N, DTA 124XS, KSR 2007
RN 2009	Tos	Si-P+R	=RN 2001: Rb=47k, Rbe=22kΩ	(RN1009	7c	TO-92	AN 1L4L, DTA 144WS, UN 411E, 2SA1347,++
RN 2010	Tos	Si-P+R	=RN 2001: Rb=4,7kΩ, Rbe=-	(RN1010	7c	TO-92	AN 1L3Z, DTA 143TS, UN 4116, 2SA1511,++
RN 2011	Tos	Si-P+R	=RN 2001: Rb=10kΩ, Rbe=-	(RN1011	7c	TO-92	AN 1A4Z, DTA 114TS, UN 4115, 2SA1497,++
RN 2101	Tos	Si-P+R	=RN 2001: SMD	(RN1101	35a(1,6mm)	SS Mini	DTA 143EE
RN 2102	Tos	Si-P+R	=RN 2002: SMD	(RN1102	35a(1,6mm)	SS Mini	DTA 114EE
RN 2103	Tos	Si-P+R	=RN 2003: SMD	(RN1103	35a(1,6mm)	SS Mini	DTA 124EE
RN 2104	Tos	Si-P+R	=RN 2004: SMD	(RN1104	35a(1,6mm)	SS Mini	DTA 144EE
RN 2105	Tos	Si-P+R	=RN 2005: SMD	(RN1105	35a(1,6mm)	SS Mini	DTA 123JE
RN 2106	Tos	Si-P+R	=RN 2006: SMD	(RN1106	35a(1,6mm)	SS Mini	DTA 143ZE
RN 2107	Tos	Si-P+R	=RN 2007: SMD	(RN1107	35a(1,6mm)	SS Mini	DTA 114YE
RN 2108	Tos	Si-P+R	=RN 2008: SMD	(RN1108	35a(1,6mm)	SS Mini	DTA 124XE
RN 2109	Tos	Si-P+R	=RN 2009: SMD	(RN1109	35a(1,6mm)	SS Mini	DTA 144WE
RN 2110	Tos	Si-P+R	=RN 2010: SMD	(RN1110	35a(1,6mm)	SS Mini	DTA 143TE
RN 2111	Tos	Si-P+R	=RN 2011: SMD	(RN1111	35a(1,6mm)	SS Mini	DTA 114TE
RN 2201...2211	Tos	Si-P+R	=RN 2001...2011:	(RN1201...11	41c	-RN 2001...	-RN 2001...2011
RN 2221	Tos	Si-P+R	S, Rb=Rbe=1kΩ, 50/50V, 0,8A, 0,3W, 200MHz	(RN1221	41c		
RN 2222	Tos	Si-P+R	=RN 2221: Rb=Rbe=2,2kΩ	(RN1222	41c		

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International	
RN 2223	Tos	Si-P+R	=RN 2221: Rb=Rbe=4,7kΩ	{RN1223 41c			-	
RN 2224	Tos	Si-P+R	=RN 2221: Rb=Rbe=10kΩ	{RN1224 41c			-	
RN 2225	Tos	Si-P+R	=RN 2221: Rb=0,47k, Rbe=10kΩ	{RN1225 41c			-	
RN 2226	Tos	Si-P+R	=RN 2221: Rb=1k, Rbe=10kΩ	{RN1226 41c			-	
RN 2227	Tos	Si-P+R	=RN 2221: Rb=2,2k, Rbe=10kΩ	{RN1227 41c			-	
RN 2301	Tos	Si-P+R	=RN 2001: SMD	{RN1301 35a(2mm)	SOT-323		DTA 143EU	
RN 2302	Tos	Si-P+R	=RN 2002: SMD	{RN1302 35a(2mm)	SOT-323		DTA 114EU, 2SA1678	
RN 2303	Tos	Si-P+R	=RN 2003: SMD	{RN1303 35a(2mm)	SOT-323		DTA 124EU, 2SA1677	
RN 2304	Tos	Si-P+R	=RN 2004: SMD	{RN1304 35a(2mm)	SOT-323		DTA 144EU, 2SA1676	
RN 2305	Tos	Si-P+R	=RN 2005: SMD	{RN1305 35a(2mm)	SOT-323		DTA 123JU	
RN 2306	Tos	Si-P+R	=RN 2006: SMD	{RN1306 35a(2mm)	SOT-323		DTA 143ZU	
RN 2307	Tos	Si-P+R	=RN 2007: SMD	{RN1307 35a(2mm)	SOT-323		DTA 114YU	
RN 2308	Tos	Si-P+R	=RN 2008: SMD	{RN1308 35a(2mm)	SOT-323		DTA 124XU	
RN 2309	Tos	Si-P+R	=RN 2009: SMD	{RN1309 35a(2mm)	SOT-323		DTA 144WU	
RN 2310	Tos	Si-P+R	=RN 2010: SMD	{RN1310 35a(2mm)	SOT-323		DTA 143TU	
RN 2311	Tos	Si-P+R	=RN 2011: SMD	{RN1311 35a(2mm)	SOT-323		DTA 114TU	
RN 2401	Tos	Si-P+R	=RN 2001: SMD	{RN1401 35a	SOT-23		FN 1L3M, DTA 143EK, UN 211L, 2SA1655,++	
RN 2402	Tos	Si-P+R	=RN 2002: SMD	{RN1402 35a	SOT-23		FN 1A4M, DTA 114EK, UN 2111, 2SA1344,++	
RN 2403	Tos	Si-P+R	=RN 2003: SMD	{RN1403 35a	SOT-23		FN 1F4M, DTA 124EK, UN 2112, 2SA1342,++	
RN 2404	Tos	Si-P+R	=RN 2004: SMD	{RN1404 35a	SOT-23		FN 1L4M, DTA 144EK, UN 2113, 2SA1341,++	
RN 2405	Tos	Si-P+R	=RN 2005: SMD	{RN1405 35a	SOT-23		DTA 123JK, KSR 2113	
RN 2406	Tos	Si-P+R	=RN 2006: SMD	{RN1406 35a	SOT-23		DTA 143ZK, KSR 2114	
RN 2407	Tos	Si-P+R	=RN 2007: SMD	{RN1407 35a	SOT-23		FN 1A4P, DTA 114YK, UN 2114, 2SA1563,++	
RN 2408	Tos	Si-P+R	=RN 2008: SMD	{RN1408 35a	SOT-23		BCR 192, FN 1F4N, DTA 124XK, KSR 2107	
RN 2409	Tos	Si-P+R	=RN 2009: SMD	{RN1409 35a	SOT-23		FN 1L4L, DTA 144WK, UN 211E, 2SA1343,++	
RN 2410	Tos	Si-P+R	=RN 2010: SMD	{RN1410 35a	SOT-23		FN 1L3Z, DTA 143TK, UN 2116, 2SA1510,++	
RN 2411	Tos	Si-P+R	=RN 2011: SMD	{RN1411 35a	SOT-23		FN 1A4Z, DTA 114TK, UN 2115, 2SA1496,++	
RN 2421...2427	Tos	Si-P+R	=RN 2221...2227: SMD	{RN1421...27 35a	SOT-23		-	
RN 2501...2511	Tos	Si-P+R	=RN 2001...2011: SMD, Dual	{RN1501...11 45	SOT-153		-	
RN 2601...2611	Tos	Si-P+R	=RN 2001...2011: SMD, Dual	{RN1601...11 46	SOT-163		-	
RN 2901...2911	Tos	Si-P+R	=RN 2001...2011: SMD, Dual	{RN1901...11 46(2mm)	SOT-363		-	
RN 4601	Tos	Si-P/N+R	=RN 2001+1001: SMD	46	SOT-163		-	
RN 4602	Tos	Si-P/N+R	=RN 2002+1002: SMD	46	SOT-163		-	
RN 4603	Tos	Si-P/N+R	=RN 2003+1003: SMD	46	SOT-163		-	
RN 4604	Tos	Si-P/N+R	=RN 2004+1004: SMD	46	SOT-163		-	
RN 4605	Tos	Si-P/N+R	=RN 2005+1005: SMD	46	SOT-163		-	
RN 4606	Tos	Si-P/N+R	=RN 2006+1006: SMD	46	SOT-163		-	
RN 4607	Tos	Si-P/N+R	=RN 2007+1007: SMD	46	SOT-163		-	
RN 4608	Tos	Si-P/N+R	=RN 2008+1008: SMD	46	SOT-163		-	
RN 4609	Tos	Si-P/N+R	=RN 2009+1009: SMD	46	SOT-163		-	
RN 4610	Tos	Si-P/N+R	=RN 2010+1010: SMD	46	SOT-163		-	
RN 4611	Tos	Si-P/N+R	=RN 2011+1011: SMD	46	SOT-163		-	
RN 5001	Tos	Si-N+R	SMD, S, Motor Drv, Rbe=2kΩ, 30V, 2A, 120MHz	{RN6001 39b	SOT-89		-	
RN 5002	Tos	Si-N+R	=RN 5001: Rbe=5,6kΩ	{RN6002 39b	SOT-89		-	
RN 5003	Tos	Si-N+R	=RN 5001: Rbe=10kΩ	{RN6003 39b	SOT-89		-	
RN 5006	Tos	Si-N+R+Di	=RN 5001: Rbe=10kΩ, Damper-Diode, 140MHz	{RN6006 39b	SOT-89		-	
RN 6001	Tos	Si-P+R	SMD, S, Motor Drv, Rbe=2kΩ, 30V, 2A, 120MHz	{RN5001 39b	SOT-89		-	
RN 6002	Tos	Si-P+R	=RN 6001: Rbe=5,6kΩ	{RN5002 39b	SOT-89		-	
RN 6003	Tos	Si-P+R	=RN 6001: Rbe=10kΩ	{RN5003 39b	SOT-89		-	
RN 6006	Tos	Si-P+R+Di	=RN 6001: Rbe=10kΩ, Damper-Diode, 140MHz	{RN5006 39b	SOT-89		-	
RO		Si-P	=2SA1204-O (SMD-Marking)	39	SOT-89		*2SA1204	
RO		Si-N	=2SC2715-O (SMD-Marking)	35	SOT-23		*2SC2715	
RO		Si-P	=KTA1664-O (SMD-Marking)	39	SOT-89		*KTA 1664	
RO		Si-N	=KTC3879-O (SMD-Marking)	35	SOT-23		*KTC 3879	
RO 2(A...Z)	Sak	Si-Di	Rr, 200...1000V, 1,2A, Uf<0,92V(1,5A) RO 2=400V, A=600V, B=800V, C=1000V, Z=200V	31a	DO-14	BY 133	31a	BY 226...227, BY 251...255, 1N5393...99, ++
RP		Z-Di	=SM 4T 27A (SMD-Marking)	71a(6x4mm)	SOD-6		-	*SM 4T....
RH 1 H	Sak	Si-Di	FRr, 2000V, 0,1A, Uf<7V(0,1A), 200ns	31a	DO-14	BY 203/20	31a	BY 203/20, SHG 2
RP 2,7...33	Tho	Z-Di	=ZP 2,7...33	31a	DO-35	Z-Diode ...V	31a	BZX55/..., BZX83/..., BZX97/..., ZPD....,++
RP 4 Z	Sak	Si-Di	FRr, 200V, 3A, Uf<1V(3A), 400ns	31a	(7x7mmØ)	BYW 95 C	31a	BY 397...399, BYW 72...76, BYW 95A...C,++
RP 16 AT...KT	Gie	Si-Di	Dual, S P, 50...800V, 16A, <150...500ns	17e	TO-220			FE 16A...J, MUR 1605CT...1660CT
RP 30 A...M	Sym	Si-Di	FRr, 50...1000V, 3A, Uf<1,35V(3A), <250...500ns A=50, B=100, D=200, G=400, J=600, K=800, M=1000V	31a	DO-27A	RGP 30 M	31a	BYW95A...C, BYW96D...E, RG3A...M, RGP30A...M
RP 30 AP...MP	Gie	Si-Di	Dual, Rr-S, 50...1000V, 30A,<150...500ns	16e	TO-247			RGP 30AP...MP, MUR 3005PT...3060PT
RP 30...M		Si-Di	=RP 30 AP...MP:	23f	TO-3			-
RP 300 A...M	Gie	Si-Di	FRr, 50...1000V, 3A, Uf<1,25V(9,4A), <200...500ns A=50, B=100, D=200, G=400, J=600, K=800, M=1000V	31a	DO-27A	BYW 96 E	31a	BYW 95A...C, BYW 96D...E, RGP 30A...M, ++
RPD 2,7...130	Tho	Z-Di	2,7...130V, 5%, 0,5W	31a	DO-35	Z-Diode ...V	31a	BZX55/..., BZX83/..., BZX97/..., ZPD....,++
RPY....		Opto	Foto-Widerstand/Photo Resistor					
RPY 1...100	Tho	Z-Di	=ZPY 1...100	31a	DO-41	Z-Diode ...V	31a	BZW22/..., BZX61/..., BZX85/..., ZY....,++
RQ		Si-N	=2SD1280-Q (SMD-Marking)	39	SOT-89			*2SD1280
RQ		Z-Di	=SM 4T 30 (SMD-Marking)	71a(6x4mm)	SOD-6			*SM 4T....
RR		Si-P	=2SA1514K-R (SMD-Marking)	35	SOT-23			*2SA1514K
RR		Si-P	=2SA1579-R (SMD-Marking)	35(2mm)	SOT-323			*2SA1579
RR		Si-N	=2SC2715-R (SMD-Marking)	35	SOT-23			*2SC2715
RR		Si-N	=2SD1280-R (SMD-Marking)	39	SOT-89			*2SD1280
RR		Si-N	=KTC3879-R (SMD-Marking)	35	SOT-23			*KTC 3879
RR		Z-Di	=SM 4T 30A (SMD-Marking)	71a(6x4mm)	SOD-6			*SM 4T....
RR 8 AT...MT	Gie	Si-Di	=RS 8 AT...MT:	17m	TO-220			-
RRF 120...RRF 833	Tca	MOS-FET	=IRF 120...IRF 833					*IRF 120...833
RRFF 110...RRFF 133	Rca	MOS-FET	=IRFF 110...IRFF 133					*IRFF 110...133
RS		Si-P	=2SA1514K-S (SMD-Marking)	35	SOT-23			*2SA1514K
RS		Si-P	=2SA1579-S (SMD-Marking)	35(2mm)	SOT-323			*2SA1579
RS		Si-N	=2SC2480-S (SMD-Marking)	35	SOT-23			*2SC2480
RS		Si-N	=2SC3932-S (SMD-Marking)	35(2mm)	SOT-323			*2SC3932
RS		Si-N	=2SC4974-S (SMD-Marking)	~35	(T Mini)			*2SC4974
RS		Si-N	=2SD1280-S (SMD-Marking)	39	SOT-89			*2SD1280
RS		Z-Di	=SM 4T 33 (SMD-Marking)	71a(6x4mm)	SOD-6			*SM 4T....
RS 1(A...Z)	Sak	Si-Di	FRr, 200...1000V, 0,7A, Uf<2,5V(0,8A) RS 1=400V, A=600V, B=800V, C=1000V, Z=200V	31a	DO-14	BY 133	31a	BY 126...127, BY 133...134, 1N4003...07, ++
RS 3 FS	Sak	Si-Di	TV Damper-Di, 1500V, 2A, Uf<1,1V(3A), 2µs	31a	DO-27	BY 228	31a	BY 228, BY 448
RS 4 FS	Sak	Si-Di	TV Damper-Di, 1500V, 1,5A, Uf<1,5V(3A), 2µs	31a	DO-27	BY 228	31a	BY 228, BY 448
RS 8 AT...MT	Gie	Si-Di	S P, 50...1000V, 8A, 150...500ns	17k	TO-220			BY 229/..., BY 329/..., RGP 80A...M

Original	Fabric.	Constr.	Info	{ Compl. Fig.	JAEGER	Fig.	International
<b>RT</b>							
RT		Si-N	=2SC2480-T (SMD-Marking)	35	SOT-23		-2SC2480
RT		Si-N	=2SC3932-T (SMD-Marking)	35(2mm)	SOT-323		-2SC3932
RT		Si-N	=2SC4000 (SMD-Marking)	35	SOT-23		-2SC4000
RT		Si-N	=2SC4400 (SMD-Marking)	35(2mm)	SOT-323		-2SC4400
RT		Si-N	=2SC4432 (SMD-Marking)	35	SOT-23		-2SC4432
RT		Si-N	=2SC4974-T (SMD-Marking)	=35	(T Mini)		-2SC4974
RT		Si-N	=2SD1280-T (SMD-Marking)	39	SOT-89		-2SD1280
RT		Z-Di	=SM 4T 33A (SMD-Marking)	71a(6x4mm)	SOD-6		-SM 4T...
RT 1 N137L	Mit	Si-N+R	Rb=1k,Rbe=22kΩ, 40/40V, 1/2A, 0,9W, 150MHz	RT1P137	7c(9mm)	TO-92L	-
RT 1 N137P		Si-N+R	=RT 1N137L: SMD		39b	SOT-89	-
RT 1 N140C		Si-N+R	=RT 1N140S: SMD		35a(2,9mm)	SOT-23	FA 1A4Z, DTC 114TK, RN 1411, UN 2215,++ DTC 114TU, RN 1311
RT 1 N140M		Si-N+R	=RT 1N140S: SMD		35a(2mm)	SOT-323	
RT 1 N140S	Mit	Si-N+R	Rb=10kΩ, 50/50V, 0,1/0,2A, 0,3W, 200MHz	IRT1P140...	41b	(TO-92S)	AA 1A4Z, DTC 114TS, RN 1011, UU 4215,++
RT 1 N141C		Si-N+R	=RT 1N141S: SMD		35a(2,9mm)	SOT-23	FA 1A4M, DTC 114EK, RN 1402, UN 2211,++
RT 1 N141M		Si-N+R	=RT 1N141S: SMD		35a(2mm)	SOT-323	DTC 114EU, RN 1302, 2SC4398
RT 1 N141S	Mit	Si-N+R	=RT 1N140S: Rb=Rbe=10kΩ	IRT1P141...	41b	(TO-92S)	AA 1A4M, DTC 114EK, RN 1002, UN 4211,++
RT 1 N144C		Si-N+R	=RT 1N144S: SMD		35a(2,9mm)	SOT-23	FA 1A4P, DTC 114YK, RN 1407, UN 2214,++
RT 1 N144M		Si-N+R	=RT 1N144S: SMD		35a(2mm)	SOT-323	DTC 114YU, RN 1307
RT 1 N144S	Mit	Si-N+R	=RT 1N140S: Rb=10k, Rbe=47kΩ	IRT1P144...	41b	(TO-92S)	AA 1A4P, DTC 114YS, RN 1007, UN 4214,++
RT 1 N241C		Si-N+R	=RT 1N241S: SMD		35a(2,9mm)	SOT-23	FA 1F4M, DTC 124EK, RN 1403, UN 2212,++
RT 1 N241M		Si-N+R	=RT 1N241S: SMD		35a(2mm)	SOT-323	DTC 124EU, RN 1303, 2SC4397
RT 1 N241S	Mit	Si-N+R	=RT 1N140S: Rb=Rbe=22kΩ	IRT1P241...	41b	(TO-92S)	AA 1F4M, DTC 124ES, RN 1003, UN 4212,++
RT 1 N430C		Si-N+R	=RT 1N430S: SMD		35a(2,9mm)	SOT-23	FA 1L3Z, DTC 143TK, RN 1410, UN 2216,++
RT 1 N430M		Si-N+R	=RT 1N430S: SMD		35a(2mm)	SOT-323	DTC 143TU, RN 1310
RT 1 N430S	Mit	Si-N+R	=RT 1N140S: Rb=4,7kΩ, Rbe=-	IRT1P430...	41b	(TO-92S)	AA 1L3Z, DTC 143TS, RN 1010, UN 4216,++
RT 1 N434C		Si-N+R	=RT 1N434S: SMD		35a(2,9mm)	SOT-23	-
RT 1 N434M		Si-N+R	=RT 1N434S: SMD		35a(2mm)	SOT-323	-
RT 1 N434S	Mit	Si-N+R	=RT 1N140S: Rb=4,7k, Rbe=22kΩ	IRT1P434...	41b	(TO-92S)	-
RT 1 N441C		Si-N+R	=RT 1N441S: SMD		35a(2,9mm)	SOT-23	FA 1L4M, DTC 114EK, RN 1404, UN 2213,++
RT 1 N441M		Si-N+R	=RT 1N441S: SMD		35a(2mm)	SOT-323	DTC 144EU, RN1304, 2SC4396
RT 1 N441S	Mit	Si-N+R	=RT 1N140S: Rb=Rbe=47kΩ	IRT1P441...	41b	(TO-92S)	AA 1L4M, DTC 144ES, RN 1004, UN 4213,++
RT 1 P137L	Mit	Si-P+R	Rb=1k,Rbe=22kΩ, 40/40V, 1/2A, 0,9W, 130MHz	IRT1N137	7c(9mm)	TO-92L	-
RT 1 P137P		Si-P+R	=RT 1P137L: SMD		39b	SOT-89	-
RT 1 P140C		Si-P+R	=RT 1P140S: SMD		35a(2,9mm)	SOT-23	FN 1A4Z, DTA 114TK, RN 2411, UN 2115,++
RT 1 P140M		Si-P+R	=RT 1P140S: SMD		35a(2mm)	SOT-323	DTA 114TU, RN 2311
RT 1 P140S	Mit	Si-P+R	Rb=10kΩ, 50/50V, 0,1/0,2A, 0,3W, 150MHz	IRT1N140...	41b	(TO-92S)	AN 1A4Z, DTA 114TS, RN 2011, UU 4115,++
RT 1 P141C		Si-P+R	=RT 1P141S: SMD		35a(2,9mm)	SOT-23	FN 1A4M, DTA 114EK, RN 2402, UN 2111,++
RT 1 P141M		Si-P+R	=RT 1P141S: SMD		35a(2mm)	SOT-323	DTA 114EU, RN 2302, 2SA1678
RT 1 P141S	Mit	Si-P+R	=RT 1N140S: Rb=Rbe=10kΩ	IRT1N141...	41b	(TO-92S)	AN 1A4M, DTA 114ES, RN 2002, UN 4111,++
RT 1 P144C		Si-P+R	=RT 1P144S: SMD		35a(2,9mm)	SOT-23	FN 1A4P, DTA 114YK, RN 2407, UN 2114,++
RT 1 P144M		Si-P+R	=RT 1P144S: SMD		35a(2mm)	SOT-323	DTA 114YU, RN 2307
RT 1 P144S	Mit	Si-P+R	=RT 1N140S: Rb=10k, Rbe=47kΩ	IRT1N144...	41b	(TO-92S)	AN 1A4P, DTA 114YS, RN 2007, UN 4114,++
RT 1 P241C		Si-P+R	=RT 1P241S: SMD		35a(2,9mm)	SOT-23	FN 1F4M, DTA 124EK, RN 2403, UN 2112,++
RT 1 P241M		Si-P+R	=RT 1P241S: SMD		35a(2mm)	SOT-323	DTA 124EU, RN 2303, 2SA1677
RT 1 P241S	Mit	Si-P+R	=RT 1N140S: Rb=Rbe=22kΩ	IRT1N241...	41b	(TO-92S)	AN 1F4M, DTA 124ES, RN 2003, UN 4112,++
RT 1 P430C		Si-P+R	=RT 1P430S: SMD		35a(2,9mm)	SOT-23	FN 1L3Z, DTA 143TK, RN 2410, UN 2116,++
RT 1 P430M		Si-P+R	=RT 1P430S: SMD		35a(2mm)	SOT-323	DTA 143TU, RN 2310
RT 1 P430S	Mit	Si-P+R	=RT 1N140S: Rb=4,7kΩ, Rbe=-	IRT1N430...	41b	(TO-92S)	AN 1L3Z, DTA 143TS, RN 2010, UN 4116,++
RT 1 P434C		Si-P+R	=RT 1P434S: SMD		35a(2,9mm)	SOT-23	-
RT 1 P434M		Si-P+R	=RT 1P434S: SMD		35a(2mm)	SOT-323	-
RT 1 P434S	Mit	Si-P+R	=RT 1N140S: Rb=4,7k, Rbe=22kΩ	IRT1N434...	41b	(TO-92S)	-
RT 1 P441C		Si-P+R	=RT 1P441S: SMD		35a(2,9mm)	SOT-23	FN 1L4M, DTA 144EK, RN 2404, UN 2113,++
RT 1 P441M		Si-P+R	=RT 1P441S: SMD		35a(2mm)	SOT-323	DTA 144EU, RN 2304, 2SA1676
RT 1 P441S	Mit	Si-P+R	=RT 1N140S: Rb=Rbe=47kΩ	IRT1N441...	41b	(TO-92S)	AN 1L4M, DTA 144ES, RN 2004, UN 4113,++
RTC 0803	Tra	50Hz-Thy	30V, 0,25A(Tc=80°C), Igt/Ih<2μA/1mA		2a	TO-18	-
RTC 0806	Tra	50Hz-Thy	=RTC 0803: 60V		2a	TO-18	-
RTC 0810	Tra	50Hz-Thy	=RTC 0803: 100V		2a	TO-18	-
RTC 0815	Tra	50Hz-Thy	=RTC 0803: 150V		2a	TO-18	-
RTC 0820	Tra	50Hz-Thy	=RTC 0803: 200V		2a	TO-18	-
RTD 0203	Tra	50Hz-Thy	30V, 1,6A(Tc=80°C), Igt/Ih<0,1/<5mA		2a	TO-39	-
RTD 0206	Tra	50Hz-Thy	=RTD 0203: 60V		2a	TO-39	-
RTD 0210	Tra	50Hz-Thy	=RTD 0203: 100V		2a	TO-39	-
RTD 0220	Tra	50Hz-Thy	=RTD 0203: 200V		2a	TO-39	-
RTD 0230	Tra	50Hz-Thy	=RTD 0203: 300V		2a	TO-39	-
RTD 0240	Tra	50Hz-Thy	=RTD 0203: 400V		2a	TO-39	-
RTD 0203...0240-1		50Hz-Thy	=RTD 0203...0240: Igt<5μA		2a	TO-39	-
RTD 0203...0240-2		50Hz-Thy	=RTD 0203...0240: Igt<10μA		2a	TO-39	-
RTD 0203...0240-3	Tra	50Hz-Thy	=RTD 0203...0240: Igt/Ih<0,25/<20mA		2a	TO-39	-
RTD 0301	Tra	50Hz-Thy	15V, 1A(Tc=80°C), Igt/Ih<0,2/10mA		2a	TO-39	TAG 103 X 2a 2N2322...2329, TAG 615-100
RTD 0303	Tra	50Hz-Thy	=RTD 0301: 30V		2a	TO-39	TAG 103 X 2a 2N2323...2329, TAG 615-100
RTD 0306	Tra	50Hz-Thy	=RTD 0301: 60V		2a	TO-39	2N2324...2329, TAG 615-100
RTD 0310	Tra	50Hz-Thy	=RTD 0301: 100V		2a	TO-39	2N2324...2329, TAG 615-100
RTD 0315	Tra	50Hz-Thy	=RTD 0301: 150V		2a	TO-39	2N2325...2329, TAG 615-200
RTD 0320	Tra	50Hz-Thy	=RTD 0301: 200V		2a	TO-39	2N2326...2329, TAG 615-200
RTD 0330	Tra	50Hz-Thy	=RTD 0301: 300V		2a	TO-39	2N2328...2329, TAG 615-400
RTD 0340	Tra	50Hz-Thy	=RTD 0301: 400V		2a	TO-39	2N2329, TAG 615-400
RTD 0350	Tra	50Hz-Thy	=RTD 0301: 500V		2a	TO-39	TAG 615-600
RTD 0401	Tra	50Hz-Thy	15V, 1A(Tc=80°C), Igt/Ih<0,1/5mA		2a	TO-39	-
RTD 0403	Tra	50Hz-Thy	=RTD 0401: 30V		2a	TO-39	-
RTD 0406	Tra	50Hz-Thy	=RTD 0401: 60V		2a	TO-39	-
RTD 0410	Tra	50Hz-Thy	=RTD 0401: 100V		2a	TO-39	-
RTD 0415	Tra	50Hz-Thy	=RTD 0401: 150V		2a	TO-39	-
RTD 0420	Tra	50Hz-Thy	=RTD 0401: 200V		2a	TO-39	-
RTD 0430	Tra	50Hz-Thy	=RTD 0401: 300V		2a	TO-39	-
RTD 0440	Tra	50Hz-Thy	=RTD 0401: 400V		2a	TO-39	-
RTD 2103	Tra	50Hz-Thy	30V, 1A(Tc=80°C), Igt/Ih<10/20mA		2a	TO-39	BTX30/50, S2600B, T1N100A, TAG612-100
RTD 2106	Tra	50Hz-Thy	=RTD 2103: 60V		2a	TO-39	BTX30/100, S2600B, T1N100A, TAG612-100
RTD 2110	Tra	50Hz-Thy	=RTD 2103: 100V		2a	TO-39	BTX30/100, S2600B, T1N100A, TAG612-100
RTD 2120	Tra	50Hz-Thy	=RTD 2103: 200V		2a	TO-39	BTX30/200, S2600B, T1N200A, TAG612-200
RTD 2130	Tra	50Hz-Thy	=RTD 2103: 300V		2a	TO-39	BTX30/300, S2600D, T1N300A, TAG612-400
RTD 2140	Tra	50Hz-Thy	=RTD 2103: 400V		2a	TO-39	BTX30/400, S2600D, T1N400A, TAG612-400

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International	
RTED 0302	Tra	50Hz-Thy	20V, 3.2A(Tc=75°C), Igt/Ih<15/20mA	2a	TO-39		(S 2620B) <sup>4</sup>	
RTED 0305	Tra	50Hz-Thy	=RTED 0302: 50V	2a	TO-39		(S 2620B) <sup>4</sup>	
RTED 0310	Tra	50Hz-Thy	=RTED 0302: 100V	2a	TO-39		(S 2620B) <sup>4</sup>	
RTED 0320	Tra	50Hz-Thy	=RTED 0302: 200V	2a	TO-39		(S 2620B) <sup>4</sup>	
RTED 0330	Tra	50Hz-Thy	=RTED 0302: 300V	2a	TO-39		(S 2620D) <sup>4</sup>	
RTED 0340	Tra	50Hz-Thy	=RTED 0302: 400V	2a	TO-39		(S 2620D) <sup>4</sup>	
RTED 0350	Tra	50Hz-Thy	=RTED 0302: 500V	2a	TO-39		(S 2620M) <sup>4</sup>	
RTF 10...80	Tho	Si-Di	P FRR, 100...800V, 10A, <300ns	17k	TO-220	BY 329/1200	17k	ESM 765/...
RTF 10...60 R		Si-Di	=RTF 10...60:	17m	TO-220	BY 329/1200 <sup>5</sup>	17k	(ESM 765/...) <sup>5</sup>
RTF 0101	Tra	50Hz-Thy	15V, 1A(Tc=80°C), Igt/Ih<0.2/<5mA	2a	TO-39	TAG 103 X	2a	2N2322...2329, TAG 615-100
RTF 0103	Tra	50Hz-Thy	=RTF 0101: 30V	2a	TO-39	TAG 103 X	2a	2N2323...2329, TAG 615-100
RTF 0106	Tra	50Hz-Thy	=RTF 0101: 60V	2a	TO-39			2N2324...2329, TAG 615-100
RTF 0110	Tra	50Hz-Thy	=RTF 0101: 100V	2a	TO-39			2N2324...2329, TAG 615-100
RTF 0115	Tra	50Hz-Thy	=RTF 0101: 150V	2a	TO-39			2N2325...2329, TAG 615-200
RTF 0120	Tra	50Hz-Thy	=RTF 0101: 200V	2a	TO-39			2N2326...2329, TAG 615-200
RTF 0125	Tra	50Hz-Thy	=RTF 0101: 250V	2a	TO-39			2N2327...2329, TAG 615-400
RTF 0130	Tra	50Hz-Thy	=RTF 0101: 300V	2a	TO-39			2N2328...2329, TAG 615-400
RTF 0135	Tra	50Hz-Thy	=RTF 0101: 350V	2a	TO-39			2N2329, TAG 615-400
RTF 0140	Tra	50Hz-Thy	=RTF 0101: 400V	2a	TO-39			2N2329, TAG 615-400
RTF 0201...0240	Tra	50Hz-Thy	=RTF 0101...0140: Igt/Ih<1/<10mA	2a	TO-39			TAG 1..., TAG 2..., MCR 1906-..., TAG 614...
RTF 0301...0340	Tra	50Hz-Thy	=RTF 0101...0140: Igt/Ih<0.2/<10mA	2a	TO-39			2N2322...2329, TAG 615-...
RTF 0401...0440	Tra	50Hz-Thy	=RTF 0101...0140: Igt/Ih<0.1/<5mA	2a	TO-39			-
RTF 0501...0540	Tra	50Hz-Thy	=RTF 0101...0140: Igt/Ih<0.02/<3mA	2a	TO-39			2N2322...2329A, 2N6322...6337
RTF 0601...0640	Tra	50Hz-Thy	=RTF 0101...0140: Igt/Ih<0.02/<2mA	2a	TO-39			2N2322...2329A, 2N6322...6337
RTGC 0101	Tra	GTO-Thy	+15V, 0.25A(Ta=75°C), Igt/Ih<0.5/<10mA	2a	TO-18			-
RTGC 0103	Tra	GTO-Thy	=RTGC 0101: +30V	2a	TO-18			-
RTGC 0106	Tra	GTO-Thy	=RTGC 0101: +60V	2a	TO-18			-
RTGC 0110	Tra	GTO-Thy	=RTGC 0101: +100V	2a	TO-18			-
RTGC 0115	Tra	GTO-Thy	=RTGC 0101: +150V	2a	TO-18			-
RTGC 0120	Tra	GTO-Thy	=RTGC 0101: +200V	2a	TO-18			-
RTGC 0125	Tra	GTO-Thy	=RTGC 0101: +250V	2a	TO-18			-
RTGD 0101	Tra	GTO-Thy	+15V, 0.5A(Ta=75°C), Igt/Ih<0.5/<10mA	2a	TO-18			-
RTGD 0103	Tra	GTO-Thy	=RTGD 0101: +30V	2a	TO-18			-
RTGD 0106	Tra	GTO-Thy	=RTGD 0101: +60V	2a	TO-18			-
RTGD 0110	Tra	GTO-Thy	=RTGD 0101: +100V	2a	TO-18			-
RTGD 0115	Tra	GTO-Thy	=RTGD 0101: +150V	2a	TO-18			-
RTGD 0120	Tra	GTO-Thy	=RTGD 0101: +200V	2a	TO-18			-
RTGD 0125	Tra	GTO-Thy	=RTGD 0101: +250V	2a	TO-18			-
RTGD 0130	Tra	GTO-Thy	=RTGD 0101: +300V	2a	TO-18			-
RTJ 0103	Tra	50Hz-Thy	30V, 0.4A(Tc=80°C), Igt/Ih<0.1/<5mA	7n	TO-92			-
RTJ 0106	Tra	50Hz-Thy	=RTJ 0103: 60V	7n	TO-92			-
RTJ 0110	Tra	50Hz-Thy	=RTJ 0103: 100V	7n	TO-92			-
RTJ 0120	Tra	50Hz-Thy	=RTJ 0103: 200V	7n	TO-92			-
RTJ 0130	Tra	50Hz-Thy	=RTJ 0103: 300V	7n	TO-92			-
RTJ 0140	Tra	50Hz-Thy	=RTJ 0103: 400V	7n	TO-92			-
RTJ 0103...0140-1		50Hz-Thy	=RTJ 0103...0140: Igt<2µA	7n	TO-92			-
RTJ 0103...0140-2		50Hz-Thy	=RTJ 0103...0140: Igt<5µA	7n	TO-92			-
RTJ 0203	Tra	50Hz-Thy	30V, 0.5A(Tc=55°C), Igt/Ih<1/10mA	7n	TO-92	BRX 49	7a	(BRY 55/30, BT 149F, TAG 70D, TAG 72D)
RTJ 0206	Tra	50Hz-Thy	=RTJ 0203: 60V	7n	TO-92	BRX 49	7a	(BRY 55/60, BT 149A, TAG 70D, TAG 72D)
RTJ 0210	Tra	50Hz-Thy	=RTJ 0203: 100V	7n	TO-92	BRX 49	7a	(BRY 55/100, BT 149A, TAG 70D, TAG 72D)
RTJ 0215	Tra	50Hz-Thy	=RTJ 0203: 150V	7n	TO-92	BRX 49	7a	(BRY 55/200, BT 149B, TAG 70D, TAG 72D)
RTJ 0220	Tra	50Hz-Thy	=RTJ 0203: 200V	7n	TO-92	BRX 49	7a	(BRY 55/200, BT 149B, TAG 70D, TAG 72D)
RTJ 0230	Tra	50Hz-Thy	=RTJ 0203: 300V	7n	TO-92	BRX 49	7a	(BRY 55/300, BT 149D, TAG 70D, TAG 72D)
RTJ 0501	Tra	50Hz-Thy	15V, 0.8A(Tc=55°C), Igt/Ih<0.02/3mA	7n	TO-92			-
RTJ 0503	Tra	50Hz-Thy	=RTJ 0501: 30V	7n	TO-92			-
RTJ 0506	Tra	50Hz-Thy	=RTJ 0501: 60V	7n	TO-92			-
RTJ 0510	Tra	50Hz-Thy	=RTJ 0501: 100V	7n	TO-92			-
RTJ 0515	Tra	50Hz-Thy	=RTJ 0501: 150V	7n	TO-92			-
RTJ 0520	Tra	50Hz-Thy	=RTJ 0501: 200V	7n	TO-92			-
RTJ 0525	Tra	50Hz-Thy	=RTJ 0501: 250V	7n	TO-92			-
RTJ 0530	Tra	50Hz-Thy	=RTJ 0501: 300V	7n	TO-92			-
RTL 0605	Tra	50Hz-Thy	50V, 6A(Tc=80°C), Igt/Ih<50/<100mA	17e	TO-220			BT 152/400R, BSID1026, 2N6400...6405
RTL 0610	Tra	50Hz-Thy	=RTL 0605: 100V	17e	TO-220			BT 152/400R, BSID1026, 2N6401...6405
RTL 0620	Tra	50Hz-Thy	=RTL 0605: 200V	17e	TO-220			BT 152/400R, BSID1026, 2N6402...6405
RTL 0640	Tra	50Hz-Thy	=RTL 0605: 400V	17e	TO-220			BT 152/400R, BSID1026, 2N6403...6405
RTL 0660	Tra	50Hz-Thy	=RTL 0605: 600V	17e	TO-220			BT 152/600R, BSID1040, 2N6404...6405
RTL 0805	Tra	50Hz-Thy	50V, 8A(Tc=80°C), Igt/Ih<50/<100mA	17e	TO-220			BT 152/400R, BSID1026, 2N6504...6509
RTL 0810	Tra	50Hz-Thy	=RTL 0805: 100V	17e	TO-220			BT 152/400R, BSID1026, 2N6505...6509
RTL 0820	Tra	50Hz-Thy	=RTL 0805: 200V	17e	TO-220			BT 152/400R, BSID1026, 2N6506...6509
RTL 0840	Tra	50Hz-Thy	=RTL 0805: 400V	17e	TO-220			BT 152/400R, BSID1026, 2N6507...6509
RTL 0860	Tra	50Hz-Thy	=RTL 0805: 600V	17e	TO-220			BT 152/600R, BSID1040, 2N6508...6509
RTL 1005	Tra	50Hz-Thy	50V, 10A(Tc=80°C), Igt/Ih<50/<100mA	17e	TO-220			BSID1026M, BT 152/400R, 2N6504...6509
RTL 1010	Tra	50Hz-Thy	=RTL 1005: 100V	17e	TO-220			BSID1026M, BT 152/400R, 2N6505...6509
RTL 1020	Tra	50Hz-Thy	=RTL 1005: 200V	17e	TO-220			BSID1026M, BT 152/400R, 2N6506...6509
RTL 1030	Tra	50Hz-Thy	=RTL 1005: 300V	17e	TO-220			BSID1026M, BT 152/400R, 2N6507...6509
RTL 1040	Tra	50Hz-Thy	=RTL 1005: 400V	17e	TO-220			BSID1026M, BT 152/400R, 2N6507...6509
RTL 1050	Tra	50Hz-Thy	=RTL 1005: 500V	17e	TO-220			BSID1033M, BT 152/600R, 2N6508...6509
RTL 1060	Tra	50Hz-Thy	=RTL 1005: 600V	17e	TO-220			BSID1040M, BT 152/600R, 2N6508...6509
RTL 1510	Tra	50Hz-Thy	100V, 15A(Tc=80°C), Igt/Ih<100/<100mA	17e	TO-220			MCR 69-3, 2N6504...6509
RTL 1520	Tra	50Hz-Thy	=RTL 1510: 200V	17e	TO-220			2N6505...6509
RTL 1540	Tra	50Hz-Thy	=RTL 1510: 400V	17e	TO-220			2N6507...6509
RTL 1560	Tra	50Hz-Thy	=RTL 1510: 600V	17e	TO-220			2N6508...6509
RTL 1610	Tra	50Hz-Thy	100V, 16A(Tc=80°C), Igt/Ih<50/<100mA	17e	TO-220			MCR 69-3, 2N6504...6509
RTL 1620	Tra	50Hz-Thy	=RTL 1610: 200V	17e	TO-220			2N6505...6509
RTL 1640	Tra	50Hz-Thy	=RTL 1610: 400V	17e	TO-220			2N6507...6509
RTL 1660	Tra	50Hz-Thy	=RTL 1610: 600V	17e	TO-220			2N6508...6509
RTM 1005...1060		50Hz-Thy	=RTL 1005...1060: Iso	17b	TO-220Iso			-
RTN 0805...0860		50Hz-Thy	=RTL 0805...0860:	21b	TO-64			BTW 42/..., TAG 9N..., TAG 15..., CS 13...
RTR 0305	Tra	50Hz-Thy	50V, 5A(Tc=80°C), Igt/Ih<20/25mA	22a	TO-66	TD 3FP 800H1*	17f	BSIC0506, TAG 671-100, TAG 676-100
RTR 0310	Tra	50Hz-Thy	=RTR 0305: 100V	22a	TO-66	TD 3FP 800H1*	17f	BSIC0506, TAG 671-100, TAG 676-100
RTR 0320	Tra	50Hz-Thy	=RTR 0305: 200V	22a	TO-66	TD 3FP 800H1*	17f	BSIC0513, TAG 671-200, TAG 676-200
RTR 0330	Tra	50Hz-Thy	=RTR 0305: 300V	22a	TO-66	TD 3FP 800H1*	17f	BSIC0526, TAG 671-300, TAG 676-300
RTR 0340	Tra	50Hz-Thy	=RTR 0305: 400V	22a	TO-66	TD 3FP 800H1*	17f	BSIC0526, TAG 671-400, TAG 676-400



Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International	
RTR 0350	Tra	50Hz-Thy	=RTR 0305: 500V	22a	TO-66	TD 3FP 800H1*	BSIC0533, TAG 671-500, TAG 676-500	
RTR 0360	Tra	50Hz-Thy	=RTR 0305: 600V	22a	TO-66	TD 3FP 800H1*	BSIC0540, TAG 671-600, TAG 676-600	
RTR 0605...0660	Tra	50Hz-Thy	=RTL 0605...0660:	22a	TO-66		TAG 675-...	
RTR 1005...1060	Tra	50Hz-Thy	=RTL 1005...1060:	22a	TO-66		-	
RTS 0605...0660	Tra	50Hz-Thy	=RTL 0605...0660:	29b	TO-203		BSIE40...M	
RTS 1005...1060	Tra	50Hz-Thy	=RTL 1005...1060:	29b	TO-203		BSIE40...M	
RTS 1610...1660	Tra	50Hz-Thy	=RTL 1610...1660:	29b	TO-203		BSIE40...M	
RTS 2505	Tra	50Hz-Thy	50V, 25A(Tc=80°C), Igt/Ih<50/<100mA	29b	TO-203		-	
RTS 2510	Tra	50Hz-Thy	=RTS 2505: 100V	29b	TO-203		-	
RTS 2520	Tra	50Hz-Thy	=RTS 2505: 200V	29b	TO-203		-	
RTS 2540	Tra	50Hz-Thy	=RTS 2505: 400V	29b	TO-203		-	
RTS 2560	Tra	50Hz-Thy	=RTS 2505: 600V	29b	TO-203		-	
RTT 2505...2560	Tra	50Hz-Thy	=RTS 2505...2560:	21b	TO-48		BTW 48/... CS 23-..., T 24N..., TAG 24N...	
RTU 0605...0660	Tra	50Hz-Thy	=RTL 0605...0660:	21b	TO-48		TAG 9N..., TAG 15-..., BTW 39/..., CS 13...	
RTU 0710	Tra	50Hz-Thy	100V, 25A(Tc=65°C), Igt/Ih<50/200mA	21b	TO-48		BTW48/200, CS23-02, T24N200, TAG24N400	
RTU 0720	Tra	50Hz-Thy	=RTU 0710: 200V	21b	TO-48		BTW48/200, CS23-02, T24N200, TAG24N400	
RTU 0730	Tra	50Hz-Thy	=RTU 0710: 300V	21b	TO-48		BTW48/400, CS23-04, T24N400, TAG24N400	
RTU 0740	Tra	50Hz-Thy	=RTU 0710: 400V	21b	TO-48		BTW48/400, CS23-04, T24N400, TAG24N400	
RTU 0750	Tra	50Hz-Thy	=RTU 0710: 500V	21b	TO-48		BTW48/500, CS23-06, T24N600, TAG24N600	
RTU 0760	Tra	50Hz-Thy	=RTU 0710: 600V	21b	TO-48		BTW48/600, CS23-06, T24N600, TAG24N600	
RTU 1005...1060	Tra	50Hz-Thy	=RTL 1005...1060:	21b	TO-48		2N1842...1850, TAG 9N..., TAG 15-..., ++	
RTU 1610...1660	Tra	50Hz-Thy	=RTL 1610...1660:	21b	TO-48		TAG 14N..., BTW 39/..., BTW 47/..., CS 13...	
RTU 2505...2560	Tra	50Hz-Thy	=RTS 2505...2560:	21b	TO-48		BTW 48/... CS 23-..., T 24N..., TAG 24N...	
RTV 0102	Tra	50Hz-Thy	25V, 10A(Tc=65°C), Igt/Ih<50/<200mA	21b	TO-48		TAG 9N400, TAG 15-100, TAG 14N400, ++	
RTV 0105	Tra	50Hz-Thy	=RTV 0102: 50V	21b	TO-48		TAG 9N400, TAG 15-100, TAG 14N400, ++	
RTV 0110	Tra	50Hz-Thy	=RTV 0102: 100V	21b	TO-48		TAG 9N400, TAG 15-100, TAG 14N400, ++	
RTV 0120	Tra	50Hz-Thy	=RTV 0102: 200V	21b	TO-48		TAG 9N400, TAG 15-200, TAG 14N400, ++	
RTV 0130	Tra	50Hz-Thy	=RTV 0102: 300V	21b	TO-48		TAG 9N400, TAG 15-400, TAG 14N400, ++	
RTV 0140	Tra	50Hz-Thy	=RTV 0102: 400V	21b	TO-48		TAG 9N400, TAG 15-400, TAG 14N400, ++	
RTV 0150	Tra	50Hz-Thy	=RTV 0102: 500V	21b	TO-48		TAG 9N600, TAG 15-500, TAG 14N600, ++	
RTV 0160	Tra	50Hz-Thy	=RTV 0102: 600V	21b	TO-48		TAG 9N600, TAG 15-600, TAG 14N600, ++	
RTV 0202	Tra	50Hz-Thy	25V, 16A(Tc=65°C), Igt/Ih<50/<200mA	21b	TO-48		BTW 40/200R, BTW 92/200R, T 17N200, ++	
RTV 0205	Tra	50Hz-Thy	=RTV 0202: 50V	21b	TO-48		BTW 40/200R, BTW 92/200R, T 17N200, ++	
RTV 0210	Tra	50Hz-Thy	=RTV 0202: 100V	21b	TO-48		BTW 40/200R, BTW 92/200R, T 17N200, ++	
RTV 0220	Tra	50Hz-Thy	=RTV 0202: 200V	21b	TO-48		BTW 40/200R, BTW 92/200R, T 17N200, ++	
RTV 0230	Tra	50Hz-Thy	=RTV 0202: 300V	21b	TO-48		BTW 40/400R, BTW 92/400R, T 17N400, ++	
RTV 0240	Tra	50Hz-Thy	=RTV 0202: 400V	21b	TO-48		BTW 40/400R, BTW 92/400R, T 17N400, ++	
RTV 0250	Tra	50Hz-Thy	=RTV 0202: 500V	21b	TO-48		BTW 40/600R, BTW 92/600R, T 17N600, ++	
RTV 0260	Tra	50Hz-Thy	=RTV 0202: 600V	21b	TO-48		BTW 40/600R, BTW 92/600R, T 17N600, ++	
RTV 0302	Tra	50Hz-Thy	25V, 16A(Tc=65°C), Igt/Ih<25/<50mA	21b	TO-48		C 230U, BSIE4126N	
RTV 0305	Tra	50Hz-Thy	=RTV 0302: 50V	21b	TO-48		C 230F, BSIE4126N	
RTV 0310	Tra	50Hz-Thy	=RTV 0302: 100V	21b	TO-48		C 230A, BSIE4126N	
RTV 0320	Tra	50Hz-Thy	=RTV 0302: 200V	21b	TO-48		C 230B, BSIE4126N	
RTV 0330	Tra	50Hz-Thy	=RTV 0302: 300V	21b	TO-48		C 230C, BSIE4126N	
RTV 0340	Tra	50Hz-Thy	=RTV 0302: 400V	21b	TO-48		C 230D, BSIE4126N	
RTV 0350	Tra	50Hz-Thy	=RTV 0302: 500V	21b	TO-48		C 230E, BSIE4133N	
RTV 0360	Tra	50Hz-Thy	=RTV 0302: 600V	21b	TO-48		C 230M, BSIE4140N	
RTV 0402...0460	Tra	50Hz-Thy	=RTV 0102...0160	21b	TO-48		-RTV 0102...0160	
RTV 0502...0560	Tra	50Hz-Thy	=RTV 0202...0260	21b	TO-48		-RTV 0202...0260	
RTV 0602...0660	Tra	50Hz-Thy	=RTV 0302...0360	21b	TO-48		-RTV 0302...0360	
RU		Z-Di	=SM 4T 36 (SMD-Marking)	71a(6x4mm)	SOD-6		-SM 4T...	
RU-1AV		Si-Di	=BY 298	31a		-BY 298		
RU 1(A,B,C)	Sak	Si-Di	FRr, 400...1000V, 0,25A, Uf<2.5V(0,25A), <400ns RU 1=400V, A=600V, B=800V, C=1000V	31a	-DO-14	BA 159	31a	BA 157...159, BY 204/..., BY 208/...
RU 1 P	Sak	Si-Di	FRr, 1000V, 0,4A, Uf<4V(0,4A), 100ns	31a	DO-14	BA 159	31a	BA 159, BY204/10, BY208/1000, RGP 10M, ++
RU 2	Sak	Si-Di	FRr, 600V, 1A, Uf<1,5V(1A), <400ns	31a	-DO-14	BYD 33 M	31a	BY 231/800, BYX 55/600, RGP 10J...M, ++
RU 2 AM	Sak	Si-Di	=RU 2: 600V, 1,1A, Uf<1,2V(1,1A)	31a	-DO-14	BYD 33 M	31a	BY 231/800, BYX 55/600, RGP 10J...M, ++
RU 2 B	Sak	Si-Di	=RU 2: 800V, 1A, Uf<1,5V(1A)	31a	-DO-14	BYD 33 M	31a	BYD 33K...M, BY 231/800, RGP 10K...M, ++
RU 2 C	Sak	Si-Di	=RU 2: 1000V, 0,8A, Uf<1,5V(1A)	31a	-DO-14	BYD 33 M	31a	BYD 33M, BY 231/800, RGP 10M, ++
RU 2 M	Sak	Si-Di	=RU 2: 400V, 1,1A, Uf<1,2V(1,1A)	31a	-DO-14	BYD 33 M	31a	BY 231/800, BYX 55/600, RGP 10G...M, ++
RU 2 YX	Sak	Si-Di	=RU 2: 100V, 1,5A, Uf<0,95V(1,5A), 200ns	31a	-DO-14	BYD 33 M	31a	BY 231/800, BYX 55/350, RGP 10B...M, ++
RU 2 Z	Sak	Si-Di	=RU 2: 200V	31a	-DO-14	BYD 33 M	31a	BY 231/800, BYX 55/350, RGP 10D...M, ++
RU 3	Sak	Si-Di	FRr, 400V, 1,5A, Uf<1,5V(1,5A), 400ns	31a	DO-14	BYD 33 M	31a	BY 258/400, BYW 95B...C, RGP 15G...M, ++
RU 3 A	Sak	Si-Di	=RU 3: 600V	31a	DO-14	BYD 33 M	31a	BY 258/650, BYW 95C, RGP 15J...M, ++
RU 3 AM	Sak	Si-Di	=RU 3: 600V, Uf<1,1V(1,5A)	31a	DO-14	BYD 33 M	31a	BY 258/650, BYW 95C, RGP 15J...M, ++
RU 3 B	Sak	Si-Di	=RU 3: 800V, 1,1A, Uf<1,5V(1A)	31a	DO-14	BYD 33 M	31a	BY 258/800, BYW 96D...E, RGP 15K...M, ++
RU 3 C	Sak	Si-Di	=RU 3: 1000V, Uf<2V(1,5A)	31a	DO-14	BYD 33 M	31a	BY 299, BY 438, BYW 96E, RGP 15M, ++
RU 3 M	Sak	Si-Di	=RU 3: 400V, Uf<1,1V(1,5A)	31a	DO-14	BYD 33 M	31a	BY 258/400, BYW 95B...C, RGP 15G...M, ++
RU 3 YX	Sak	Si-Di	=RU 3: 100V, 2A, Uf<0,95V(2A), 200ns	31a	DO-14	BYD 33 M	31a	BY 258/100, BYW 95A...C, RGP 15B...M, ++
RU 4	Sak	Si-Di	FRr, 400V, 3A, Uf<1,5V(3A), 400ns	31a	-DO-26	BYW 95 C	31a	BY 398...399, BYW 95B...C, RGP 30G...M, ++
RU 4 A	Sak	Si-Di	=RU 4: 600V	31a	-DO-26	BYW 95 C	31a	BY 399, BYW 95C, MR 856, RGP 30J...M, ++
RU 4 AM	Sak	Si-Di	=RU 4: 600V, 3,5A, Uf<1,3V(3,5A)	31a	-DO-26	BYW 95 C	31a	BY 399, BYW 95C, MR 856, RGP 30J...M, ++
RU 4 B	Sak	Si-Di	=RU 4: 800V, Uf<1,6A(3A)	31a	-DO-26	BYW 96 E	31a	BY 399, BYW 96D...E, RGP 30K...M, ++
RU 4 C	Sak	Si-Di	=RU 4: 1000V, 2,5A, Uf<1,6A(3A)	31a	-DO-26	BYW 96 E	31a	BY 399S, BY 438, BYW 96E, RGP 30M, ++
RU 4 D	Sak	Si-Di	TV Damper-Di, 1300V, 1,5A, Uf<1,8V(1,5A), 400ns	31a	-DO-26	BY 228	31a	BY 228, BY 328, BY 448
RU 4 DS	Sak	Si-Di	TV Damper-Di, 1300V, 2,5A, Uf<1,8V(3A), 400ns	31a	-DO-26	BY 228	31a	BY 228, BY 328
RU 4 M	Sak	Si-Di	=RU 4: 400V, 3,5A, Uf<1,3V(3,5A)	31a	-DO-26	BYW 95 C	31a	BY 398...399, BYW 95B...C, RGP 30G...M, ++
RU 4 Y	Sak	Si-Di	=RU 4: 100V	31a	-DO-26	BY 500/800	31a	BY 500/100, FE 5B...D, EGP 50B...G, ++
RU 4 YX	Sak	Si-Di	=RU 4: 100V, 4A, Uf<0,85V(2A), 200ns	31a	-DO-26	BY 500/800	31a	BY 500/100, FE 5B...D, EGP 50B...G, ++
RU 4 Z	Sak	Si-Di	=RU 4: 250V	31a	-DO-26	BY 500/800	31a	BY 500/400, EGP 50F...G, MR 824...828
RU 30(A,Z)	Sak	Si-Di	FRr, 200...600V, 2A, Uf<0,97V(3,5A), 400ns RU 30=400V, A=600V, Z=200V	31a	DO-27A	BYW 95 C	31a	BY 296...299, BYW 32...36, BYW 95A...C, ++
RUR-810...860	Rca	Si-Di	S P, 100...600V, 8A, <35...50ns	17k	TO-220		BYR 29/..., BYT 12P/..., MUR 810...8100	
RUR-D 810...860		Si-Di	=RUR 810...860: Dual	17e	TO-220		BYR 28/..., BYT 28/...	
RUR-1610...1620CT	Rca	Si-Di	=MUR 1610...1620	17k	TO-220		-MUR 1605...1660CT	
RUR-D 1610...1620	Rca	Si-Di	Dual, S P, 100...200V, 16A, <35ns	22f	TO-66		-	
<b>RV...RZ</b>								
RV		Z-Di	=SM 4T 36A (SMD-Marking)	71a(6x4mm)	SOD-6		-SM 4T...	
RV 03	Fui	Hybrid-IC	Kabelverstärker/Cable Receiver				-	
RV 09	Fui	Hybrid-IC	Kabelverstärker/Cable Receiver				-	
RV 4136 D	Ray,Tix	OP-IC	=RC 4136: SMD, -40...+85°	14-MDIP			-	
RV 4136 J.N	Ray,Tix	OP-IC	=RC 4136: -40...+85°	14-DIC,DIP			RM 4136, µA 4136DM	

Original	Fabric.	Constr.	Info	(Compl. Fig.	JAEGER	Fig.	International	
RV 4558 D	Ray,Tix	OP-IC	=RC 4558DE,J.G.P: SMD, -25...+85°	8-DIC,DIP			... 158..... 258..... 1558...	
RW		Z-Di	=SM 4T 39 (SMD-Marking)	71a(6x4mm)	SOD-6		-SM 4T....	
RW 01M...10M	Gie	Si-Br	100...1000V, 1,5A	8		B500C1500	8	B70...700C1500
RX		Z-Di	=SM 4T 39A (SMD-Marking)	71a(6x4mm)	SOD-6		-SM 4T....	
RY		Si-P	=2SA1204-Y (SMD-Marking)	39	SOT-89		-2SA1204	
RY		Si-N	=2SC2715-Y (SMD-Marking)	35	SOT-23		-2SC2715	
RY		Si-N	=2SC3898 (SMD-Marking)	35	SOT-23		-2SC3898	
RY		Si-P	=KTA1664-Y (SMD-Marking)	39	SOT-89		-KTA 1664	
RY		Si-N	=KTC3879-Y (SMD-Marking)	35	SOT-23		-KTC 3879	
RY 23	Sak	Z-Di	Avalanche, UR=200V, Uz=250...400V	31a			DO-14	
RY 24	Sak	Z-Di	Avalanche, UR=400V, Uz=400...450V	31a			DO-14	
<b>S</b>								
S		Si-N	=2SD1483 (SMD-Marking)	39	SOT-89		-2SD1483	
S 1		Si-Di	=1SS239 (SMD-Marking)	71(2,7mm)			+1SS239	
S 1(p)		Si-Di	=BBY 31 (SMD-Marking)	35	SOT-23		+BBY 31	
S 1		Si-N	=BSV 35A (SMD-Marking)	35(2mm)	SOT-323		+BSV 35A	
S-1.5-01...-10(FR)	Org	Si-Di	Rr, Uni, 100...1000V, 1...1.3A	31a	DO-14	BY 133	31a	BY 126...127, BY 133...134, 1N4002...07, ++
S 1 A60...A150	Shi	Si-Di	Rr, S, 600...1500V, 0.1A, <1.5µs	31a		BY 203/20	31a	BY 203/... RGP 01-..., SHG 1...1.5
s 1 A		Si-N	=SMBT 3904 (SMD-Marking)	35	SOT-23		+SMBT 3904	
S 1 A		Si-N	=SXT 3904 (SMD-Marking)	39	SOT-89		+SXT 3904	
S 1 A...M	Die	Si-Di	=G 1A...M: 0.6A, Uf<1.1V(0.6A)	71a(5mm)			BYG 20... BYG 21...	
s 1 B		Si-N	=SMBT 2222 (SMD-Marking)	35	SOT-23		+SMBT 2222	
S 1 B....		Si-Di	+S 1 B....			-S 1 B....		
s 1 C		Si-N	=SMBTA 20 (SMD-Marking)	35	SOT-23		+SMBTA 20	
s 1 D		Si-N	=SMBTA 42 (SMD-Marking)	35	SOT-23		+SMBTA 42	
S 1 D		Si-N	=SXTA 42 (SMD-Marking)	39	SOT-89		+SXTA 42	
s 1 E		Si-N	=SMBTA 43 (SMD-Marking)	35	SOT-23		+SMBTA 43	
S 1 E		Si-N	=SXTA 43 (SMD-Marking)	39	SOT-89		+SXTA 43	
s 1 G		Si-N	=SMBTA 06 (SMD-Marking)	35	SOT-23		+SMBTA 06	
S 1 G10...G80	Shi	Si-Di	Rr, Uni, 100...800V, 1A	31a	SOD-57	BY 133	31a	BY 126...127, BY 133...134, 1N4002...07, ++
S 1 G40Z...G80Z		Si-Di	=S 1G40...G80: contr.av.	31a	SOD-57			BYW 53...56, 1N4246...49, 1N5060...62
s 1 H		Si-N	=SMBTA 05 (SMD-Marking)	35	SOT-23		+SMBTA 05	
s 1 K		Si-N	=SMBT 6428 (SMD-Marking)	35	SOT-23		+SMBT 6428	
s 1 L		Si-N	=SMBT 6429 (SMD-Marking)	35	SOT-23		+SMBT 6429	
s 1 M		Si-N	=SMBTA 13 (SMD-Marking)	35	SOT-23		+SMBTA 13	
s 1 N		Si-N	=SMBTA 14 (SMD-Marking)	35	SOT-23		+SMBTA 14	
s 1 P		Si-N	=SMBT 2222A (SMD-Marking)	35	SOT-23		+SMBT 2222A	
S 1 P20...P200	Shi	Si-Di	Rr, S, 200...2000V, 0.1A, <1.5µs	31a	DO-14	BY 203/20	31a	BY 203/..., GP 10D...Y, RGP 01-..., ++
S 1 P20Z...P40Z		Si-Di	=S 1P20...P40: contr.av., 0.6A	31a	DO-14			BYW 52...56, 1N4245...49, 1N5060...62
S 1 R20...R150	Shi	Si-Di	Rr, S, 200...1500V, 0.1A, <1.5µs	31a	(7,5x40)	BY 203/20	31a	BAY 88...91, BY 203/..., RGP 01-..., ++
S 1 R20Z...R40Z		Si-Di	=S 1R20...R40: contr.av., 0.6A	31a	(7,5x40)			BYW 52...56, 1N4245...49, 1N5060...62
S 1 RA60...100	Shi	Si-Di	FRr, 600...1000V, 0.1A, <500ns	31a	(7,5x40)	BA 159	31a	BA 158...159, BY 204/..., BY 208/..., ++
S 1 RB10...RB60(Z)	Shi	Si-Br	Br Rr, 100...600V, 1A (Z=contr.av.)		(20x8x8mm)	(4x 1N4007)	31a	-
S 1 RBA10...60(Z)	Shi	Si-Br	BR Rr, 100...600V, 1A (Z=contr.av.)		(20x8x8mm)	(4x 1N4007)	31a	-
S 1 S3M	Shi	Si-Di	Schottky Rr, 30V, 1A, Uf<0,55V(1A)	31a	SOD-22	1N5822	31a	BYS 21-45, BYV 10-30, MBR 150, 1N5818
S 1 S4M	Shi	Si-Di	Schottky Rr, 40V, 1A, Uf<0,55V(1A)	31a	SOD-22	1N5822	31a	BYS 21-45, BYV 10-40, MBR 150, 1N5819
S 1 S6M	Shi	Si-Di	Schottky Rr, 60V, 1A, Uf<0,58V(1A)	31a	SOD-22			BYS 21-90, BYV 10-60, MBR 160, SB 160
s 1 V		Si-N-Darl	=SMBT 6427 (SMD-Marking)	35	SOT-23			+SMBT 6427
S 1 V-3		Si-St				Z-Diode 1.4V	31a	
S 1 VB10...VB40	Shi	Si-Br	Br Rr, 100...400V, 3.7A		(22x7mm)	(4x BY 255)	31a	-
S 1 WB10...WB60	Shi	Si-Br	Br Rr, 100...600V, 0.6A	4-DIP		B250C1500	8	A 0506...0580
S 1 YB10...YB60	Shi	Si-Br	Br Rr, 100...600V, 0.4A	4-DIP		B250C1500	8	-
S 2		Si-Di	=BBY 40 (SMD-Marking)	35	SOT-23		+BBY 40	
S 2		Si-N	=BFQ 31 (SMD-Marking)	35	SOT-23		+BFQ 31	
S 2		Si-N	=BSV 35 (SMD-Marking)	35(2mm)	SOT-323		+BSV 35	
S 2		Si-Di	=HSM 112WK (SMD-Marking)	35	SOT-23		+HSM 112WK	
S 2		Si-Di	=1SS242 (SMD-Marking)	71(2,7mm)	SOD-123		+1SS242	
S 2		C-Di	=1SS315 (SMD-Marking)	71(1,7mm)	SOD-323		+1SS315	
S 2		Si-P	=2SA813-S2 (SMD-Marking)	35	SOT-23		+2SA813	
s 2 A		Si-P	=SMBT 3906 (SMD-Marking)	35	SOT-23		+SMBT 3906	
S 2 A		Si-P	=SXT 3906 (SMD-Marking)	39	SOT-89		+SXT 3906	
s 2 B		Si-P	=SMBT 3907 (SMD-Marking)	35	SOT-23		+SMBT 3907	
s 2 C		Si-P	=SMBTA 70 (SMD-Marking)	35	SOT-23		+SMBTA 70	
s 2 D		Si-P	=SMBTA 92 (SMD-Marking)	35	SOT-23		+SMBTA 92	
S 2 D		Si-P	=SXTA 92 (SMD-Marking)	39	SOT-89		+SXTA 92	
s 2 E		Si-P	=SMBTA 93 (SMD-Marking)	35	SOT-23		+SMBTA 93	
S 2 E		Si-P	=SXTA 93 (SMD-Marking)	39	SOT-89		+SXTA 93	
s 2 F		Si-P	=SMBT 2907A (SMD-Marking)	35	SOT-23		+SMBT 2907A	
S 2 F		Si-P	=SXT 2907A (SMD-Marking)	39	SOT-89		+SXT2907A	
s 2 G		Si-P	=SMBTA 56 (SMD-Marking)	35	SOT-23		+SMBTA 56	
s 2 H		Si-P	=SMBTA 55 (SMD-Marking)	35	SOT-23		+SMBTA 55	
s 2 O		Si-P	=SMBT 5087 (SMD-Marking)	35	SOT-23		+SMBT 5087	
s 2 P		Si-P	=SMBT 5086 (SMD-Marking)	35	SOT-23		+SMBT 5086	
S 2 P		Si-N	=SXT 2222A (SMD-Marking)	39	SOT-89		+SXT2222A	
s 2 U		Si-P	=SMBTA 63 (SMD-Marking)	35	SOT-23		+SMBTA 63	
s 2 V		Si-P	=SMBTA 64 (SMD-Marking)	35	SOT-23		+SMBTA 64	
P 2 V		Si-P	=PZTA 64 (SMD-Marking)	-39°	SOT-223		+PZTA 64	
S 3		Si-Di	=1SS357 (SMD-Marking)	71(1,7mm)	SOD-323		+1SS357	
S 3		Si-Di	=1SS369 (SMD-Marking)	71(1,3mm)			+1SS369	
S 3		Si-P	=2SA813-S3 (SMD-Marking)	35	SOT-23		+2SA813	
S 3		Si-N	=BFQ 31R (SMD-Marking)	35	SOT-23		+BFQ 31R	
S 3		Si-N	=BSV 36 (SMD-Marking)	35(2mm)	SOT-323		+BSV 36	
S3 0		C-Di	=BB 804-0 (SMD-Marking)	35	SOT-23		+BB 804-0	
S3 1		C-Di	=BB 804-1 (SMD-Marking)	35	SOT-23		+BB 804-1	
S3 2		C-Di	=BB 804-2 (SMD-Marking)	35	SOT-23		+BB 804-2	
S3 3		C-Di	=BB 804-3 (SMD-Marking)	35	SOT-23		+BB 804-3	
S3 4		C-Di	=BB 804-4 (SMD-Marking)	35	SOT-23		+BB 804-4	
S 4		Si-Di	=1SS367 (SMD-Marking)	71(1,7mm)	SOD-323		+1SS367	
S 4		Si-Di	=1SS373 (SMD-Marking)	71(1,3mm)			+1SS373	
S 4		Si-P	=2SA813-S4 (SMD-Marking)	35	SOT-23		+2SA813	
S 4		Si-N	=2SC3361-S4 (SMD-Marking)	35	SOT-23		+2SC3361	
S 4		C-Di	=BBY 62 (SMD-Marking)	44	SOT-143		+BBY 62	